Rethinking Memory System Design
(for Data-Intensive Computing)

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August 29, 2018

NVMSA-RTCSA Joint Keynote Talk

SAFARI

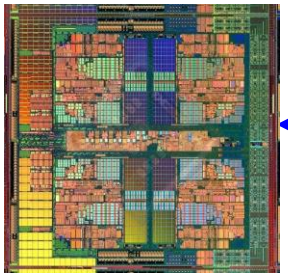
ETH zürich

Carnegie Mellon

Current Research Focus Areas

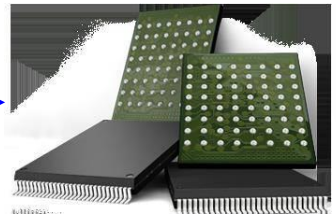
***Research Focus:* Computer architecture, HW/SW, bioinformatics, security**

- ***Memory and storage (DRAM, flash, emerging), interconnects***
- ***Heterogeneous & parallel systems, GPUs, systems for data analytics***
- ***System/architecture interaction, new execution models, new interfaces***
- ***Hardware security, energy efficiency, fault tolerance, performance***
- ***Genome sequence analysis & assembly algorithms and architectures***
- ***Biologically inspired systems & system design for bio/medicine***

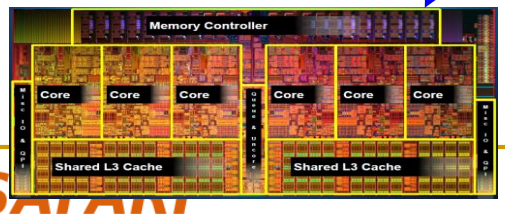


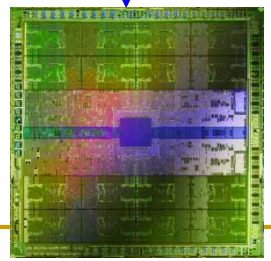
Heterogeneous Processors and Accelerators

Hybrid Main Memory



Persistent Memory/Storage





Graphics and Vision Processing

Broad research spanning apps, systems, logic with architecture at the center

Four Key Directions

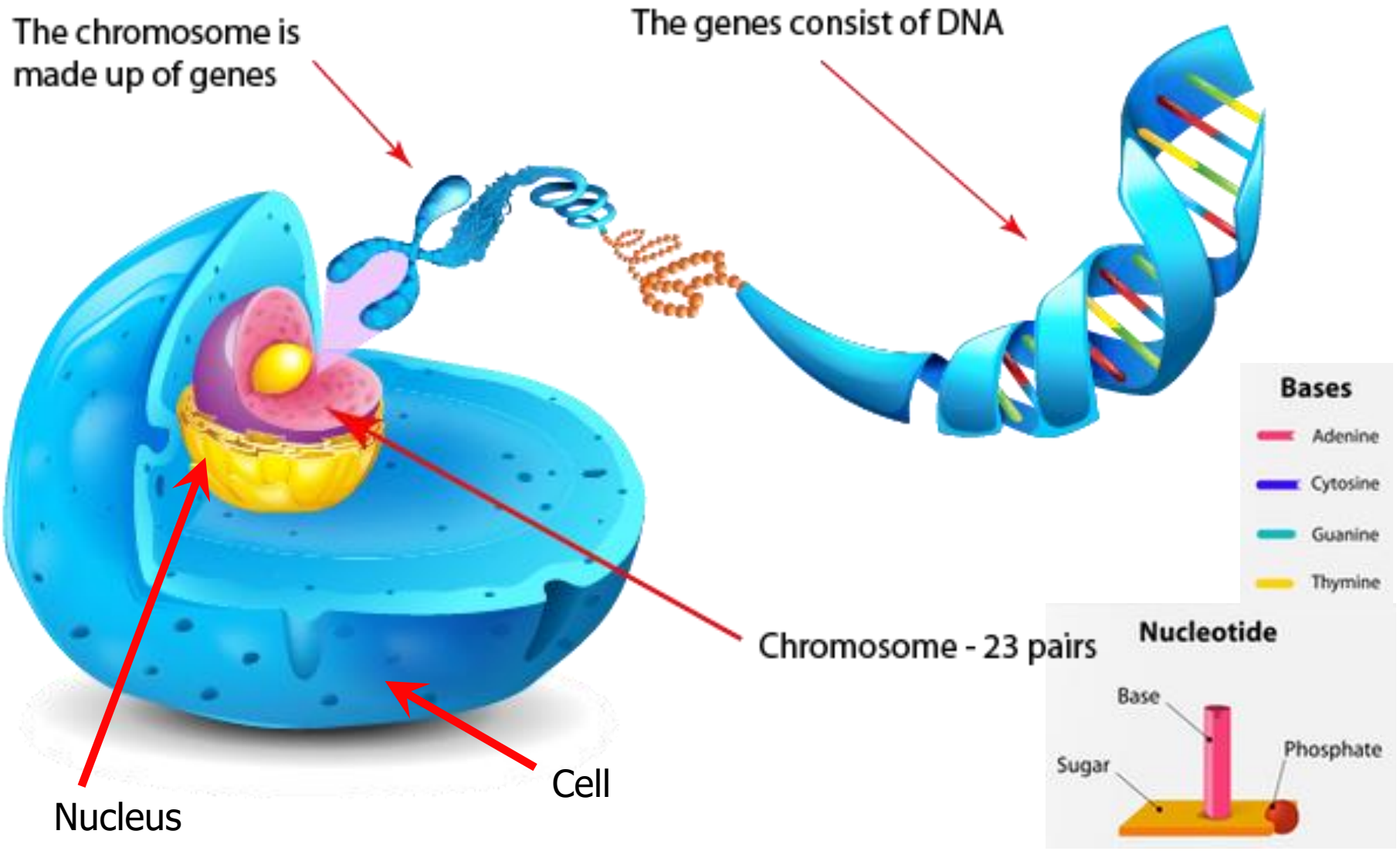
- Fundamentally Secure/Reliable/Safe Architectures
- Fundamentally Energy-Efficient Architectures
  - Memory-centric (Data-centric) Architectures
- Fundamentally Low-Latency Architectures
- Architectures for Genomics, Medicine, Health

A Motivating Detour: Genome Sequence Analysis

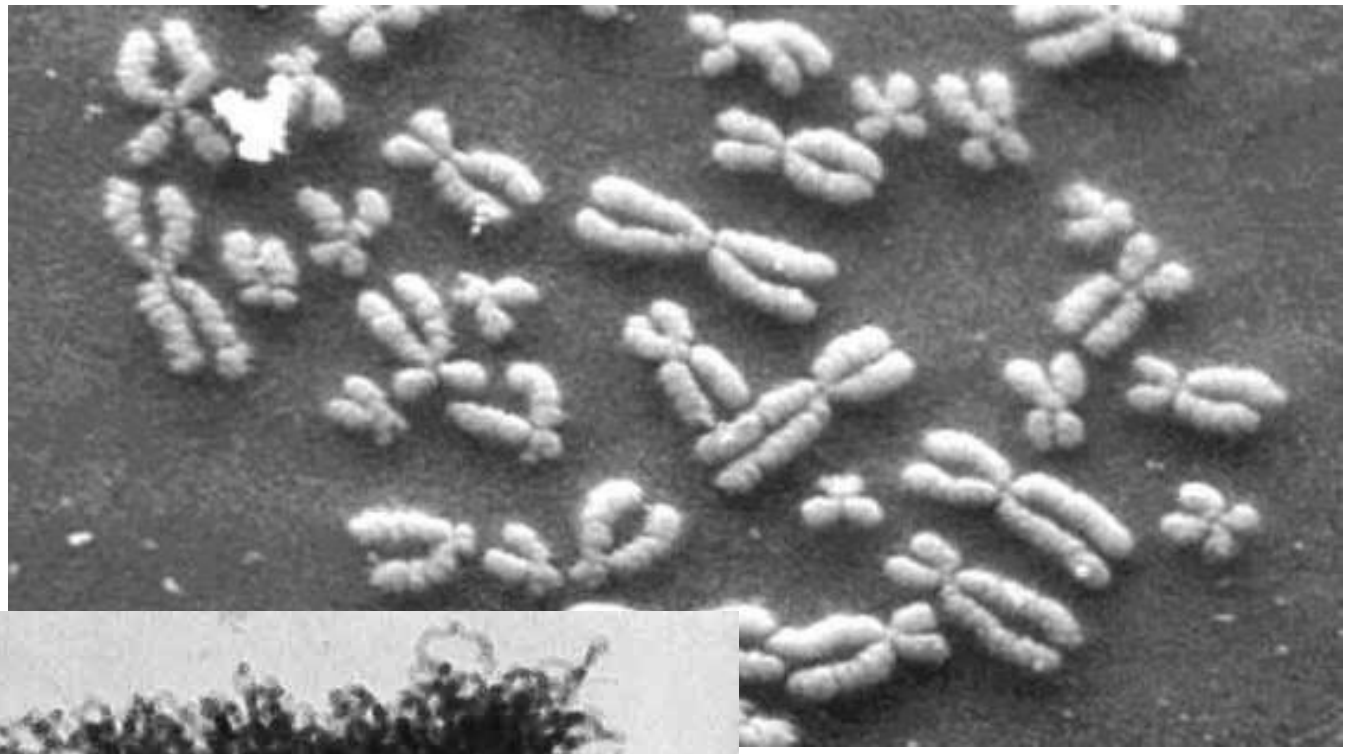
Our Dream

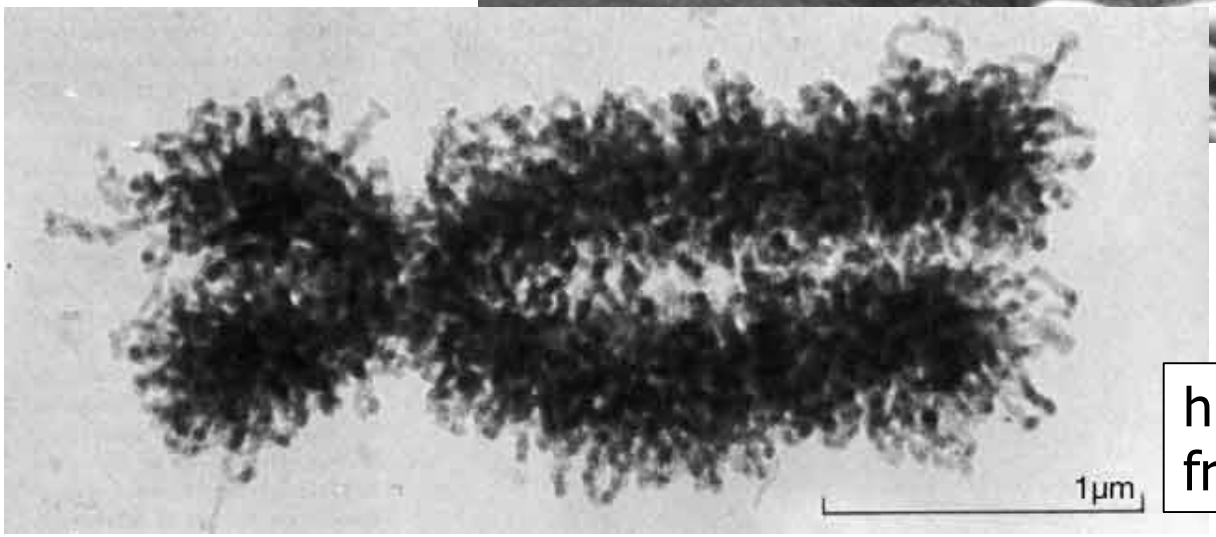
- An embedded device that can perform comprehensive genome analysis in real time (within a minute)
  - Which of these DNAs does this DNA segment match with?
  - What is the likely genetic disposition of this patient to this drug?
  - . . .

What Is a Genome Made Of?



DNA Under Electron Microscope





human chromosome #12
from HeLa's cell

DNA Sequencing

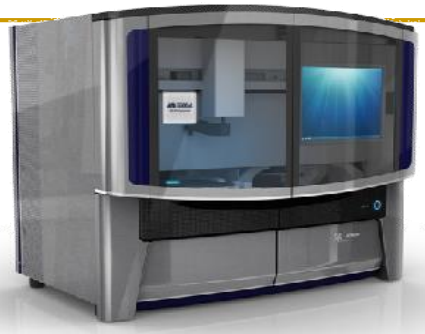
- Goal:
  - Find the complete sequence of A, C, G, T's in DNA.

- Challenge:
  - There is no machine that takes long DNA as an input, and gives the complete sequence as output
  - All sequencing machines chop DNA into pieces and identify relatively small pieces (but not how they fit together)

Untangling Yarn Balls & DNA Sequencing

Genome Sequencers

Roche/454



AB SOLiD

Illumina MiSeq

Complete Genomics

Oxford Nanopore MinION

Illumina HiSeq2000

Pacific Biosciences RS

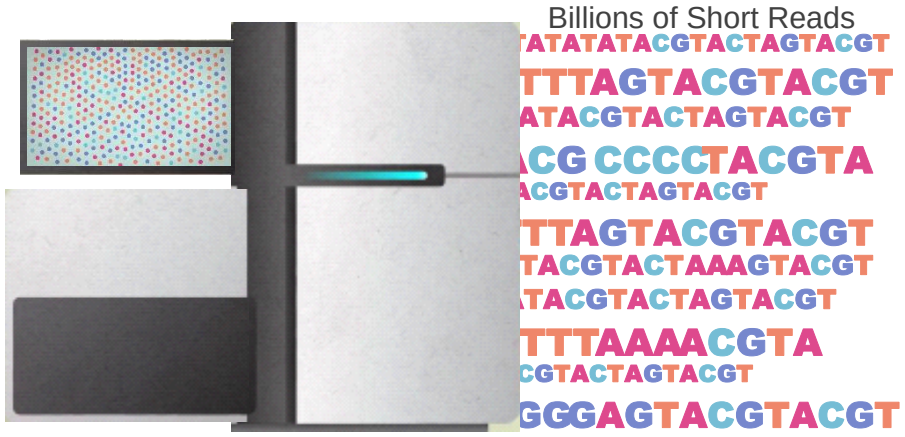
Illumina NovaSeq 6000

Oxford Nanopore GridION

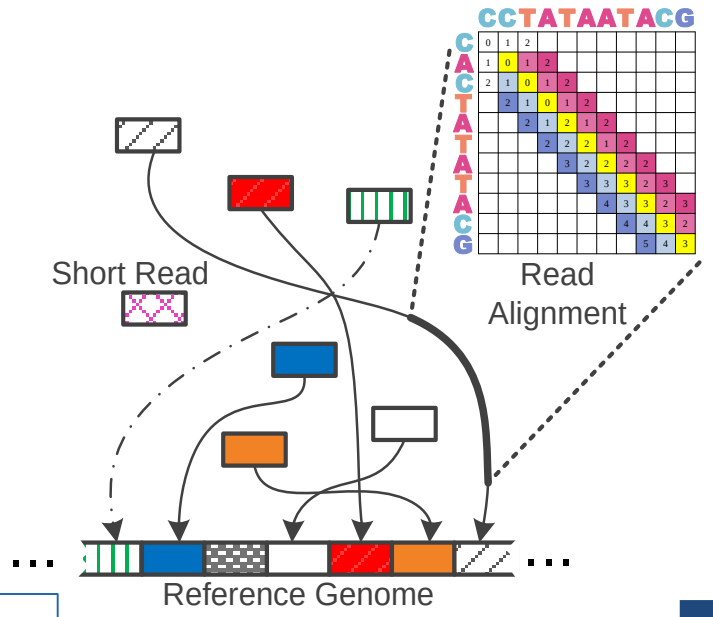
Ion Torrent PGM

Ion Torrent Proton

… and more! All produce data with different properties.



1 Sequencing



Read Mapping 2

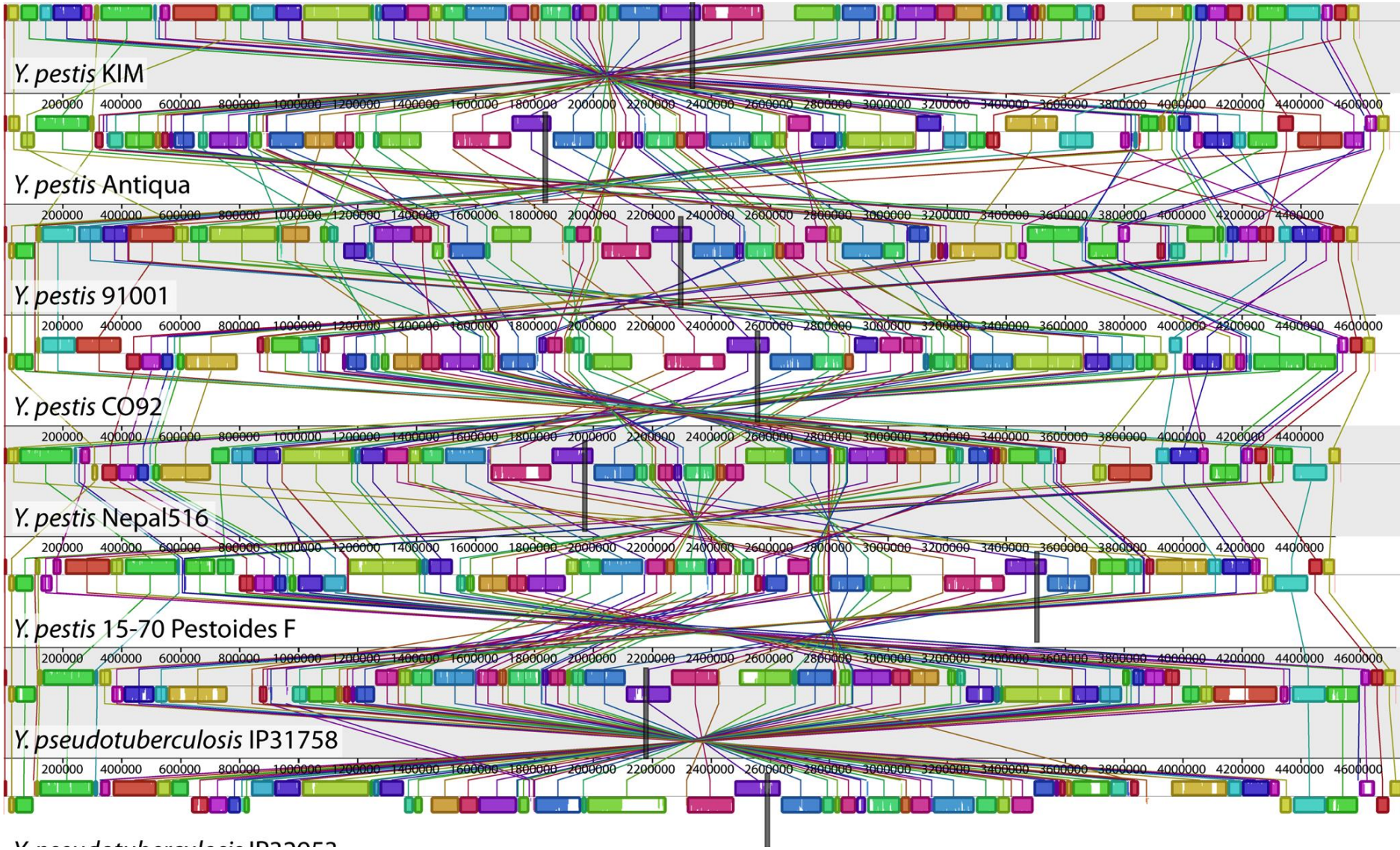
Genome Analysis

```
reference: TTTATCGCTTCCATGACGCAG
read1:       ATCGCATCC
read2:      TATCGCATC
read3:           CATCCATGA
read4:         CGCTTCCAT
read5:               CCATGACGC
read6:             TTCCATGAC
```

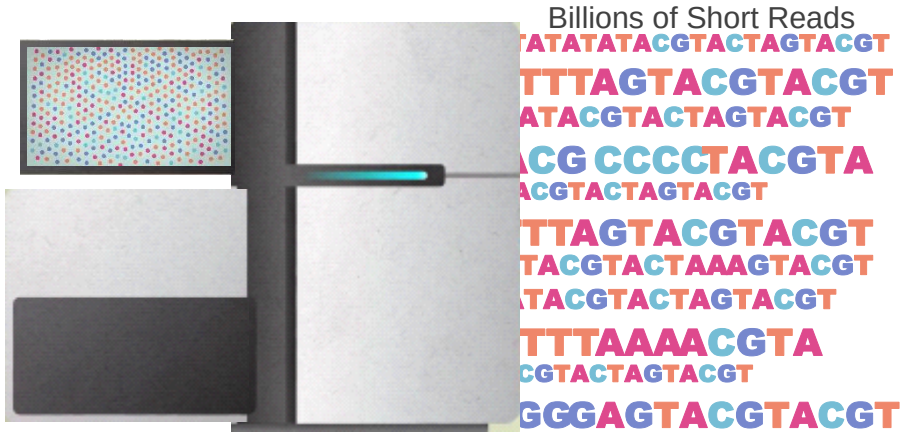
3 Variant Calling

Scientific Discovery 4

Genome Sequence Alignment: Example



Source: By Aaron E. Darling, István Miklós, Mark A. Ragan - Figure 1 from Darling AE, Miklós I, Ragan MA (2008). "Dynamics of Genome Rearrangement in Bacterial Populations". PLOS Genetics. DOI:10.1371/journal.pgen.1000128., CC BY 2.5, https://commons.wikimedia.org/w/index.php?curid=30550950



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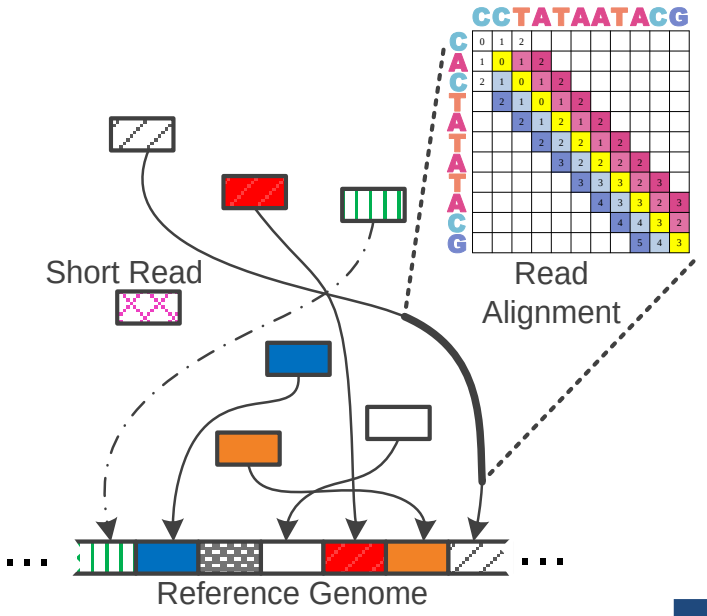


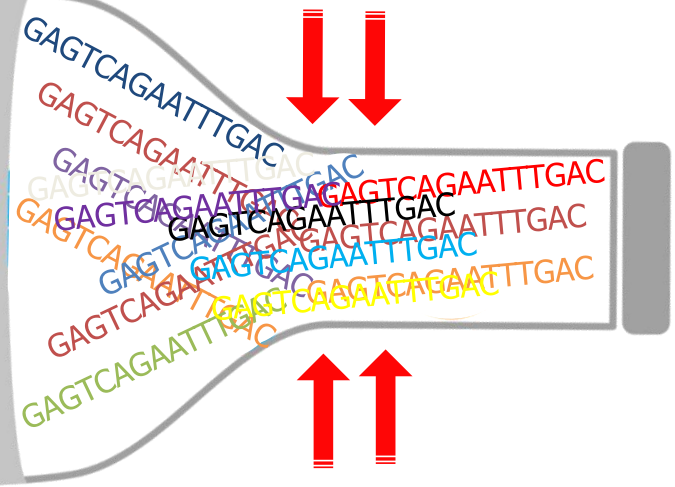
Read Mapping 2

Bottlenecked in Mapping!!

Illumina HiSeq4000

300 M

bases/min



on average

2 M

bases/min

(0.6%)

Hash Table Based Read Mappers

- + Guaranteed to find *all* mappings → sensitive
- + Can tolerate up to *e* errors

nature genetics

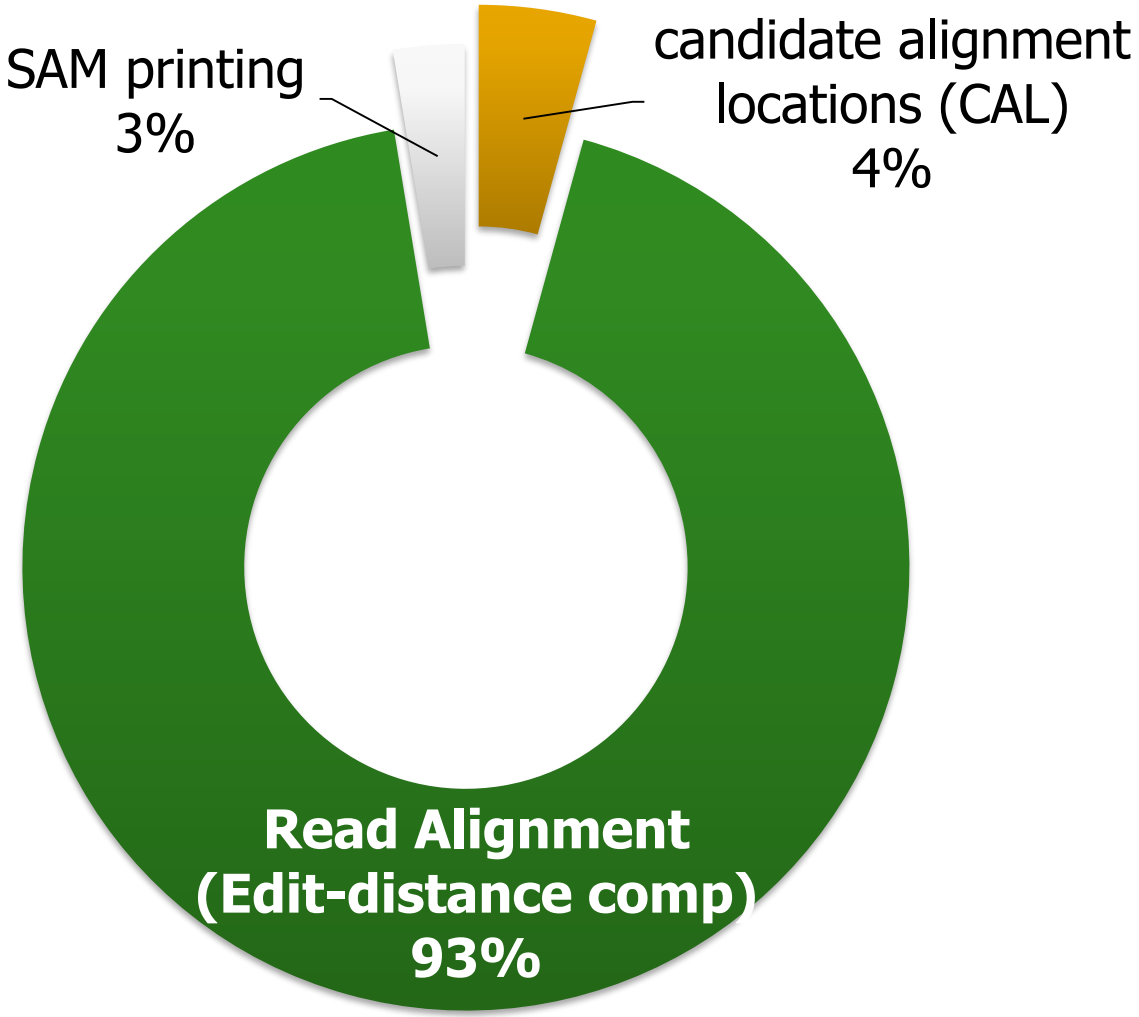
http://mrfast.sourceforge.net/

Personalized copy number and segmental duplication maps using next-generation sequencing

Can Alkan[1,2], Jeffrey M Kidd[1], Tomas Marques-Bonet[1,3], Gozde Aksay[1], Francesca Antonacci[1], Fereydoun Hormozdiari[4], Jacob O Kitzman[1], Carl Baker[1], Maika Malig[1], Onur Mutlu[5], S Cenk Sahinalp[4], Richard A Gibbs[6] & Evan E Eichler[1,2]

Alkan+, **"Personalized copy number and segmental duplication maps using next-generation sequencing"**, Nature Genetics 2009.

Read Mapping Execution Time Breakdown



Idea

Filter fast before you align

Minimize costly
"approximate string comparisons"

Our First Filter: Pure Software Approach

- Download source code and try for yourself
  - Download link to FastHASH

Xin *et al. BMC Genomics* 2013, **14**(Suppl 1):S13
http://www.biomedcentral.com/1471-2164/14/S1/S13

BMC Genomics

PROCEEDINGS Open Access

Accelerating read mapping with FastHASH

Hongyi Xin[1], Donghyuk Lee[1], Farhad Hormozdiari[2], Samihan Yedkar[1], Onur Mutlu[1*], Can Alkan[3*]

From The Eleventh Asia Pacific Bioinformatics Conference (APBC 2013)
Vancouver, Canada. 21-24 January 2013

Shifted Hamming Distance: SIMD Acceleration

Bioinformatics, 31(10), 2015, 1553–1560
doi: 10.1093/bioinformatics/btu856
Advance Access Publication Date: 10 January 2015
Original Paper

Sequence analysis

Shifted Hamming distance: a fast and accurate SIMD-friendly filter to accelerate alignment verification in read mapping

Hongyi Xin[1,*], John Greth[2], John Emmons[2], Gennady Pekhimenko[1], Carl Kingsford[3], Can Alkan[4,*] and Onur Mutlu[2,*]

Xin+, **"Shifted Hamming Distance: A Fast and Accurate SIMD-friendly Filter to Accelerate Alignment Verification in Read Mapping", Bioinformatics 2015.**

An Example Solution: GateKeeper

1 **High throughput DNA sequencing (HTS) technologies**

2 **Read Pre-Alignment Filtering**
Fast & Low False Positive Rate

3 **Read Alignment**
Slow & Zero False Positives

FPGA-Based Alignment Filtering

- Mohammed Alser, Hasan Hassan, Hongyi Xin, Oguz Ergin, Onur Mutlu, and Can Alkan
  "GateKeeper: A New Hardware Architecture for Accelerating Pre-Alignment in DNA Short Read Mapping"
  Bioinformatics, [published online, May 31], 2017.
  [Source Code]
  [Online link at Bioinformatics Journal]

GateKeeper: a new hardware architecture for accelerating pre-alignment in DNA short read mapping

Mohammed Alser ✉, Hasan Hassan, Hongyi Xin, Oğuz Ergin, Onur Mutlu ✉, Can Alkan ✉

Bioinformatics, Volume 33, Issue 21, 1 November 2017, Pages 3355–3363,
https://doi.org/10.1093/bioinformatics/btx342

Published: 31 May 2017 **Article history** ▾

DNA Read Mapping & Filtering

- Problem: **Heavily bottlenecked by Data Movement**
- GateKeeper FPGA performance limited by DRAM bandwidth [Alser+, Bioinformatics 2017]
- Ditto for SHD on SIMD [Xin+, Bioinformatics 2015]
- Solution: Processing-in-memory can alleviate the bottleneck
- However, we need to design mapping & filtering algorithms to fit processing-in-memory

In-Memory DNA Sequence Analysis

- Jeremie S. Kim, Damla Senol Cali, Hongyi Xin, Donghyuk Lee, Saugata Ghose, Mohammed Alser, Hasan Hassan, Oguz Ergin, Can Alkan, and Onur Mutlu, **"GRIM-Filter: Fast Seed Location Filtering in DNA Read Mapping Using Processing-in-Memory Technologies"**
  BMC Genomics, 2018.
  *Proceedings of the 16th Asia Pacific Bioinformatics Conference (**APBC**)*, Yokohama, Japan, January 2018.
  arxiv.org Version (pdf)

GRIM-Filter: Fast seed location filtering in DNA read mapping using processing-in-memory technologies

Jeremie S. Kim[1,6*], Damla Senol Cali[1], Hongyi Xin[2], Donghyuk Lee[3], Saugata Ghose[1], Mohammed Alser[4], Hasan Hassan[6], Oguz Ergin[5], Can Alkan[4*] and Onur Mutlu[6,1*]

From The Sixteenth Asia Pacific Bioinformatics Conference 2018
Yokohama, Japan. 15-17 January 2018

Quick Note: Key Principles and Results

- Two key principles:
  - Exploit the structure of the genome to minimize computation
  - Morph and exploit the structure of the underlying hardware to maximize performance and efficiency

- **Algorithm-architecture co-design** for DNA read mapping
  - **Speeds up** read mapping by **~200X (sometimes more)**
  - **Improves accuracy** of read mapping in the presence of errors

Xin et al., "Accelerating Read Mapping with FastHASH," BMC Genomics 2013.

Xin et al., "Shifted Hamming Distance: A Fast and Accurate SIMD-friendly Filter to Accelerate Alignment Verification in Read Mapping," Bioinformatics 2015.

Alser et al., "GateKeeper: A New Hardware Architecture for Accelerating Pre-Alignment in DNA Short Read Mapping," Bioinformatics 2017.

Kim et al., "Genome Read In-Memory (GRIM) Filter," BMC Genomics 2018.

New Genome Sequencing Technologies

Nanopore sequencing technology and tools for genome assembly: computational analysis of the current state, bottlenecks and future directions

Damla Senol Cali ✉, Jeremie S Kim, Saugata Ghose, Can Alkan, Onur Mutlu

Briefings in Bioinformatics, bby017, https://doi.org/10.1093/bib/bby017
Published: 02 April 2018 **Article history** ▾

Oxford Nanopore MinION

Senol Cali+, "**Nanopore Sequencing Technology and Tools for Genome Assembly: Computational Analysis of the Current State, Bottlenecks and Future Directions**," Briefings in Bioinformatics, 2018.
[Preliminary arxiv.org version]

Nanopore Genome Assembly Pipeline

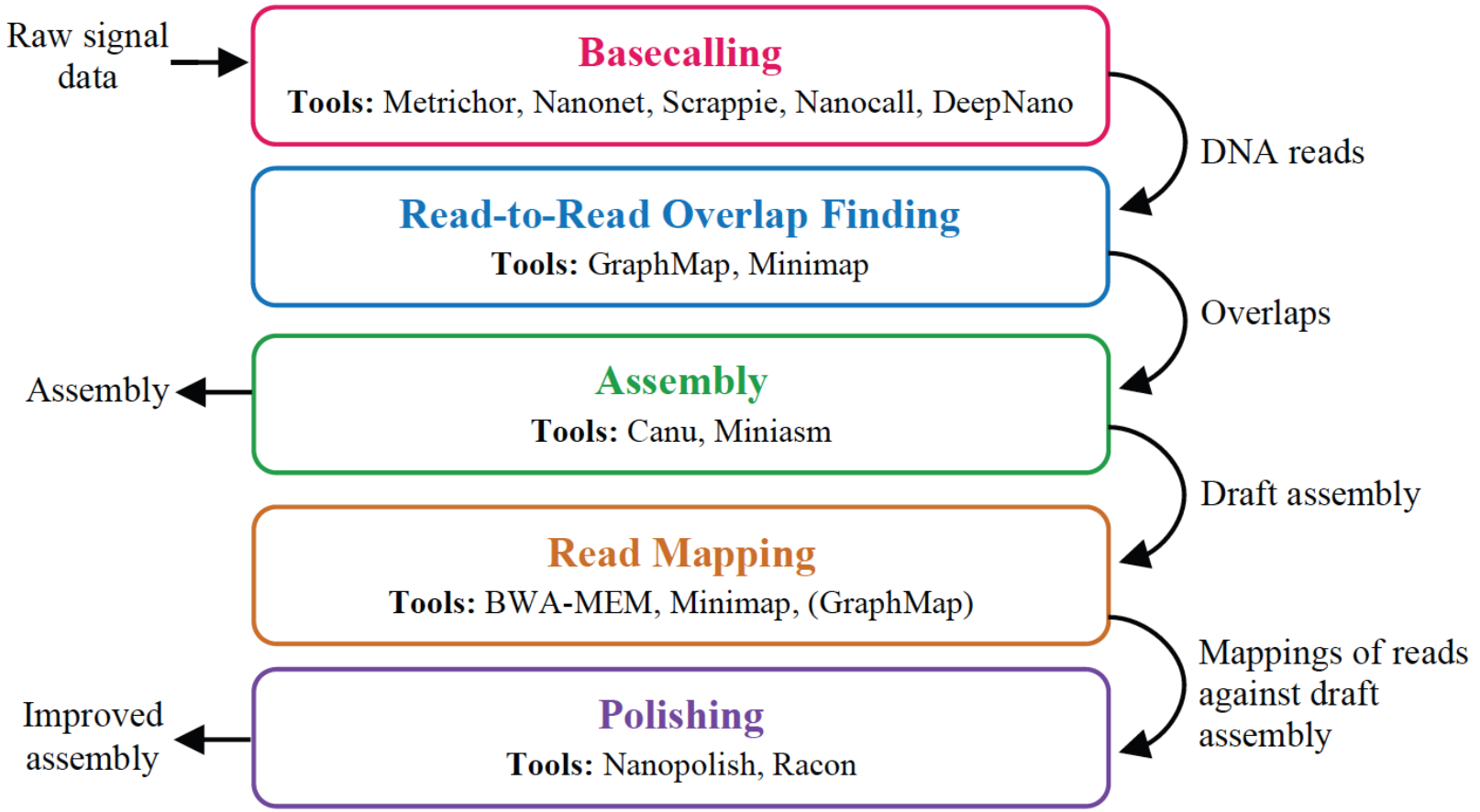


Figure 1. The analyzed genome assembly pipeline using nanopore sequence data, with its five steps and the associated tools for each step.

Senol Cali+, "**Nanopore Sequencing Technology and Tools for Genome Assembly,**" Briefings in Bioinformatics, 2018.

More on Genome Analysis: Another Talk

Accelerating Genome Analysis

A Primer on an Ongoing Journey

Onur Mutlu
omutlu@gmail.com
https://people.inf.ethz.ch/omutlu

May 21, 2018

HiCOMB-17 Keynote Talk

SAFARI

ETH zürich

Recall Our Dream

- An embedded device that can perform comprehensive genome analysis in real time (within a minute)

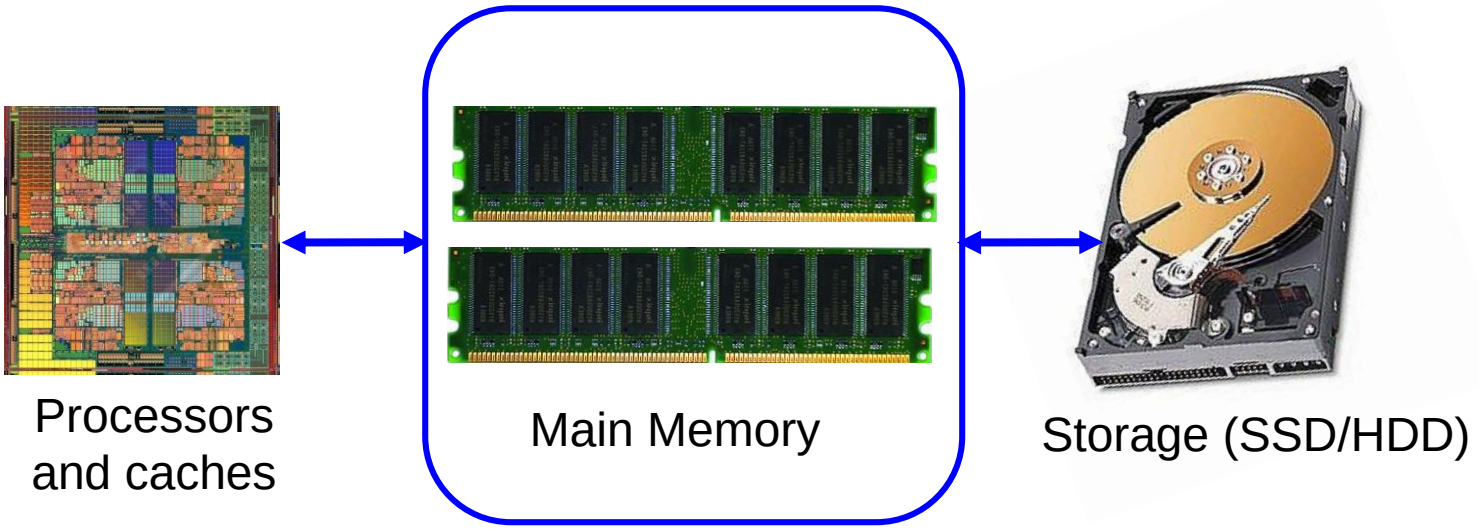
- Still a long ways to go
  - Energy efficiency
  - Performance (latency)
  - Security
  - Huge memory bottleneck

Four Key Directions

- Fundamentally Secure/Reliable/Safe Architectures
- Fundamentally Energy-Efficient Architectures
  - Memory-centric (Data-centric) Architectures
- Fundamentally Low-Latency Architectures
- Architectures for Genomics, Medicine, Health

Memory & Storage

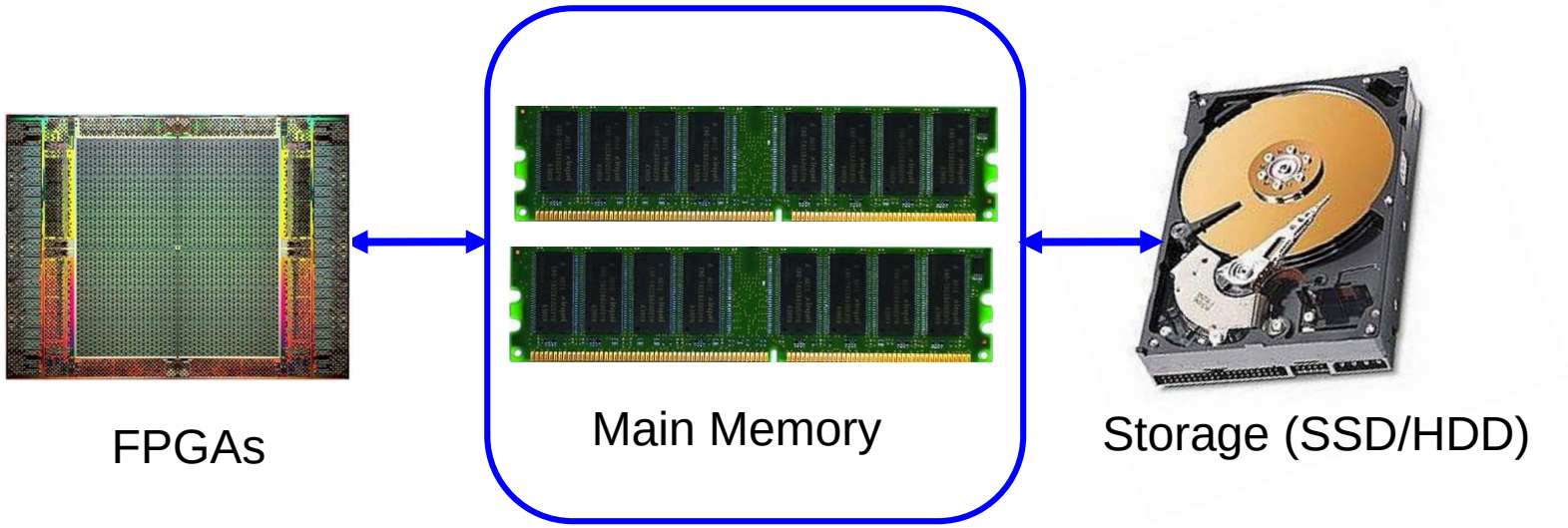
The Main Memory System



- Main memory is a critical component of all computing systems: server, mobile, embedded, desktop, sensor

- Main memory system must scale (in *size*, *technology*, *efficiency*, *cost*, and *management algorithms*) to maintain performance growth and technology scaling benefits

The Main Memory System



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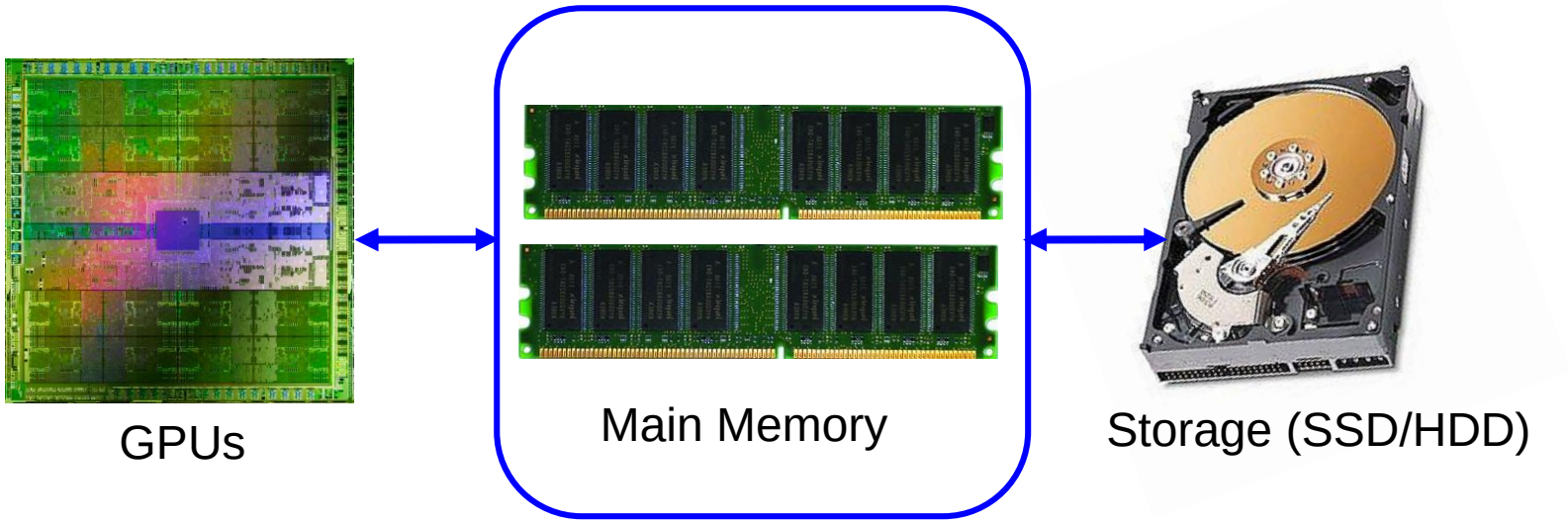

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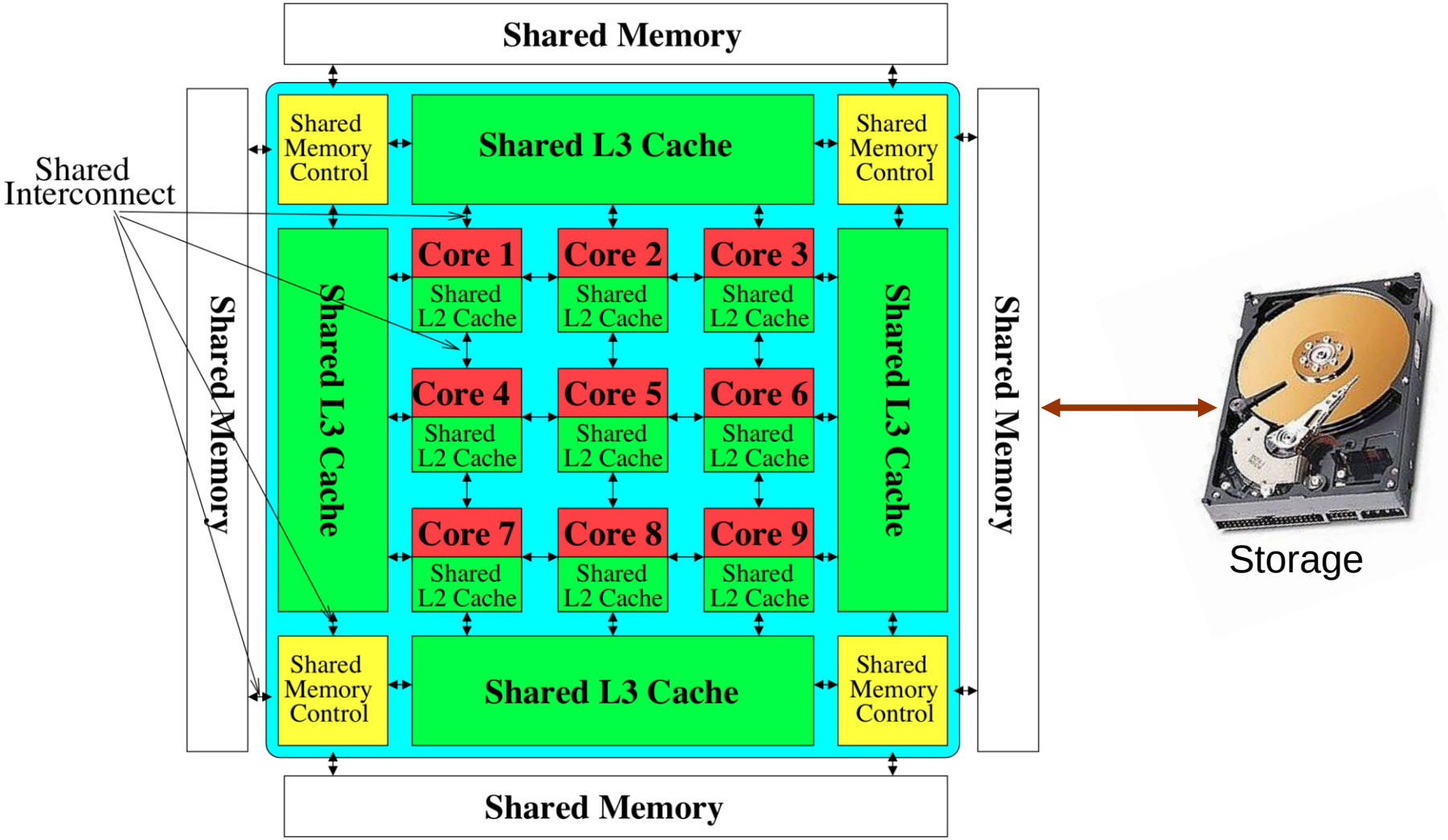
Memory System: A *Shared Resource* View



Most of the system is dedicated to storing and moving data

State of the Main Memory System

- Recent technology, architecture, and application trends
  - lead to new requirements
  - exacerbate old requirements

- DRAM and memory controllers, as we know them today, are (will be) unlikely to satisfy all requirements

- Some emerging non-volatile memory technologies (e.g., PCM) enable new opportunities: memory+storage merging

- We need to rethink the main memory system
  - to fix DRAM issues and enable emerging technologies
  - to satisfy all requirements

Agenda

- Major Trends Affecting Main Memory
- Key Challenges and Solution Directions
  - Robustness: Reliability and Security
  - Energy and Performance: In-Memory Computation
  - Low Latency/Energy and Latency/Energy/Reliability Tradeoffs
  - Scalability and More: Enabling Emerging Technologies
- Solution Principles
- Concluding Remarks

Major Trends Affecting Main Memory (I)

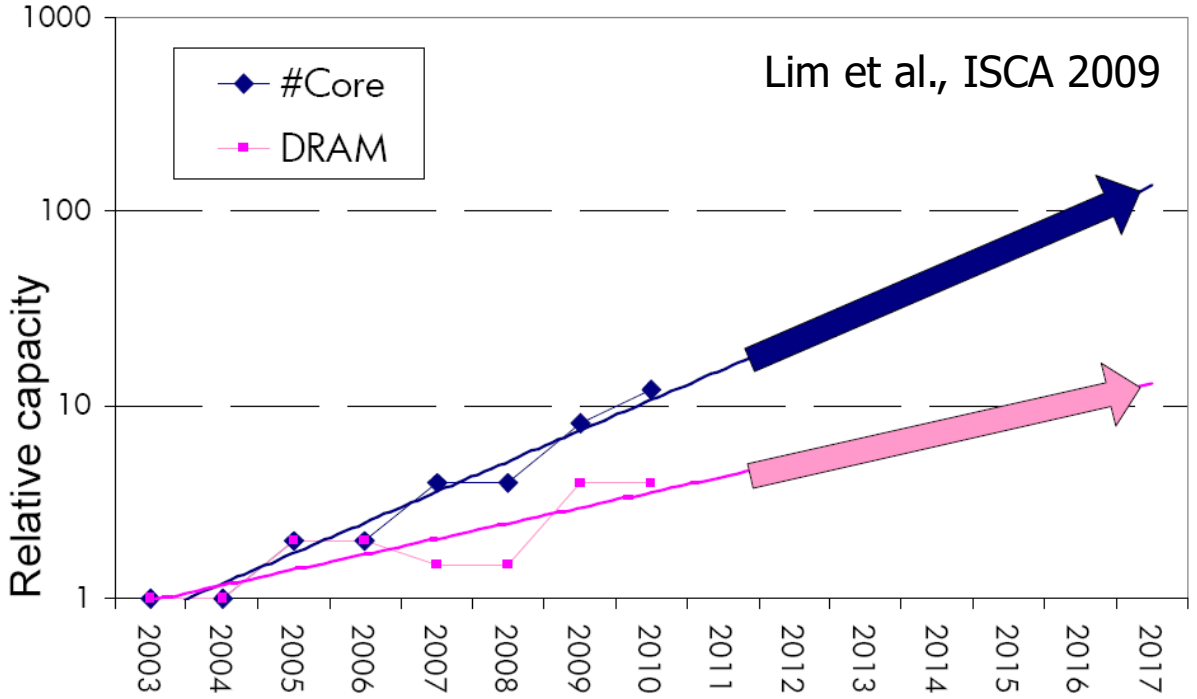
- Need for main memory capacity, bandwidth, QoS increasing
- Main memory energy/power is a key system design concern
- DRAM technology scaling is ending

Major Trends Affecting Main Memory (II)

- Need for main memory capacity, bandwidth, QoS increasing
  - Multi-core: increasing number of cores/agents
  - Data-intensive applications: increasing demand/hunger for data
  - Consolidation: cloud computing, GPUs, mobile, heterogeneity
- Main memory energy/power is a key system design concern
- DRAM technology scaling is ending

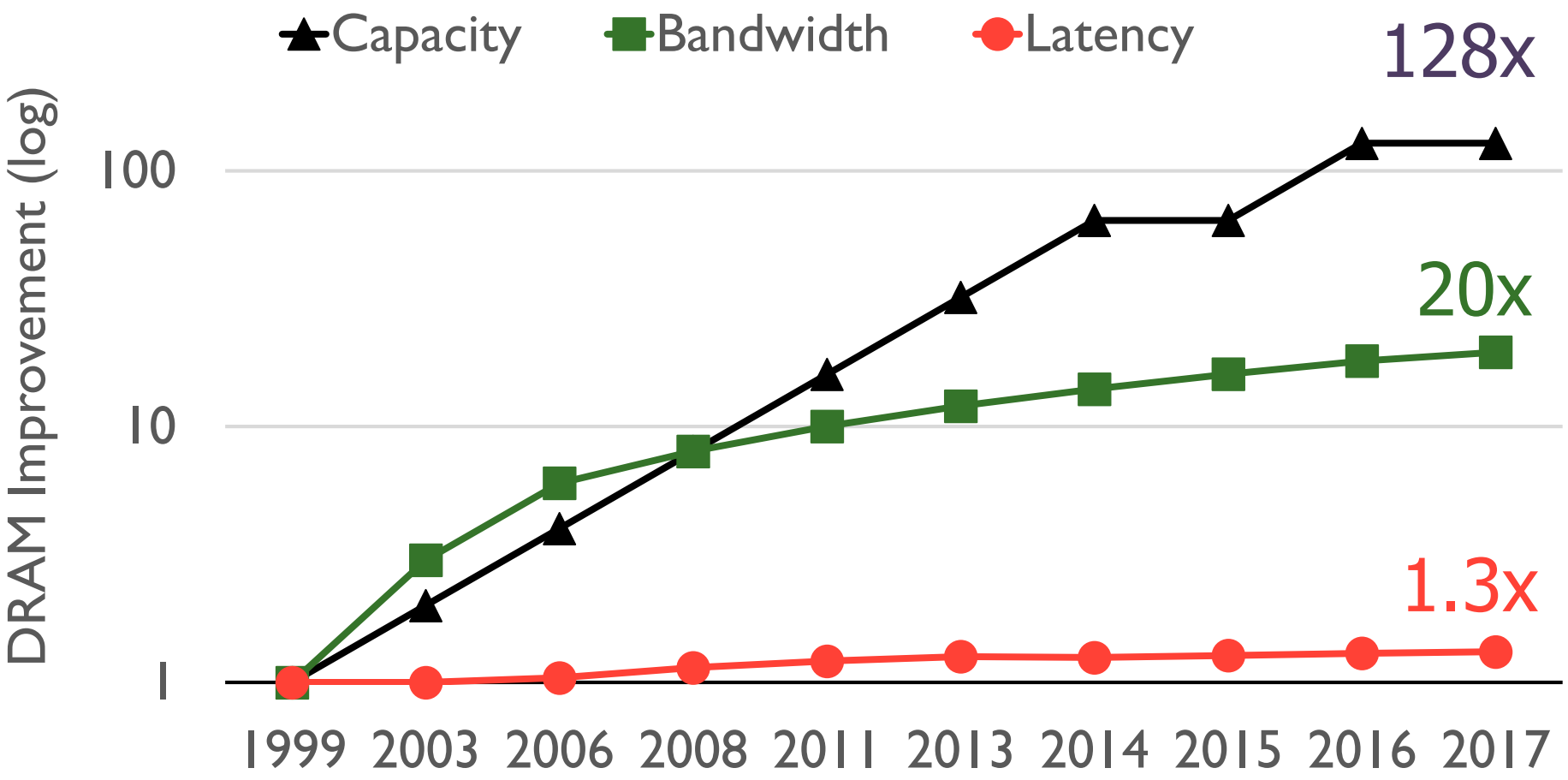
Example: The Memory Capacity Gap

Core count doubling ~ every 2 years
DRAM DIMM capacity doubling ~ every 3 years



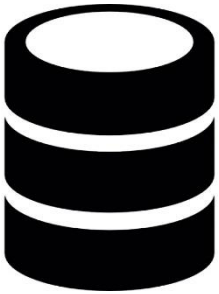
- *Memory capacity per core* expected to drop by 30% every two years
- Trends worse for *memory bandwidth per core*!

DRAM Capacity, Bandwidth, Latency Trends



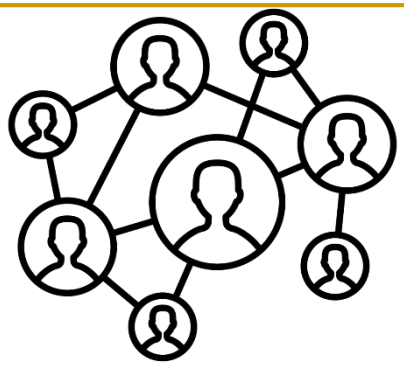
Memory latency remains almost constant

DRAM Latency Is Critical for Performance



In-memory Databases

[Mao+, EuroSys'12;
Clapp+ (**Intel**), IISWC'15]

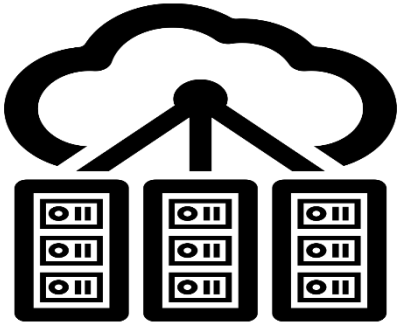


Graph/Tree Processing

[Xu+, IISWC'12; Umuroglu+, FPL'15]

In-Memory Data Analytics

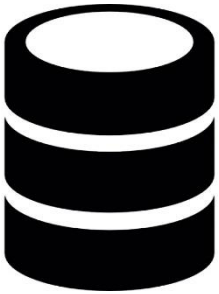
[Clapp+ (**Intel**), IISWC'15;
Awan+, BDCloud'15]



Datacenter Workloads

[Kanev+ (**Google**), ISCA'15]

DRAM Latency Is Critical for Performance



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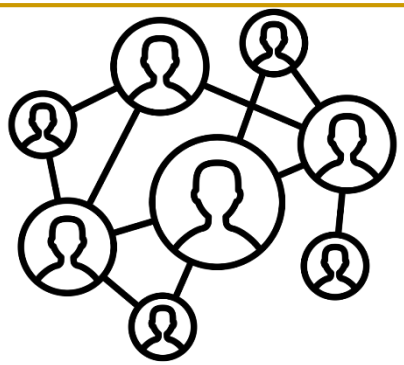
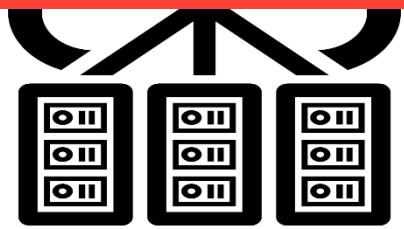


Graph/Tree Processing

Long memory latency → performance bottleneck

In-Memory Data Analytics

[Clapp+ (**Intel**), IISWC'15; Awan+, BDCloud'15]



Datacenter Workloads

[Kanev+ (**Google**), ISCA'15]

Major Trends Affecting Main Memory (III)

- Need for main memory capacity, bandwidth, QoS increasing

- Main memory energy/power is a key system design concern
  - ~40-50% energy spent in off-chip memory hierarchy [Lefurgy, IEEE Computer'03] >40% power in DRAM [Ware, HPCA'10][Paul,ISCA'15]
  - DRAM consumes power even when not used (periodic refresh)

- DRAM technology scaling is ending

Major Trends Affecting Main Memory (IV)

- Need for main memory capacity, bandwidth, QoS increasing

- Main memory energy/power is a key system design concern

- DRAM technology scaling is ending
  - ITRS projects DRAM will not scale easily below X nm
  - Scaling has provided many benefits:
    - higher capacity (density), lower cost, lower energy

Major Trends Affecting Main Memory (V)

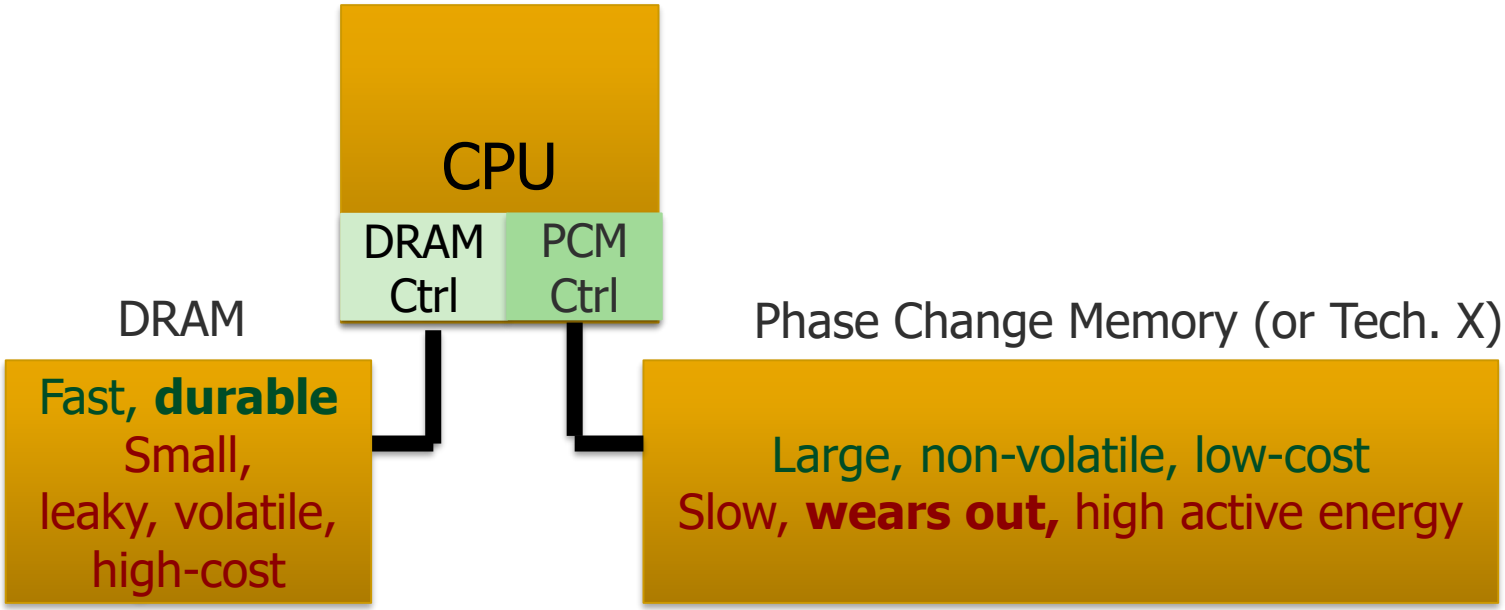
- DRAM scaling has already become increasingly difficult
  - Increasing cell leakage current, reduced cell reliability, increasing manufacturing difficulties [Kim+ ISCA 2014], [Liu+ ISCA 2013], [Mutlu IMW 2013], [Mutlu DATE 2017]
  - **Difficult to significantly improve capacity, energy**
- **Emerging memory technologies** are promising

Major Trends Affecting Main Memory (V)

- DRAM scaling has already become increasingly difficult
  - Increasing cell leakage current, reduced cell reliability, increasing manufacturing difficulties [Kim+ ISCA 2014], [Liu+ ISCA 2013], [Mutlu IMW 2013], [Mutlu DATE 2017]
  - **Difficult to significantly improve capacity, energy**
- **Emerging memory technologies** are promising

3D-Stacked DRAM	higher bandwidth	smaller capacity
Reduced-Latency DRAM (e.g., RL/TL-DRAM, FLY-RAM)	lower latency	higher cost
Low-Power DRAM (e.g., LPDDR3, LPDDR4, Voltron)	lower power	higher latency higher cost
Non-Volatile Memory (NVM) (e.g., PCM, STTRAM, ReRAM, 3D Xpoint)	larger capacity	higher latency higher dynamic power lower endurance

Major Trend: Hybrid Main Memory



Hardware/software manage data allocation and movement
to achieve the best of multiple technologies

Meza+, "Enabling Efficient and Scalable Hybrid Memories," IEEE Comp. Arch. Letters, 2012.

Yoon+, "Row Buffer Locality Aware Caching Policies for Hybrid Memories," ICCD 2012 Best Paper Award.

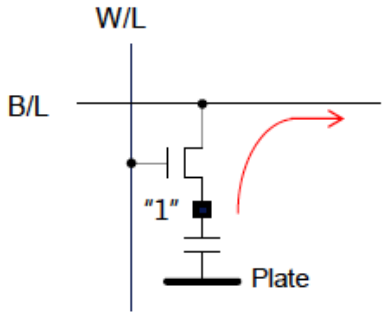
One Foreshadowing

Main Memory Needs Intelligent Controllers

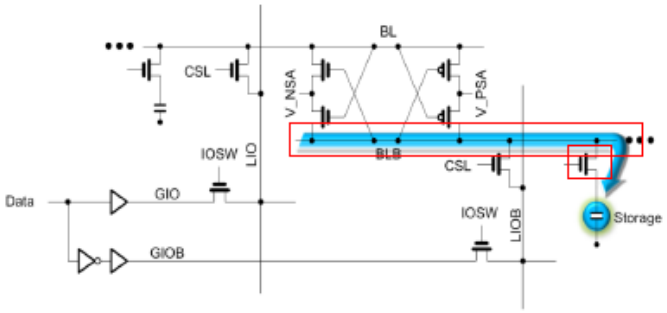
Industry Is Writing Papers About It, Too

DRAM Process Scaling Challenges

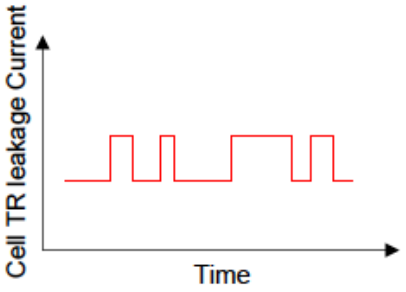
- **Refresh**
  - Difficult to build high-aspect ratio cell capacitors decreasing cell capacitance
  - Leakage current of cell access transistors increasing
- **tWR**
  - Contact resistance between the cell capacitor and access transistor increasing
  - On-current of the cell access transistor decreasing
  - Bit-line resistance increasing
- **VRT**
  - Occurring more frequently with cell capacitance decreasing



Refresh



tWR



VRT

Call for Intelligent Memory Controllers

DRAM Process Scaling Challenges

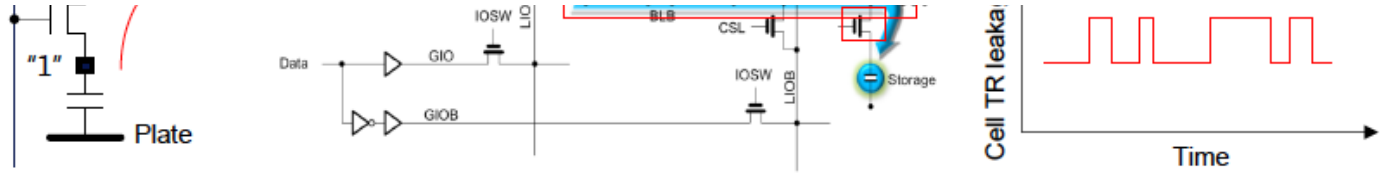
- **Refresh**
  - Difficult to build high-aspect ratio cell capacitors decreasing cell capacitance

THE MEMORY FORUM 2014

Co-Architecting Controllers and DRAM to Enhance DRAM Process Scaling

Uksong Kang, Hak-soo Yu, Churoo Park, *Hongzhong Zheng,
**John Halbert, **Kuljit Bains, SeongJin Jang, and Joo Sun Choi

*Samsung Electronics, Hwasung, Korea / *Samsung Electronics, San Jose / **Intel*



Refresh **tWR** **VRT**

Agenda

- Major Trends Affecting Main Memory
- Key Challenges and Solution Directions
  - Robustness: Reliability and Security
  - Energy and Performance: In-Memory Computation
  - Low Latency/Energy and Latency/Energy/Reliability Tradeoffs
  - Scalability and More: Enabling Emerging Technologies
- Solution Principles
- Concluding Remarks

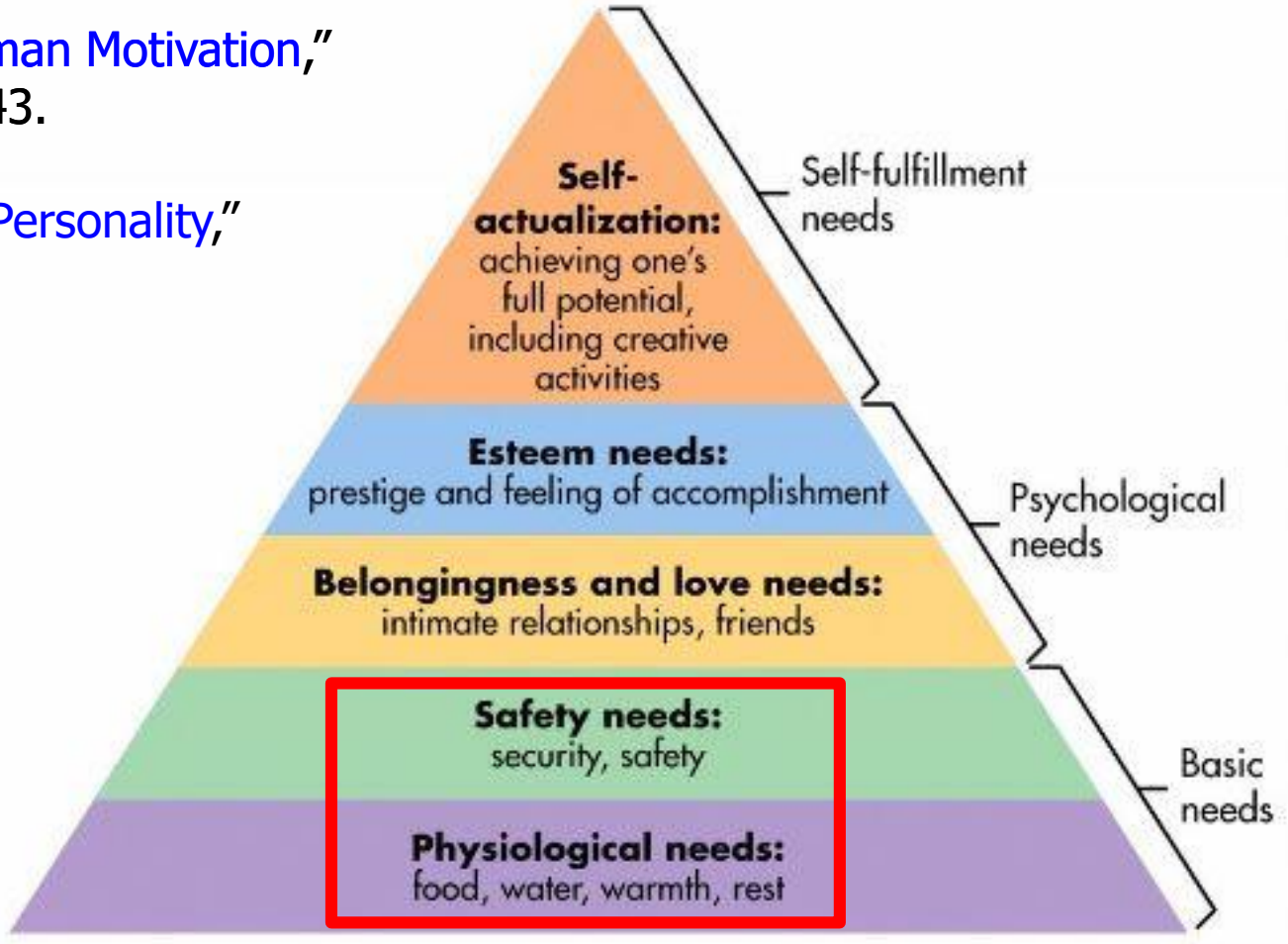
Four Key Issues in Future Platforms

- Fundamentally Secure/Reliable/Safe Architectures
- Fundamentally Energy-Efficient Architectures
  - Memory-centric (Data-centric) Architectures
- Fundamentally Low-Latency Architectures
- Architectures for Genomics, Medicine, Health

Maslow's (Human) Hierarchy of Needs

Maslow, "A Theory of Human Motivation," Psychological Review, 1943.

Maslow, "Motivation and Personality," Book, 1954-1970.



- We need to start with reliability and security...

Source: https://www.simplypsychology.org/maslow.html

Source: By User:Factoryjoe - Mazlow's Hierarchy of Needs.svg, CC BY-SA 3.0, https://commons.wikimedia.org/w/index.php?curid=7964065

How Reliable/Secure/Safe is This Bridge?

Source: http://www.technologystudent.com/struct1/tacom1.png

Collapse of the "Galloping Gertie"

Source: AP
http://www.wsdot.wa.gov/tnbhistory/connections/connections3.htm

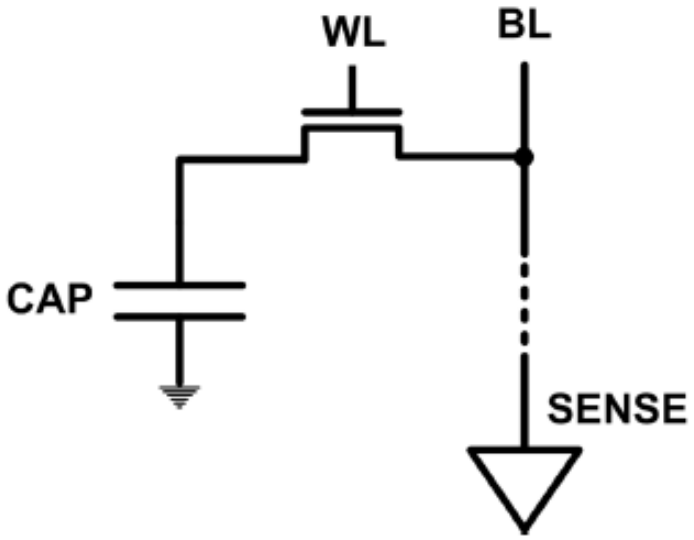
How Secure Are These People?

Security is about preventing unforeseen consequences

Source: https://s-media-cache-ak0.pinimg.com/originals/48/09/54/4809543a9c7700246a0cf8acdae27abf.jpg

The DRAM Scaling Problem

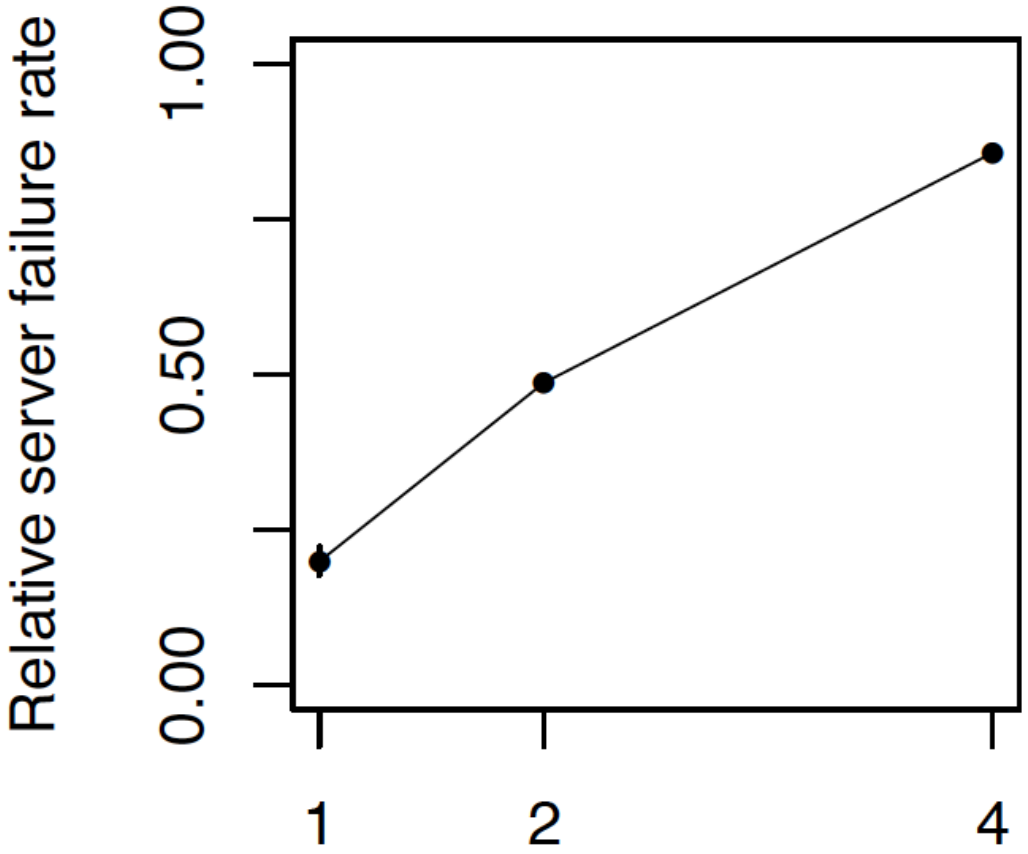
- DRAM stores charge in a capacitor (charge-based memory)
  - Capacitor must be large enough for reliable sensing
  - Access transistor should be large enough for low leakage and high retention time
  - Scaling beyond 40-35nm (2013) is challenging [ITRS, 2009]



- DRAM capacity, cost, and energy/power hard to scale

As Memory Scales, It Becomes Unreliable

- Data from all of Facebook's servers worldwide
- Meza+, "Revisiting Memory Errors in Large-Scale Production Data Centers," DSN'15.

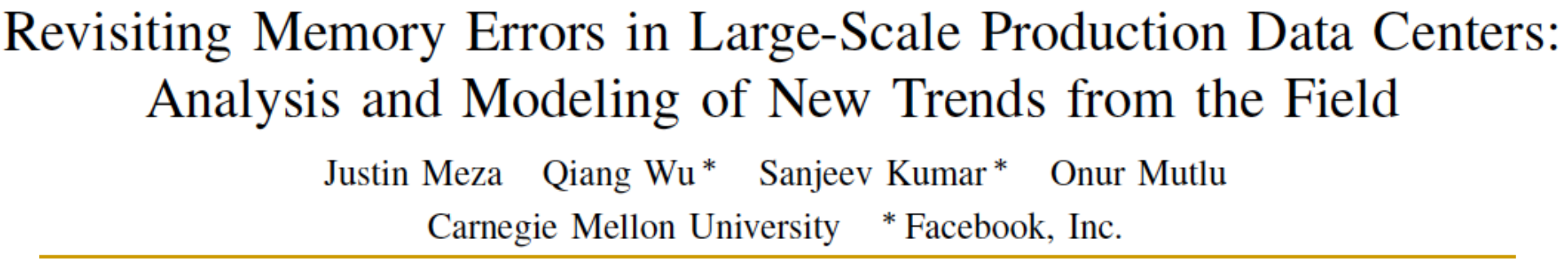


Intuition: quadratic increase in capacity

Large-Scale Failure Analysis of DRAM Chips

- Analysis and modeling of memory errors found in all of Facebook's server fleet

- Justin Meza, Qiang Wu, Sanjeev Kumar, and Onur Mutlu, **"Revisiting Memory Errors in Large-Scale Production Data Centers: Analysis and Modeling of New Trends from the Field"** *Proceedings of the 45th Annual IEEE/IFIP International Conference on Dependable Systems and Networks (**DSN**)*, Rio de Janeiro, Brazil, June 2015.
  [Slides (pptx) (pdf)] [DRAM Error Model]


Revisiting Memory Errors in Large-Scale Production Data Centers: Analysis and Modeling of New Trends from the Field

Justin Meza Qiang Wu * Sanjeev Kumar * Onur Mutlu

Carnegie Mellon University * Facebook, Inc.

Infrastructures to Understand Such Issues

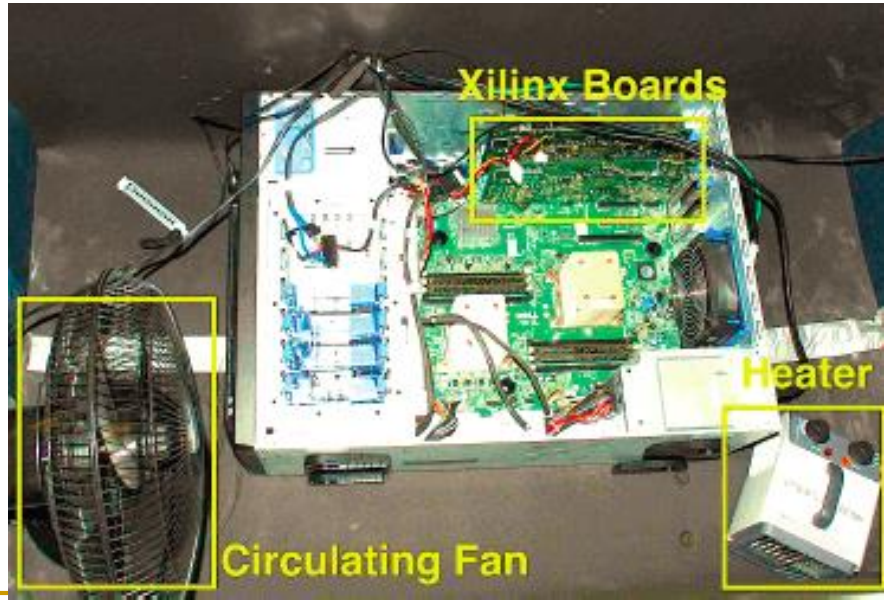
Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors (Kim et al., ISCA 2014)

Adaptive-Latency DRAM: Optimizing DRAM Timing for the Common-Case (Lee et al., HPCA 2015)

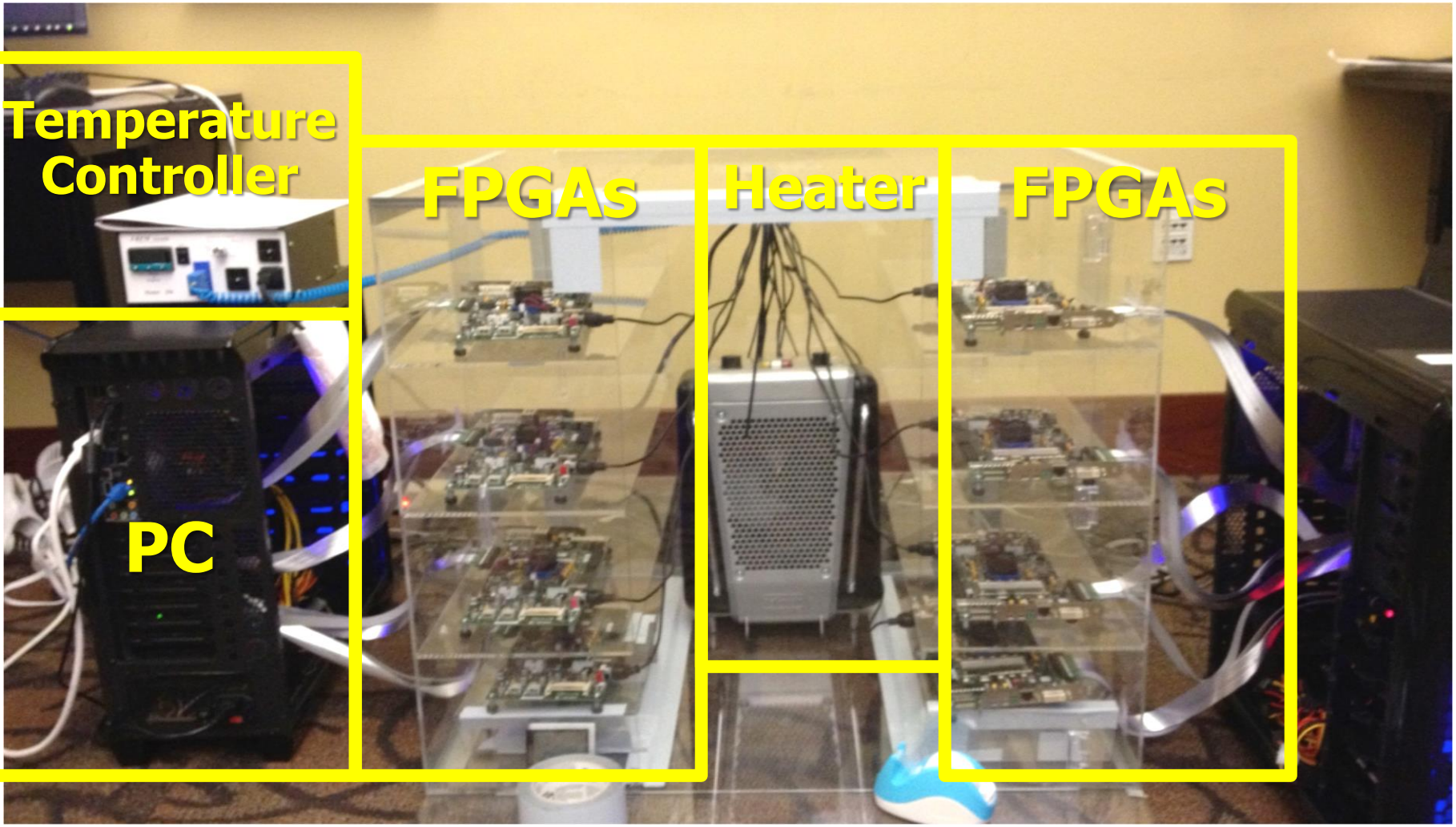
AVATAR: A Variable-Retention-Time (VRT) Aware Refresh for DRAM Systems (Qureshi et al., DSN 2015)

An Experimental Study of Data Retention Behavior in Modern DRAM Devices: Implications for Retention Time Profiling Mechanisms (Liu et al., ISCA 2013)

The Efficacy of Error Mitigation Techniques for DRAM Retention Failures: A Comparative Experimental Study (Khan et al., SIGMETRICS 2014)



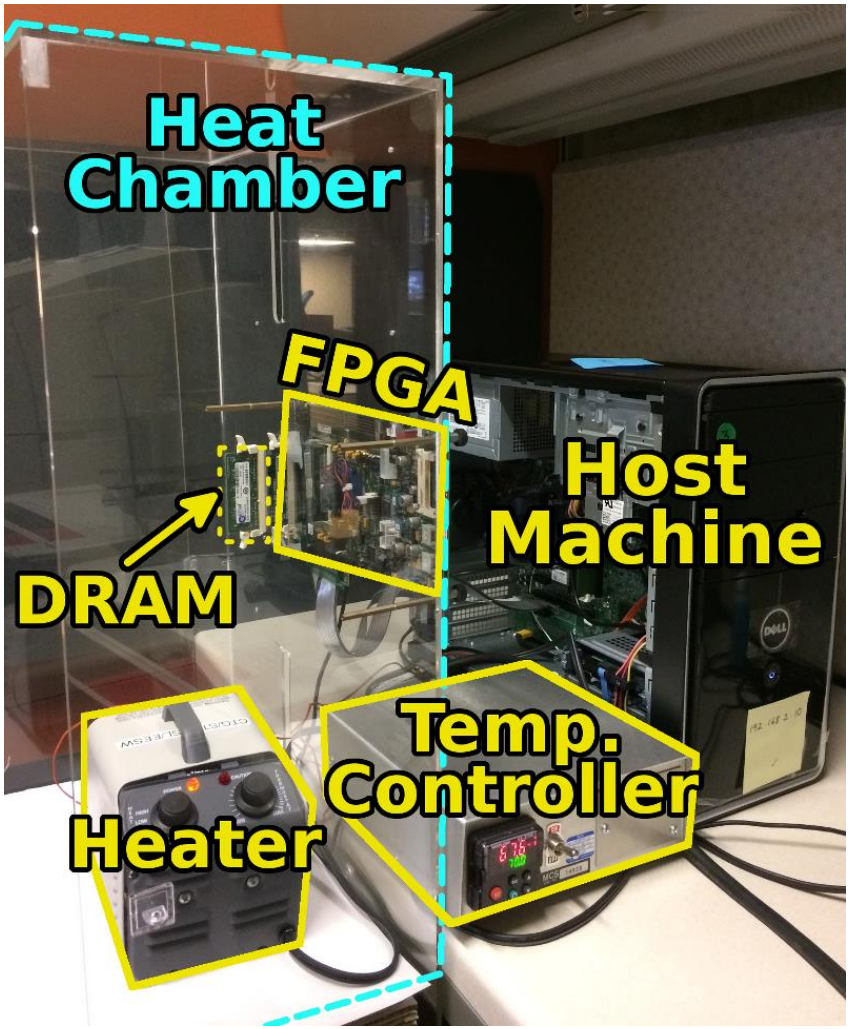
Infrastructures to Understand Such Issues



Kim+, "Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors," ISCA 2014.

SoftMC: Open Source DRAM Infrastructure

- Hasan Hassan et al., "**SoftMC: A Flexible and Practical Open-Source Infrastructure for Enabling Experimental DRAM Studies**," HPCA 2017.



- **Flexible**
- **Easy to Use (C++ API)**
- **Open-source**

  github.com/CMU-SAFARI/SoftMC

SoftMC

- https://github.com/CMU-SAFARI/SoftMC

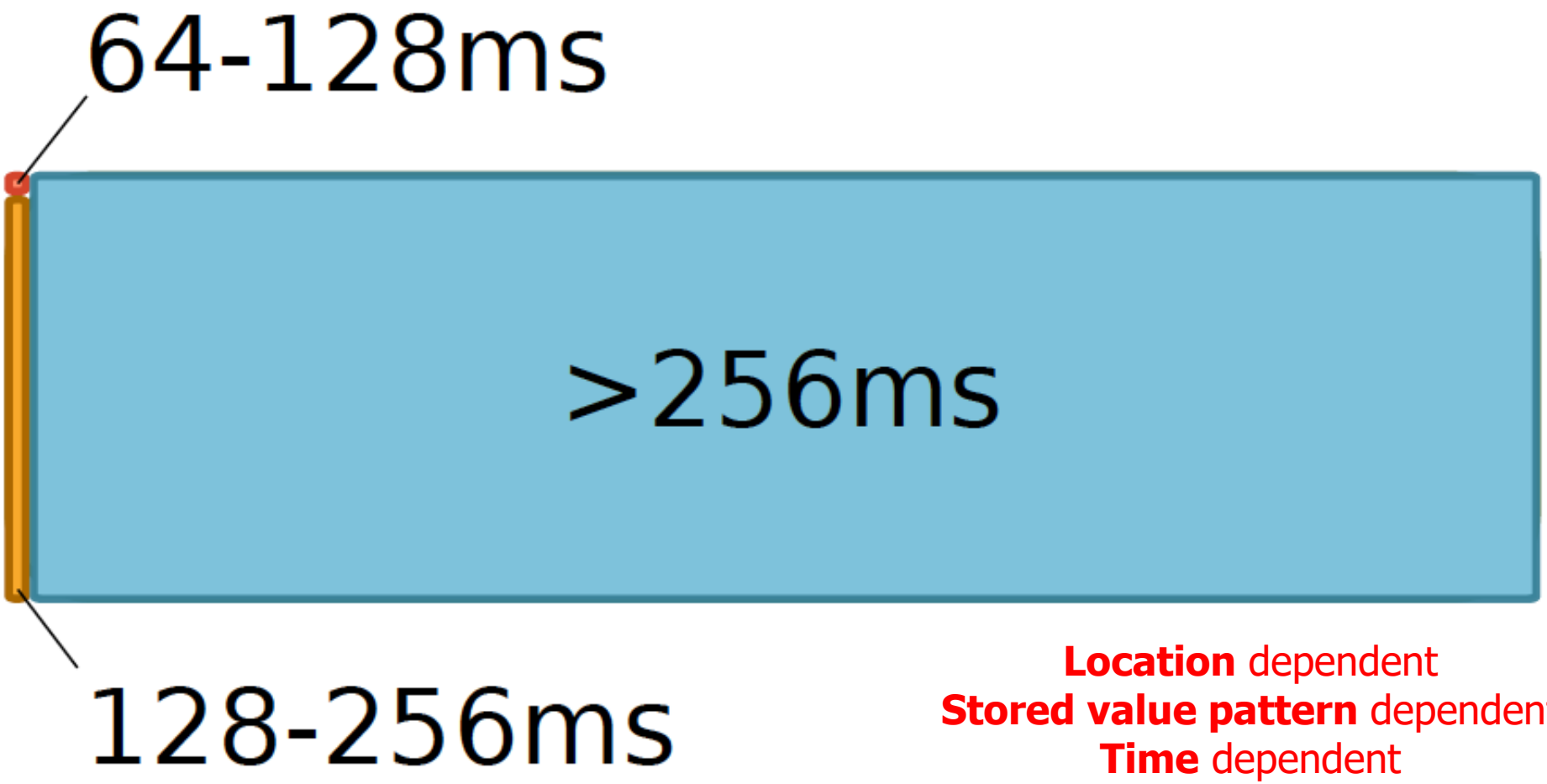
SoftMC: A Flexible and Practical Open-Source Infrastructure for Enabling Experimental DRAM Studies

Hasan Hassan[1,2,3] Nandita Vijaykumar[3] Samira Khan[4,3] Saugata Ghose[3] Kevin Chang[3]
Gennady Pekhimenko[5,3] Donghyuk Lee[6,3] Oguz Ergin[2] Onur Mutlu[1,3]

[1]*ETH Zürich* [2]*TOBB University of Economics & Technology* [3]*Carnegie Mellon University*
[4]*University of Virginia* [5]*Microsoft Research* [6]*NVIDIA Research*

Data Retention in Memory [Liu et al., ISCA 2013]

- Retention Time Profile of DRAM looks like this:



Location dependent
Stored value pattern dependent
Time dependent

A Curious Discovery [Kim et al., ISCA 2014]

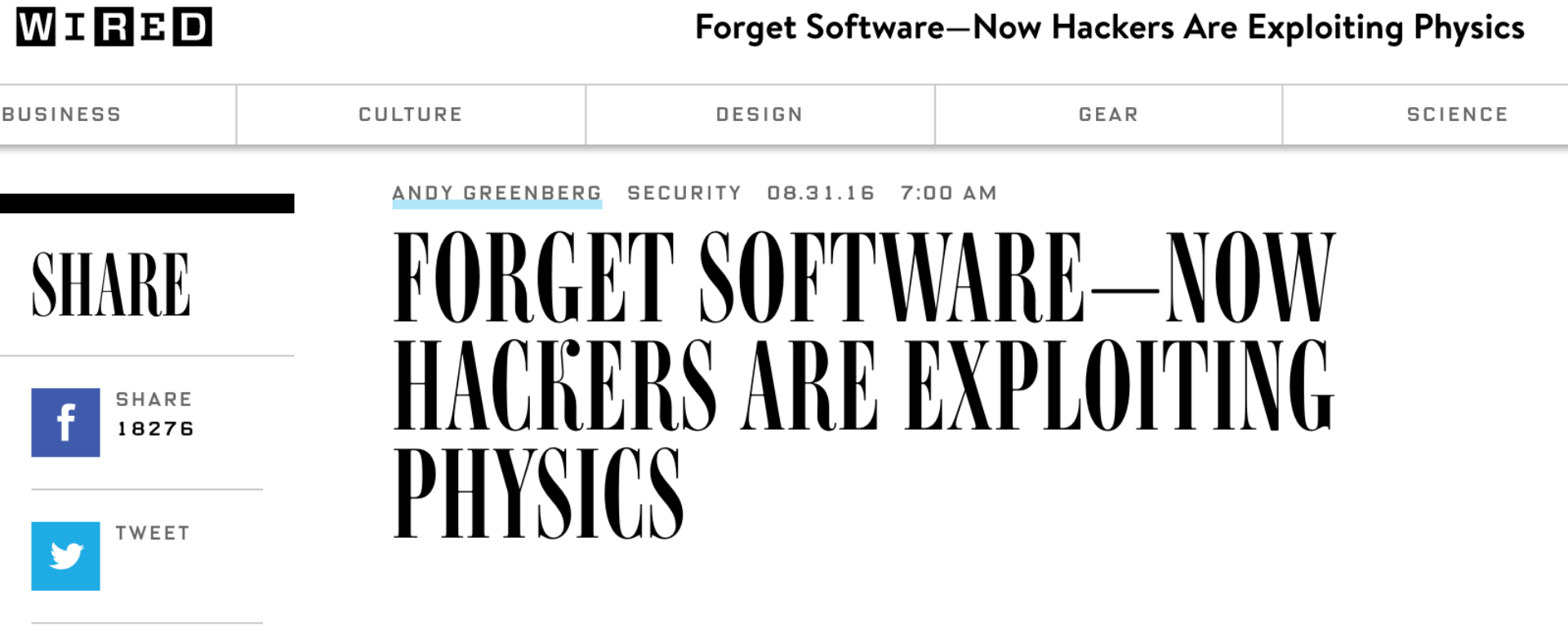
One can

predictably induce errors

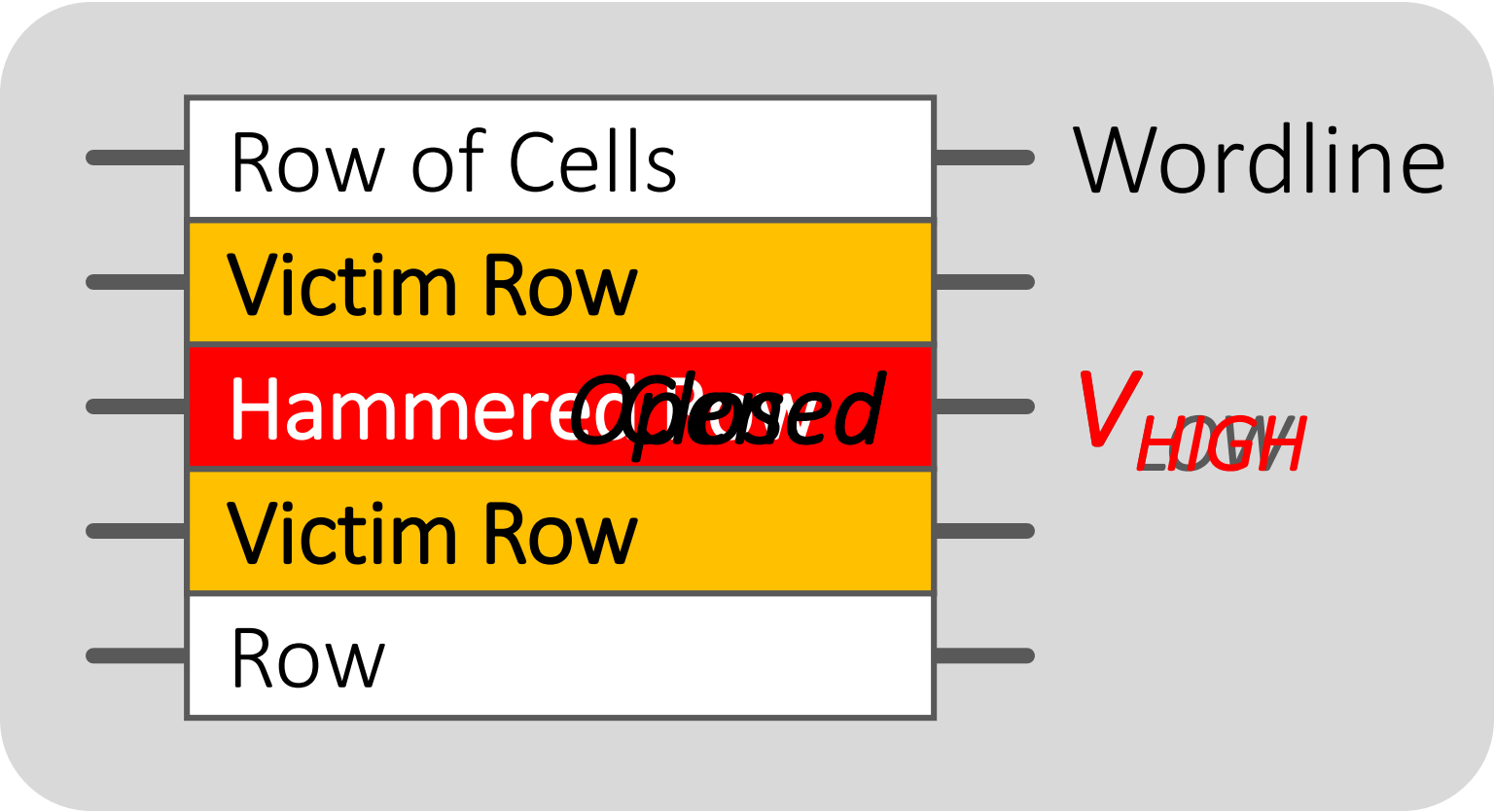
in most DRAM memory chips

DRAM RowHammer

A simple hardware failure mechanism
can create a widespread
system security vulnerability



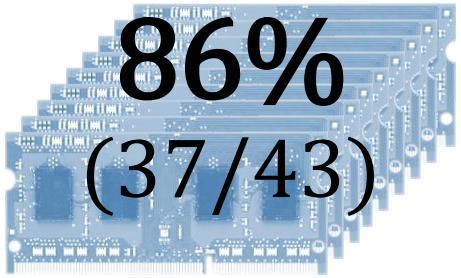
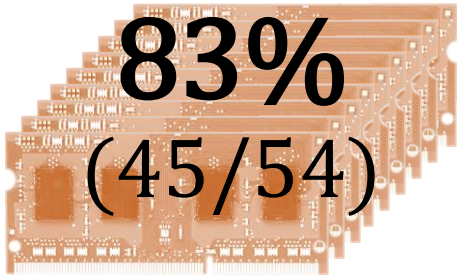
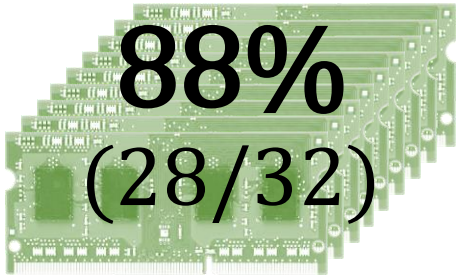
Modern DRAM is Prone to Disturbance Errors



Repeatedly reading a row enough times (before memory gets refreshed) induces disturbance errors in **adjacent rows** in most real DRAM chips you can buy today

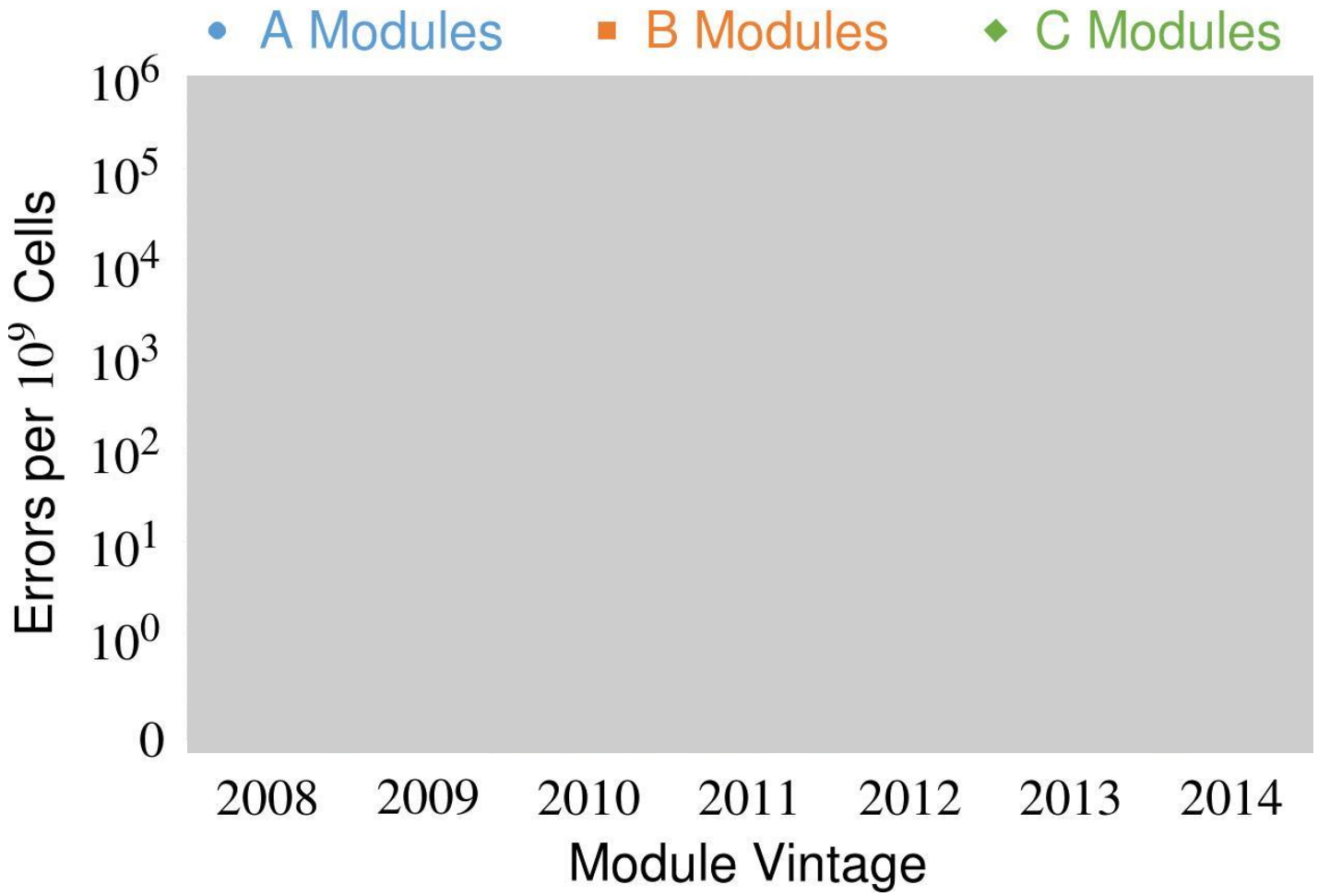
Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors, (Kim et al., ISCA 2014)

Most DRAM Modules Are Vulnerable

A company	B company	C company
		
86% (37/43)	**83%** (45/54)	**88%** (28/32)
Up to **1.0×10^7** errors	Up to **2.7×10^6** errors	Up to **3.3×10^5** errors

Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors, (Kim et al., ISCA 2014)

Recent DRAM Is More Vulnerable



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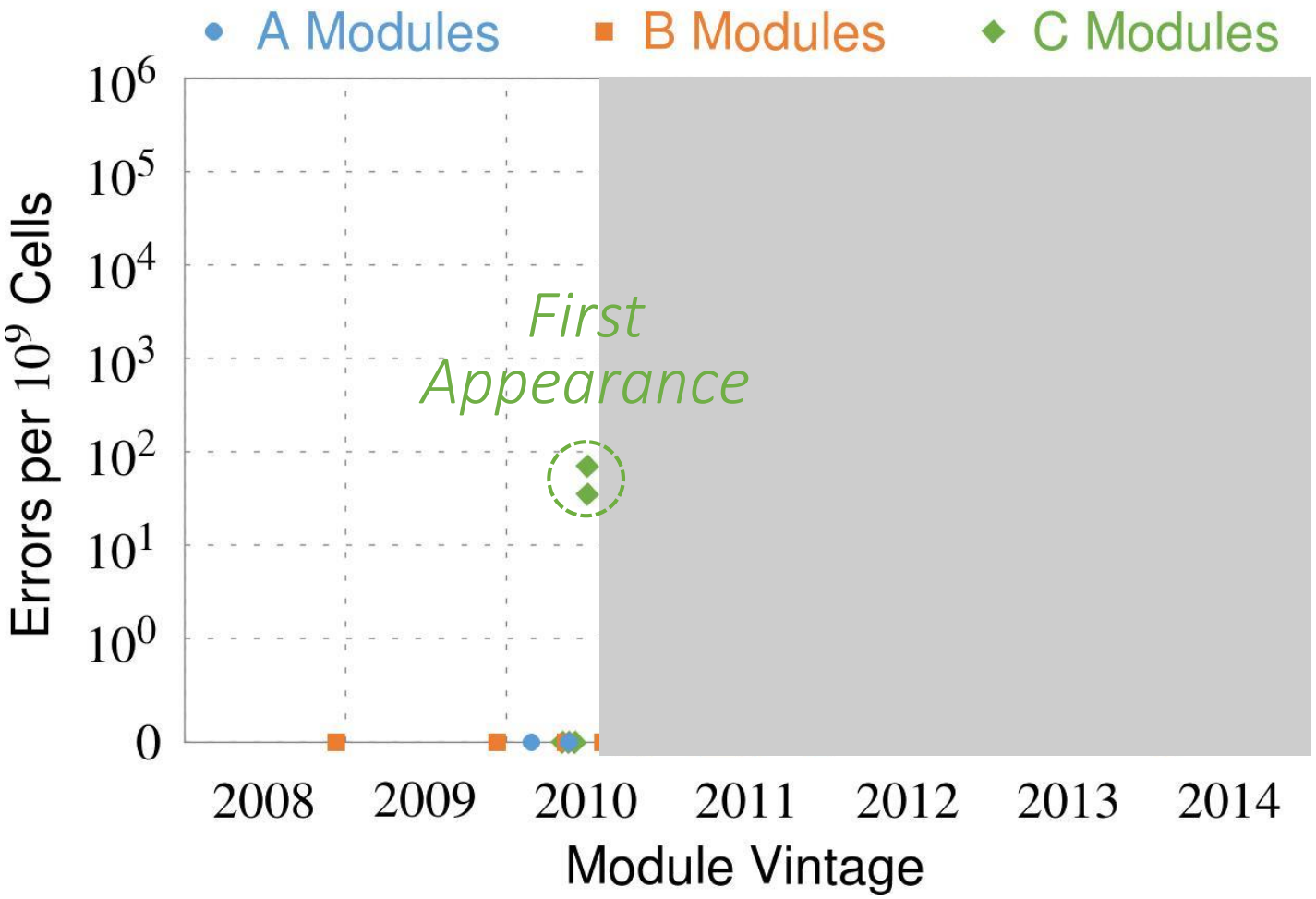

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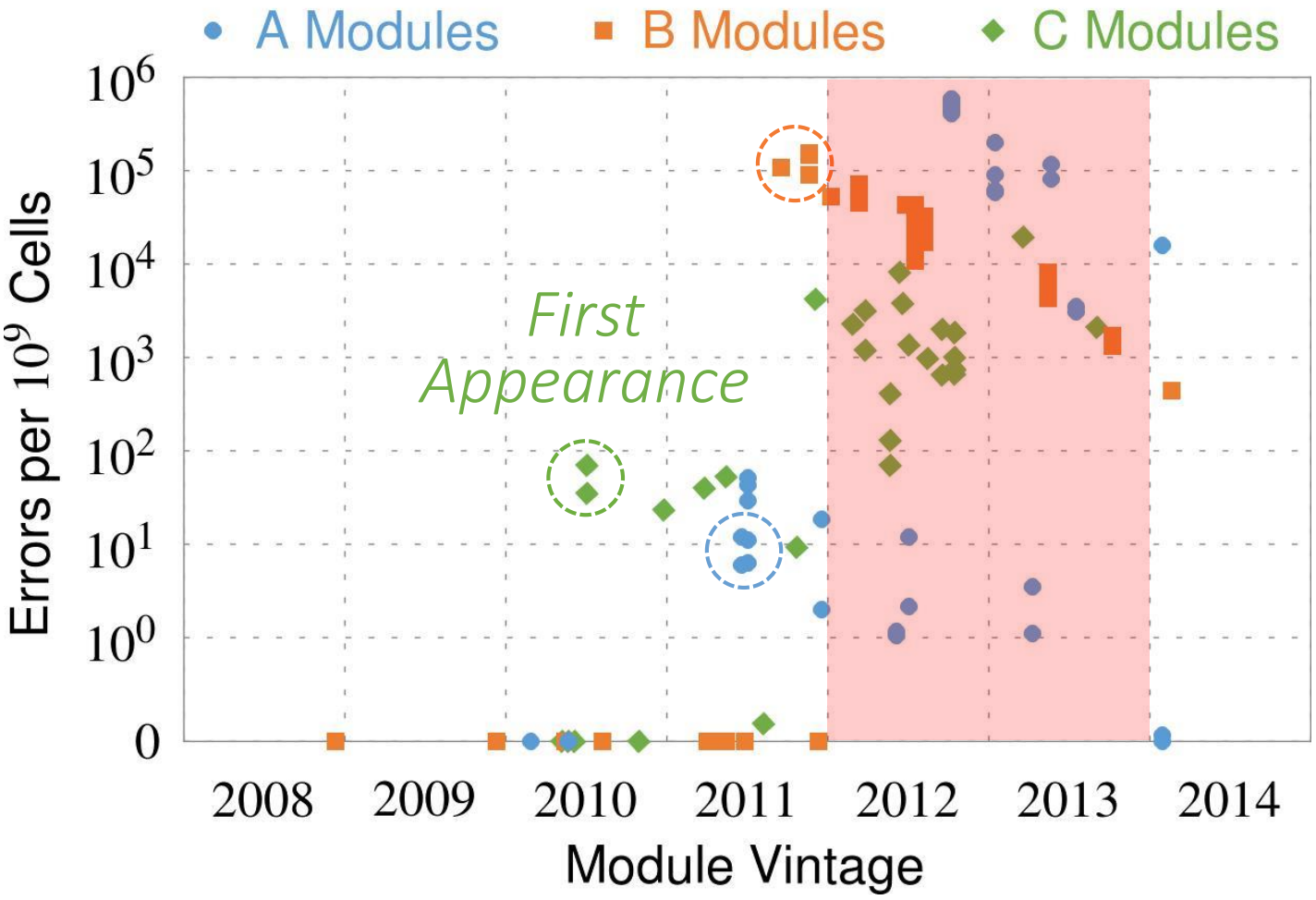
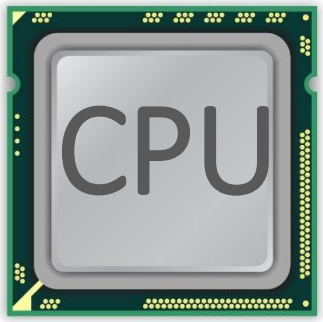
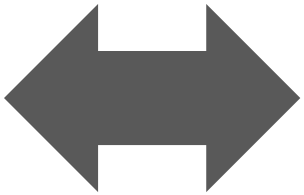
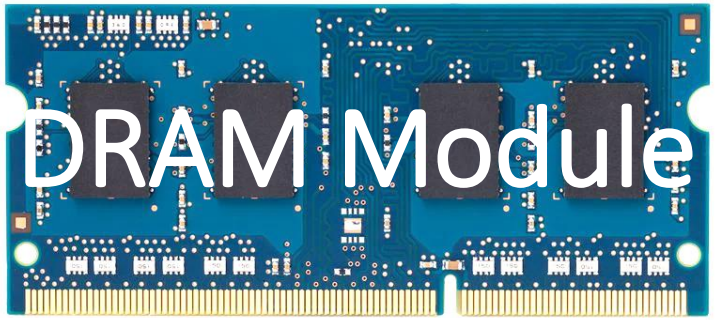


All modules from 2012–2013 are vulnerable

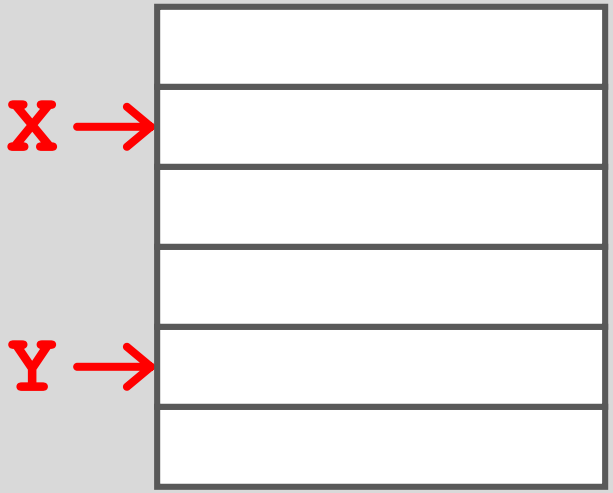
A Simple Program Can Induce Many Errors





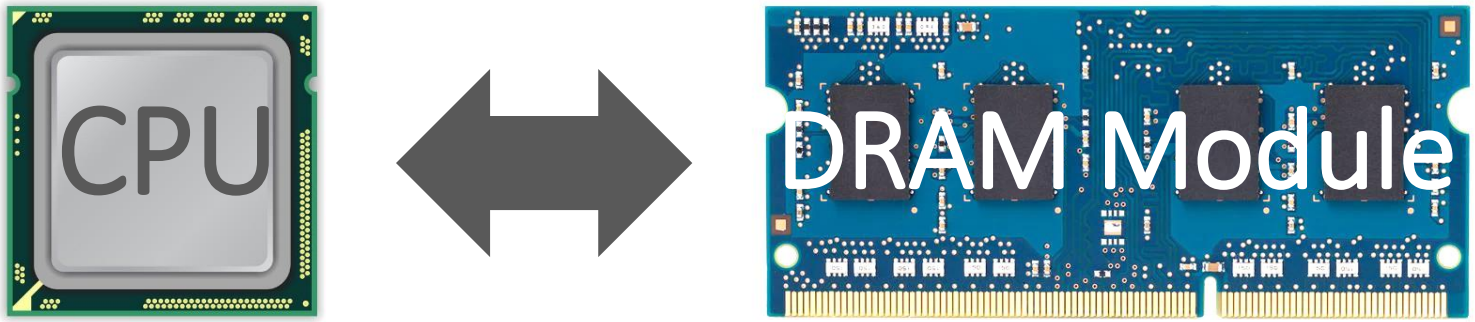



```
loop:
   mov (X), %eax
   mov (Y), %ebx
   clflush (X)
   clflush (Y)
   mfence
   jmp loop
```



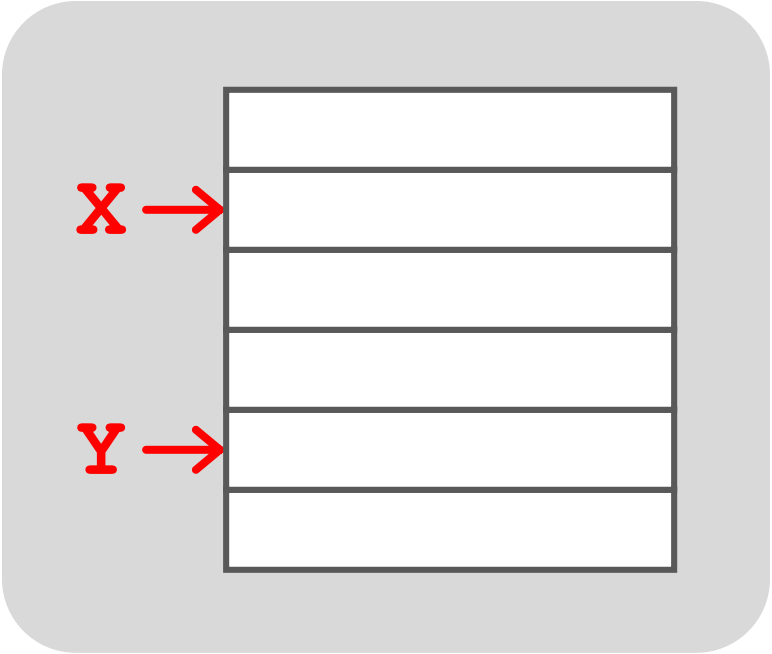
Download from: https://github.com/CMU-SAFARI/rowhammer

A Simple Program Can Induce Many Errors



1. Avoid ***cache hits***
   – Flush **X** from cache

2. Avoid ***row hits*** to **X**
   – Read **Y** in another row



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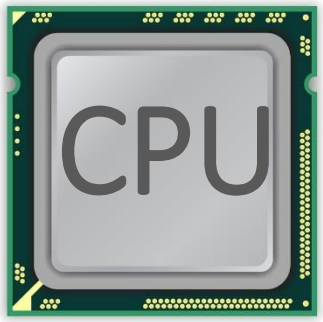

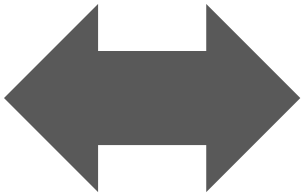

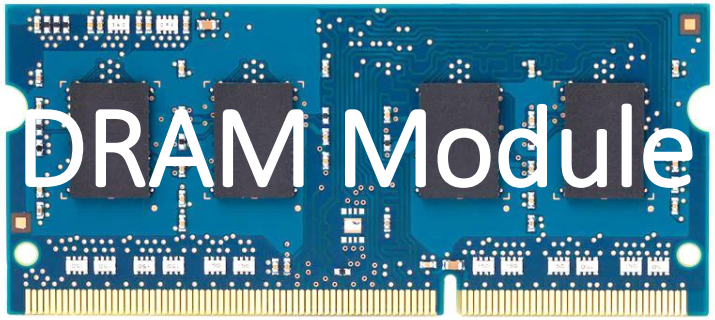


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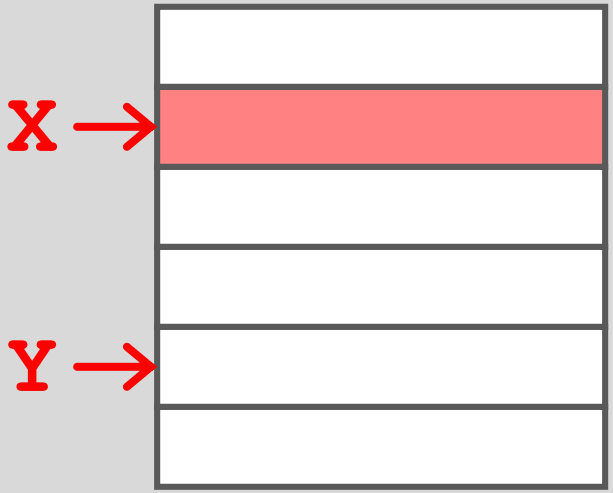

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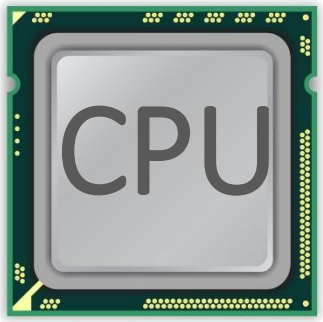
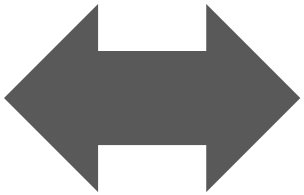
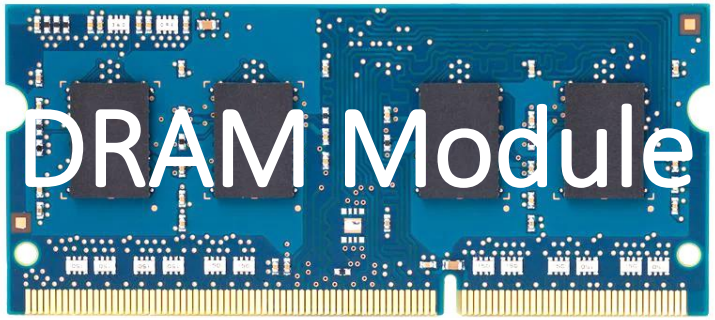
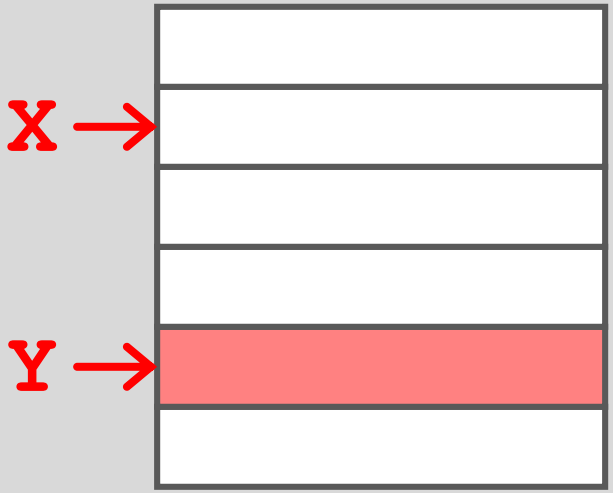




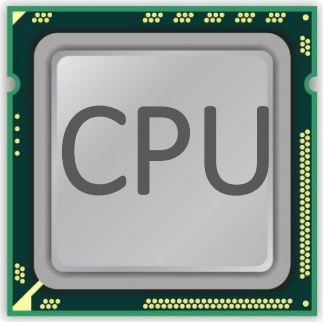


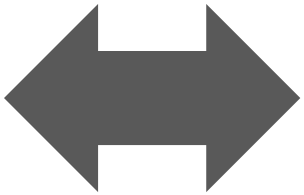

```
loop:
   mov (X), %eax
   mov (Y), %ebx
   clflush (X)
   clflush (Y)
   mfence
   jmp loop
```

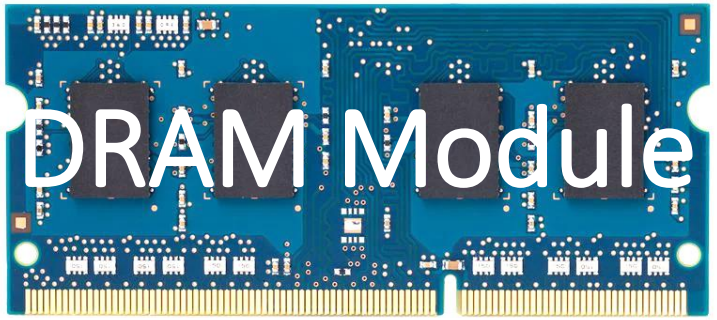


Download from: https://github.com/CMU-SAFARI/rowhammer

A Simple Program Can Induce Many Errors








```
loop:
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   clflush (X)
   clflush (Y)
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   jmp loop
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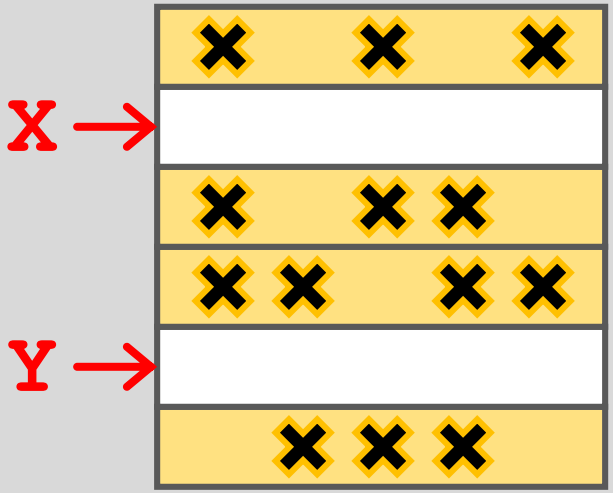


Download from: https://github.com/CMU-SAFARI/rowhammer

Observed Errors in Real Systems

CPU Architecture	Errors	Access-Rate
Intel Haswell (2013)	22.9K	12.3M/sec
Intel Ivy Bridge (2012)	20.7K	11.7M/sec
Intel Sandy Bridge (2011)	16.1K	11.6M/sec
AMD Piledriver (2012)	59	6.1M/sec

A real reliability & security issue

Kim+, "Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors," ISCA 2014.

One Can Take Over an Otherwise-Secure System

Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors

Abstract. Memory isolation is a key property of a reliable and secure computing system — an access to one memory address should not have unintended side effects on data stored in other addresses. However, as DRAM process technology

Project Zero

[Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors] (Kim et al., ISCA 2014)

News and updates from the Project Zero team at Google

[Exploiting the DRAM rowhammer bug to gain kernel privileges] (Seaborn, 2015)

Monday, March 9, 2015

Exploiting the DRAM rowhammer bug to gain kernel privileges

RowHammer Security Attack Example

- "Rowhammer" is a problem with some recent DRAM devices in which repeatedly accessing a row of memory can cause bit flips in adjacent rows (Kim et al., ISCA 2014).
  - Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors (Kim et al., ISCA 2014)
- We tested a selection of laptops and found that a subset of them exhibited the problem.
- We built two working privilege escalation exploits that use this effect.
  - Exploiting the DRAM rowhammer bug to gain kernel privileges (Seaborn+, 2015)
- One exploit uses rowhammer-induced bit flips to gain kernel privileges on x86-64 Linux when run as an unprivileged userland process.
- When run on a machine vulnerable to the rowhammer problem, the process was able to induce bit flips in page table entries (PTEs).
- It was able to use this to gain write access to its own page table, and hence gain read-write access to all of physical memory.

Security Implications

Security Implications

It's like breaking into an apartment by repeatedly slamming a neighbor's door until the vibrations open the door you were after

Selected Readings on RowHammer (I)

- Our first detailed study: Rowhammer analysis and solutions (June 2014)
  - Yoongu Kim, Ross Daly, Jeremie Kim, Chris Fallin, Ji Hye Lee, Donghyuk Lee, Chris Wilkerson, Konrad Lai, and Onur Mutlu,
    "Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors"
    *Proceedings of the 41st International Symposium on Computer Architecture (**ISCA**)*, Minneapolis, MN, June 2014. [Slides (pptx) (pdf)] [Lightning Session Slides (pptx) (pdf)] [Source Code and Data]

- Our Source Code to Induce Errors in Modern DRAM Chips (June 2014)
  - https://github.com/CMU-SAFARI/rowhammer

- Google Project Zero's Attack to Take Over a System (March 2015)
  - Exploiting the DRAM rowhammer bug to gain kernel privileges (Seaborn+, 2015)
  - https://github.com/google/rowhammer-test
  - **Double-sided Rowhammer**

Selected Readings on RowHammer (II)

- Remote RowHammer Attacks via JavaScript (July 2015)
  - http://arxiv.org/abs/1507.06955
  - https://github.com/IAIK/rowhammerjs
  - Gruss et al., DIMVA 2016.
  - **CLFLUSH-free Rowhammer**
  - "A fully automated attack that requires nothing but a website with JavaScript to **trigger faults on remote hardware**."
  - "We can gain unrestricted access to systems of website visitors."

- ANVIL: Software-Based Protection Against Next-Generation Rowhammer Attacks (March 2016)
  - http://dl.acm.org/citation.cfm?doid=2872362.2872390
  - Aweke et al., ASPLOS 2016
  - **CLFLUSH-free Rowhammer**
  - Software based monitoring for rowhammer detection

Selected Readings on RowHammer (III)

- Dedup Est Machina: Memory Deduplication as an Advanced Exploitation Vector (May 2016)
  - https://www.ieee-security.org/TC/SP2016/papers/0824a987.pdf
  - Bosman et al., IEEE S&P 2016.
  - Exploits Rowhammer and Memory Deduplication to overtake a browser
  - "We report on the **first reliable remote exploit for the Rowhammer vulnerability** running entirely in Microsoft Edge."
  - "[an attacker] … can reliably "own" a system with all defenses up, even if the software is entirely free of bugs."

Selected Readings on RowHammer (IV)

- Flip Feng Shui: Hammering a Needle in the Software Stack (August 2016)
  - https://www.usenix.org/system/files/conference/usenixsecurity16/sec16_paper_razavi.pdf
  - Razavi et al., USENIX Security 2016.
  - Combines memory deduplication and RowHammer
  - "**A malicious VM can gain unauthorized access to a co-hosted VM running OpenSSH**."
  - Breaks OpenSSH public key authentication

- Drammer: Deterministic Rowhammer Attacks on Mobile Platforms (October 2016)
  - http://dl.acm.org/citation.cfm?id=2976749.2978406
  - Van Der Veen et al., CCS 2016
  - **Can take over an ARM-based Android system deterministically**
  - Exploits predictable physical memory allocator behavior
    - Can deterministically place security-sensitive data (e.g., page table) in an attacker-chosen, vulnerable location in memory

Selected Readings on RowHammer (V)

- Grand Pwning Unit: Accelerating Microarchitectural Attacks with the GPU (May 2018)
  - https://www.vusec.net/wp-content/uploads/2018/05/glitch.pdf
  - Frigo et al., IEEE S&P 2018.
  - The first end-to-end remote Rowhammer exploit on mobile platforms that use our GPU-based primitives in orchestration to **compromise browsers on mobile devices in under two minutes**.

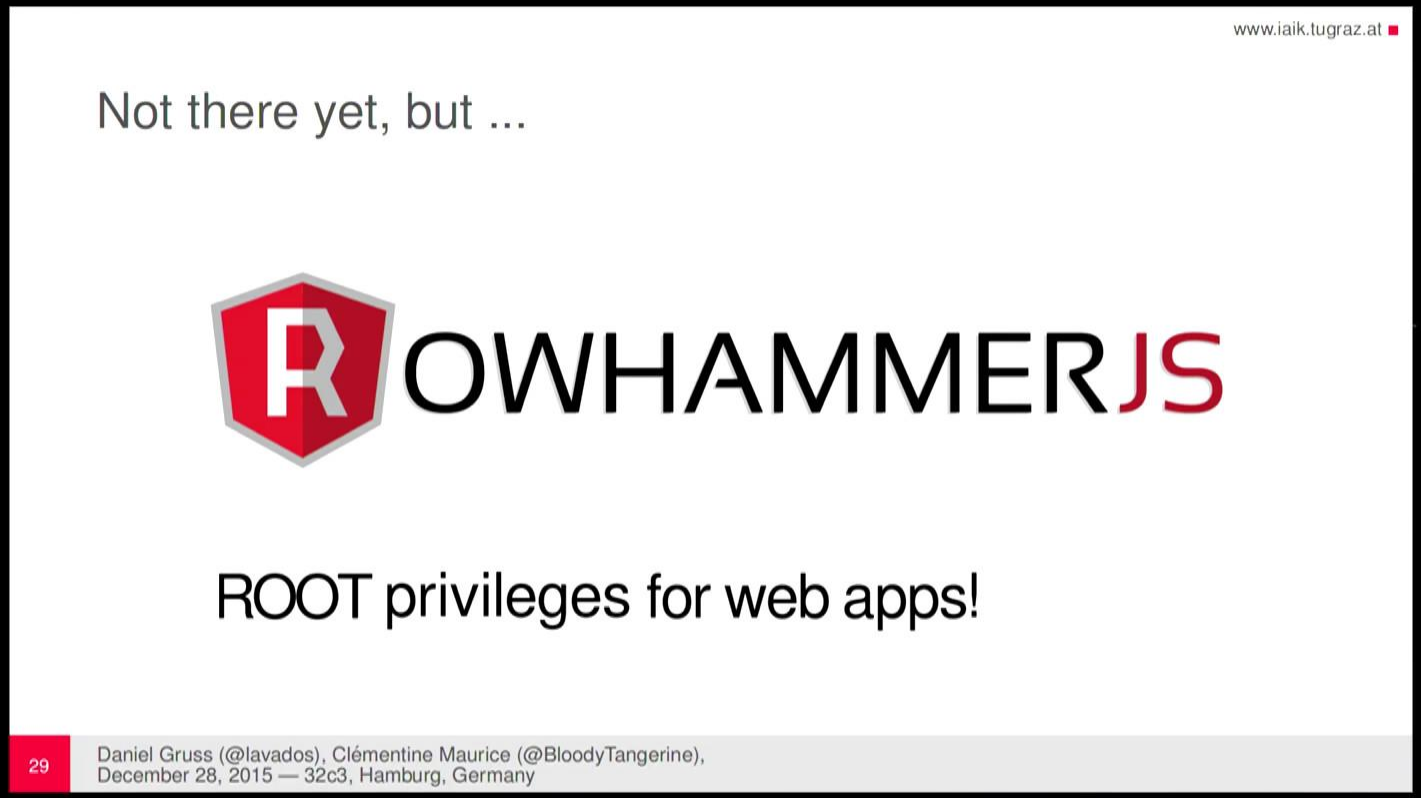
- Throwhammer: Rowhammer Attacks over the Network and Defenses (July 2018)
  - https://www.cs.vu.nl/~herbertb/download/papers/throwhammer_atc18.pdf
  - Tatar et al., USENIX ATC 2018.
  - "[We] show that **an attacker can trigger and exploit Rowhammer bit flips directly from a remote machine by only sending network packets**."

Selected Readings on RowHammer (VI)

- Nethammer: Inducing Rowhammer Faults through Network Requests (July 2018)
  - https://arxiv.org/pdf/1805.04956.pdf
  - Lipp et al., arxiv.org 2018.
  - "Nethammer is the first truly **remote Rowhammer attack**, without a single attacker-controlled line of code on the targeted system."

More Security Implications (I)

"We can gain unrestricted access to systems of website visitors."



Rowhammer.js: A Remote Software-Induced Fault Attack in JavaScript (DIMVA'16)

Source: https://lab.dsst.io/32c3-slides/7197.html

More Security Implications (II)

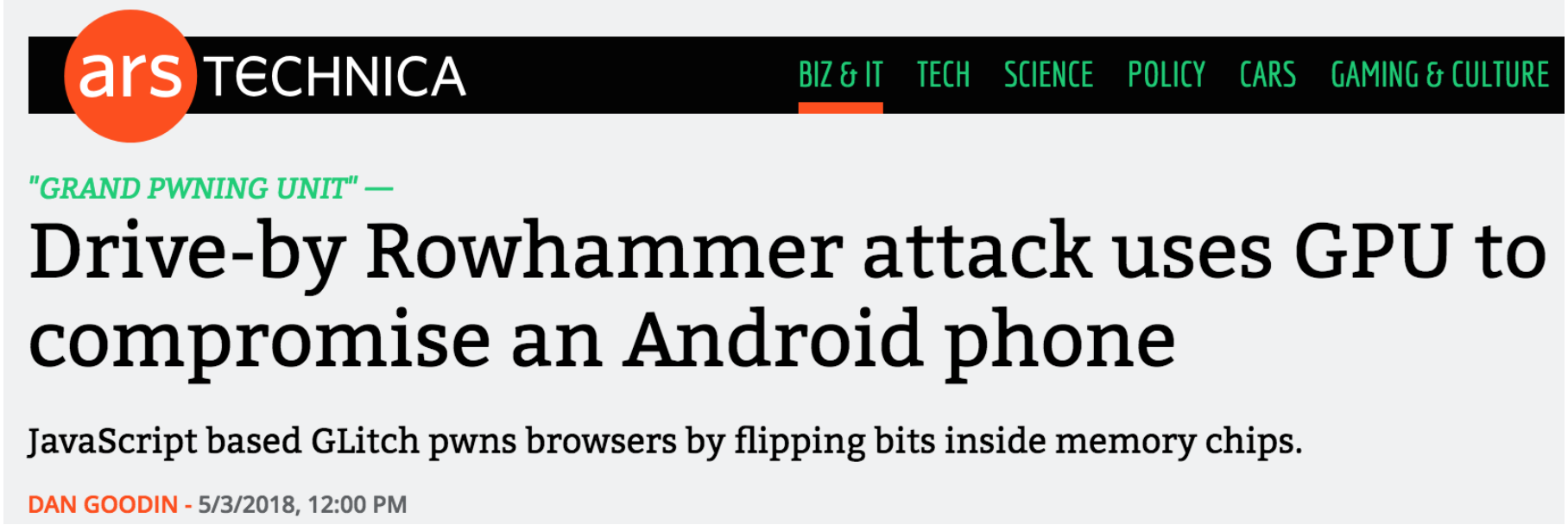
"Can gain control of a smart phone deterministically"

Drammer: Deterministic Rowhammer Attacks on Mobile Platforms, CCS'16

Source: https://fossbytes.com/drammer-rowhammer-attack-android-root-devices/

More Security Implications (III)

- Using an integrated GPU in a mobile system to remotely escalate privilege via the WebGL interface



Grand Pwning Unit: Accelerating Microarchitectural Attacks with the GPU

Pietro Frigo
Vrije Universiteit
Amsterdam
p.frigo@vu.nl

Cristiano Giuffrida
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Herbert Bos
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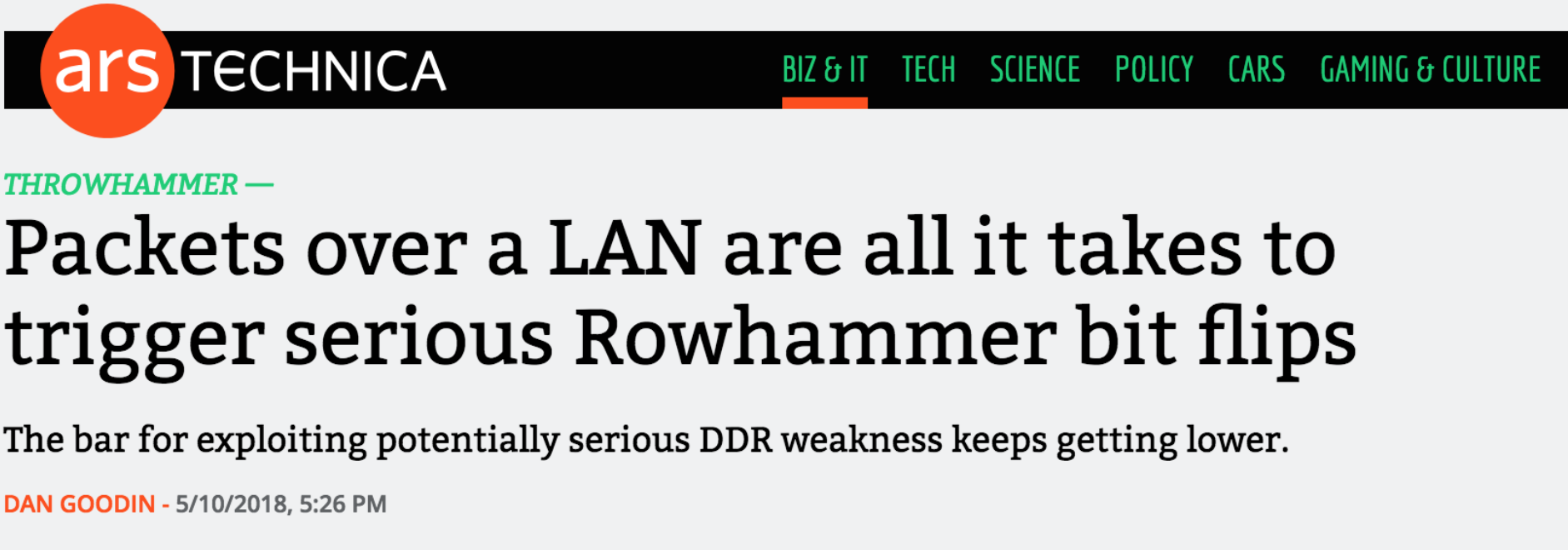
Amsterdam
herbertb@cs.vu.nl

Kaveh Razavi
Vrije Universiteit
Amsterdam
kaveh@cs.vu.nl

More Security Implications (IV)

- Rowhammer over RDMA (I)



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BIZ & IT TECH SCIENCE POLICY CARS GAMING & CULTURE

THROWHAMMER —

Packets over a LAN are all it takes to trigger serious Rowhammer bit flips

The bar for exploiting potentially serious DDR weakness keeps getting lower.

DAN GOODIN - 5/10/2018, 5:26 PM

Throwhammer: Rowhammer Attacks over the Network and Defenses

Andrei Tatar
VU Amsterdam

Radhesh Krishnan
VU Amsterdam

Elias Athanasopoulos
University of Cyprus

Cristiano Giuffrida
VU Amsterdam

Herbert Bos
VU Amsterdam

Kaveh Razavi
VU Amsterdam

More Security Implications (V)

- Rowhammer over RDMA (II)

The Hacker News™
Security in a serious way

Nethammer—Exploiting DRAM Rowhammer Bug Through Network Requests

Nethammer:
Inducing Rowhammer Faults through Network Requests

Moritz Lipp
Graz University of Technology

Misiker Tadesse Aga
University of Michigan

Michael Schwarz
Graz University of Technology

Daniel Gruss
Graz University of Technology

Clémentine Maurice
Univ Rennes, CNRS, IRISA

Lukas Raab
Graz University of Technology

Lukas Lamster
Graz University of Technology

More Security Implications?

Some Potential Solutions

- Make better DRAM chips — Cost
- Refresh frequently — Power, Performance
- Sophisticated ECC — Cost, Power
- Access counters — Cost, Power, Complexity

Apple's Patch for RowHammer

- https://support.apple.com/en-gb/HT204934

Available for: OS X Mountain Lion v10.8.5, OS X Mavericks v10.9.5

Impact: A malicious application may induce memory corruption to escalate privileges

Description: A disturbance error, also known as Rowhammer, exists with some DDR3 RAM that could have led to memory corruption. This issue was mitigated by increasing memory refresh rates.

CVE-ID

CVE-2015-3693 : Mark Seaborn and Thomas Dullien of Google, working from original research by Yoongu Kim et al (2014)

HP, Lenovo, and other vendors released similar patches

Our Solution to RowHammer

- PARA: *Probabilistic Adjacent Row Activation*
- Key Idea
  - After closing a row, we activate (i.e., refresh) one of its neighbors with a low probability: $p = 0.005$
- Reliability Guarantee
  - When $p=0.005$, errors in one year: 9.4×10^{-14}
  - By adjusting the value of p, we can vary the strength of protection against errors

Advantages of PARA

- *PARA refreshes rows infrequently*
  - Low power
  - Low performance-overhead
    - Average slowdown: 0.20% (for 29 benchmarks)
    - Maximum slowdown: 0.75%
- *PARA is stateless*
  - Low cost
  - Low complexity

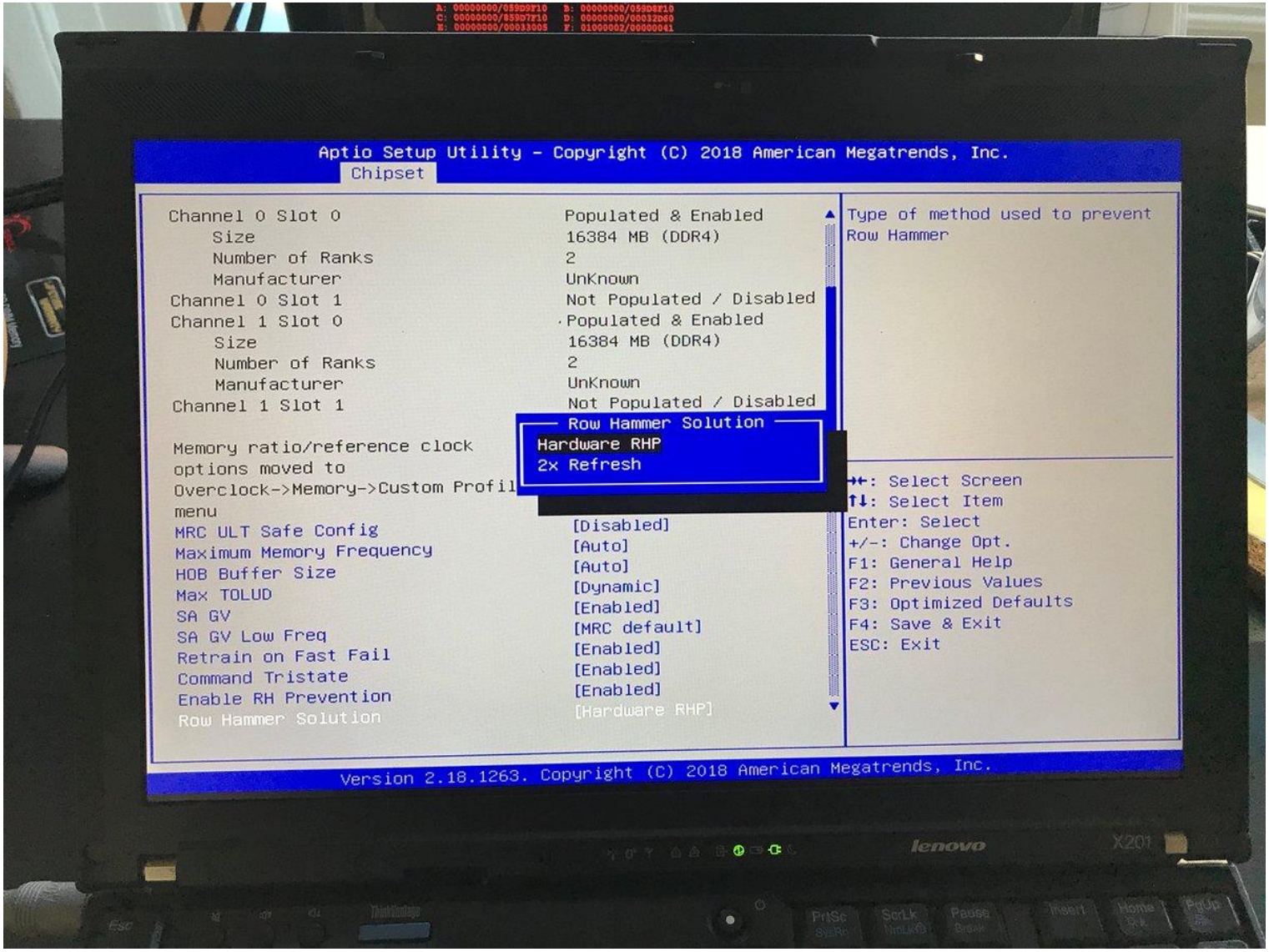
- *PARA is an effective and low-overhead solution to prevent disturbance errors*

Requirements for PARA

- If implemented in DRAM chip
  - Enough slack in timing parameters
  - Plenty of slack today:
    - Lee et al., "Adaptive-Latency DRAM: Optimizing DRAM Timing for the Common Case," HPCA 2015.
    - Chang et al., "Understanding Latency Variation in Modern DRAM Chips," SIGMETRICS 2016.
    - Lee et al., "Design-Induced Latency Variation in Modern DRAM Chips," SIGMETRICS 2017.
    - Chang et al., "Understanding Reduced-Voltage Operation in Modern DRAM Devices," SIGMETRICS 2017.
    - Ghose et al., "What Your DRAM Power Models Are Not Telling You: Lessons from a Detailed Experimental Study," SIGMETRICS 2018.

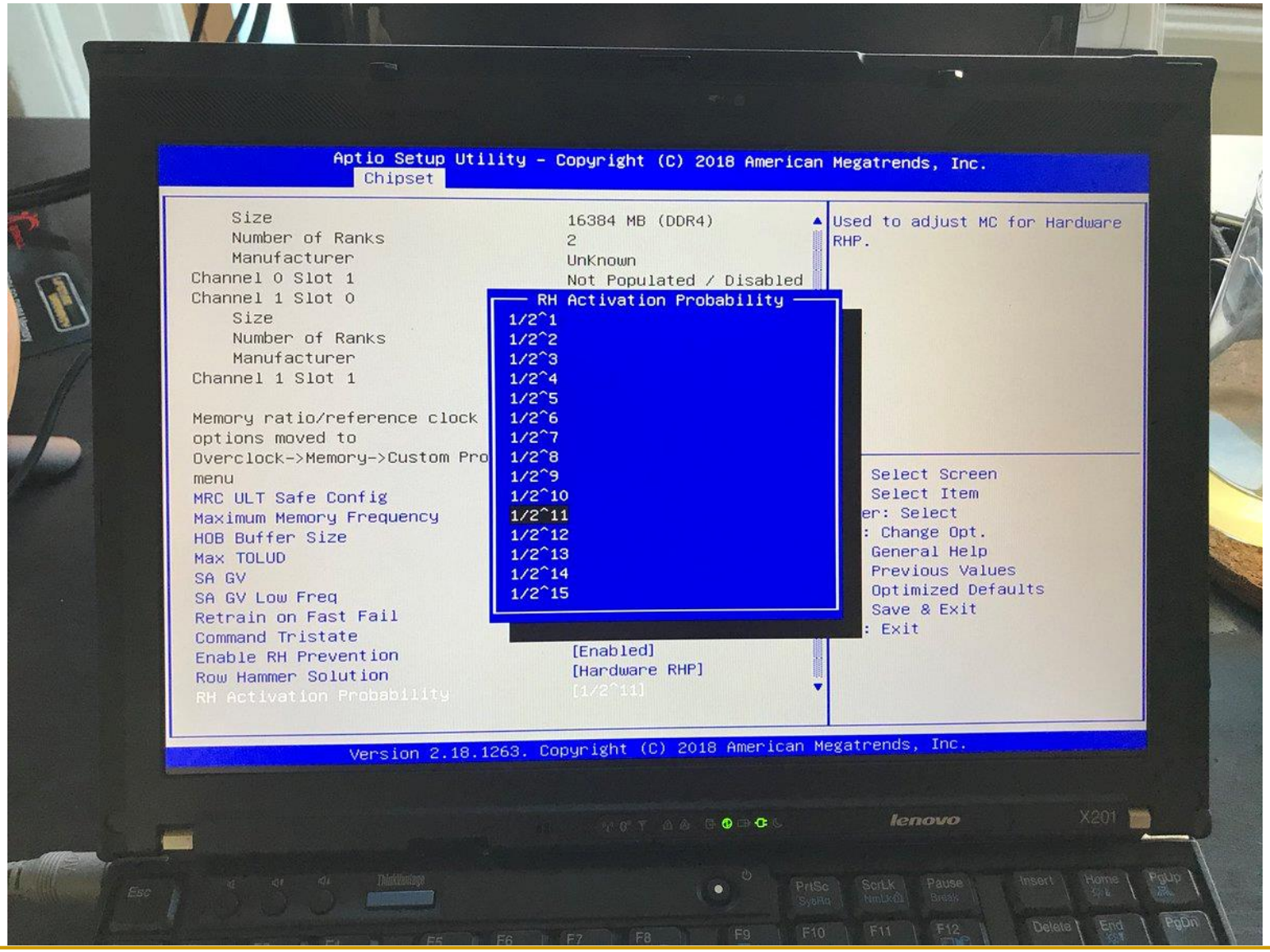
- If implemented in memory controller
  - Better coordination between memory controller and DRAM
  - Memory controller should know which rows are physically adjacent

Probabilistic Activation in Real Life (I)



https://twitter.com/isislovecruft/status/1021939922754723841

Probabilistic Activation in Real Life (II)



https://twitter.com/isislovecruft/status/1021939922754723841

More on RowHammer Analysis

- Yoongu Kim, Ross Daly, Jeremie Kim, Chris Fallin, Ji Hye Lee, Donghyuk Lee, Chris Wilkerson, Konrad Lai, and Onur Mutlu,
  "Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors"
  *Proceedings of the 41st International Symposium on Computer Architecture (**ISCA**)*, Minneapolis, MN, June 2014.
  [Slides (pptx) (pdf)] [Lightning Session Slides (pptx) (pdf)] [Source Code and Data]

Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors

Yoongu Kim[1] Ross Daly* Jeremie Kim[1] Chris Fallin* Ji Hye Lee[1]
Donghyuk Lee[1] Chris Wilkerson[2] Konrad Lai Onur Mutlu[1]

[1]Carnegie Mellon University [2]Intel Labs

Future of Memory Reliability/Security

- Onur Mutlu,
  "The RowHammer Problem and Other Issues We May Face as Memory Becomes Denser"
  *Invited Paper in Proceedings of the Design, Automation, and Test in Europe Conference (**DATE**)*, Lausanne, Switzerland, March 2017.
  [Slides (pptx) (pdf)]

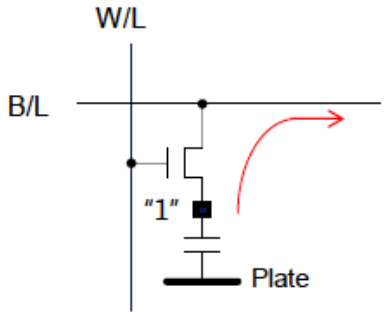
The RowHammer Problem
and Other Issues We May Face as Memory Becomes Denser

Onur Mutlu
ETH Zürich
onur.mutlu@inf.ethz.ch
https://people.inf.ethz.ch/omutlu

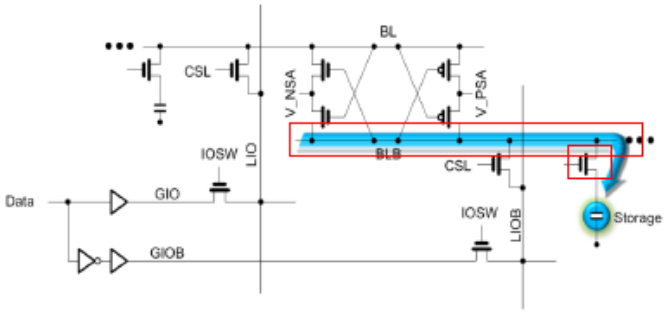
Industry Is Writing Papers About It, Too

DRAM Process Scaling Challenges

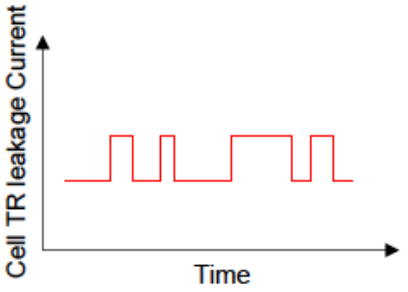
- **Refresh**
  - Difficult to build high-aspect ratio cell capacitors decreasing cell capacitance
  - Leakage current of cell access transistors increasing
- **tWR**
  - Contact resistance between the cell capacitor and access transistor increasing
  - On-current of the cell access transistor decreasing
  - Bit-line resistance increasing
- **VRT**
  - Occurring more frequently with cell capacitance decreasing



Refresh



tWR



VRT

Call for Intelligent Memory Controllers

DRAM Process Scaling Challenges

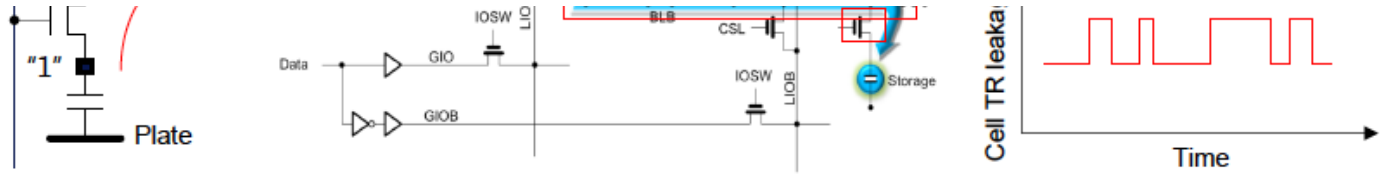
- **Refresh**
  - Difficult to build high-aspect ratio cell capacitors decreasing cell capacitance

THE MEMORY FORUM 2014

Co-Architecting Controllers and DRAM to Enhance DRAM Process Scaling

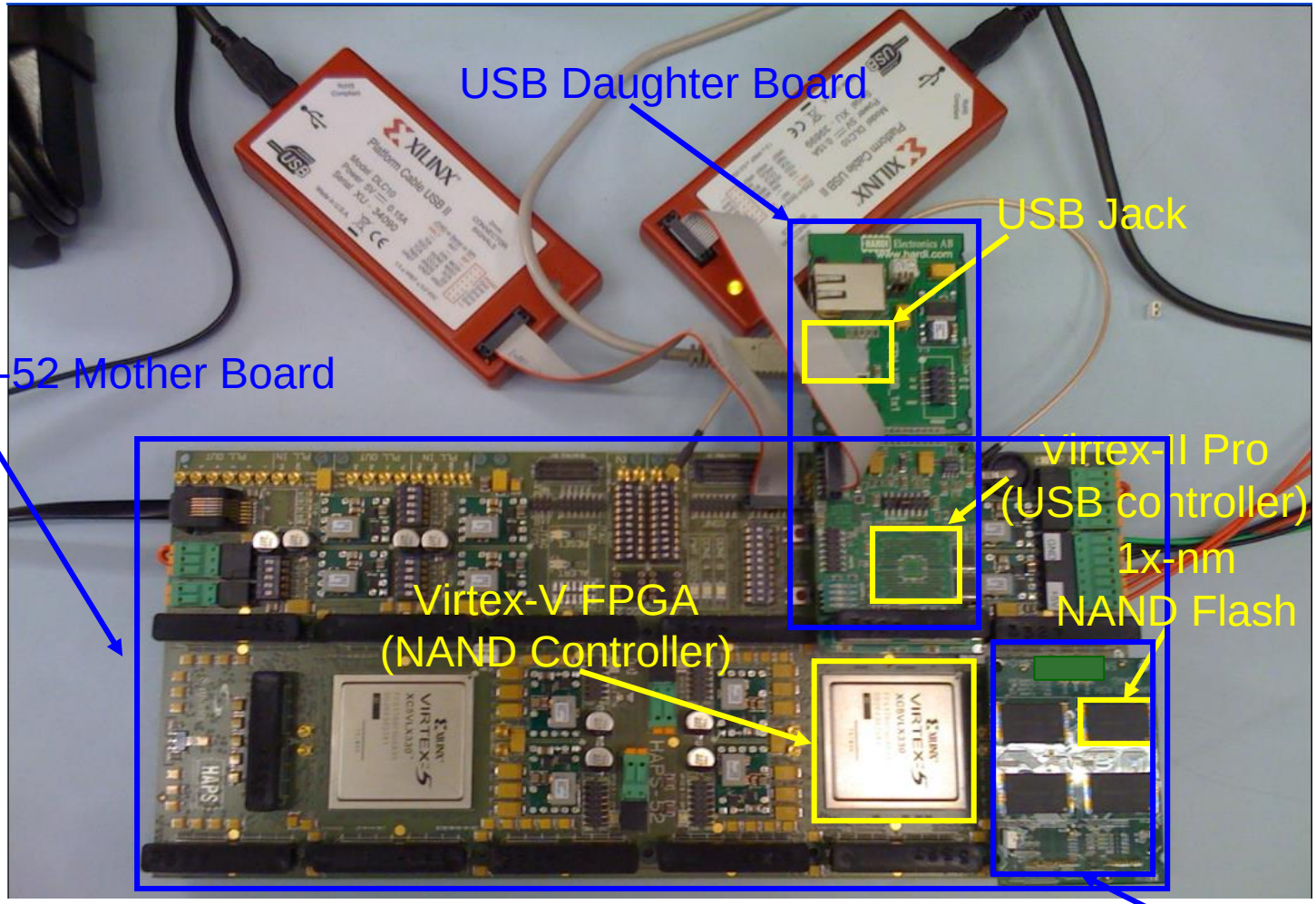
Uksong Kang, Hak-soo Yu, Churoo Park, *Hongzhong Zheng,
**John Halbert, **Kuljit Bains, SeongJin Jang, and Joo Sun Choi

*Samsung Electronics, Hwasung, Korea / *Samsung Electronics, San Jose / **Intel*



Refresh **tWR** **VRT**

Aside: Intelligent Controller for NAND Flash



[DATE 2012, ICCD 2012, DATE 2013, ITJ 2013, ICCD 2013, SIGMETRICS 2014, HPCA 2015, DSN 2015, MSST 2015, JSAC 2016, HPCA 2017, DFRWS 2017, PIEEE 2017, HPCA 2018, SIGMETRICS 2018]

Cai+, "Error Characterization, Mitigation, and Recovery in Flash Memory Based Solid State Drives," Proc. IEEE 2017.

Aside: Intelligent Controller for NAND Flash

Proceedings of the IEEE, Sept. 2017

Error Characterization, Mitigation, and Recovery in Flash-Memory-Based Solid-State Drives

This paper reviews the most recent advances in solid-state drive (SSD) error characterization, mitigation, and data recovery techniques to improve both SSD's reliability and lifetime.

By Yu Cai, Saugata Ghose, Erich F. Haratsch, Yixin Luo, and Onur Mutlu

https://arxiv.org/pdf/1706.08642

A Key Takeaway

Main Memory Needs Intelligent Controllers

Solution Direction: Principled Designs

Design fundamentally secure computing architectures

Predict and prevent such safety issues

Recall: Collapse of the "Galloping Gertie"

Source: AP
http://www.wsdot.wa.gov/tnbhistory/connections/connections3.htm

Another Example (1994)

Source: By 최광모 - Own work, CC BY-SA 4.0, https://commons.wikimedia.org/w/index.php?curid=35197984

Yet Another Example (2007)

Source: Morry Gash/AP,
https://www.npr.org/2017/08/01/540669701/10-years-after-bridge-collapse-america-is-still-crumbling?t=1535427165809

A More Recent Example (2018)

Source: AFP / Valery HACHE, https://www.capitalfm.co.ke/news/2018/08/genoa-bridge-collapse-what-we-know/

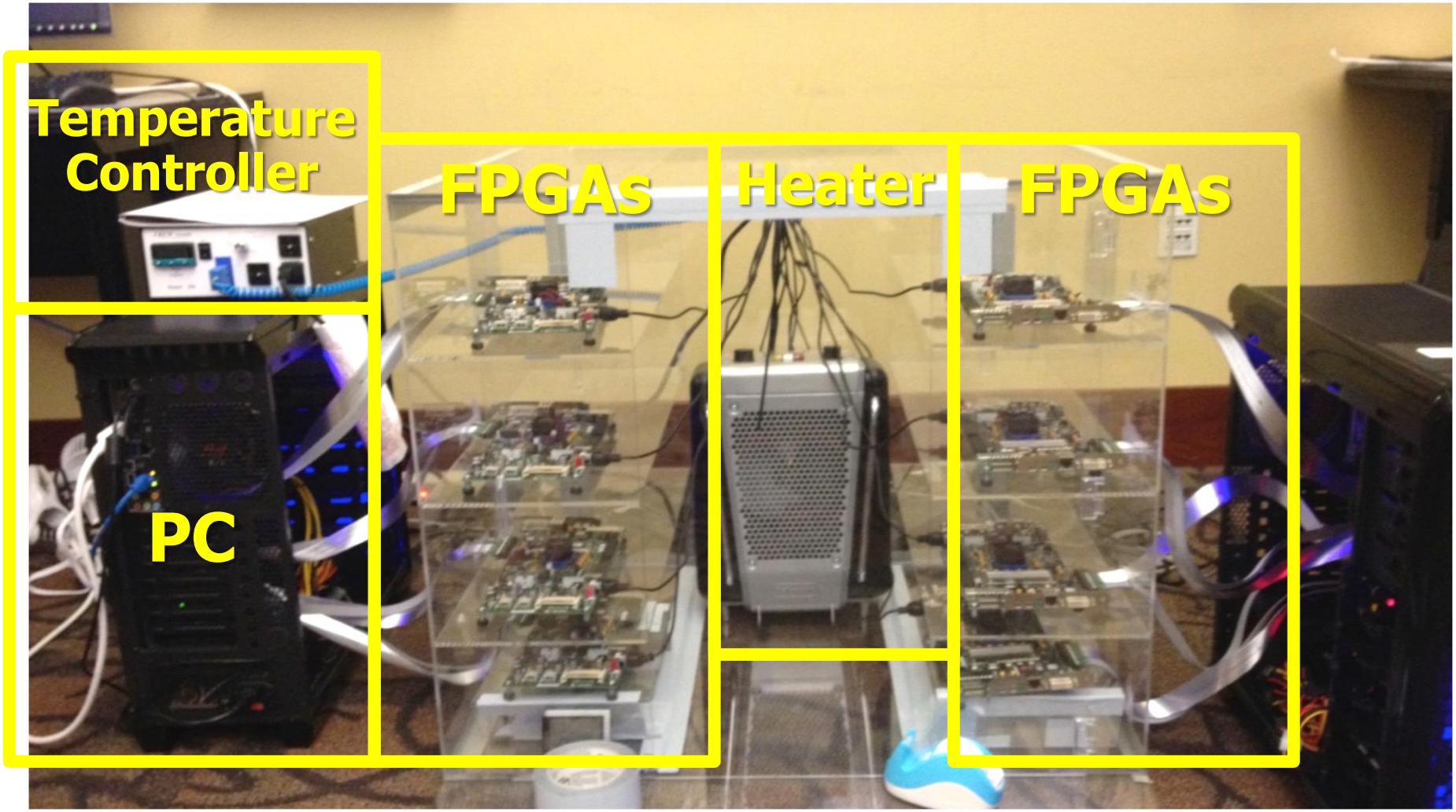
Architecting for Security

- **Understand**: Methods for vulnerability modeling & discovery
  - Modeling and prediction based on real (device) data and analysis
  - Understanding vulnerabilities
  - Developing reliable metrics

- **Architect**: Principled architectures with security as key concern
  - Good partitioning of duties across the stack
  - Cannot give up performance and efficiency
  - Patch-ability in the field

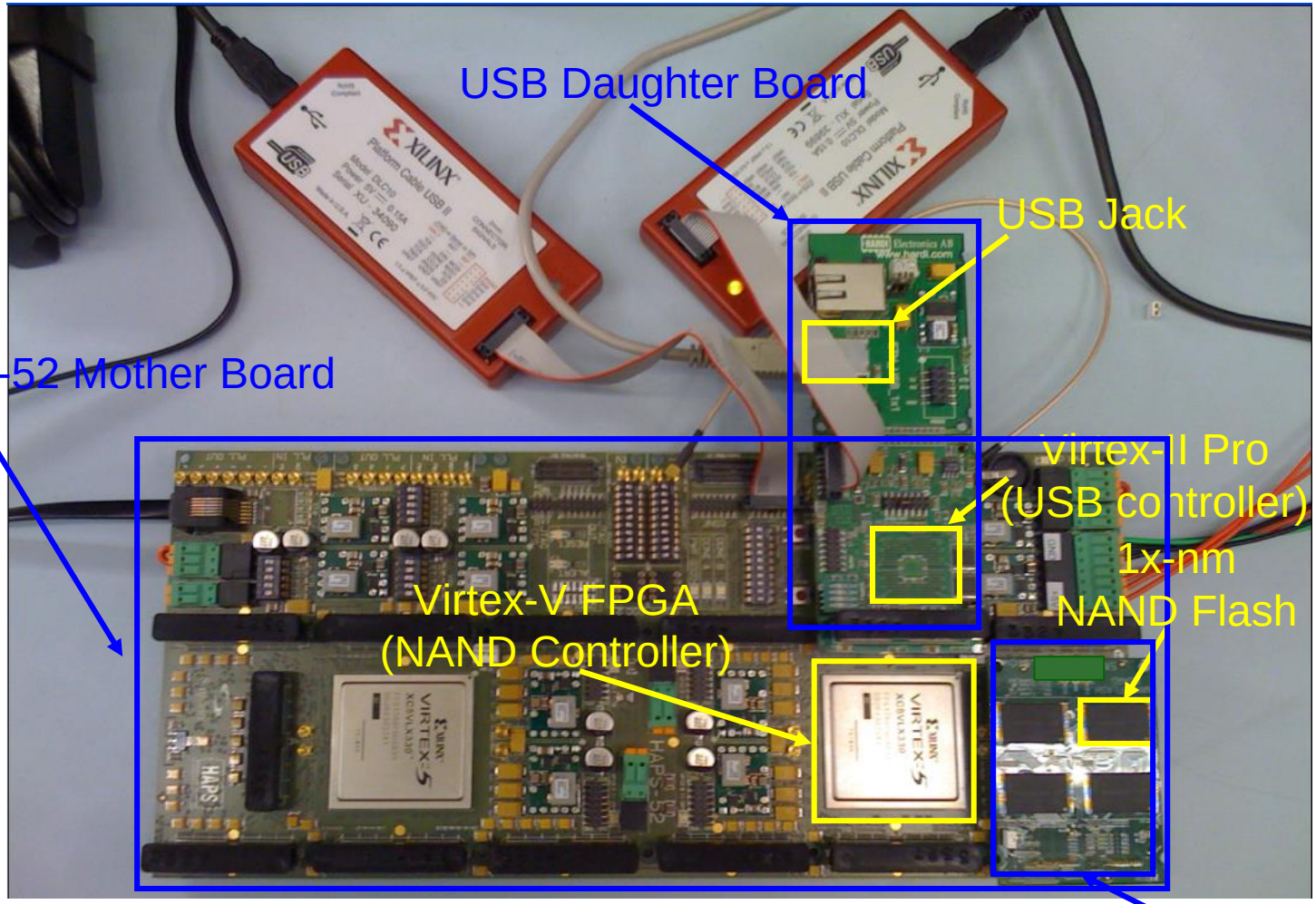
- **Design & Test**: Principled design, automation, (online) testing
  - Design for security
  - High coverage and good interaction with system reliability methods

Understand and Model with Experiments (DRAM)



Kim+, "Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors," ISCA 2014.

Understand and Model with Experiments (Flash)



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Understanding Flash Memory Reliability

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Error Characterization, Mitigation, and Recovery in Flash-Memory-Based Solid-State Drives

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https://arxiv.org/pdf/1706.08642

Understanding Flash Memory Reliability

- Justin Meza, Qiang Wu, Sanjeev Kumar, and Onur Mutlu,
  "A Large-Scale Study of Flash Memory Errors in the Field"
  *Proceedings of the ACM International Conference on Measurement and Modeling of Computer Systems (**SIGMETRICS**)*, Portland, OR, June 2015.
  [Slides (pptx) (pdf)] [Coverage at ZDNet] [Coverage on The Register]
  [Coverage on TechSpot] [Coverage on The Tech Report]

A Large-Scale Study of Flash Memory Failures in the Field

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NAND Flash Vulnerabilities [HPCA'17]

HPCA, Feb. 2017

Vulnerabilities in MLC NAND Flash Memory Programming: Experimental Analysis, Exploits, and Mitigation Techniques

Yu Cai[†] Saugata Ghose[†] Yixin Luo[‡†] Ken Mai[†] Onur Mutlu[§†] Erich F. Haratsch[‡]
[†]*Carnegie Mellon University* [‡]*Seagate Technology* [§]*ETH Zürich*

Modern NAND flash memory chips provide high density by storing two bits of data in each flash cell, called a multi-level cell *(MLC). An MLC partitions the threshold voltage range of a flash cell into four* voltage states. *When a flash cell is programmed, a high voltage is applied to the cell. Due to parasitic capacitance coupling between flash cells that are physically close to each other, flash cell programming can lead to* cell-to-cell program interference, *which introduces errors into* neighboring *flash cells. In order to reduce the impact of cell-to-cell interference on the reliability of MLC NAND flash memory, flash manufacturers adopt a* two-step programming method, *which programs the MLC in two separate steps. First, the flash memory partially programs the least significant bit of the MLC to some intermediate threshold voltage. Second, it programs the most significant bit to bring the MLC up to its full voltage state.*

In this paper, we demonstrate that two-step programming exposes new reliability and security vulnerabilities. We expe-

belongs to a different flash memory *page* (the unit of data programmed and read at the same time), which we refer to, respectively, as the least significant bit (LSB) page and the most significant bit (MSB) page [5].

A flash cell is programmed by applying a large voltage on the control gate of the transistor, which triggers charge transfer into the floating gate, thereby increasing the threshold voltage. To precisely control the threshold voltage of the cell, the flash memory uses *incremental step pulse programming* (ISPP) [12, 21, 25, 41]. ISPP applies multiple short pulses of the programming voltage to the control gate, in order to increase the cell threshold voltage by some small voltage amount (V_{step}) after each step. Initial MLC designs programmed the threshold voltage in *one shot*, issuing all of the pulses back-to-back to program *both* bits of data at the same time. However, as flash memory scales down, the distance between neighboring flash cells decreases, which

https://people.inf.ethz.ch/omutlu/pub/flash-memory-programming-vulnerabilities_hpca17.pdf

3D NAND Flash Reliability I [HPCA'18]

- Yixin Luo, Saugata Ghose, Yu Cai, Erich F. Haratsch, and Onur Mutlu, **"HeatWatch: Improving 3D NAND Flash Memory Device Reliability by Exploiting Self-Recovery and Temperature-Awareness"**
  *Proceedings of the 24th International Symposium on High-Performance Computer Architecture (**HPCA**)*, Vienna, Austria, February 2018.
  [Lightning Talk Video]
  [Slides (pptx) (pdf)] [Lightning Session Slides (pptx) (pdf)]

HeatWatch: Improving 3D NAND Flash Memory Device Reliability by Exploiting Self-Recovery and Temperature Awareness

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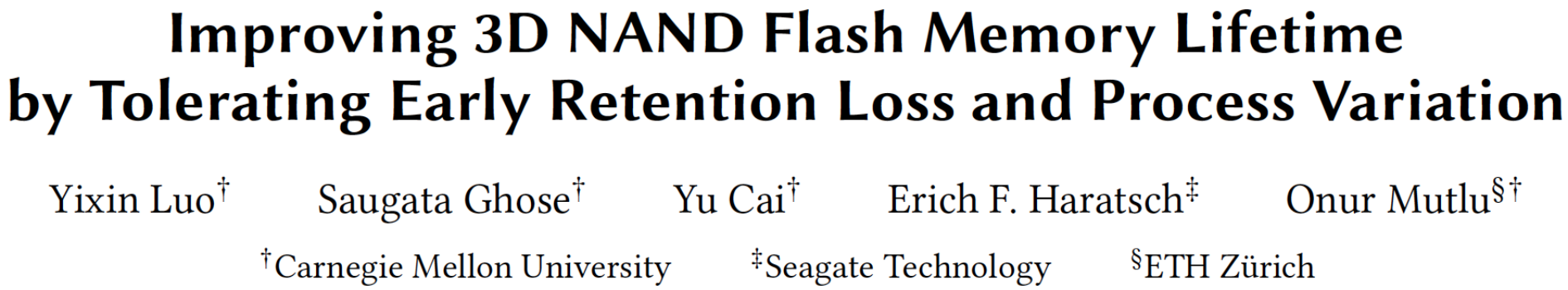
3D NAND Flash Reliability II [SIGMETRICS'18]

- Yixin Luo, Saugata Ghose, Yu Cai, Erich F. Haratsch, and Onur Mutlu, **"Improving 3D NAND Flash Memory Lifetime by Tolerating Early Retention Loss and Process Variation"**
  *Proceedings of the ACM International Conference on Measurement and Modeling of Computer Systems (**SIGMETRICS**)*, Irvine, CA, USA, June 2018.
  [Abstract]
  [POMACS Journal Version (same content, different format)]
  [Slides (pptx) (pdf)]



Improving 3D NAND Flash Memory Lifetime by Tolerating Early Retention Loss and Process Variation

Yixin Luo[†] Saugata Ghose[†] Yu Cai[†] Erich F. Haratsch[‡] Onur Mutlu[§†]

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Another Talk: NAND Flash Memory Robustness

- Yu Cai, Saugata Ghose, Erich F. Haratsch, Yixin Luo, and Onur Mutlu, **"Error Characterization, Mitigation, and Recovery in Flash Memory Based Solid State Drives"**
  to appear in Proceedings of the IEEE, 2017.

Cai+, "Error Patterns in MLC NAND Flash Memory: Measurement, Characterization, and Analysis," DATE 2012.
Cai+, "Flash Correct-and-Refresh: Retention-Aware Error Management for Increased Flash Memory Lifetime," ICCD 2012.
Cai+, "Threshold Voltage Distribution in MLC NAND Flash Memory: Characterization, Analysis and Modeling," DATE 2013.
Cai+, "Error Analysis and Retention-Aware Error Management for NAND Flash Memory," Intel Technology Journal 2013.
Cai+, "Program Interference in MLC NAND Flash Memory: Characterization, Modeling, and Mitigation," ICCD 2013.
Cai+, "Neighbor-Cell Assisted Error Correction for MLC NAND Flash Memories," SIGMETRICS 2014.
Cai+,"Data Retention in MLC NAND Flash Memory: Characterization, Optimization and Recovery," HPCA 2015.
Cai+, "Read Disturb Errors in MLC NAND Flash Memory: Characterization and Mitigation," DSN 2015.
Luo+, "WARM: Improving NAND Flash Memory Lifetime with Write-hotness Aware Retention Management," MSST 2015.
Meza+, "A Large-Scale Study of Flash Memory Errors in the Field," SIGMETRICS 2015.
Luo+, "Enabling Accurate and Practical Online Flash Channel Modeling for Modern MLC NAND Flash Memory," IEEE JSAC 2016.
Cai+, "Vulnerabilities in MLC NAND Flash Memory Programming: Experimental Analysis, Exploits, and Mitigation Techniques," HPCA 2017.
Fukami+, "Improving the Reliability of Chip-Off Forensic Analysis of NAND Flash Memory Devices," DFRWS EU 2017.
Luo+, "HeatWatch: Improving 3D NAND Flash Memory Device Reliability by Exploiting Self-Recovery and Temperature-Awareness," HPCA 2018.
Luo+, "Improving 3D NAND Flash Memory Lifetime by Tolerating Early Retention Loss and Process Variation," SIGMETRICS 2018.

Cai+, "Error Characterization, Mitigation, and Recovery in Flash Memory Based Solid State Drives," Proc. IEEE 2017.

There are Two Other Solution Directions

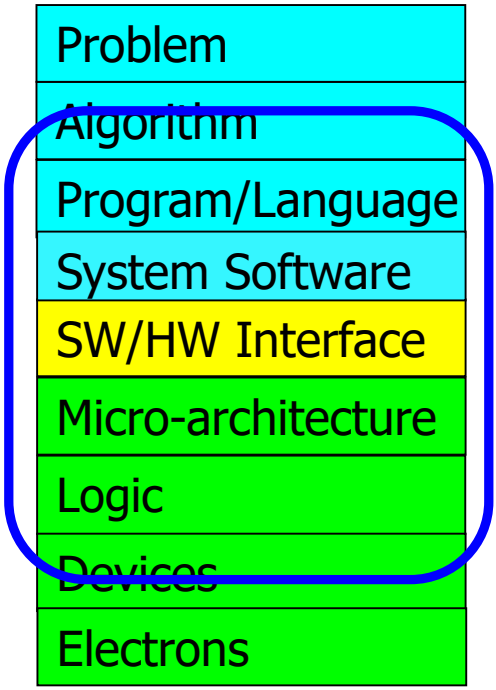
- **New Technologies:** Replace or (more likely) augment DRAM with a different technology
  - Non-volatile memories

- **Embracing Un-reliability:**

  Design memories with different reliability and store data intelligently across them

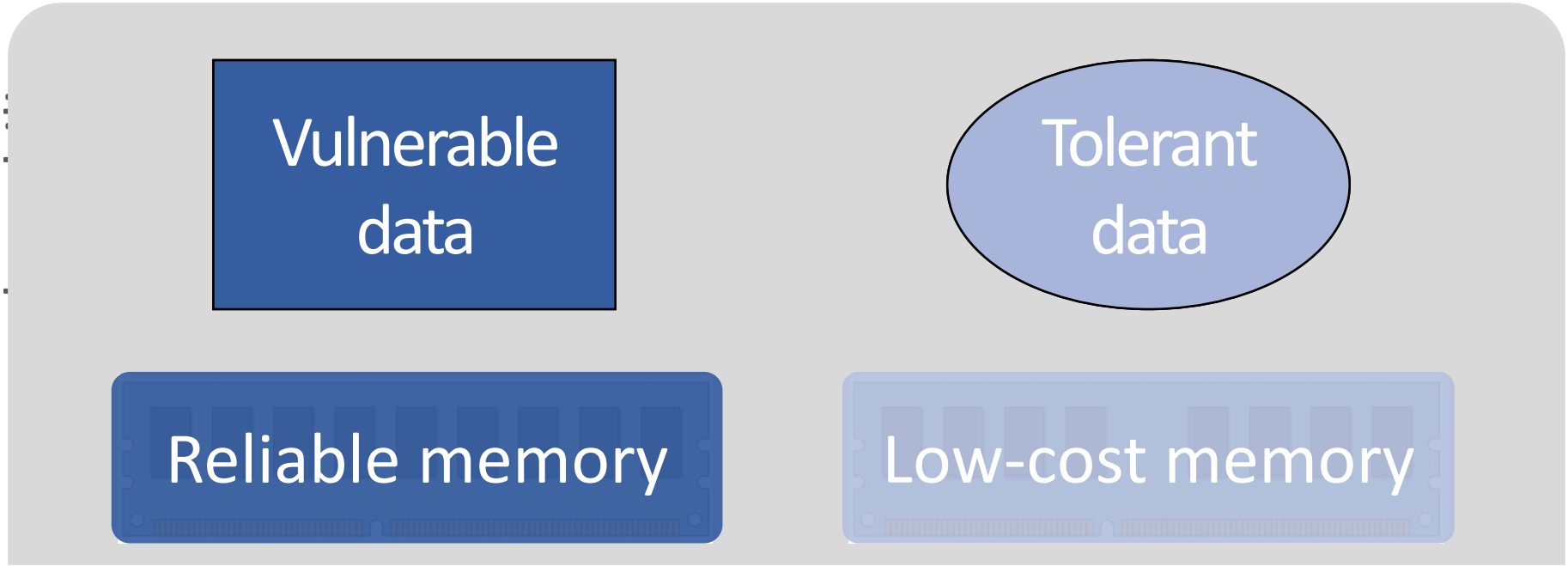
  [Luo+ DSN 2014]

- …



Fundamental solutions to security require co-design across the hierarchy

Exploiting Memory Error Tolerance with Hybrid Memory Systems



On Microsoft's Web Search workload

Reduces server hardware cost by 4.7 %

Achieves single server availability target of 99.90 %

Heterogeneous-**R**eliability **M**emory [DSN 2014]

More on Heterogeneous-Reliability Memory

- Yixin Luo, Sriram Govindan, Bikash Sharma, Mark Santaniello, Justin Meza, Aman Kansal, Jie Liu, Badriddine Khessib, Kushagra Vaid, and Onur Mutlu, **"Characterizing Application Memory Error Vulnerability to Optimize Data Center Cost via Heterogeneous-Reliability Memory"** *Proceedings of the 44th Annual IEEE/IFIP International Conference on Dependable Systems and Networks (**DSN**)*, Atlanta, GA, June 2014. [Summary] [Slides (pptx) (pdf)] [Coverage on ZDNet]

Characterizing Application Memory Error Vulnerability to Optimize Datacenter Cost via Heterogeneous-Reliability Memory

Yixin Luo Sriram Govindan* Bikash Sharma* Mark Santaniello* Justin Meza
Aman Kansal* Jie Liu* Badriddine Khessib* Kushagra Vaid* Onur Mutlu
Carnegie Mellon University, yixinluo@cs.cmu.edu, {meza, onur}@cmu.edu
*Microsoft Corporation, {srgovin, bsharma, marksan, kansal, jie.liu, bkhessib, kvaid}@microsoft.com

Summary: Memory Reliability and Security

- Memory reliability is reducing
- Reliability issues open up security vulnerabilities
  - Very hard to defend against
- Rowhammer is an example
  - Its implications on system security research are tremendous & exciting

- **Good news: We have a lot more to do.**
- Understand: Solid methodologies for failure modeling and discovery
  - Modeling based on real device data – small scale and large scale
- Architect: Principled co-architecting of system and memory
  - Good partitioning of duties across the stack
- Design & Test: Principled electronic design, automation, testing
  - High coverage and good interaction with system reliability methods

Challenge and Opportunity for Future

Fundamentally

Secure, Reliable, Safe

Computing Architectures

One Important Takeaway

Main Memory Needs Intelligent Controllers

Agenda

- Major Trends Affecting Main Memory
- Key Challenges and Solution Directions
  - Robustness: Reliability and Security
  - Energy and Performance: In-Memory Computation
  - Low Latency/Energy and Latency/Energy/Reliability Tradeoffs
  - Scalability and More: Enabling Emerging Technologies
- Solution Principles
- Concluding Remarks

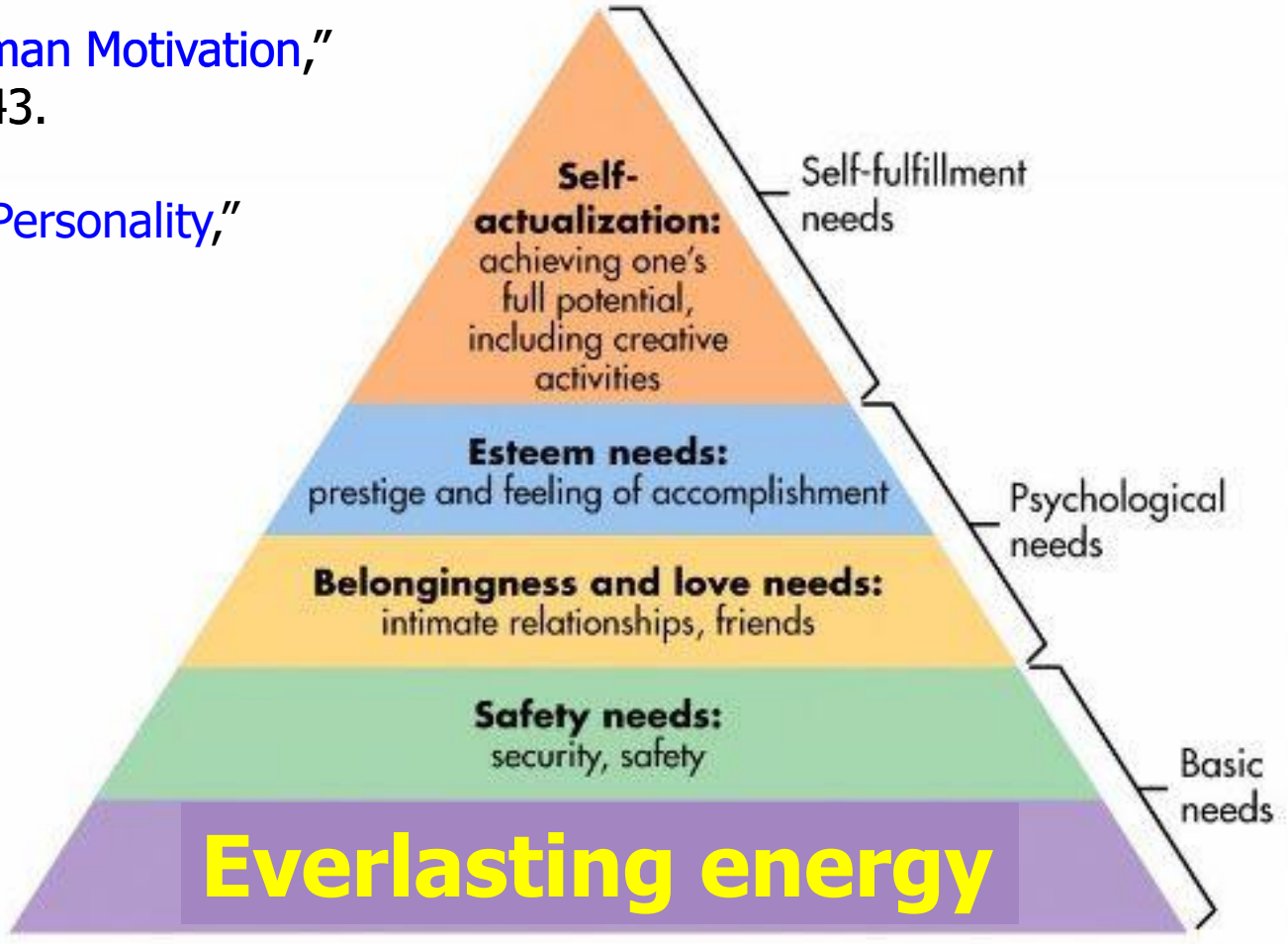
Four Key Issues in Future Platforms

- Fundamentally Secure/Reliable/Safe Architectures
- Fundamentally Energy-Efficient Architectures
  - Memory-centric (Data-centric) Architectures
- Fundamentally Low-Latency Architectures
- Architectures for Genomics, Medicine, Health

Maslow's (Human) Hierarchy of Needs, Revisited

Maslow, "A Theory of Human Motivation," Psychological Review, 1943.

Maslow, "Motivation and Personality," Book, 1954-1970.

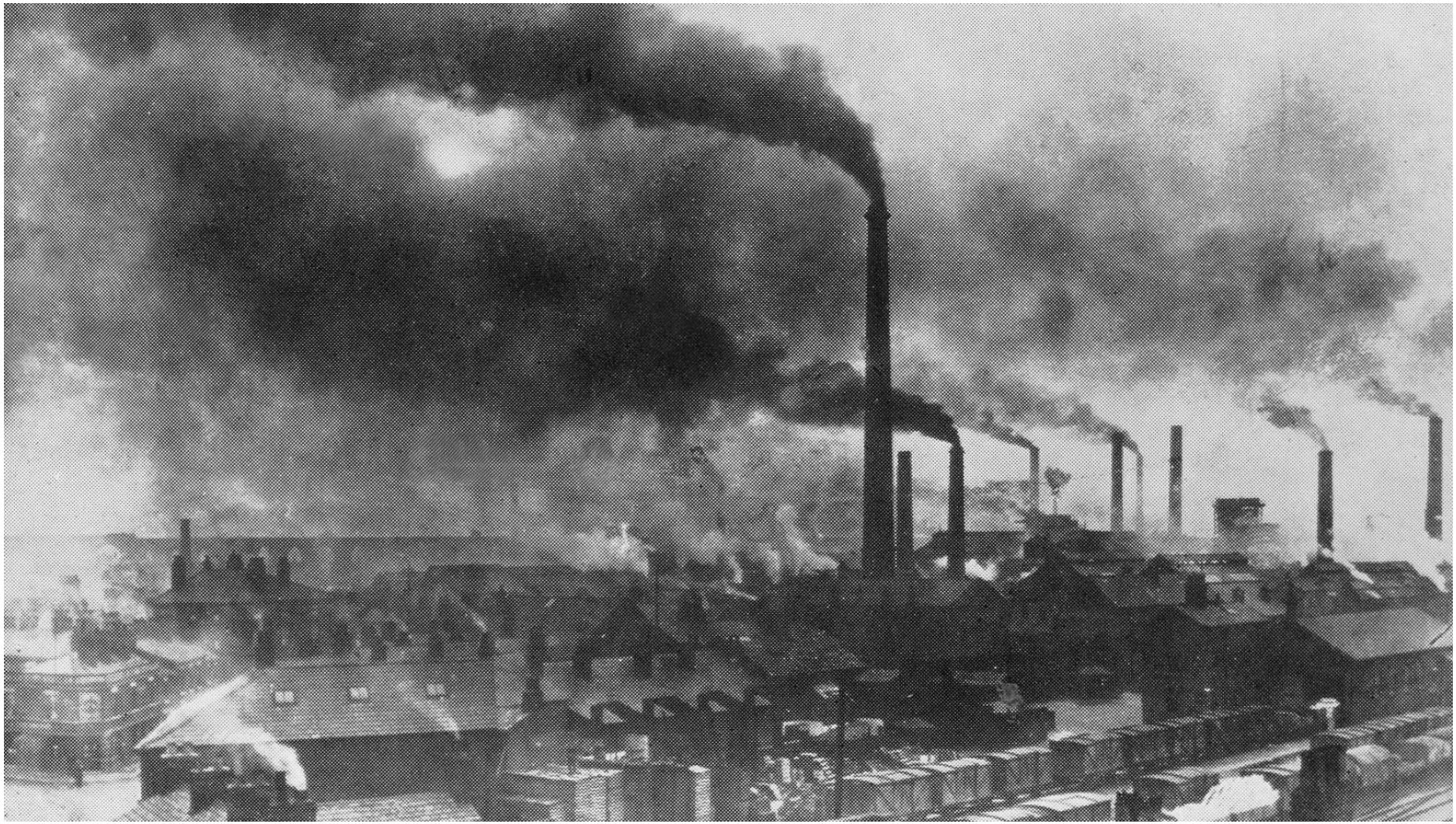


Source: https://www.simplypsychology.org/maslow.html

Do We Want This?

Source: V. Milutinovic

Or This?



Source: V. Milutinovic

Challenge and Opportunity for Future

Sustainable

and

Energy Efficient

The Problem

Data access is the major performance and energy bottleneck

Our current

design principles

cause great energy waste

(and great performance loss)

The Problem

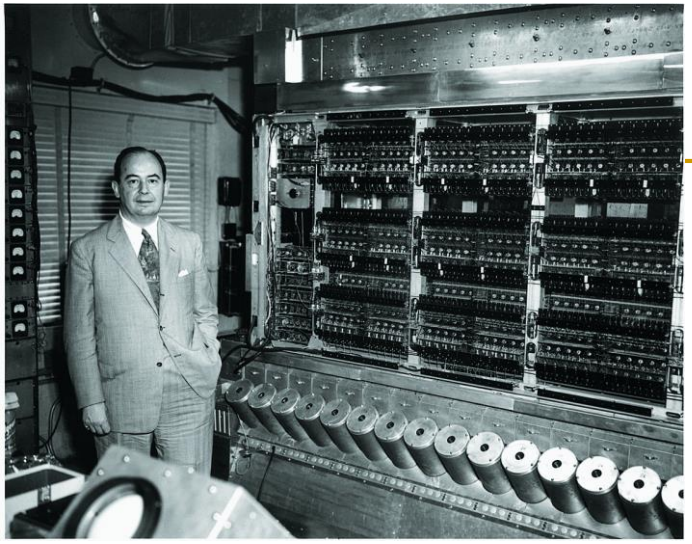
Processing of data

is performed

far away from the data

A Computing System

- Three key components
- Computation
- Communication
- Storage/memory



Burks, Goldstein, von Neumann, "Preliminary discussion of the logical design of an electronic computing instrument," 1946.

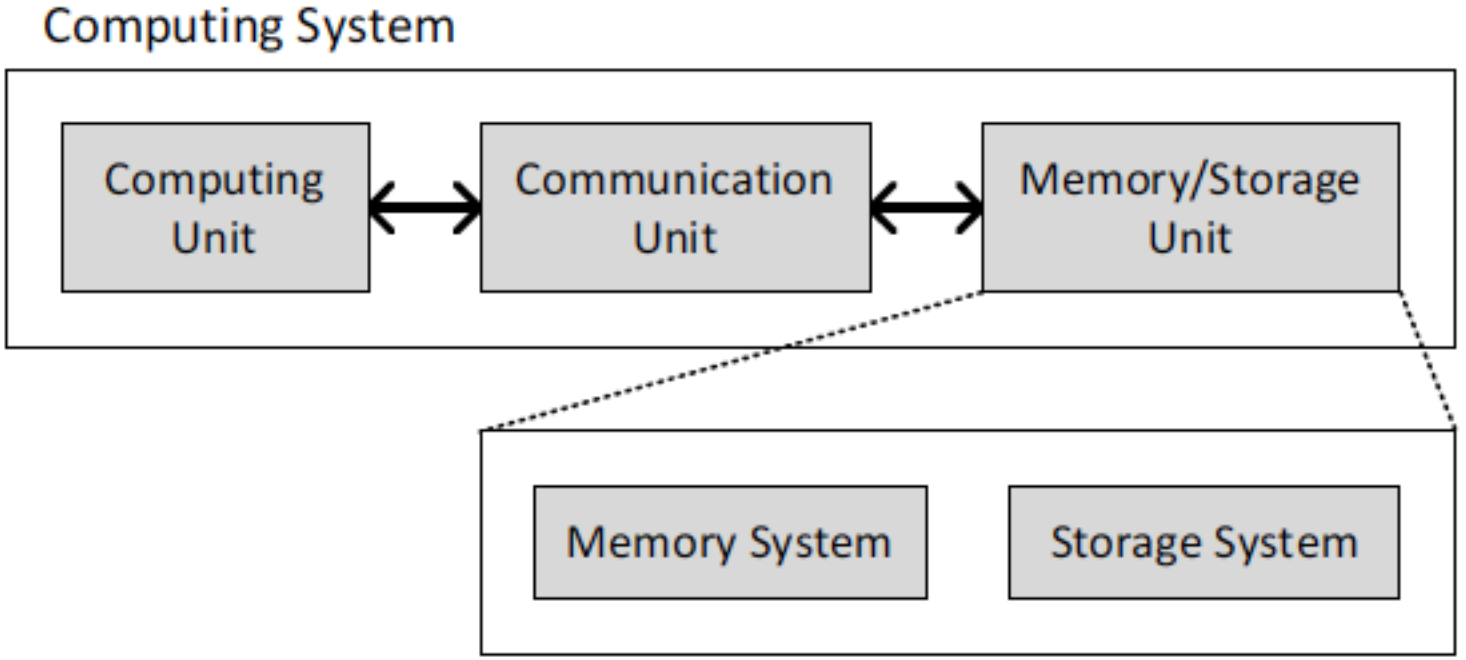


Image source: https://lbsitbytes2010.wordpress.com/2013/03/29/john-von-neumann-roll-no-15/

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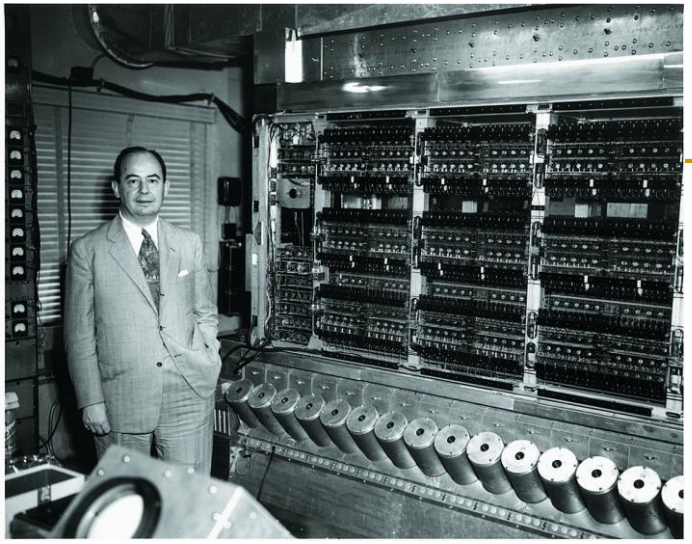

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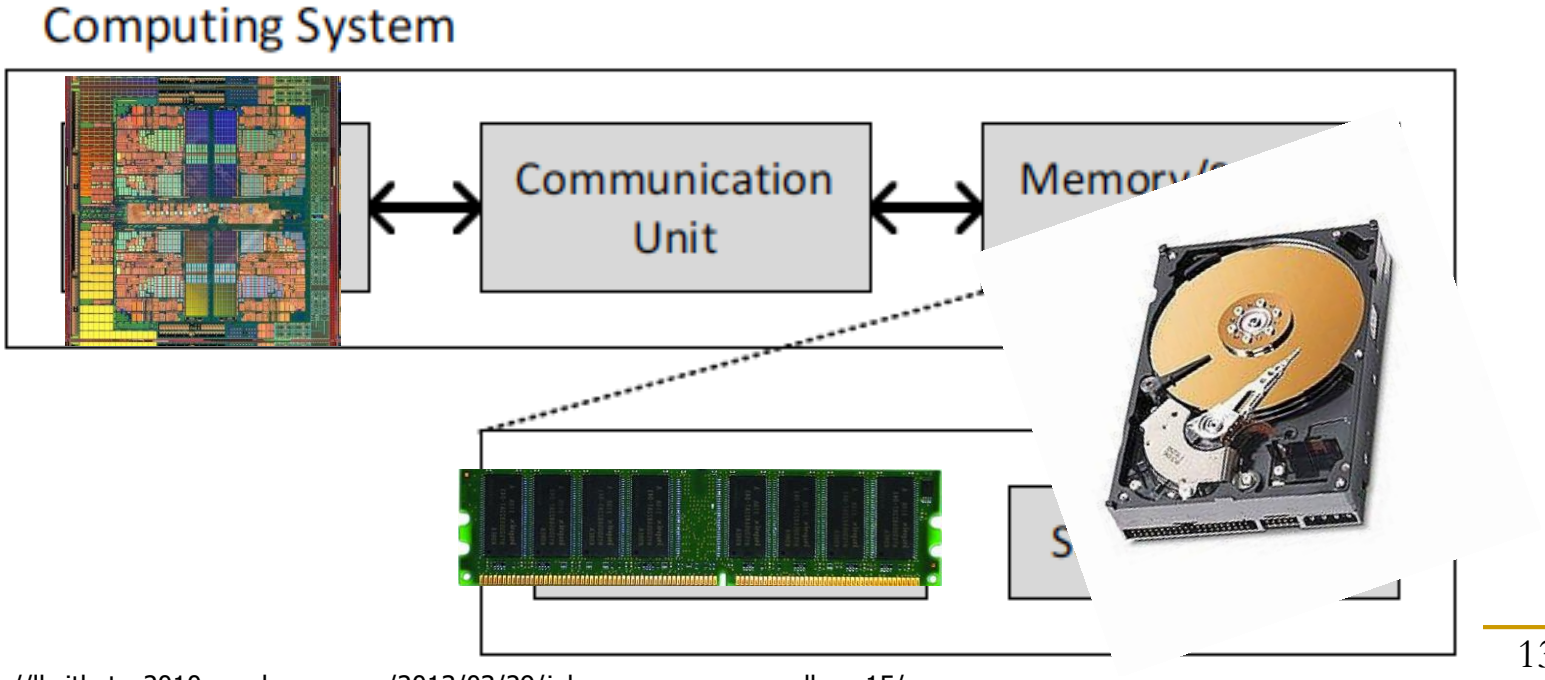
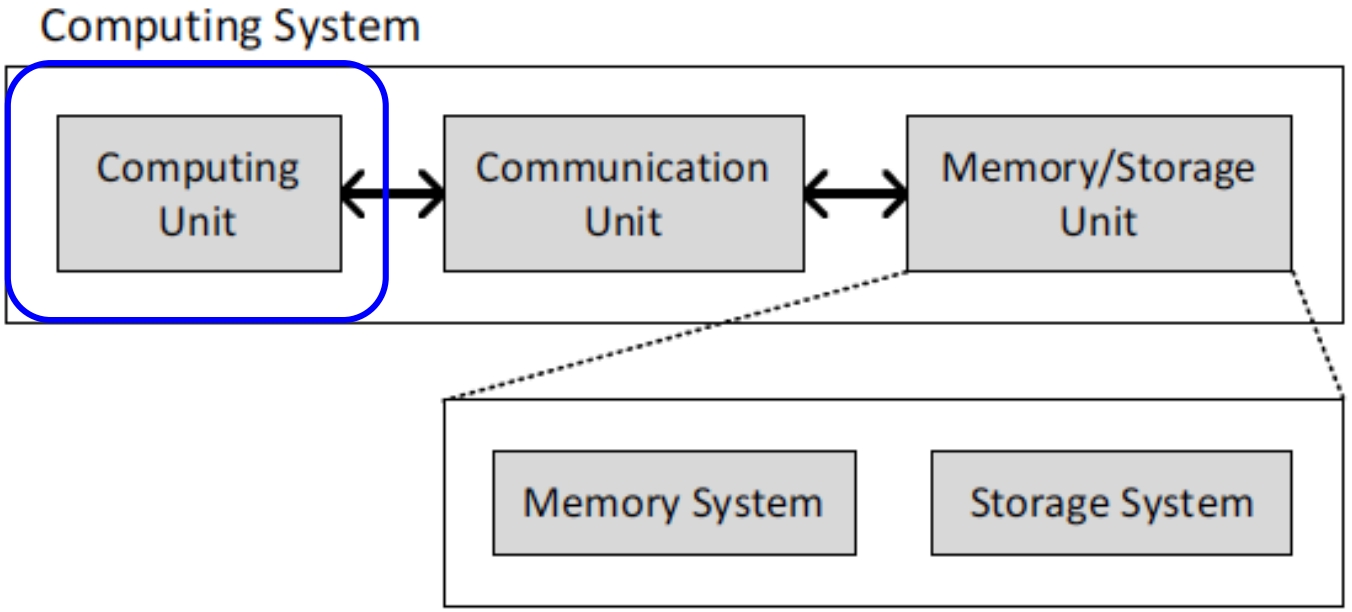


Image source: https://lbsitbytes2010.wordpress.com/2013/03/29/john-von-neumann-roll-no-15/

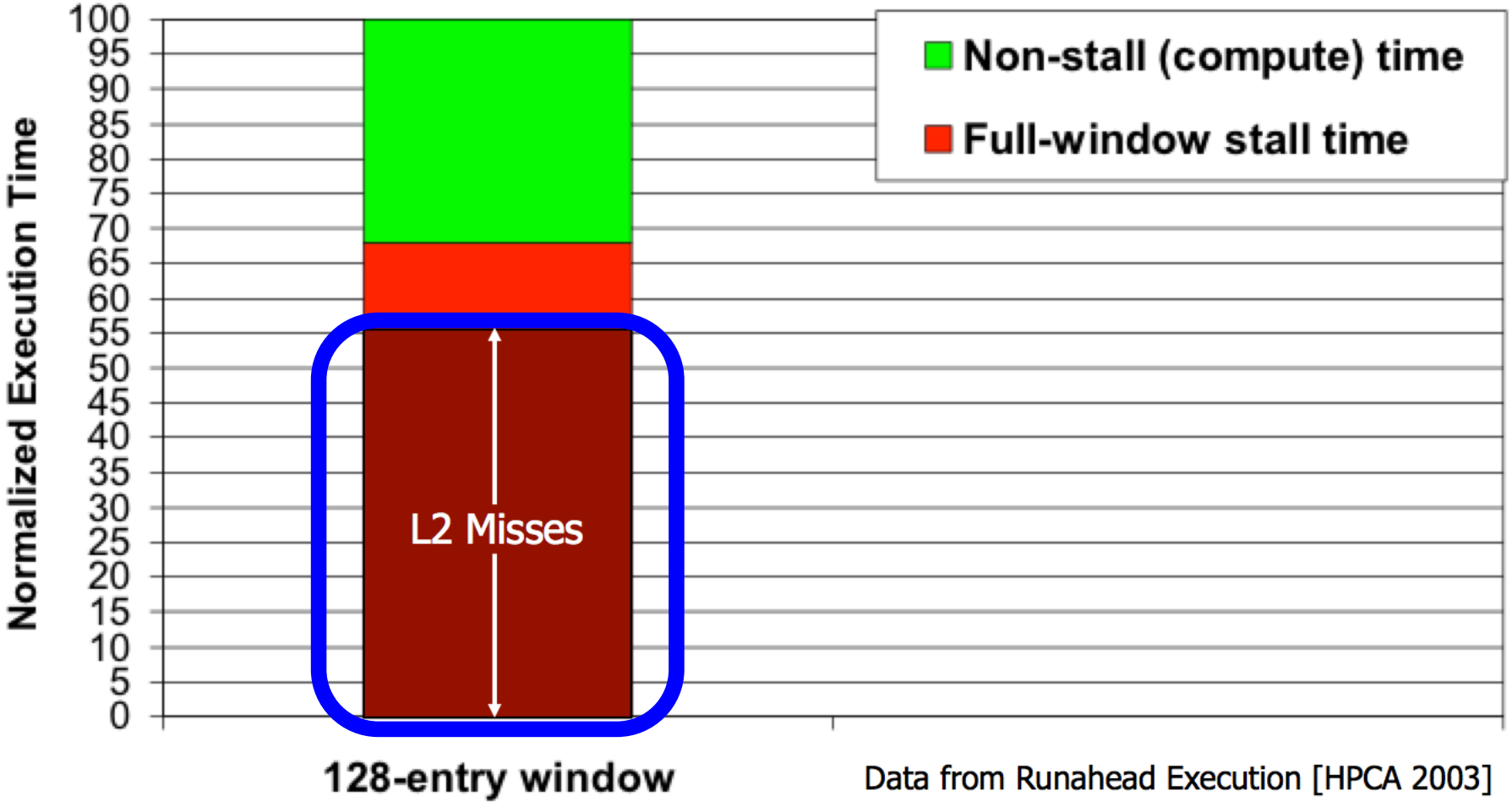
Today's Computing Systems

- Are overwhelmingly processor centric
- All data processed in the processor → at great system cost
- Processor is heavily optimized and is considered the master
- Data storage units are dumb and are largely unoptimized (except for some that are on the processor die)



Yet …

- "**It's the Memory, Stupid!**" (Richard Sites, MPR, 1996)



The Performance Perspective

- Onur Mutlu, Jared Stark, Chris Wilkerson, and Yale N. Patt, **"Runahead Execution: An Alternative to Very Large Instruction Windows for Out-of-order Processors"** *Proceedings of the 9th International Symposium on High-Performance Computer Architecture (**HPCA**)*, pages 129-140, Anaheim, CA, February 2003. Slides (pdf)

Runahead Execution: An Alternative to Very Large Instruction Windows for Out-of-order Processors

Onur Mutlu § Jared Stark † Chris Wilkerson ‡ Yale N. Patt §

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The University of Texas at Austin
{onur,patt}@ece.utexas.edu

†Microprocessor Research
Intel Labs
jared.w.stark@intel.com

‡Desktop Platforms Group
Intel Corporation
chris.wilkerson@intel.com

The Performance Perspective (Today)

- All of Google's Data Center Workloads (2015):

Kanev+, "Profiling a Warehouse-Scale Computer," ISCA 2015.

The Performance Perspective (Today)

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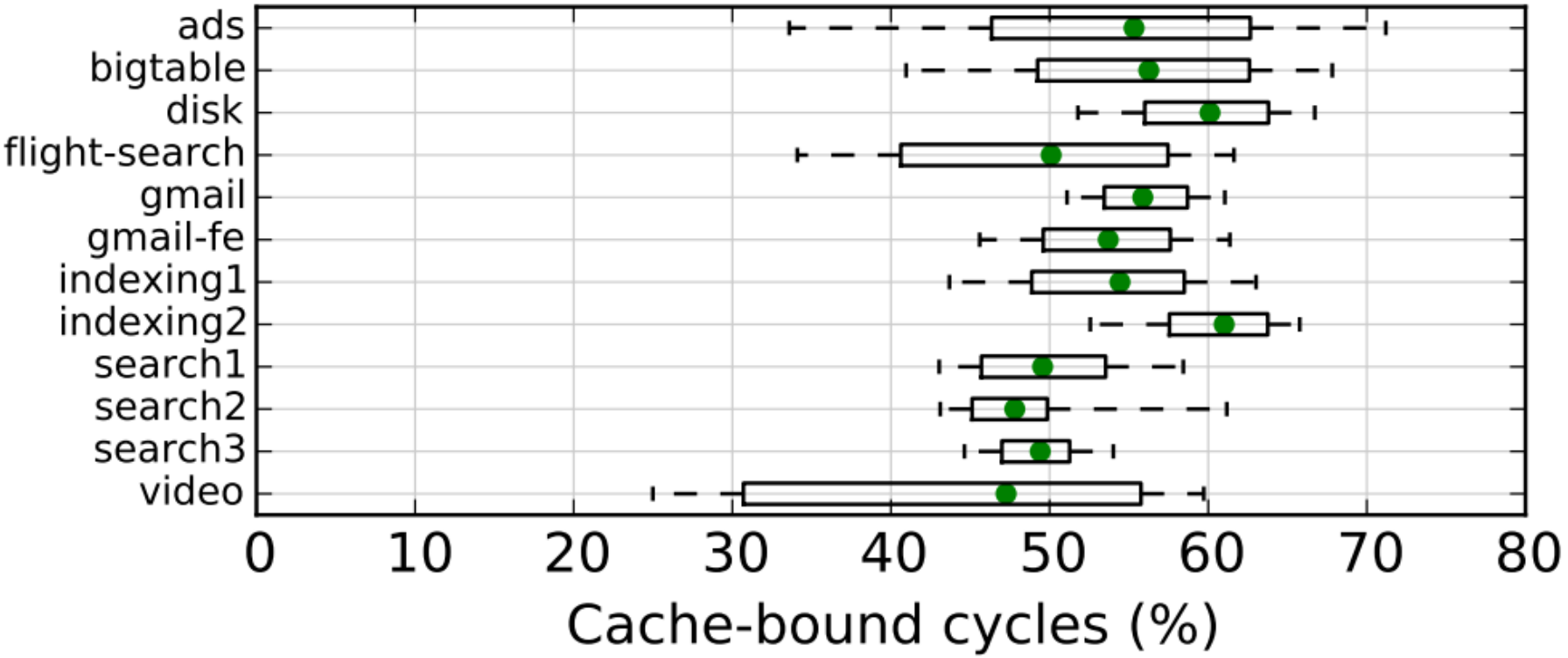


Figure 11: Half of cycles are spent stalled on caches.

Kanev+, "Profiling a Warehouse-Scale Computer," ISCA 2015.

Perils of Processor-Centric Design

- Grossly-imbalanced systems
  - Processing done only in **one place**
  - Everything else just stores and moves data: **data moves a lot**

  → Energy inefficient

  → Low performance

  → Complex

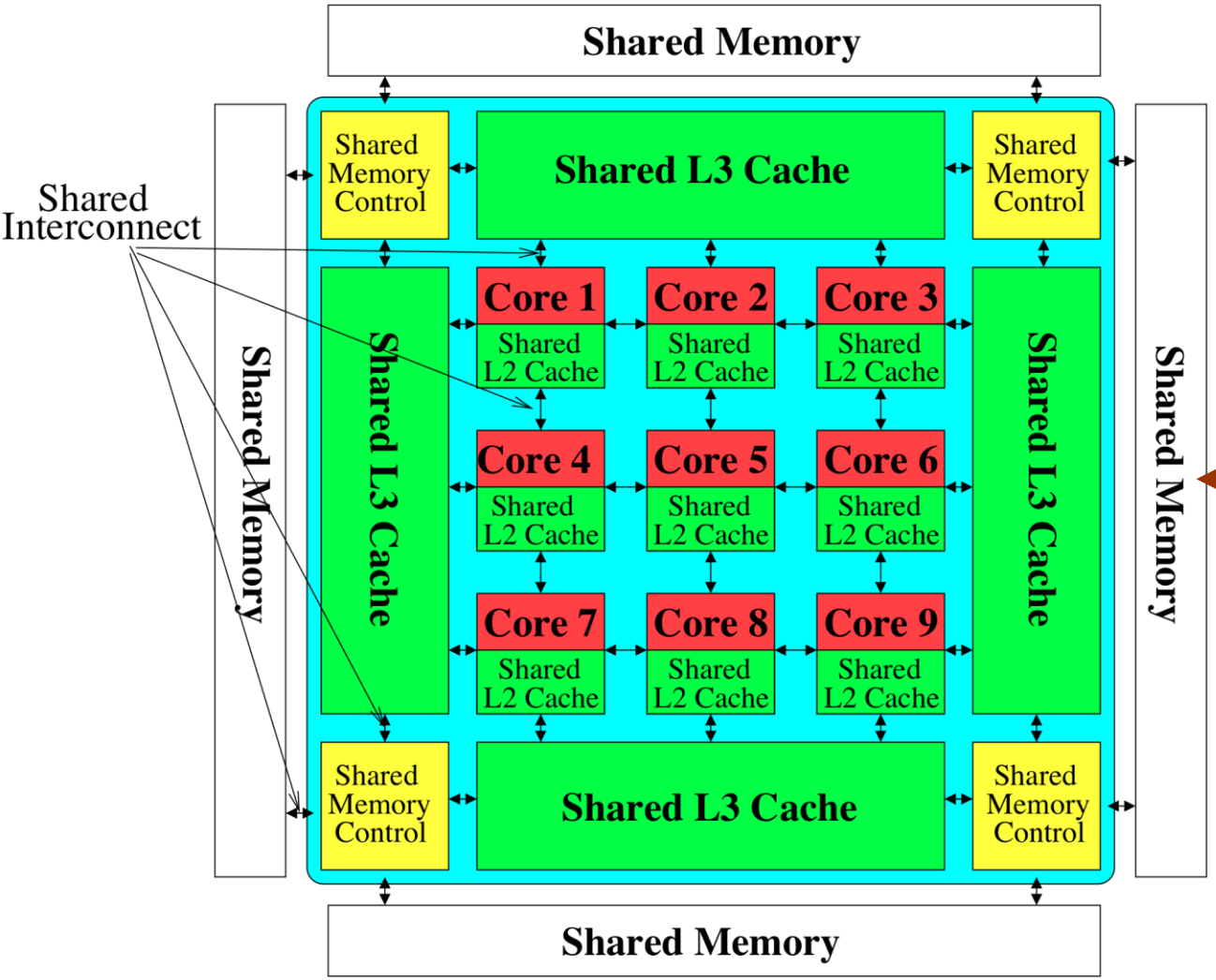
- Overly complex and bloated processor (and accelerators)
  - To tolerate data access from memory
  - Complex hierarchies and mechanisms

  → Energy inefficient

  → Low performance

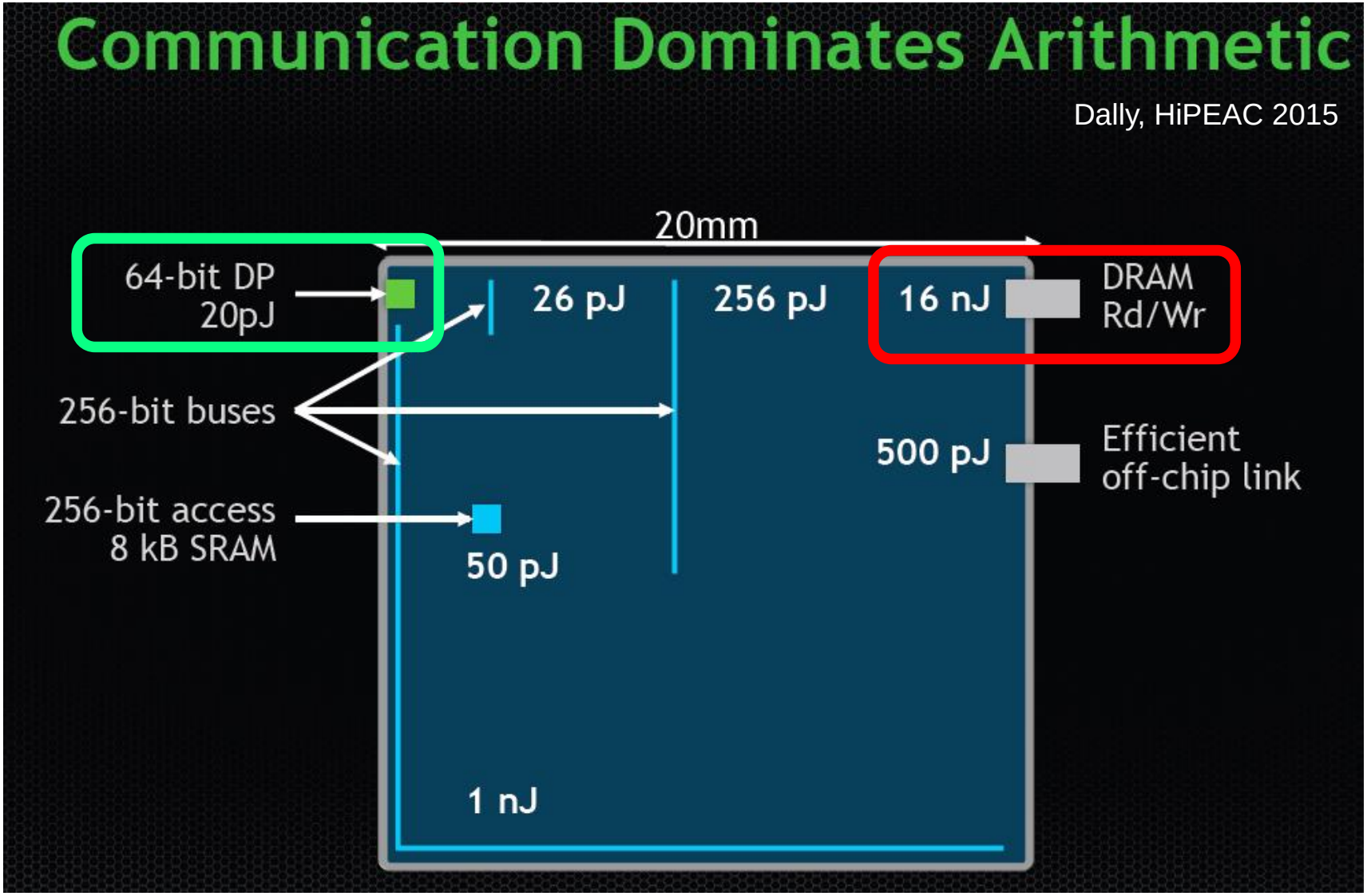
  → Complex

Perils of Processor-Centric Design

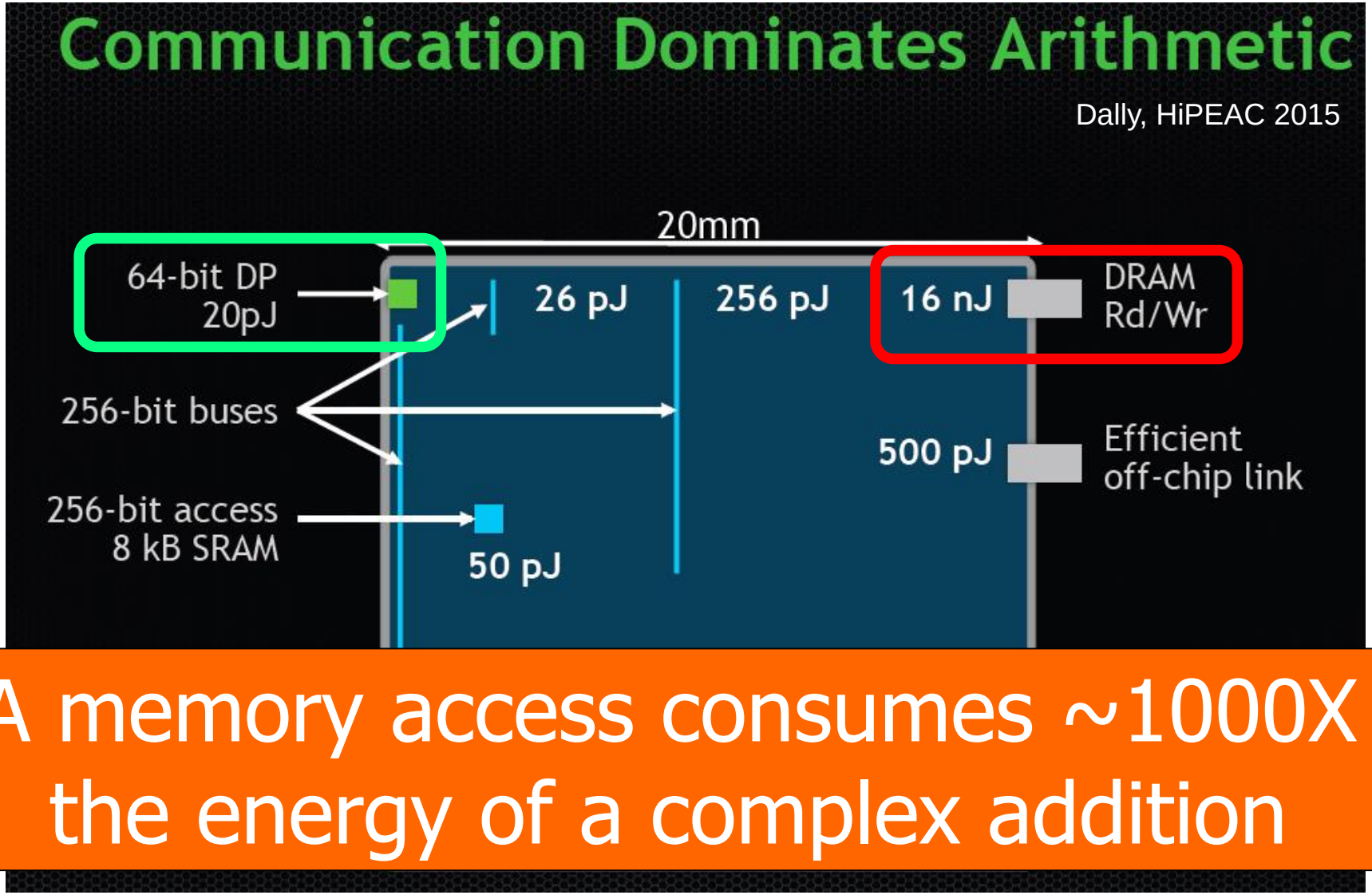


Most of the system is dedicated to storing and moving data

The Energy Perspective



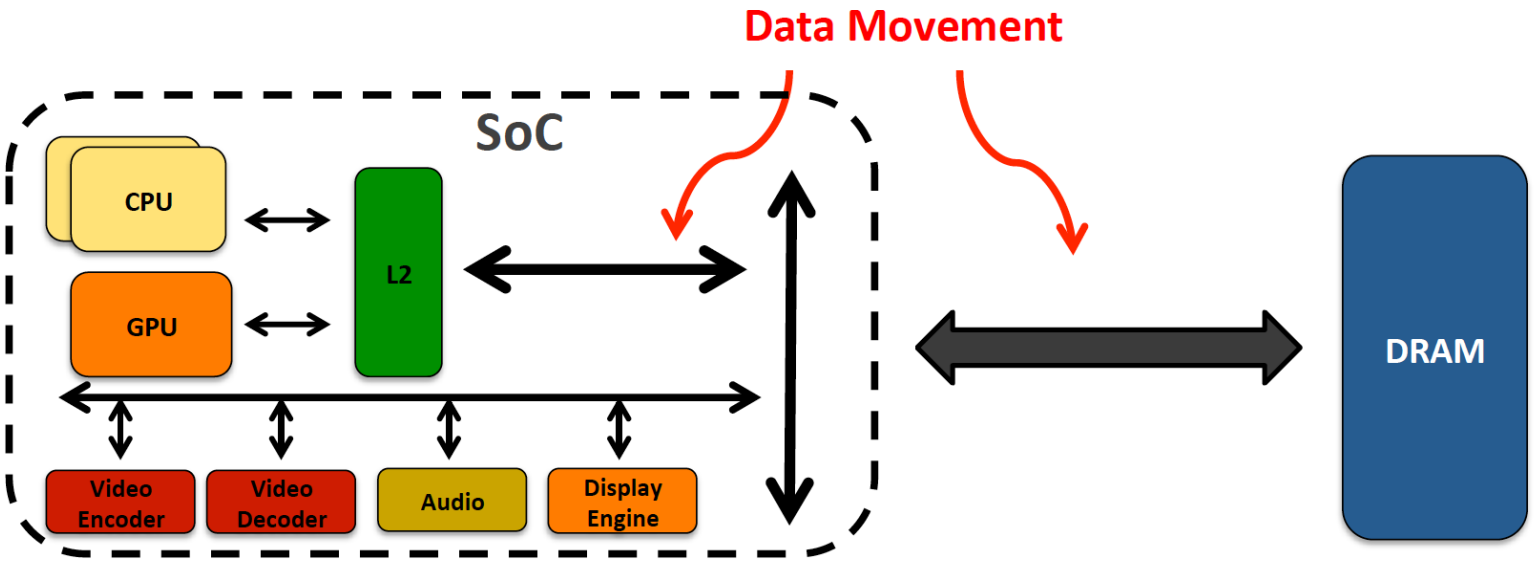
Data Movement vs. Computation Energy



A memory access consumes ~1000X the energy of a complex addition

Data Movement vs. Computation Energy

- Data movement is a major system energy bottleneck
  - Comprises 41% of mobile system energy during web browsing [2]
  - Costs ~115 times as much energy as an ADD operation [1, 2]



[1]: Reducing data Movement Energy via Online Data Clustering and Encoding (MICRO'16)

[2]: Quantifying the energy cost of data movement for emerging smart phone workloads on mobile platforms (IISWC'14)

Energy Waste in Mobile Devices

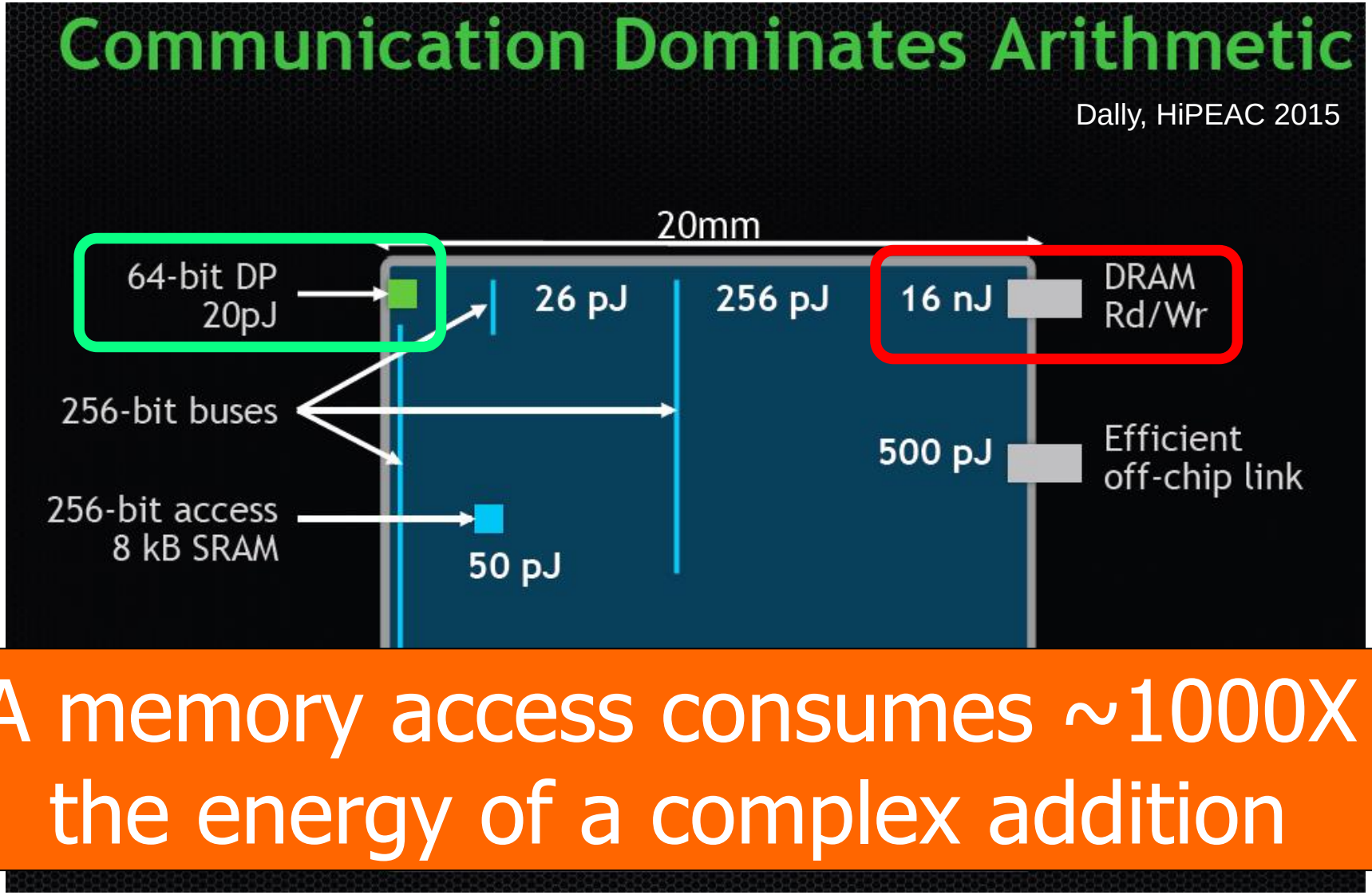
- Amirali Boroumand, Saugata Ghose, Youngsok Kim, Rachata Ausavarungnirun, Eric Shiu, Rahul Thakur, Daehyun Kim, Aki Kuusela, Allan Knies, Parthasarathy Ranganathan, and Onur Mutlu, **"Google Workloads for Consumer Devices: Mitigating Data Movement Bottlenecks"** *Proceedings of the 23rd International Conference on Architectural Support for Programming Languages and Operating Systems (**ASPLOS**)*, Williamsburg, VA, USA, March 2018.

62.7% of the total system energy is spent on data movement

Google Workloads for Consumer Devices: Mitigating Data Movement Bottlenecks

Amirali Boroumand[1] Saugata Ghose[1] Youngsok Kim[2]
Rachata Ausavarungnirun[1] Eric Shiu[3] Rahul Thakur[3] Daehyun Kim[4,3]
Aki Kuusela[3] Allan Knies[3] Parthasarathy Ranganathan[3] Onur Mutlu[5,1]

We Do Not Want to Move Data!

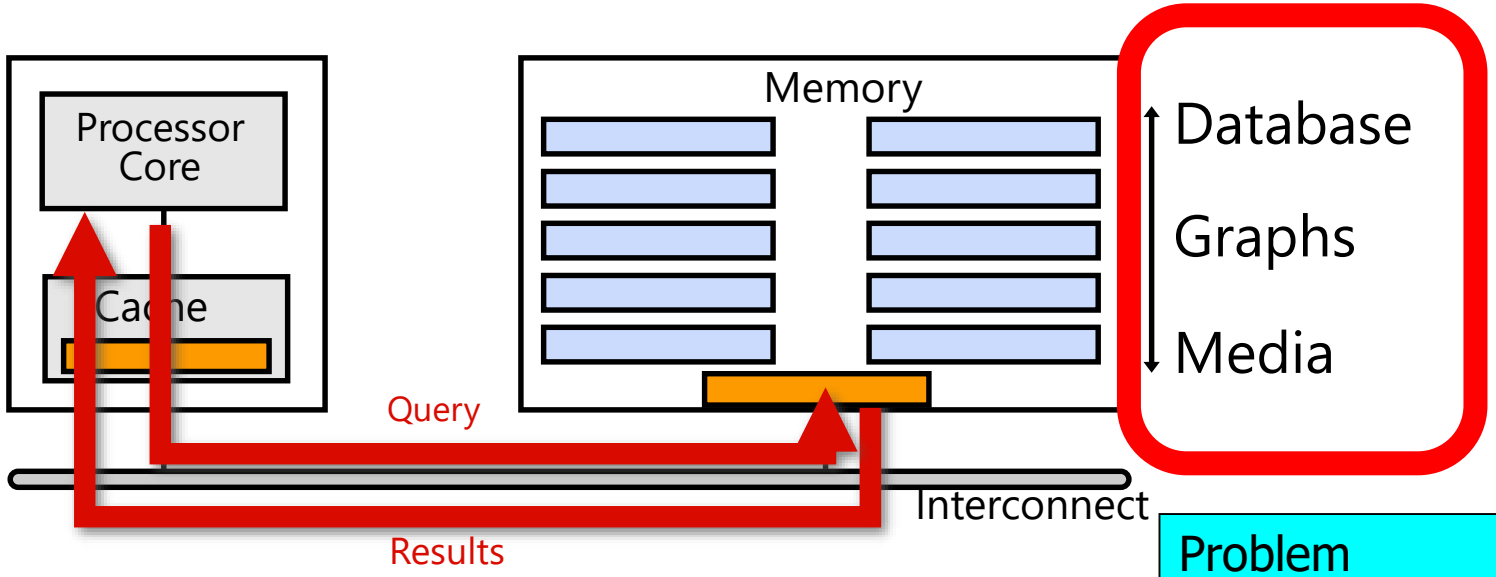


A memory access consumes ~1000X the energy of a complex addition

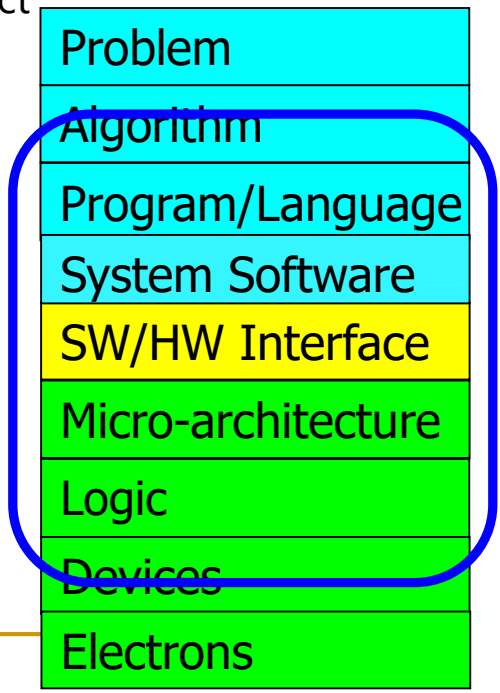
We Need A Paradigm Shift To …

- Enable computation with minimal data movement
- Compute where it makes sense (where data resides)
- Make computing architectures more data-centric

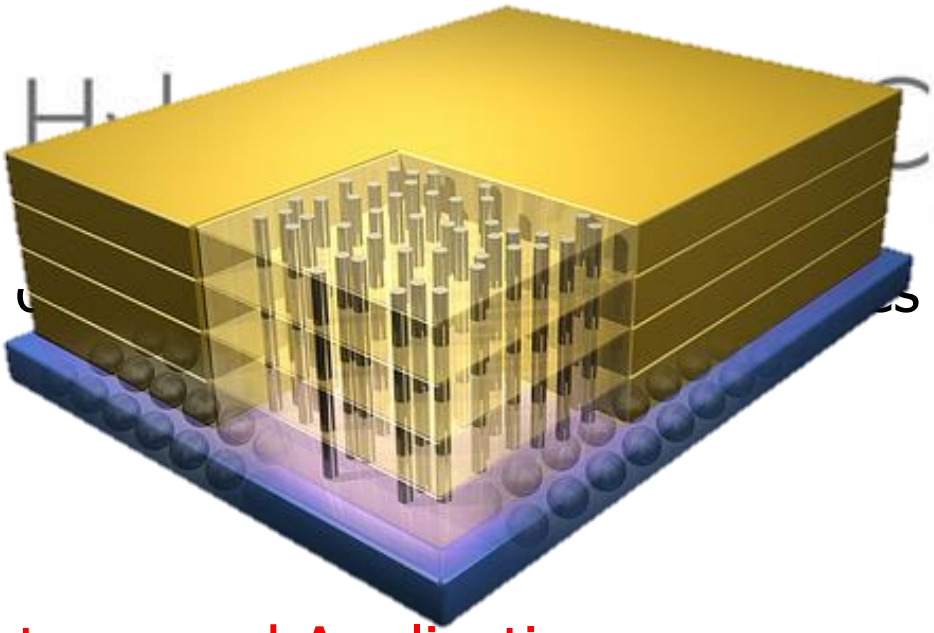
Goal: Processing Inside Memory



- Many questions … How do we design the:
  - compute-capable memory & controllers?
  - processor chip and in-memory units?
  - software and hardware interfaces?
  - system software and languages?
  - algorithms?



Why In-Memory Computation Today?



Dally, HiPEAC 2

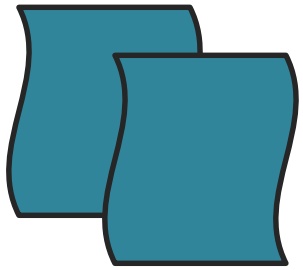
- Pull from Systems and Applications
  - Data access is a major system and application bottleneck
  - Systems are energy limited
  - Data movement much more energy-hungry than computation

Processing in Memory: Two Approaches

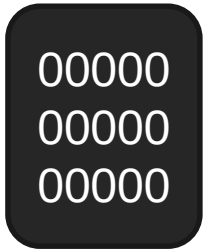
1. Minimally changing memory chips
2. Exploiting 3D-stacked memory

Starting Simple: Data Copy and Initialization

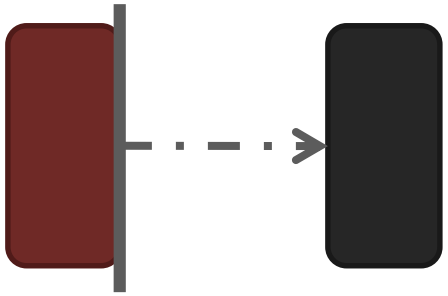
memmove & memcpy: 5% cycles in Google's datacenter [Kanev+ ISCA'15]



Forking

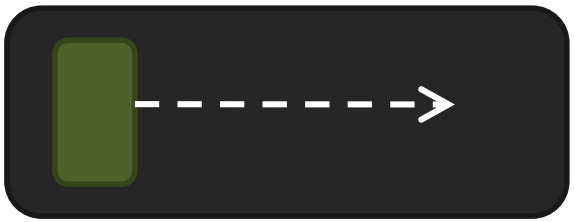


Zero initialization (e.g., security)



Checkpointing

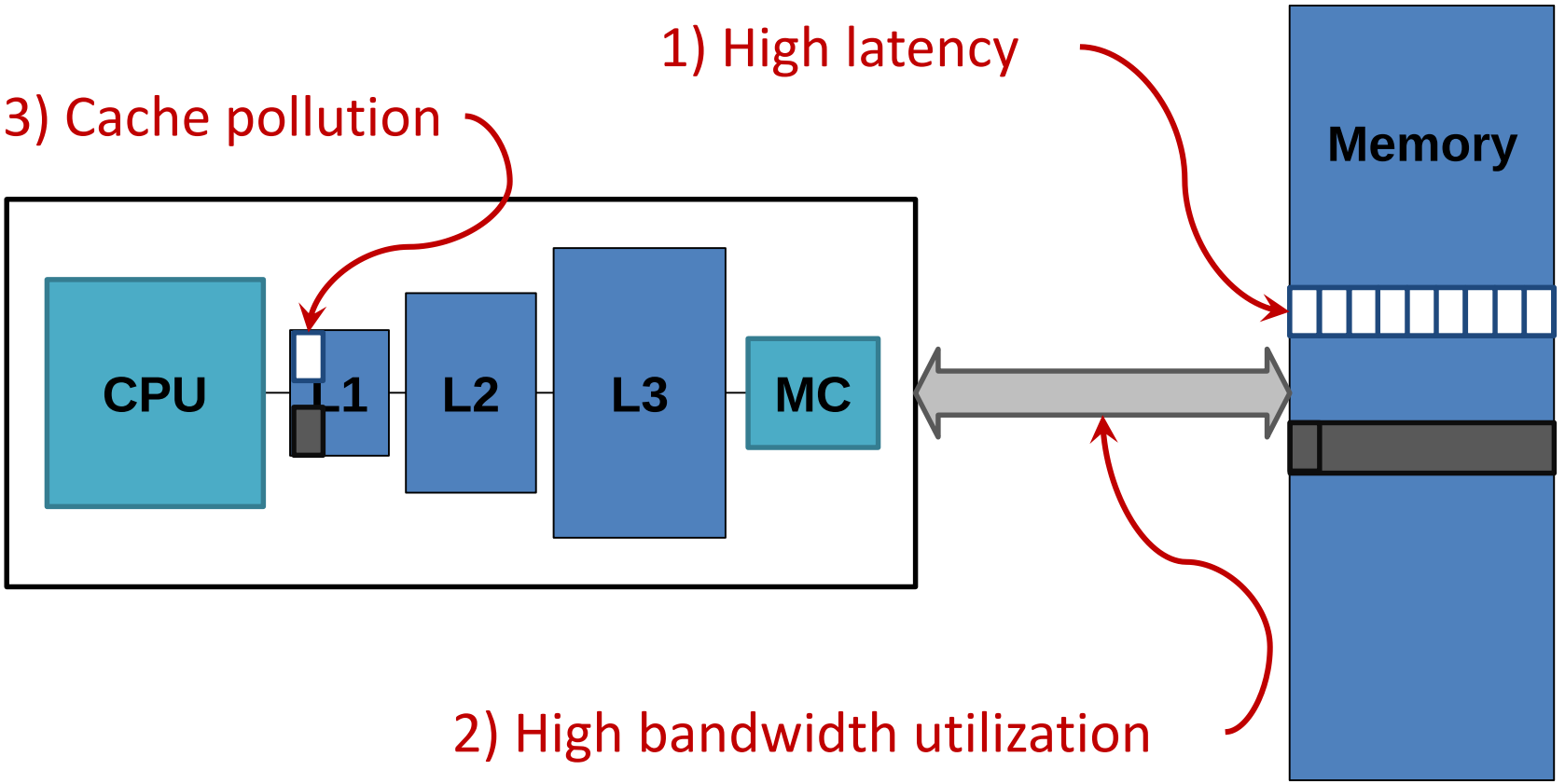
VM Cloning
Deduplication



Page Migration

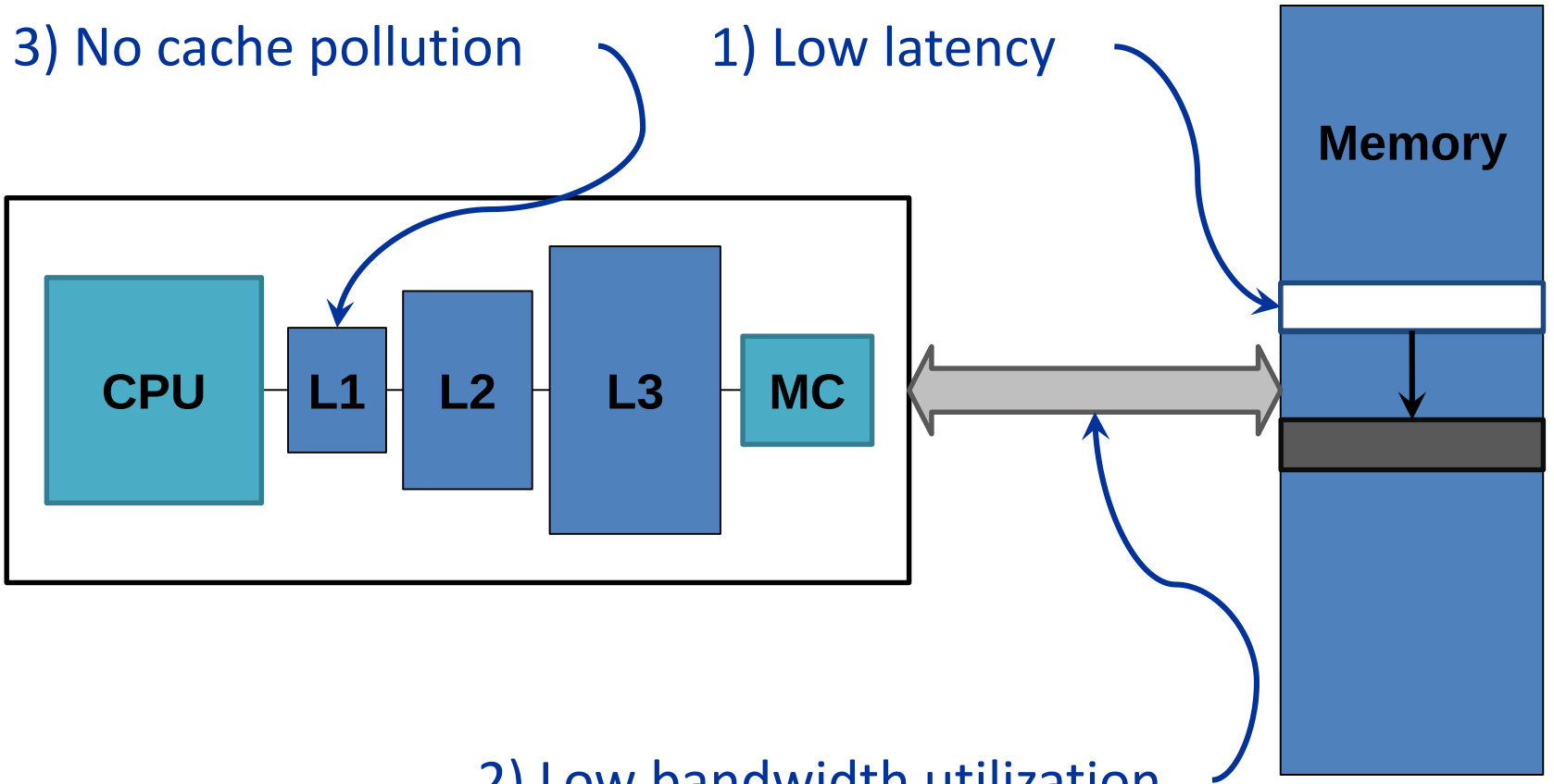
• • •
Many more

Today's Systems: Bulk Data Copy



1046ns, 3.6uJ (for 4KB page copy via DMA)

Future Systems: In-Memory Copy

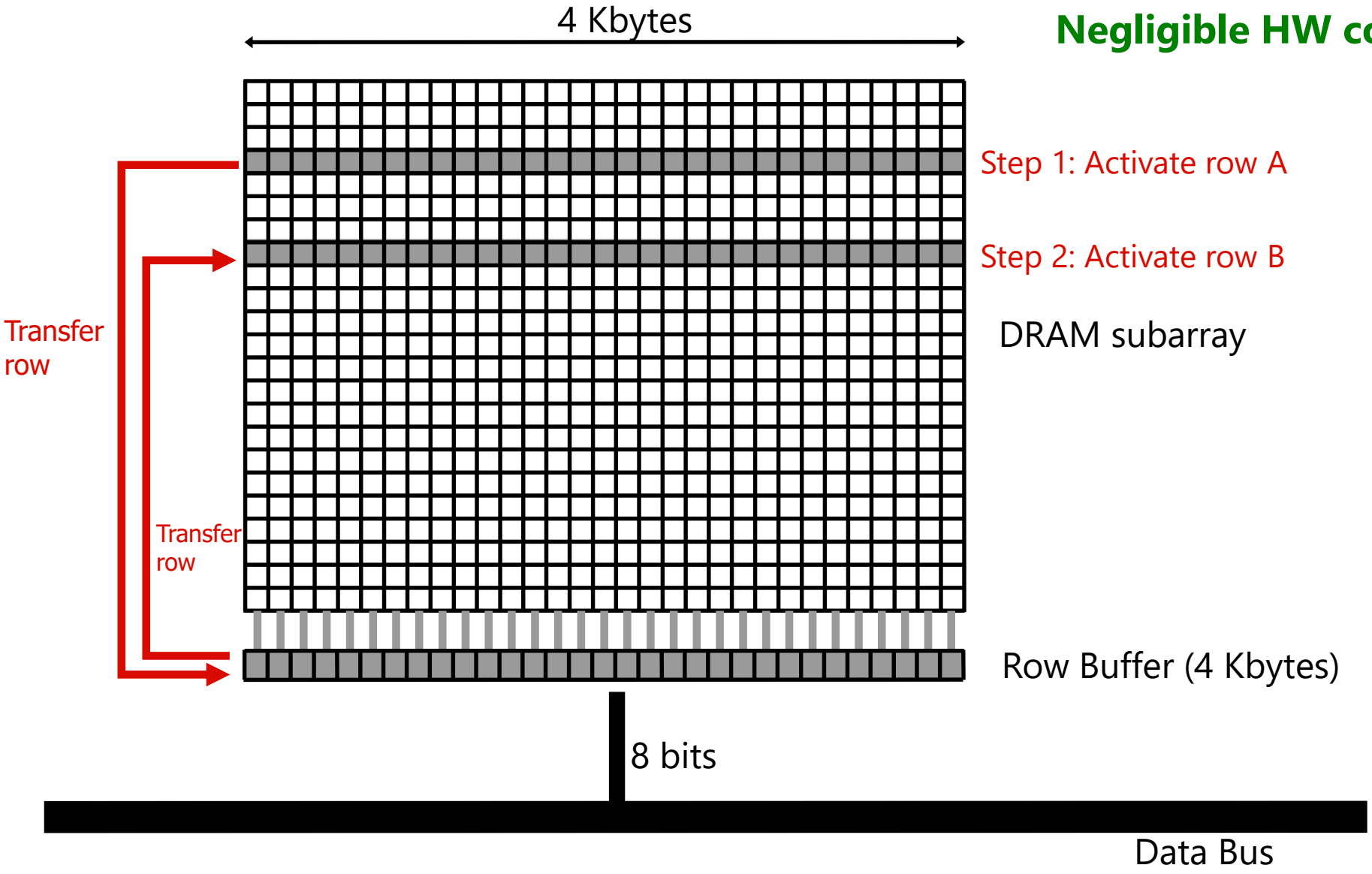


1046ns, 3.6uJ → 90ns, 0.04uJ

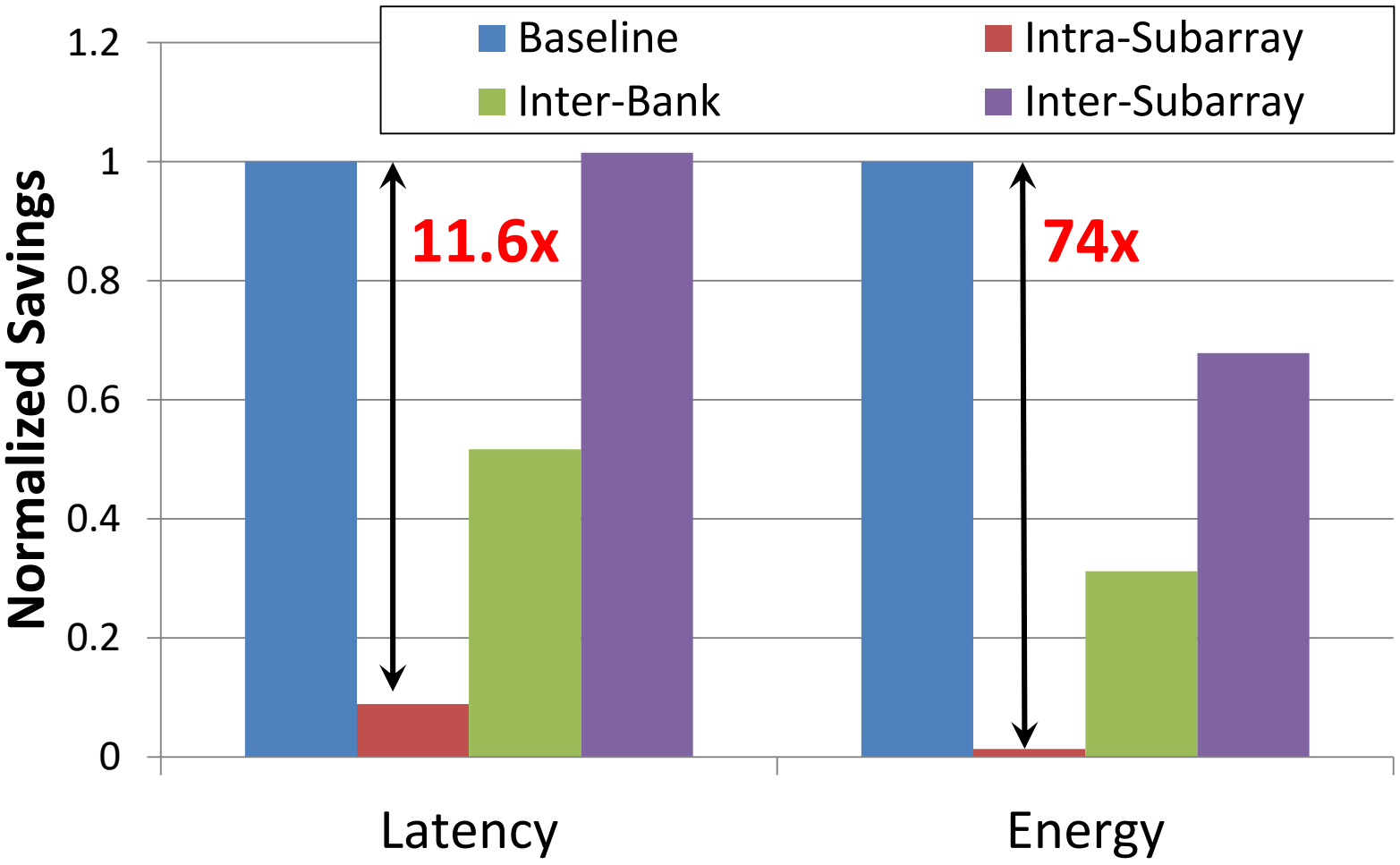
RowClone: In-DRAM Row Copy

Idea: Two consecutive ACTivates

Negligible HW cost



RowClone: Latency and Energy Savings



Seshadri et al., "RowClone: Fast and Efficient In-DRAM Copy and Initialization of Bulk Data," MICRO 2013.

More on RowClone

- Vivek Seshadri, Yoongu Kim, Chris Fallin, Donghyuk Lee, Rachata Ausavarungnirun, Gennady Pekhimenko, Yixin Luo, Onur Mutlu, Michael A. Kozuch, Phillip B. Gibbons, and Todd C. Mowry,
  "RowClone: Fast and Energy-Efficient In-DRAM Bulk Data Copy and Initialization"
  *Proceedings of the 46th International Symposium on Microarchitecture (**MICRO**)*, Davis, CA, December 2013. [Slides (pptx) (pdf)] [Lightning Session Slides (pptx) (pdf)] [Poster (pptx) (pdf)]

RowClone: Fast and Energy-Efficient In-DRAM Bulk Data Copy and Initialization

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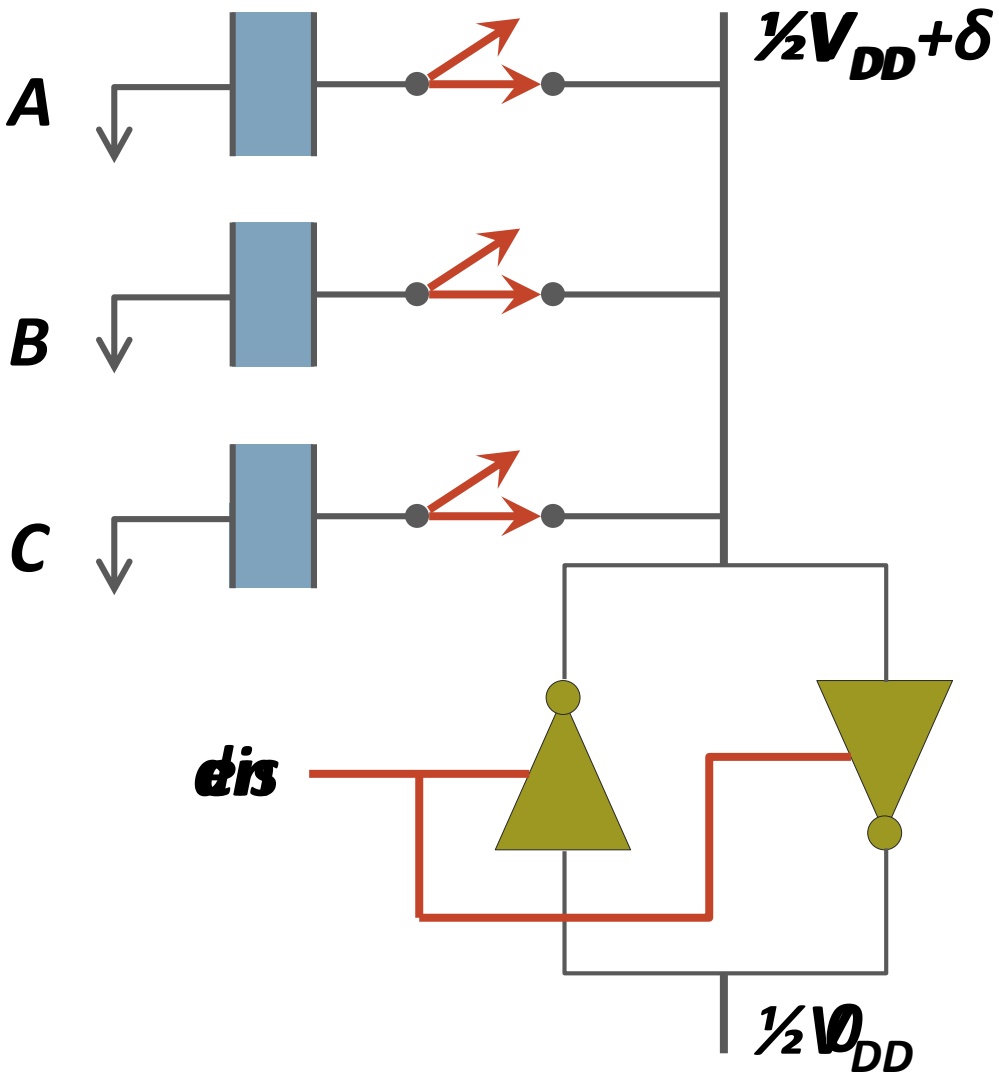
Carnegie Mellon University †Intel Pittsburgh

In-Memory Bulk Bitwise Operations

- We can support in-DRAM COPY, ZERO, AND, OR, NOT, MAJ
- At low cost
- Using analog computation capability of DRAM
  - Idea: activating multiple rows performs computation
- 30-60X performance and energy improvement
  - Seshadri+, "Ambit: In-Memory Accelerator for Bulk Bitwise Operations Using Commodity DRAM Technology," MICRO 2017.

- New memory technologies enable even more opportunities
  - Memristors, resistive RAM, phase change mem, STT-MRAM, …
  - Can operate on data with minimal movement

In-DRAM AND/OR: Triple Row Activation



Final State
AB + BC + AC

C(A + B) + ~C(AB)

Seshadri+, "Fast Bulk Bitwise AND and OR in DRAM", IEEE CAL 2015.

In-DRAM NOT: Dual Contact Cell

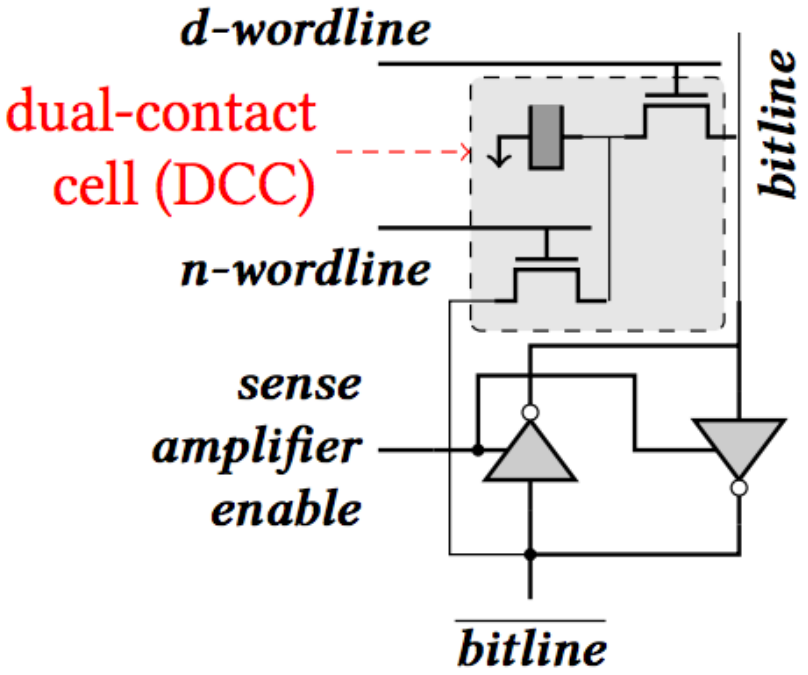


Figure 5: A dual-contact cell connected to both ends of a sense amplifier

Idea:

Feed the negated value in the sense amplifier into a special row

Seshadri+, "Ambit: In-Memory Accelerator for Bulk Bitwise Operations using Commodity DRAM Technology," MICRO 2017.

Performance: In-DRAM Bitwise Operations

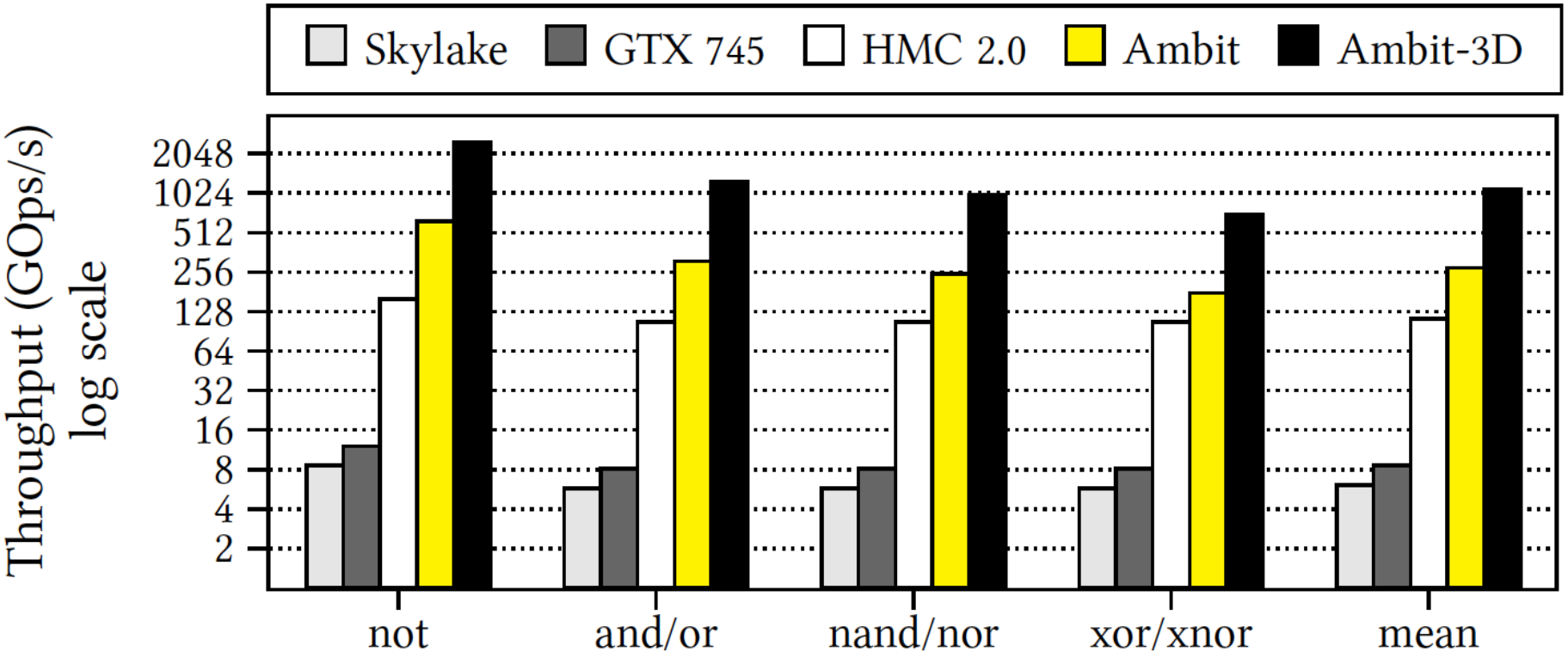


Figure 9: Throughput of bitwise operations on various systems.

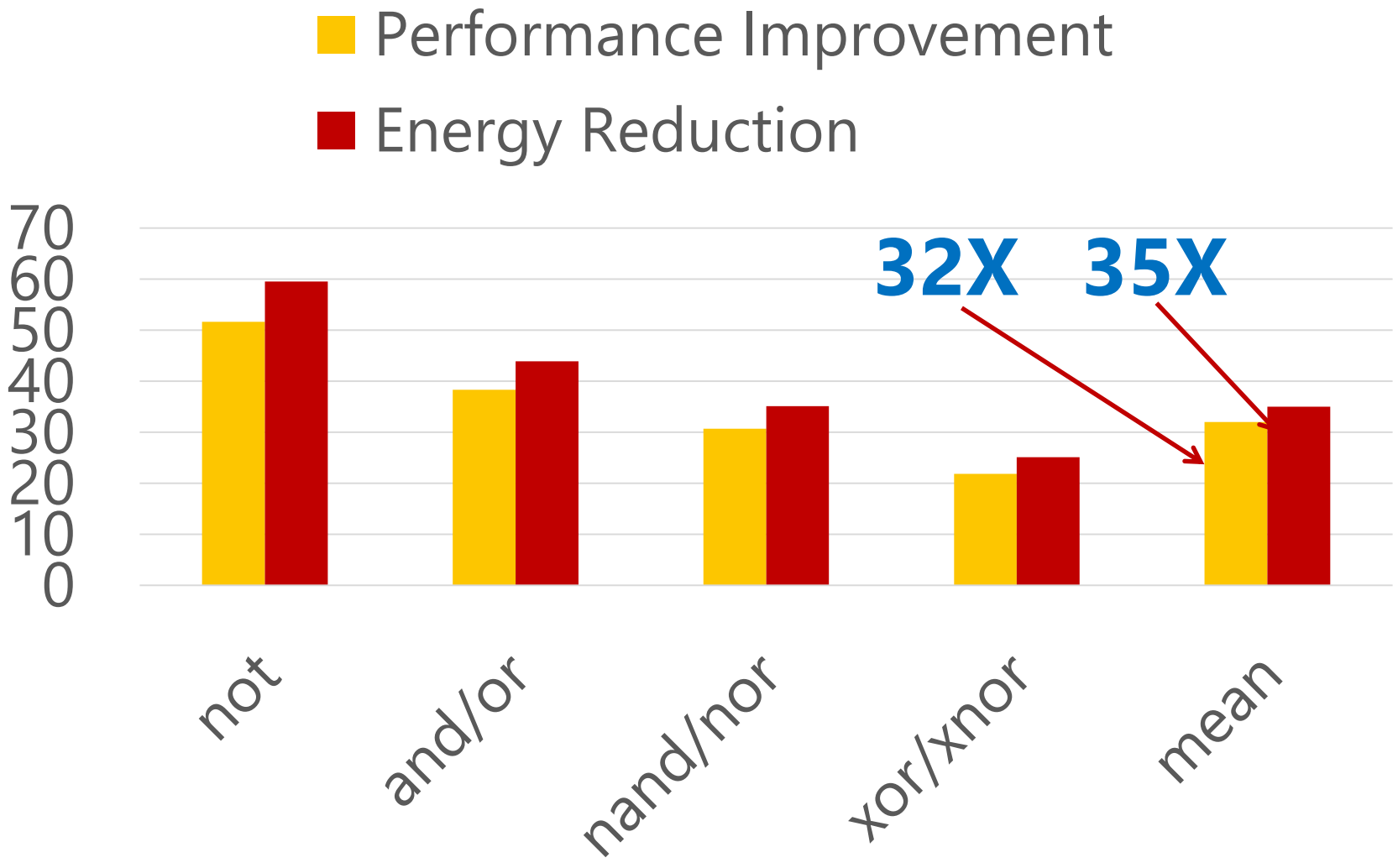
Energy of In-DRAM Bitwise Operations

	Design	not	and/or	nand/nor	xor/xnor
DRAM &	**DDR3**	93.7	137.9	137.9	137.9
Channel Energy	**Ambit**	1.6	3.2	4.0	5.5
(nJ/KB)	(↓)	59.5X	43.9X	35.1X	25.1X

Table 3: Energy of bitwise operations. (↓) indicates energy reduction of Ambit over the traditional DDR3-based design.

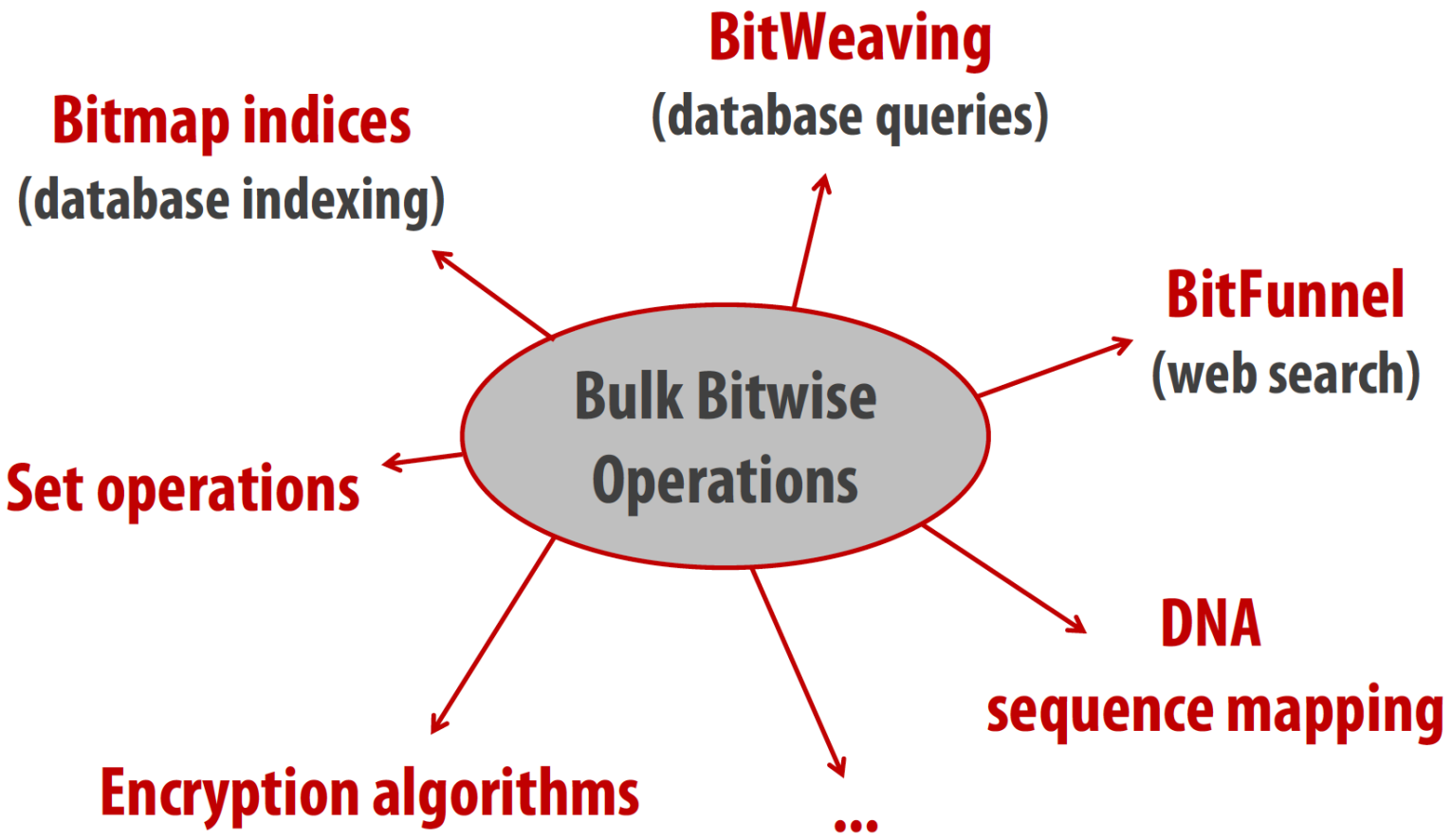
Seshadri+, "Ambit: In-Memory Accelerator for Bulk Bitwise Operations using Commodity DRAM Technology," MICRO 2017.

Ambit vs. DDR3: Performance and Energy



Seshadri+, "Ambit: In-Memory Accelerator for Bulk Bitwise Operations using Commodity DRAM Technology," MICRO 2017.

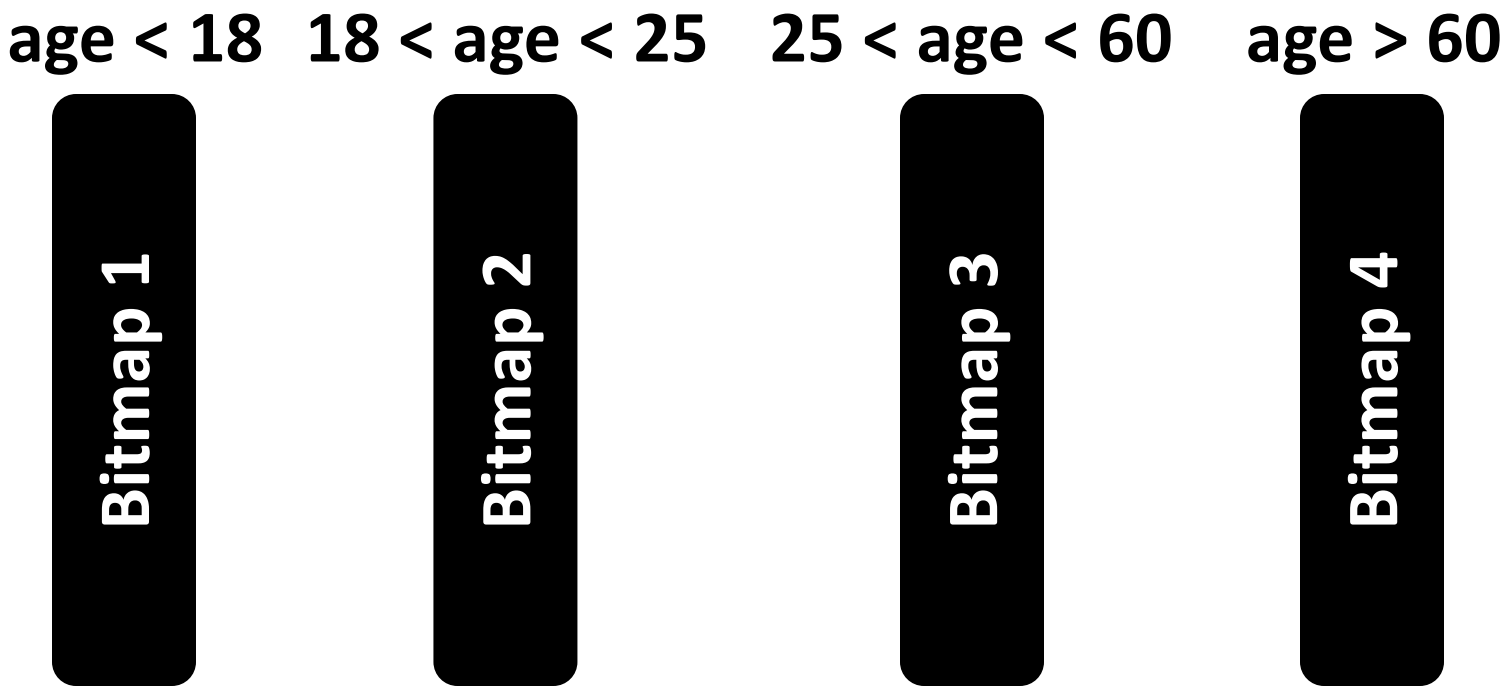
Bulk Bitwise Operations in Workloads



[1] Li and Patel, BitWeaving, SIGMOD 2013
[2] Goodwin+, BitFunnel, SIGIR 2017

Example Data Structure: Bitmap Index

- Alternative to B-tree and its variants
- Efficient for performing *range queries* and *joins*
- **Many bitwise operations to perform a query**



Performance: Bitmap Index on Ambit

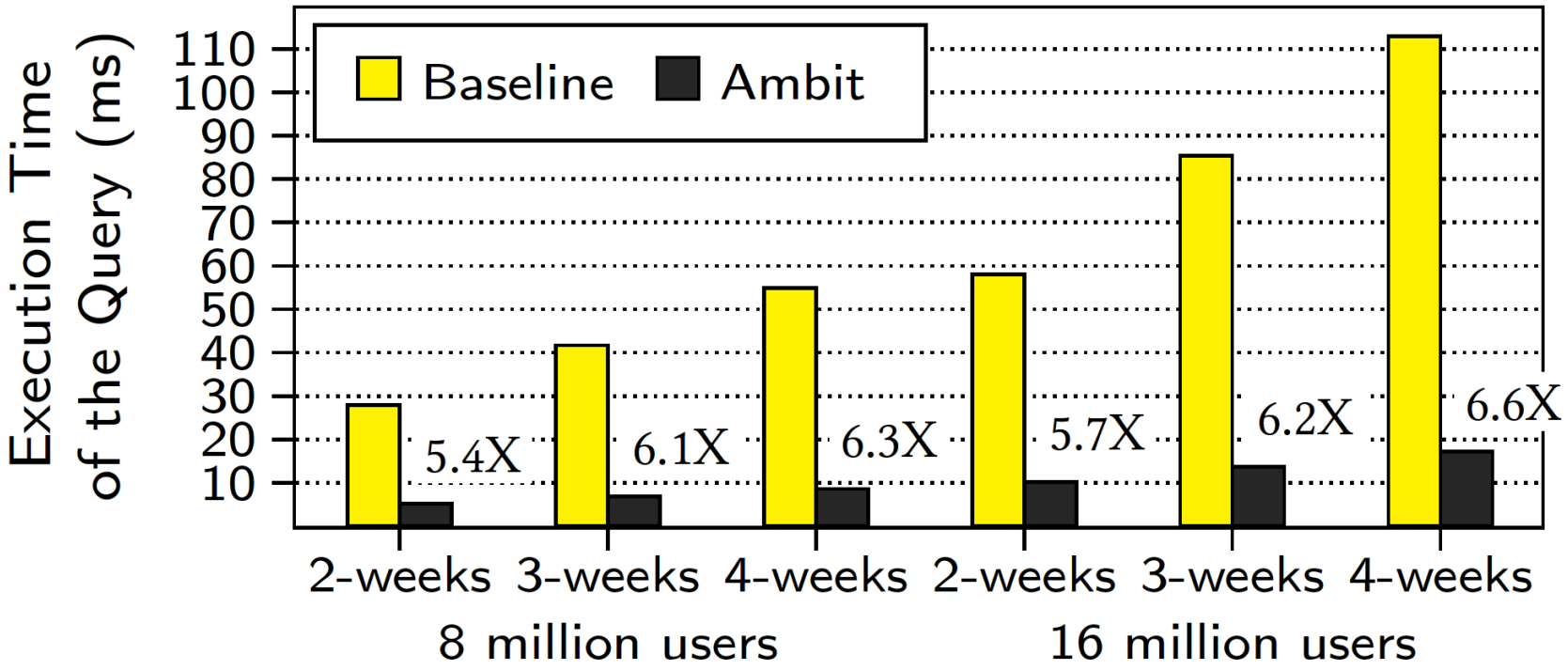


Figure 10: Bitmap index performance. The value above each bar indicates the reduction in execution time due to Ambit.

Seshadri+, "Ambit: In-Memory Accelerator for Bulk Bitwise Operations using Commodity DRAM Technology," MICRO 2017.

Performance: BitWeaving on Ambit

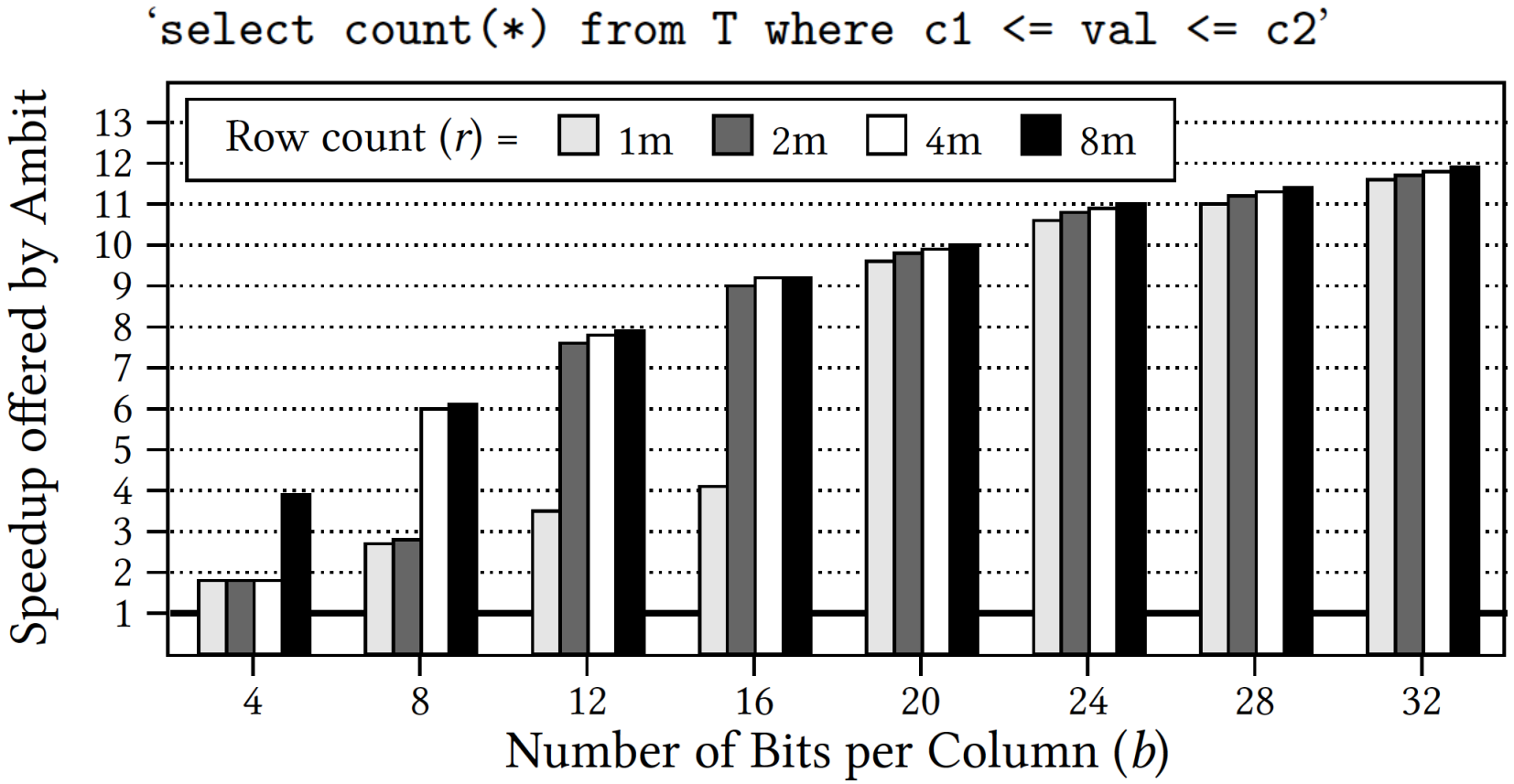


Figure 11: Speedup offered by Ambit over baseline CPU with SIMD for BitWeaving

Seshadri+, "Ambit: In-Memory Accelerator for Bulk Bitwise Operations using Commodity DRAM Technology," MICRO 2017.

More on In-DRAM Bulk AND/OR

- Vivek Seshadri, Kevin Hsieh, Amirali Boroumand, Donghyuk Lee, Michael A. Kozuch, Onur Mutlu, Phillip B. Gibbons, and Todd C. Mowry,
  "Fast Bulk Bitwise AND and OR in DRAM"
  IEEE Computer Architecture Letters (***CAL***), April 2015.

Fast Bulk Bitwise AND and OR in DRAM

Vivek Seshadri*, Kevin Hsieh*, Amirali Boroumand*, Donghyuk Lee*,
Michael A. Kozuch†, Onur Mutlu*, Phillip B. Gibbons†, Todd C. Mowry*

*Carnegie Mellon University †Intel Pittsburgh

More on In-DRAM Bitwise Operations

- Vivek Seshadri et al., "**Ambit: In-Memory Accelerator for Bulk Bitwise Operations Using Commodity DRAM Technology**," MICRO 2017.

Ambit: In-Memory Accelerator for Bulk Bitwise Operations Using Commodity DRAM Technology

Vivek Seshadri[1,5] Donghyuk Lee[2,5] Thomas Mullins[3,5] Hasan Hassan[4] Amirali Boroumand[5]
Jeremie Kim[4,5] Michael A. Kozuch[3] Onur Mutlu[4,5] Phillip B. Gibbons[5] Todd C. Mowry[5]

[1]Microsoft Research India [2]NVIDIA Research [3]Intel [4]ETH Zürich [5]Carnegie Mellon University

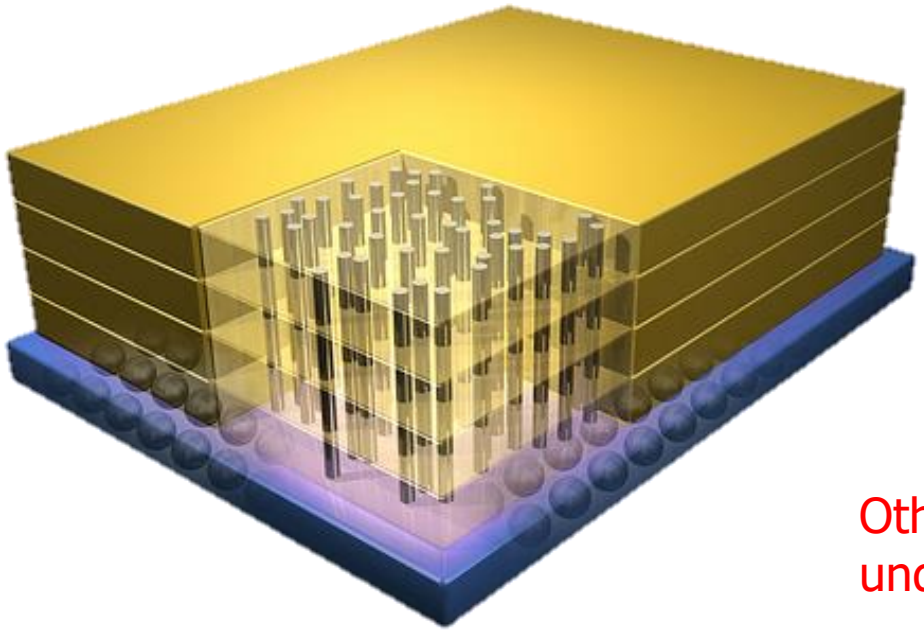
Computing Architectures with Minimal Data Movement

Processing in Memory: Two Approaches

1. Minimally changing memory chips
2. Exploiting 3D-stacked memory

Opportunity: 3D-Stacked Logic+Memory

Hybrid Memory Cube
CONSORTIUM



Other "True 3D" technologies under development

DRAM Landscape (circa 2015)

Segment	*DRAM Standards & Architectures*
Commodity	DDR3 (2007) [14]; DDR4 (2012) [18]
Low-Power	LPDDR3 (2012) [17]; LPDDR4 (2014) [20]
Graphics	GDDR5 (2009) [15]
Performance	eDRAM [28], [32]; RLDRAM3 (2011) [29]
3D-Stacked	WIO (2011) [16]; WIO2 (2014) [21]; MCDRAM (2015) [13]; HBM (2013) [19]; HMC1.0 (2013) [10]; HMC1.1 (2014) [11]
Academic	SBA/SSA (2010) [38]; Staged Reads (2012) [8]; RAIDR (2012) [27]; SALP (2012) [24]; TL-DRAM (2013) [26]; RowClone (2013) [37]; Half-DRAM (2014) [39]; Row-Buffer Decoupling (2014) [33]; SARP (2014) [6]; AL-DRAM (2015) [25]

Table 1. Landscape of DRAM-based memory

Kim+, "Ramulator: A Flexible and Extensible DRAM Simulator", IEEE CAL 2015.

Two Key Questions in 3D-Stacked PIM

- How can we accelerate important applications if we use 3D-stacked memory as a coarse-grained accelerator?
  - what is the architecture and programming model?
  - what are the mechanisms for acceleration?

- What is the minimal processing-in-memory support we can provide?
  - without changing the system significantly
  - while achieving significant benefits

Another Example: In-Memory Graph Processing

- Large graphs are everywhere (circa 2015)

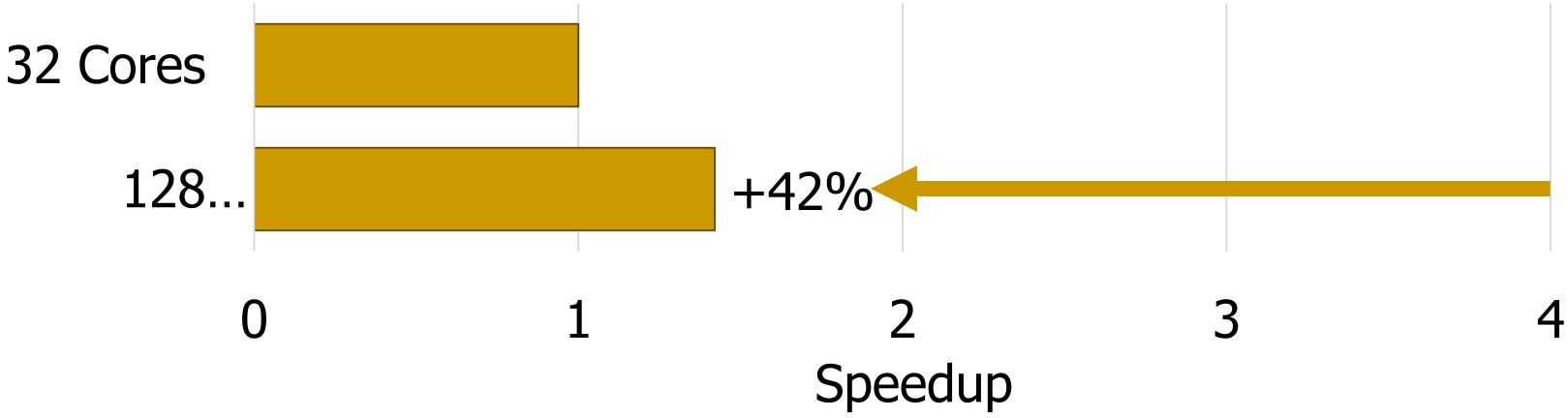
36 Million
Wikipedia Pages

1.4 Billion
Facebook Users

300 Million
Twitter Users

30 Billion
Instagram Photos

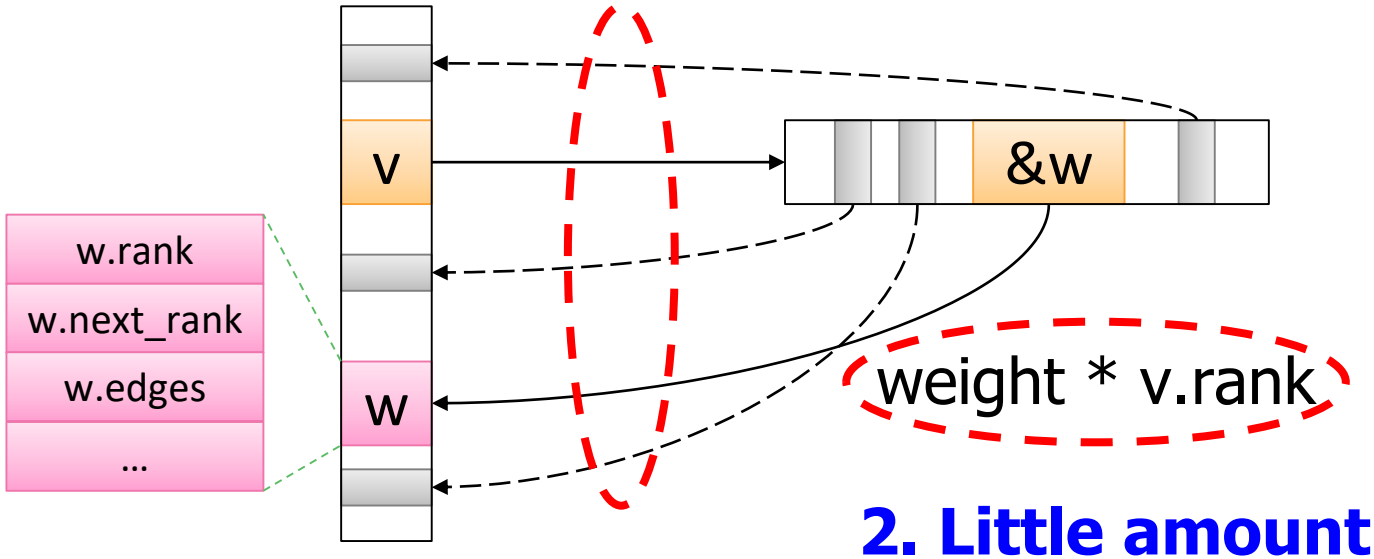
- Scalable large-scale graph processing is challenging



Key Bottlenecks in Graph Processing

```
for (v: graph.vertices) {
    for (w: v.successors) {
        w.next_rank += weight * v.rank;
    }
}
```

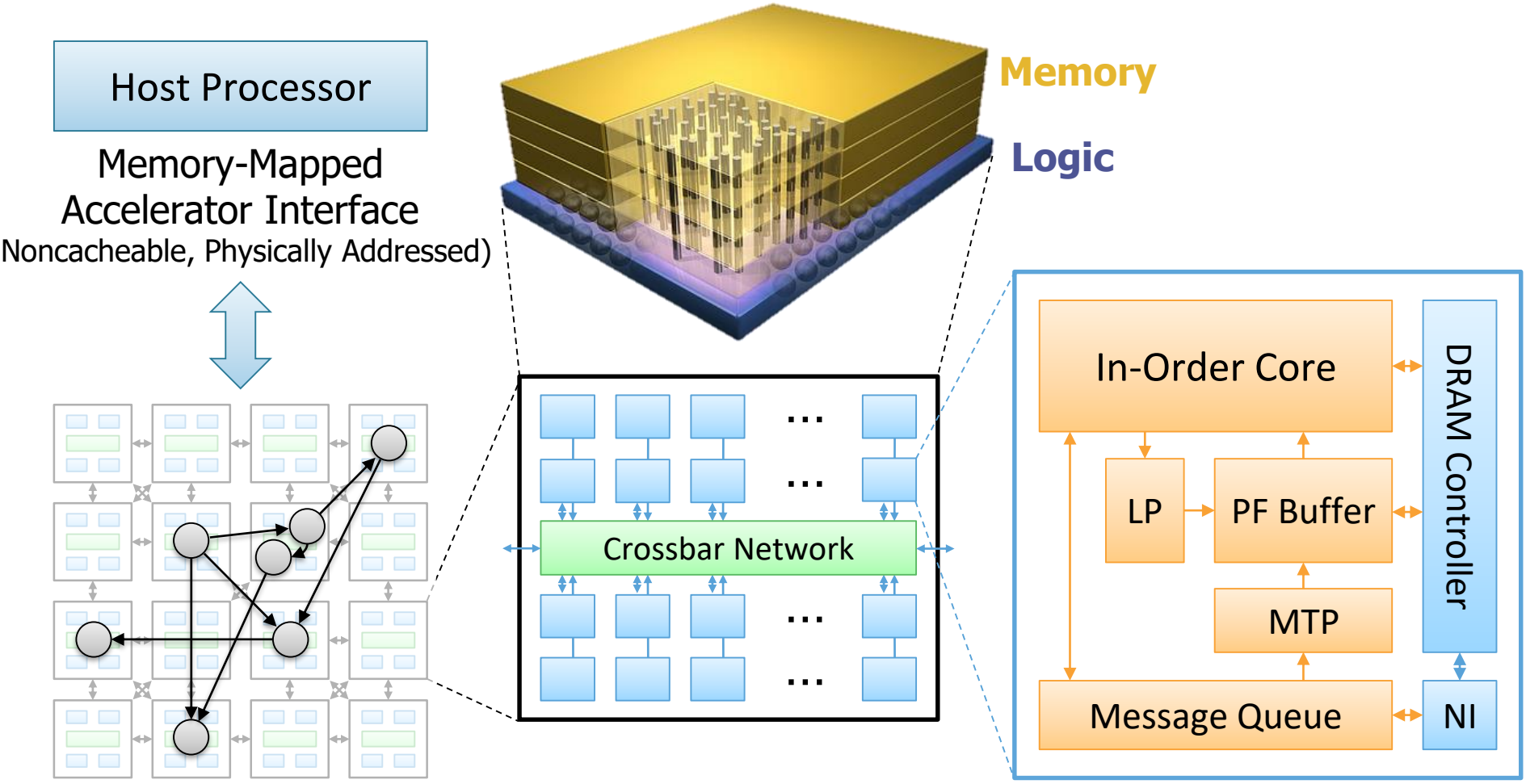
1. Frequent random memory accesses



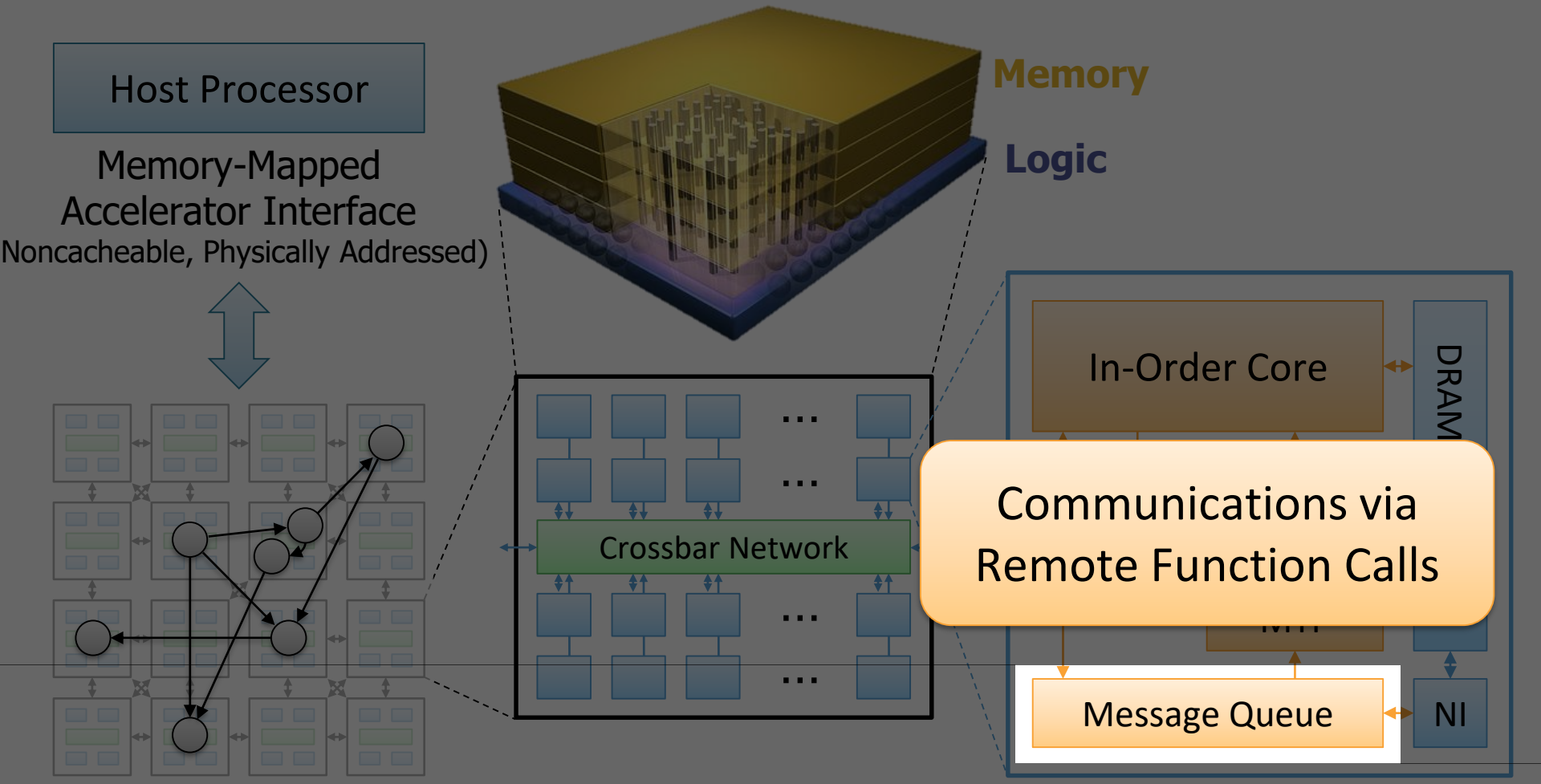
2. Little amount of computation

Tesseract System for Graph Processing

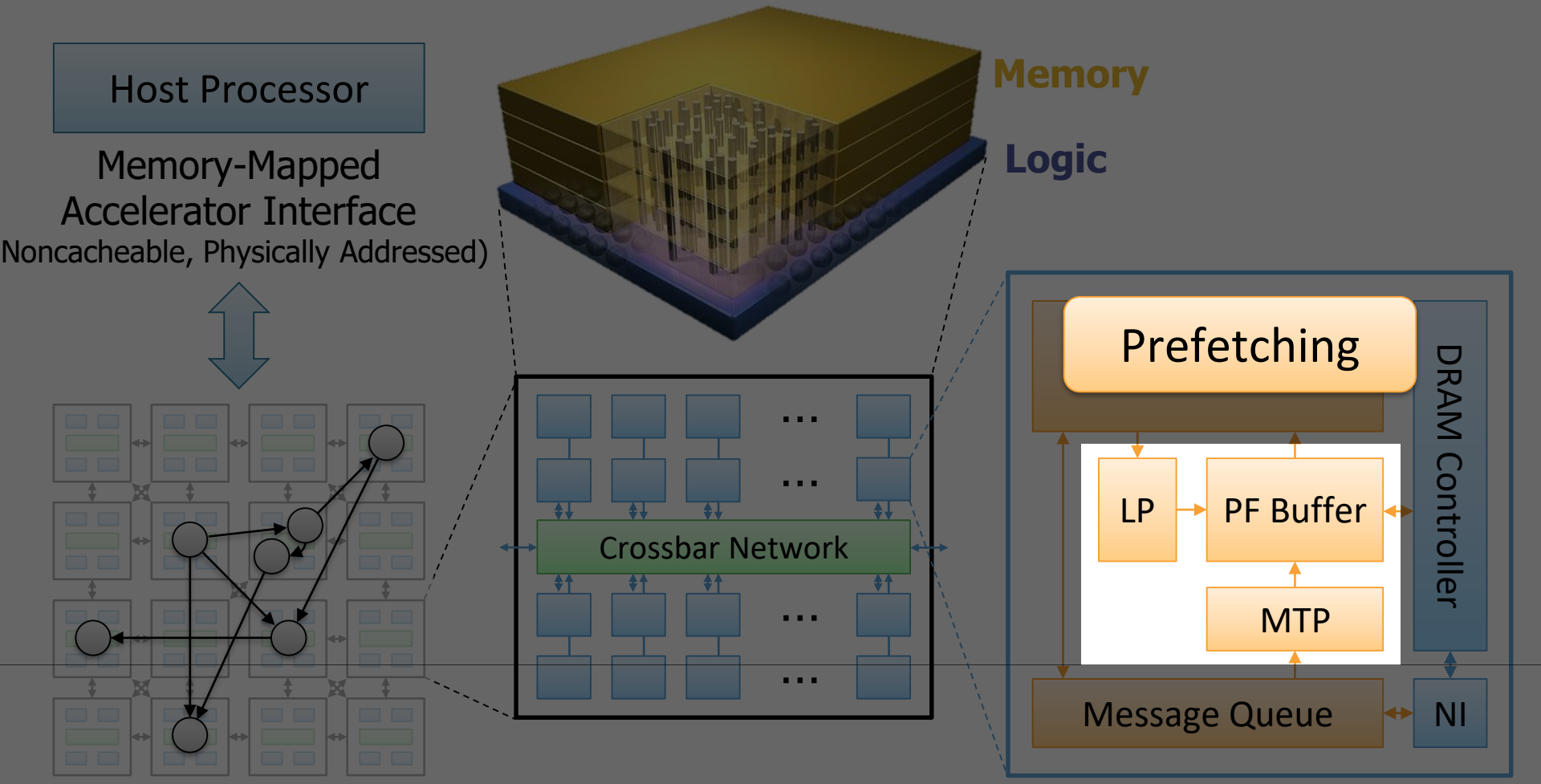
Interconnected set of 3D-stacked memory+logic chips with simple cores



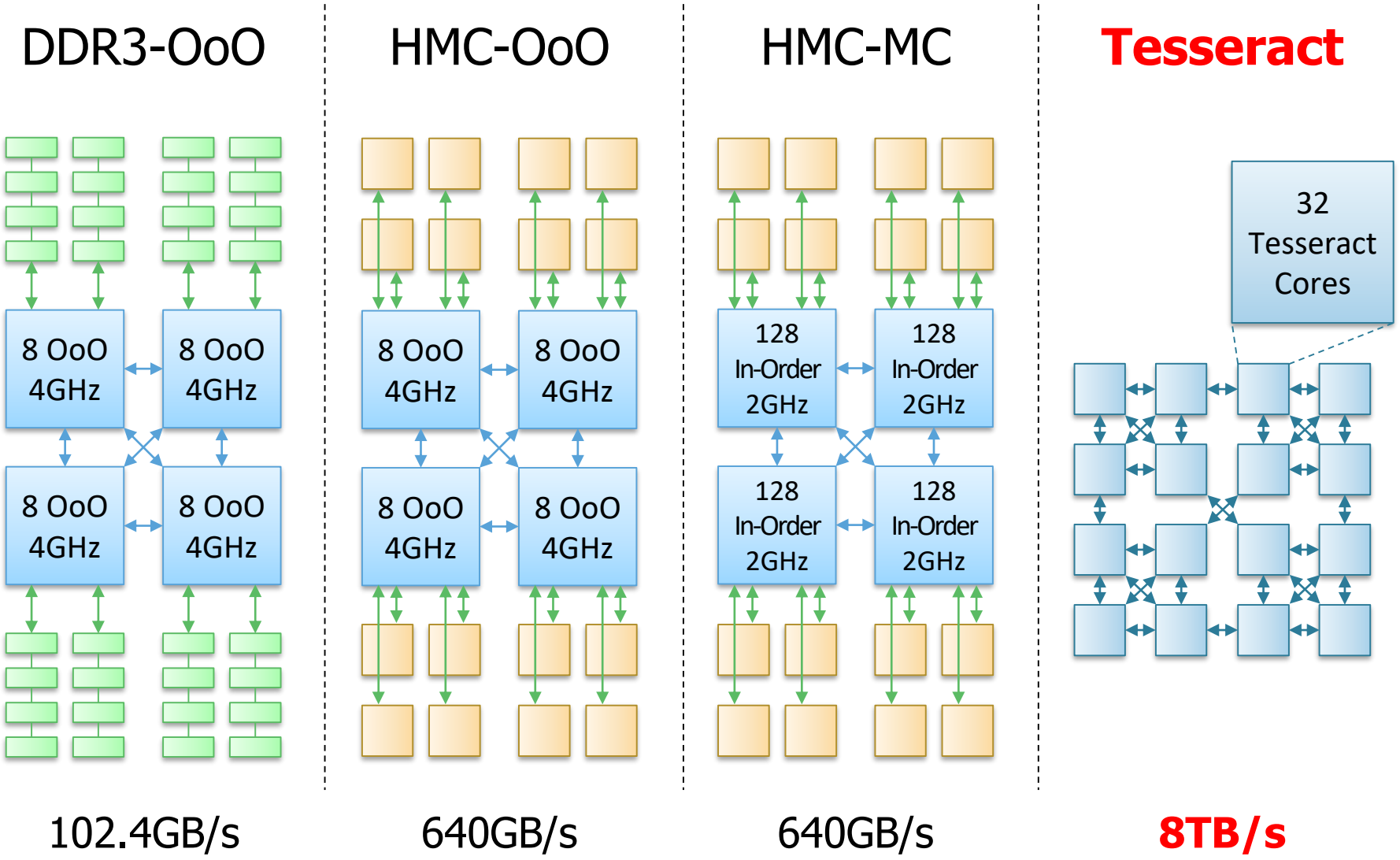
Tesseract System for Graph Processing



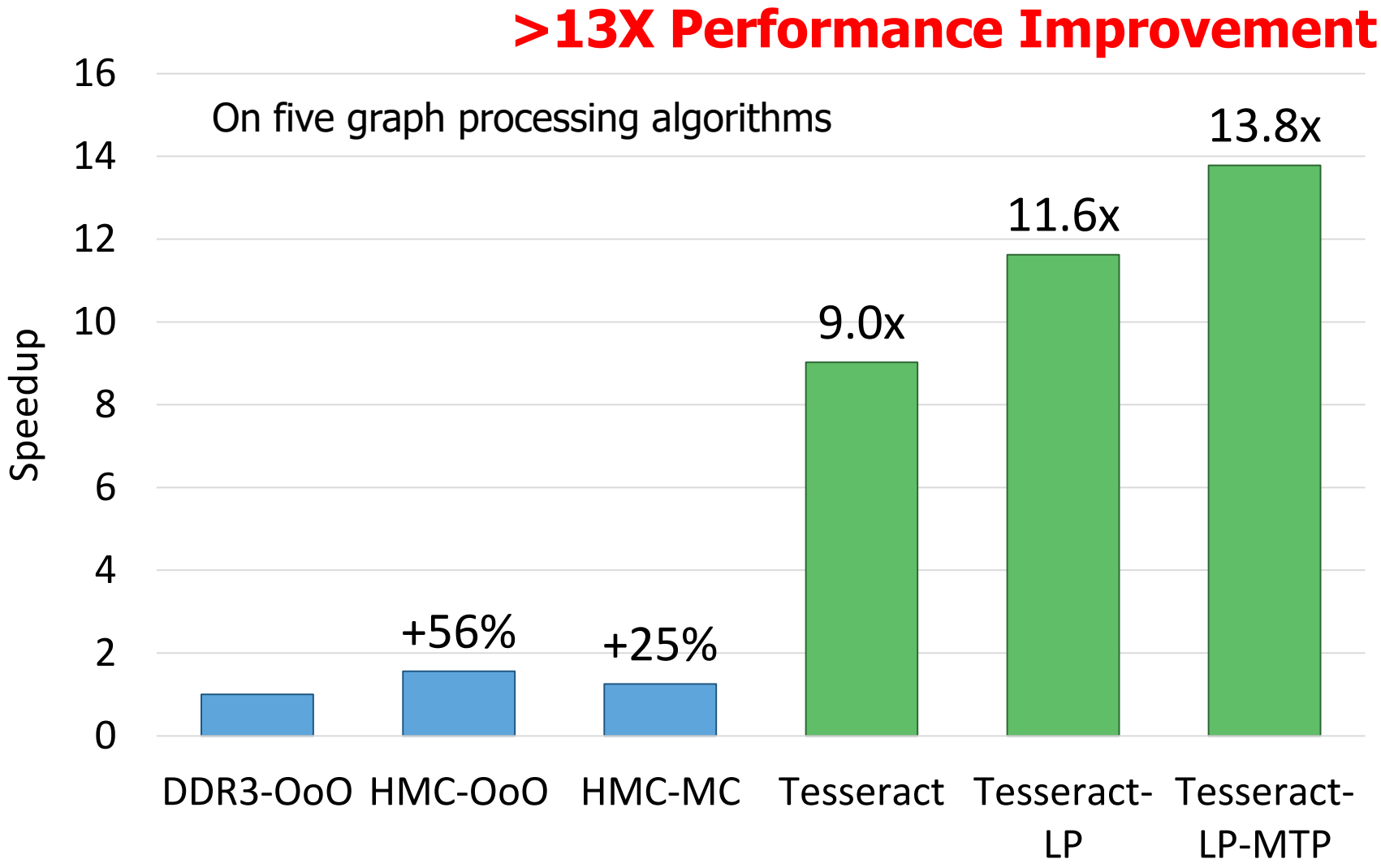
Tesseract System for Graph Processing



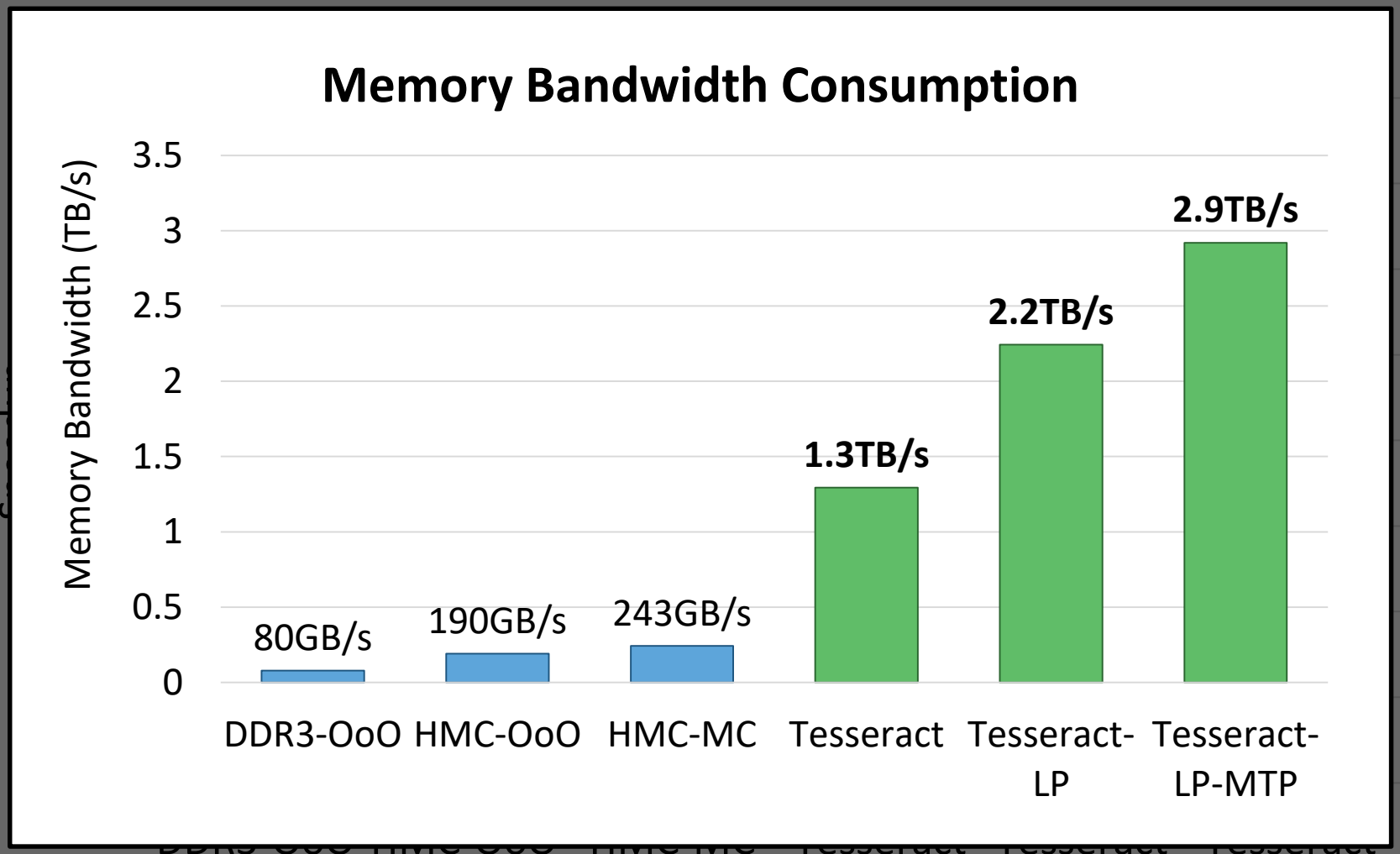
Evaluated Systems



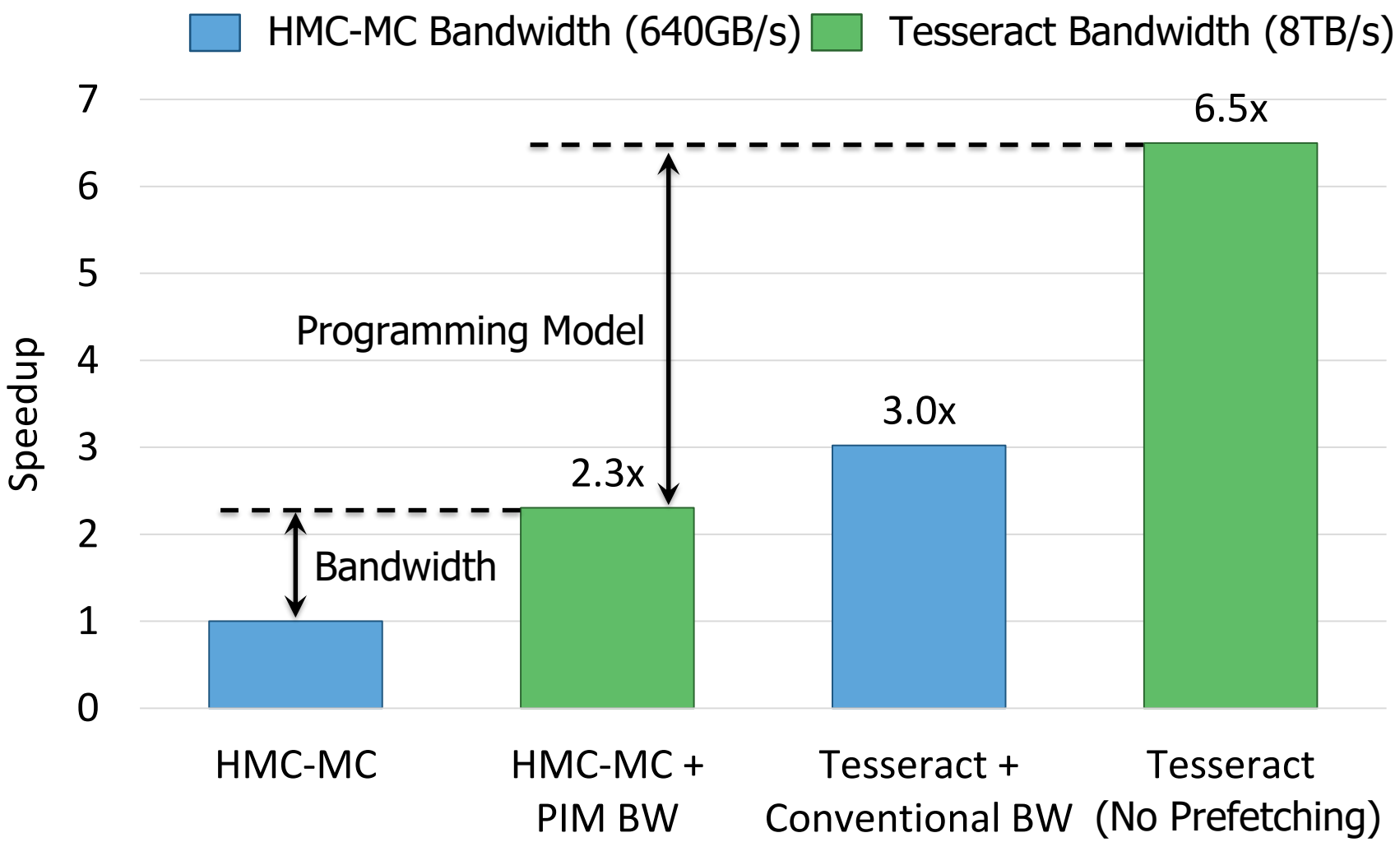
Tesseract Graph Processing Performance



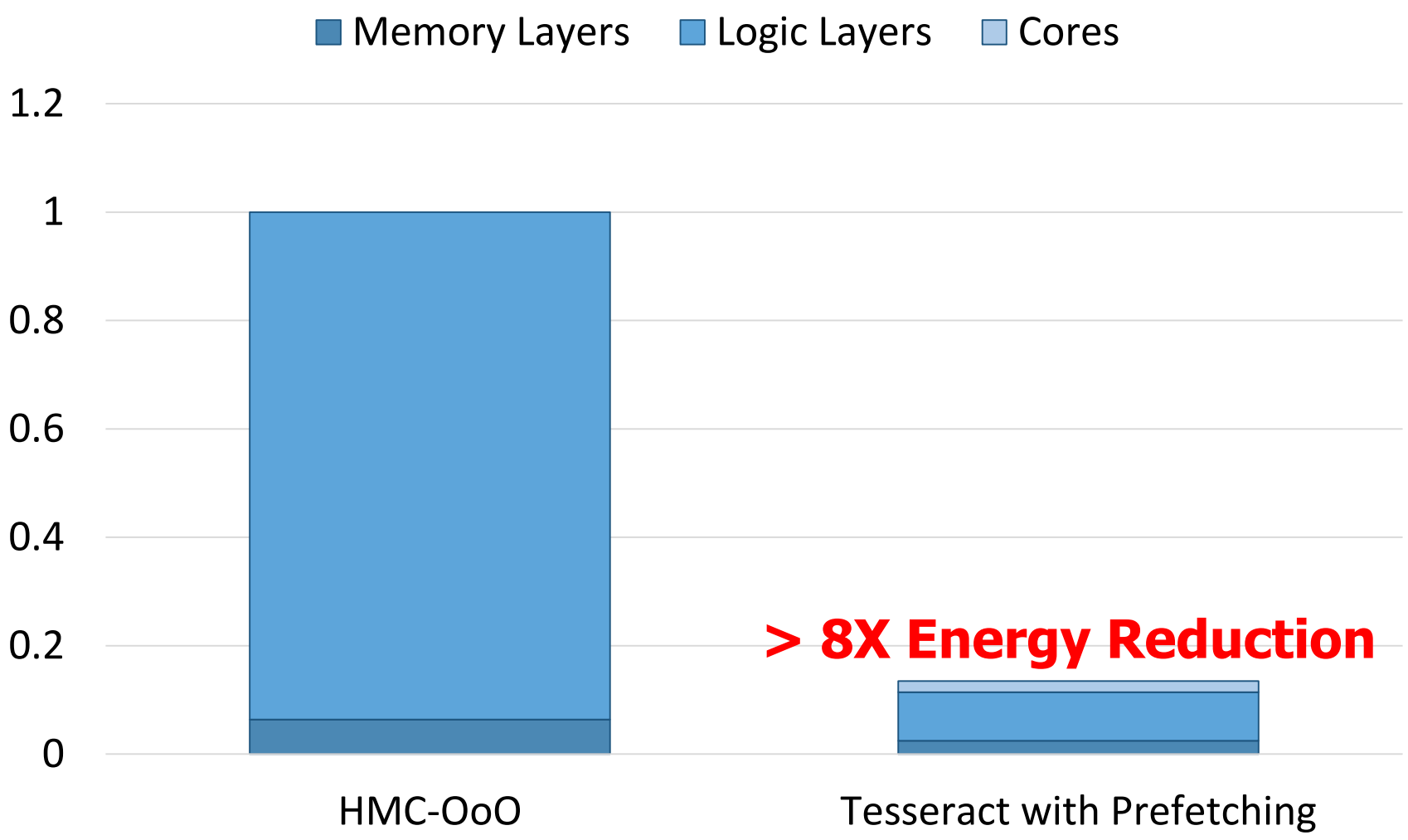
Tesseract Graph Processing Performance



Effect of Bandwidth & Programming Model



Tesseract Graph Processing System Energy



More on Tesseract

- Junwhan Ahn, Sungpack Hong, Sungjoo Yoo, Onur Mutlu, and Kiyoung Choi,
  "A Scalable Processing-in-Memory Accelerator for Parallel Graph Processing"
  *Proceedings of the 42nd International Symposium on Computer Architecture (**ISCA**)*, Portland, OR, June 2015.
  [Slides (pdf)] [Lightning Session Slides (pdf)]

A Scalable Processing-in-Memory Accelerator for Parallel Graph Processing

Junwhan Ahn Sungpack Hong[§] Sungjoo Yoo Onur Mutlu[†] Kiyoung Choi
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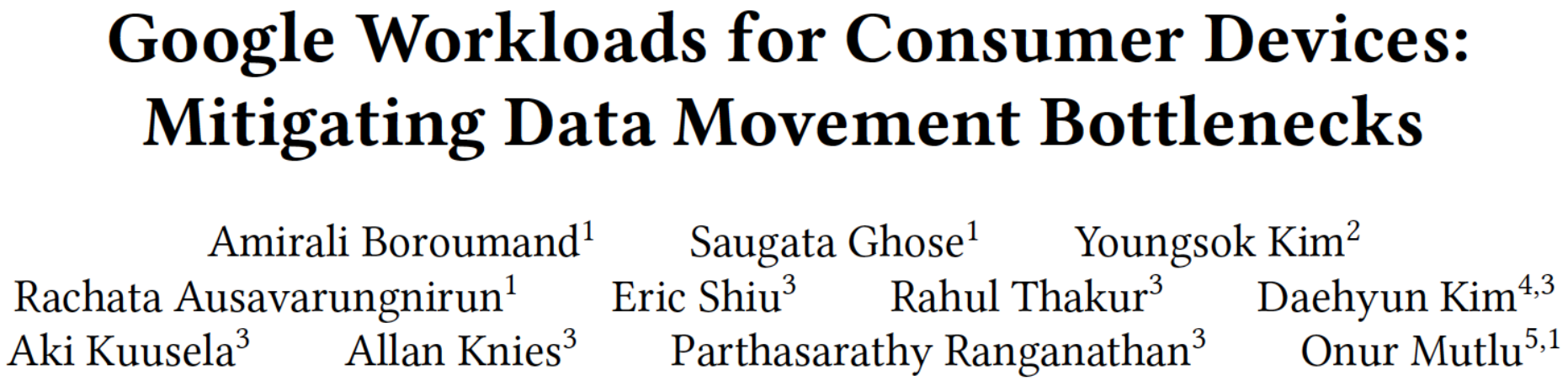
Seoul National University [§]Oracle Labs [†]Carnegie Mellon University

3D-Stacked PIM on Mobile Devices

- Amirali Boroumand, Saugata Ghose, Youngsok Kim, Rachata Ausavarungnirun, Eric Shiu, Rahul Thakur, Daehyun Kim, Aki Kuusela, Allan Knies, Parthasarathy Ranganathan, and Onur Mutlu, **"Google Workloads for Consumer Devices: Mitigating Data Movement Bottlenecks"**
  *Proceedings of the 23rd International Conference on Architectural Support for Programming Languages and Operating Systems (**ASPLOS**)*, Williamsburg, VA, USA, March 2018.



Google Workloads for Consumer Devices: Mitigating Data Movement Bottlenecks

Amirali Boroumand

Saugata Ghose, Youngsok Kim, Rachata Ausavarungnirun,
Eric Shiu, Rahul Thakur, Daehyun Kim, Aki Kuusela,
Allan Knies, Parthasarathy Ranganathan, Onur Mutlu

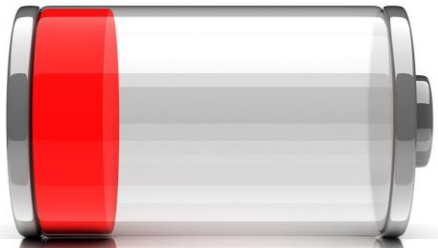
SAFARI Carnegie Mellon Google

SAMSUNG SEOUL NATIONAL UNIVERSITY ETH zürich

Consumer Devices

Consumer devices are everywhere!

Energy consumption is a first-class concern in consumer devices



Popular Google Consumer Workloads

Chrome

Google's web browser

TensorFlow Mobile

Google's machine learning framework

VP9

YouTube

Video Playback

Google's video codec

VP9

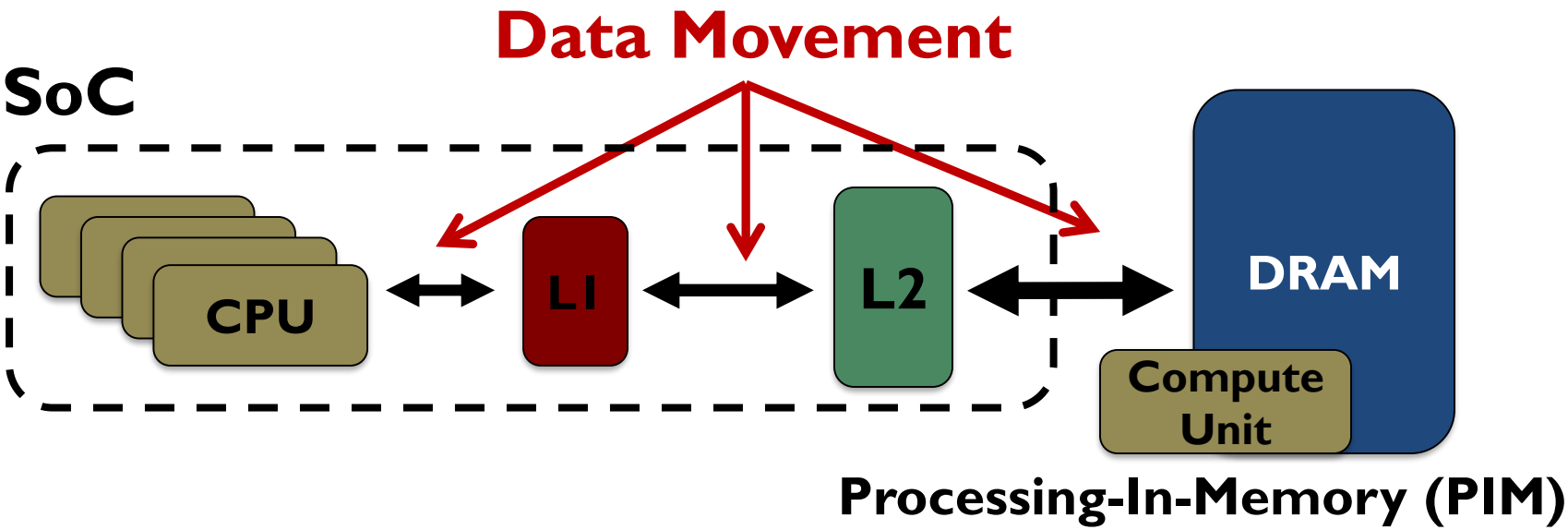
YouTube

Video Capture

Google's video codec

Energy Cost of Data Movement

1st key observation: 62.7% of the total system energy is spent on data movement



Potential solution: move computation close to data

Challenge: limited area and energy budget

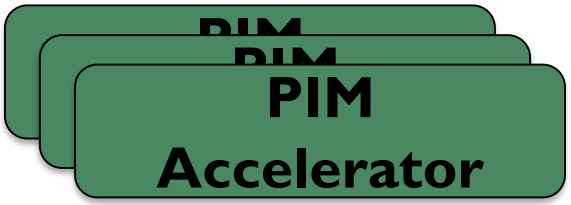
Using PIM to Reduce Data Movement

2nd key observation: a significant fraction of the data movement often comes from simple functions

We can design lightweight logic to implement these *simple functions* in memory

Small embedded low-power core

Small fixed-function accelerators



Offloading to PIM logic reduces energy and improves performance, on average, by 55.4% and 54.2%

Goals

1. Understand the data movement related bottlenecks in modern consumer workloads

2. Analyze opportunities to mitigate data movement by using processing-in-memory (PIM)

3. Design PIM logic that can maximize energy efficiency given the limited area and energy budget in consumer devices

Google Workloads for Consumer Devices: Mitigating Data Movement Bottlenecks

Amirali Boroumand

Saugata Ghose, Youngsok Kim, Rachata Ausavarungnirun, Eric Shiu, Rahul Thakur, Daehyun Kim, Aki Kuusela, Allan Knies, Parthasarathy Ranganathan, Onur Mutlu

ASPLOS 2018

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More on PIM for Mobile Devices

- Amirali Boroumand, Saugata Ghose, Youngsok Kim, Rachata Ausavarungnirun, Eric Shiu, Rahul Thakur, Daehyun Kim, Aki Kuusela, Allan Knies, Parthasarathy Ranganathan, and Onur Mutlu, **"Google Workloads for Consumer Devices: Mitigating Data Movement Bottlenecks"** *Proceedings of the 23rd International Conference on Architectural Support for Programming Languages and Operating Systems (**ASPLOS**)*, Williamsburg, VA, USA, March 2018.

62.7% of the total system energy is spent on data movement

Google Workloads for Consumer Devices: Mitigating Data Movement Bottlenecks

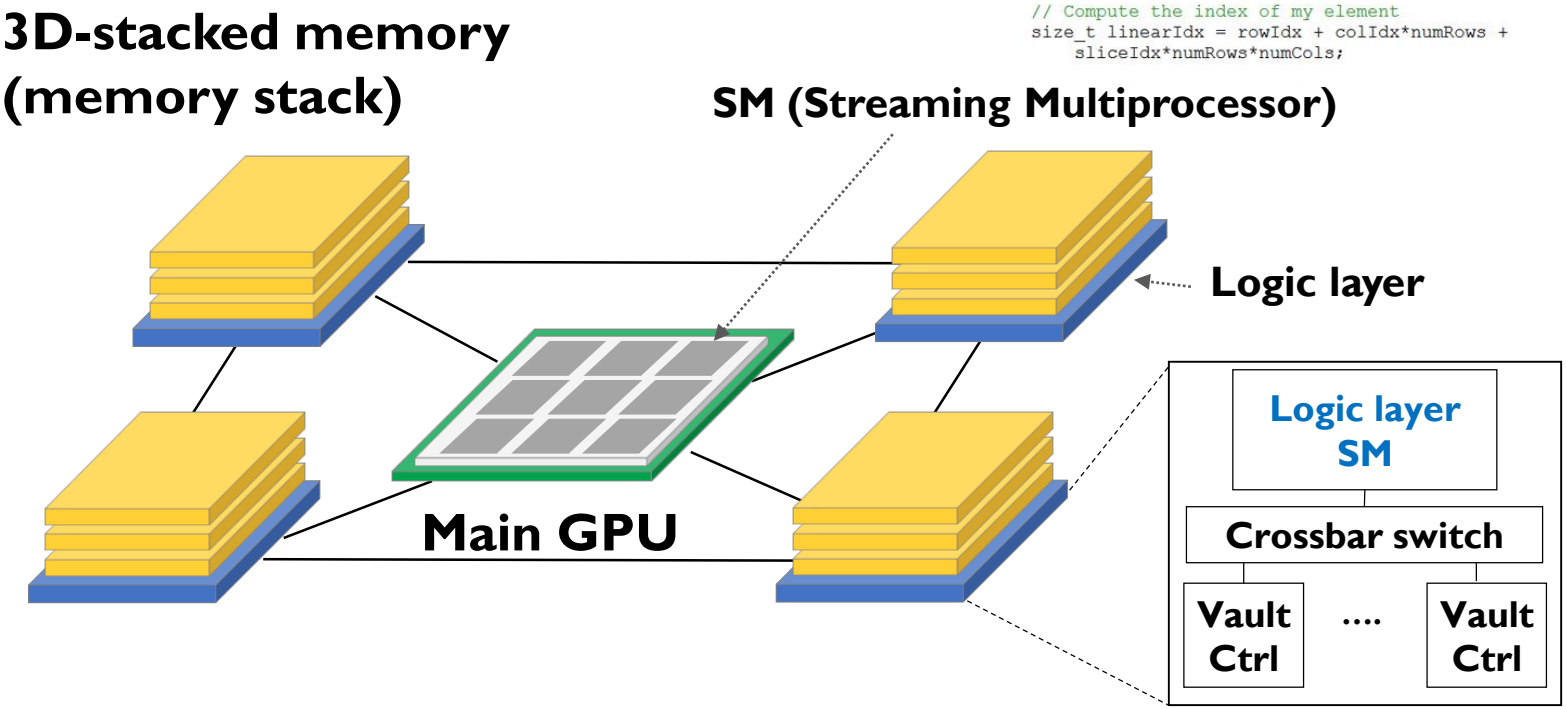
Amirali Boroumand[1] Saugata Ghose[1] Youngsok Kim[2]
Rachata Ausavarungnirun[1] Eric Shiu[3] Rahul Thakur[3] Daehyun Kim[4,3]
Aki Kuusela[3] Allan Knies[3] Parthasarathy Ranganathan[3] Onur Mutlu[5,1]

Truly Distributed GPU Processing with PIM?

```
__global__
void applyScaleFactorsKernel( uint8_T * const out,
    uint8_T const * const in, const double *factor,
    size_t const numRows, size_t const numCols )
{
    // Work out which pixel we are working on.
    const int rowIdx = blockIdx.x * blockDim.x + threadIdx.x;
    const int colIdx = blockIdx.y;
    const int sliceIdx = threadIdx.z;

    // Check this thread isn't off the image
    if( rowIdx >= numRows ) return;

    // Compute the index of my element
    size_t linearIdx = rowIdx + colIdx*numRows +
        sliceIdx*numRows*numCols;
```



Accelerating GPU Execution with PIM (I)

- Kevin Hsieh, Eiman Ebrahimi, Gwangsun Kim, Niladrish Chatterjee, Mike O'Connor, Nandita Vijaykumar, Onur Mutlu, and Stephen W. Keckler, **"Transparent Offloading and Mapping (TOM): Enabling Programmer-Transparent Near-Data Processing in GPU Systems"**
  *Proceedings of the 43rd International Symposium on Computer Architecture (**ISCA**)*, Seoul, South Korea, June 2016.
  [Slides (pptx) (pdf)]
  [Lightning Session Slides (pptx) (pdf)]

Transparent Offloading and Mapping (TOM):
Enabling Programmer-Transparent Near-Data Processing in GPU Systems

Kevin Hsieh[‡] Eiman Ebrahimi[†] Gwangsun Kim[*] Niladrish Chatterjee[†] Mike O'Connor[†]
Nandita Vijaykumar[‡] Onur Mutlu[§‡] Stephen W. Keckler[†]
[‡]Carnegie Mellon University [†]NVIDIA [*]KAIST [§]ETH Zürich

Accelerating GPU Execution with PIM (II)

- Ashutosh Pattnaik, Xulong Tang, Adwait Jog, Onur Kayiran, Asit K. Mishra, Mahmut T. Kandemir, Onur Mutlu, and Chita R. Das, **"Scheduling Techniques for GPU Architectures with Processing-In-Memory Capabilities"**
  *Proceedings of the 25th International Conference on Parallel Architectures and Compilation Techniques (**PACT**)*, Haifa, Israel, September 2016.

Scheduling Techniques for GPU Architectures with Processing-In-Memory Capabilities

Ashutosh Pattnaik[1] Xulong Tang[1] Adwait Jog[2] Onur Kayıran[3]
Asit K. Mishra[4] Mahmut T. Kandemir[1] Onur Mutlu[5,6] Chita R. Das[1]
[1]Pennsylvania State University [2]College of William and Mary
[3]Advanced Micro Devices, Inc. [4]Intel Labs [5]ETH Zürich [6]Carnegie Mellon University

Accelerating Linked Data Structures

- Kevin Hsieh, Samira Khan, Nandita Vijaykumar, Kevin K. Chang, Amirali Boroumand, Saugata Ghose, and Onur Mutlu,
  "Accelerating Pointer Chasing in 3D-Stacked Memory: Challenges, Mechanisms, Evaluation"
  *Proceedings of the 34th IEEE International Conference on Computer Design (**ICCD**)*, Phoenix, AZ, USA, October 2016.

Accelerating Pointer Chasing in 3D-Stacked Memory: Challenges, Mechanisms, Evaluation

Kevin Hsieh[†] Samira Khan[‡] Nandita Vijaykumar[†]
Kevin K. Chang[†] Amirali Boroumand[†] Saugata Ghose[†] Onur Mutlu[§†]
[†]*Carnegie Mellon University* [‡]*University of Virginia* [§]*ETH Zürich*

Accelerating Dependent Cache Misses

- Milad Hashemi, Khubaib, Eiman Ebrahimi, Onur Mutlu, and Yale N. Patt, **"Accelerating Dependent Cache Misses with an Enhanced Memory Controller"**
  *Proceedings of the 43rd International Symposium on Computer Architecture (**ISCA**)*, Seoul, South Korea, June 2016.
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Accelerating Dependent Cache Misses with an Enhanced Memory Controller

Milad Hashemi*, Khubaib†, Eiman Ebrahimi‡, Onur Mutlu§, Yale N. Patt*

*The University of Texas at Austin †Apple ‡NVIDIA §ETH Zürich & Carnegie Mellon University

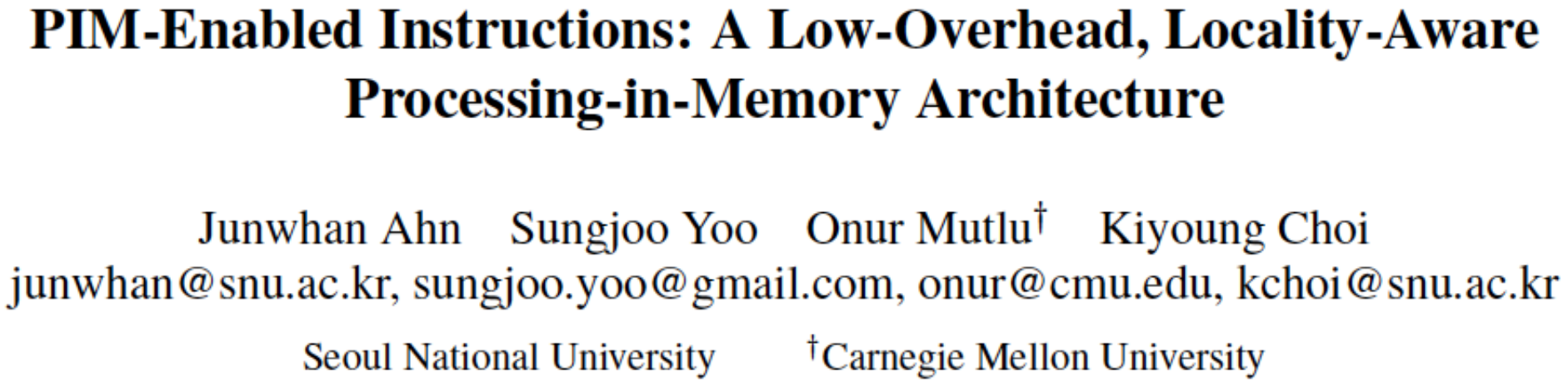
Two Key Questions in 3D-Stacked PIM

- How can we accelerate important applications if we use 3D-stacked memory as a coarse-grained accelerator?
  - what is the architecture and programming model?
  - what are the mechanisms for acceleration?

- What is the minimal processing-in-memory support we can provide?
  - without changing the system significantly
  - while achieving significant benefits

PIM-Enabled Instructions

- Junwhan Ahn, Sungjoo Yoo, Onur Mutlu, and Kiyoung Choi, **"PIM-Enabled Instructions: A Low-Overhead, Locality-Aware Processing-in-Memory Architecture"** *Proceedings of the 42nd International Symposium on Computer Architecture (**ISCA**)*, Portland, OR, June 2015. [Slides (pdf)] [Lightning Session Slides (pdf)]



PIM-Enabled Instructions: A Low-Overhead, Locality-Aware Processing-in-Memory Architecture

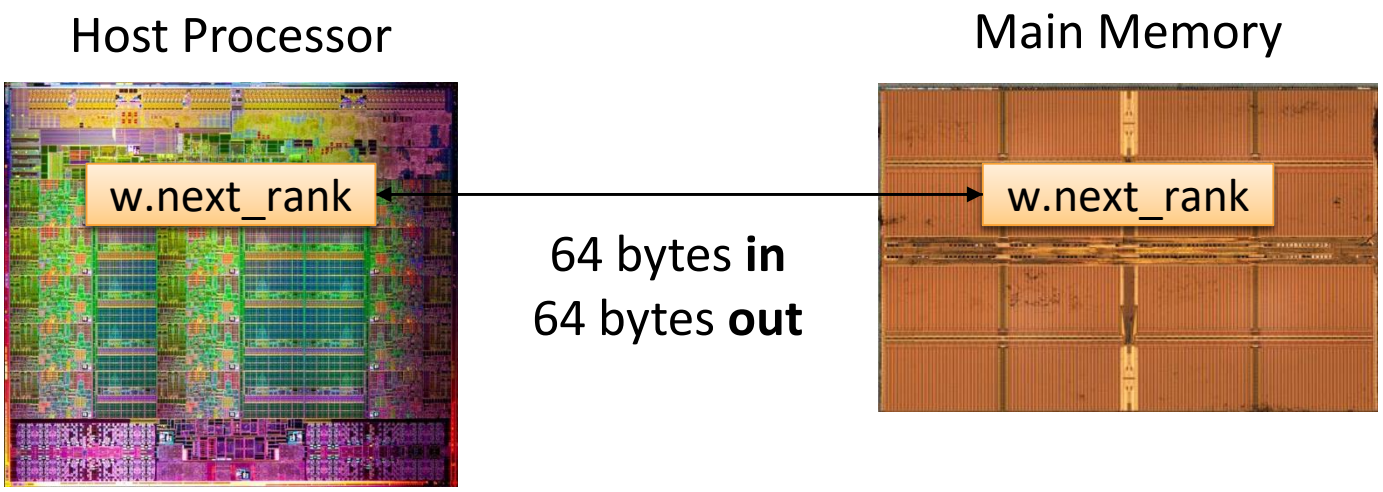
Junwhan Ahn Sungjoo Yoo Onur Mutlu† Kiyoung Choi
junwhan@snu.ac.kr, sungjoo.yoo@gmail.com, onur@cmu.edu, kchoi@snu.ac.kr
Seoul National University †Carnegie Mellon University

PEI: PIM-Enabled Instructions (Ideas)

- Goal: Develop mechanisms to get the most out of near-data processing with minimal cost, minimal changes to the system, no changes to the programming model
- Key Idea 1: Expose each PIM operation as a cache-coherent, virtually-addressed host processor instruction (called PEI) that operates on only a single cache block
  - e.g., __pim_add(&w.next_rank, value) → pim.add r1, (r2)
  - No changes sequential execution/programming model
  - No changes to virtual memory
  - Minimal changes to cache coherence
  - No need for data mapping: Each PEI restricted to a single memory module
- Key Idea 2: Dynamically decide where to execute a PEI (i.e., the host processor or PIM accelerator) based on simple locality characteristics and simple hardware predictors
  - Execute each operation at the location that provides the best performance

Simple PIM Operations as ISA Extensions (II)

```
for (v: graph.vertices) {
    value = weight * v.rank;
    for (w: v.successors) {
        w.next_rank += value;
    }
}
```

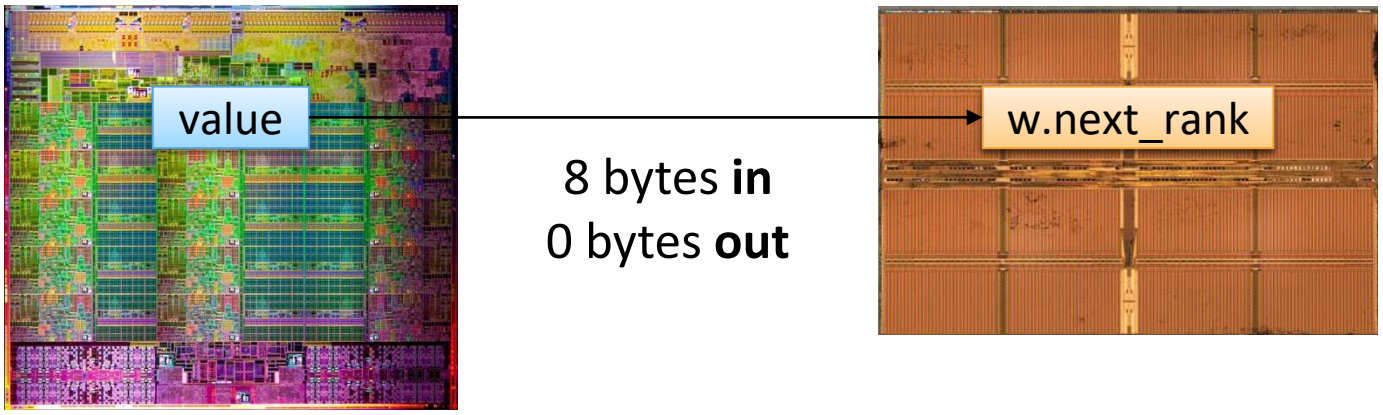


Conventional Architecture

Simple PIM Operations as ISA Extensions (III)

```
for (v: graph.vertices) {
    value = weight * v.rank;
    for (w: v.successors) {
        __pim_add(&w.next_rank, value);
    }
}
```

pim.add r1, (r2)



In-Memory Addition

PEI: PIM-Enabled Instructions (Example)

```
for (v: graph.vertices) {
  value = weight * v.rank;
  for (w: v.successors) {
    __pim_add(&w.next_rank, value);
  }
}
pfence();
```

pim.add r1, (r2)

pfence

Table 1: Summary of Supported PIM Operations

Operation	R	W	Input	Output	Applications
8-byte integer increment	O	O	0 bytes	0 bytes	AT
8-byte integer min	O	O	8 bytes	0 bytes	BFS, SP, WCC
Floating-point add	O	O	8 bytes	0 bytes	PR
Hash table probing	O	X	8 bytes	9 bytes	HJ
Histogram bin index	O	X	1 byte	16 bytes	HG, RP
Euclidean distance	O	X	64 bytes	4 bytes	SC
Dot product	O	X	32 bytes	8 bytes	SVM

- Executed either in memory or in the processor: dynamic decision
  - Low-cost locality monitoring for a single instruction
- Cache-coherent, virtually-addressed, single cache block only
- Atomic between different PEIs
- *Not* atomic with normal instructions (use *pfence* for ordering)

PEI: Initial Evaluation Results

- Initial evaluations with 10 emerging data-intensive workloads
  - Large-scale graph processing
  - In-memory data analytics
  - Machine learning and data mining
  - Three input sets (small, medium, large) for each workload to analyze the impact of data locality

Table 2: Baseline Simulation Configuration

Component	Configuration
Core	16 out-of-order cores, 4 GHz, 4-issue
L1 I/D-Cache	Private, 32 KB, 4/8-way, 64 B blocks, 16 MSHRs
L2 Cache	Private, 256 KB, 8-way, 64 B blocks, 16 MSHRs
L3 Cache	Shared, 16 MB, 16-way, 64 B blocks, 64 MSHRs
On-Chip Network	Crossbar, 2 GHz, 144-bit links
Main Memory	32 GB, 8 HMCs, daisy-chain (80 GB/s full-duplex)
HMC	4 GB, 16 vaults, 256 DRAM banks [20]
– DRAM	FR-FCFS, tCL = tRCD = tRP = 13.75 ns [27]
– Vertical Links	64 TSVs per vault with 2 Gb/s signaling rate [23]

- Pin-based cycle-level x86-64 simulation

- **Performance Improvement and Energy Reduction:**
  - 47% average speedup with large input data sets
  - 32% speedup with small input data sets
  - 25% avg. energy reduction in a single node with large input data sets

Automatic Code and Data Mapping

- Kevin Hsieh, Eiman Ebrahimi, Gwangsun Kim, Niladrish Chatterjee, Mike O'Connor, Nandita Vijaykumar, Onur Mutlu, and Stephen W. Keckler, **"Transparent Offloading and Mapping (TOM): Enabling Programmer-Transparent Near-Data Processing in GPU Systems"**
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Automatic Offloading of Critical Code

- Milad Hashemi, Khubaib, Eiman Ebrahimi, Onur Mutlu, and Yale N. Patt, **"Accelerating Dependent Cache Misses with an Enhanced Memory Controller"**
  *Proceedings of the 43rd International Symposium on Computer Architecture (**ISCA**)*, Seoul, South Korea, June 2016.
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Accelerating Dependent Cache Misses with an Enhanced Memory Controller

Milad Hashemi*, Khubaib†, Eiman Ebrahimi‡, Onur Mutlu§, Yale N. Patt*

*The University of Texas at Austin †Apple ‡NVIDIA §ETH Zürich & Carnegie Mellon University

Automatic Offloading of Prefetch Mechanisms

- Milad Hashemi, Onur Mutlu, and Yale N. Patt,
  "Continuous Runahead: Transparent Hardware Acceleration for Memory Intensive Workloads"
  *Proceedings of the 49th International Symposium on Microarchitecture (**MICRO**)*, Taipei, Taiwan, October 2016.
  [Slides (pptx) (pdf)] [Lightning Session Slides (pdf)] [Poster (pptx) (pdf)]

Continuous Runahead: Transparent Hardware Acceleration for Memory Intensive Workloads

Milad Hashemi*, Onur Mutlu§, Yale N. Patt*

*The University of Texas at Austin §ETH Zürich

Efficient Automatic Data Coherence Support

- Amirali Boroumand, Saugata Ghose, Minesh Patel, Hasan Hassan, Brandon Lucia, Kevin Hsieh, Krishna T. Malladi, Hongzhong Zheng, and Onur Mutlu,
  "LazyPIM: An Efficient Cache Coherence Mechanism for Processing-in-Memory"
  IEEE Computer Architecture Letters (***CAL***), June 2016.

LazyPIM: An Efficient Cache Coherence Mechanism for Processing-in-Memory

Amirali Boroumand[†], Saugata Ghose[†], Minesh Patel[†], Hasan Hassan[†§], Brandon Lucia[†],
Kevin Hsieh[†], Krishna T. Malladi[⋆], Hongzhong Zheng[⋆], and Onur Mutlu[‡†]
[†]*Carnegie Mellon University* [⋆]*Samsung Semiconductor, Inc.* [§]*TOBB ETÜ* [‡]*ETH Zürich*

Challenge and Opportunity for Future

Fundamentally Energy-Efficient (Data-Centric) Computing Architectures

Challenge and Opportunity for Future

Fundamentally High-Performance (Data-Centric) Computing Architectures

Computing Architectures with Minimal Data Movement

Eliminating the Adoption Barriers

How to Enable Adoption of Processing in Memory

Barriers to Adoption of PIM

1. Functionality of and applications for PIM

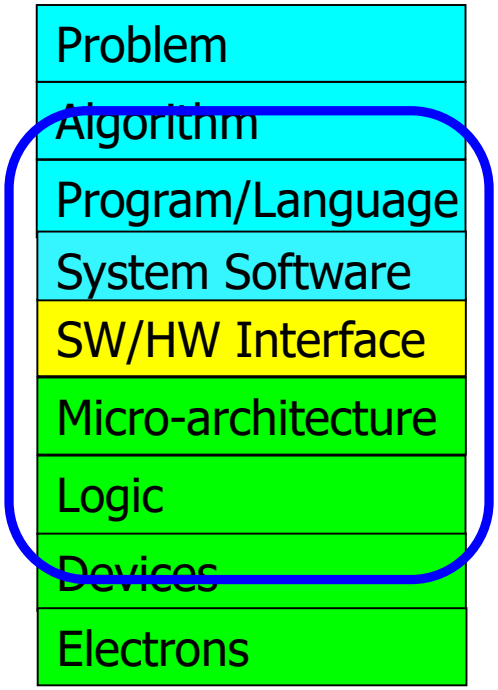
2. Ease of programming (interfaces and compiler/HW support)

3. System support: coherence & virtual memory

4. Runtime systems for adaptive scheduling, data mapping, access/sharing control

5. Infrastructures to assess benefits and feasibility

We Need to Revisit the Entire Stack



Open Problems: PIM Adoption

Enabling the Adoption of Processing-in-Memory: Challenges, Mechanisms, Future Research Directions

SAUGATA GHOSE, KEVIN HSIEH, AMIRALI BOROUMAND,
RACHATA AUSAVARUNGNIRUN
Carnegie Mellon University

ONUR MUTLU
ETH Zürich and Carnegie Mellon University

https://arxiv.org/pdf/1802.00320.pdf

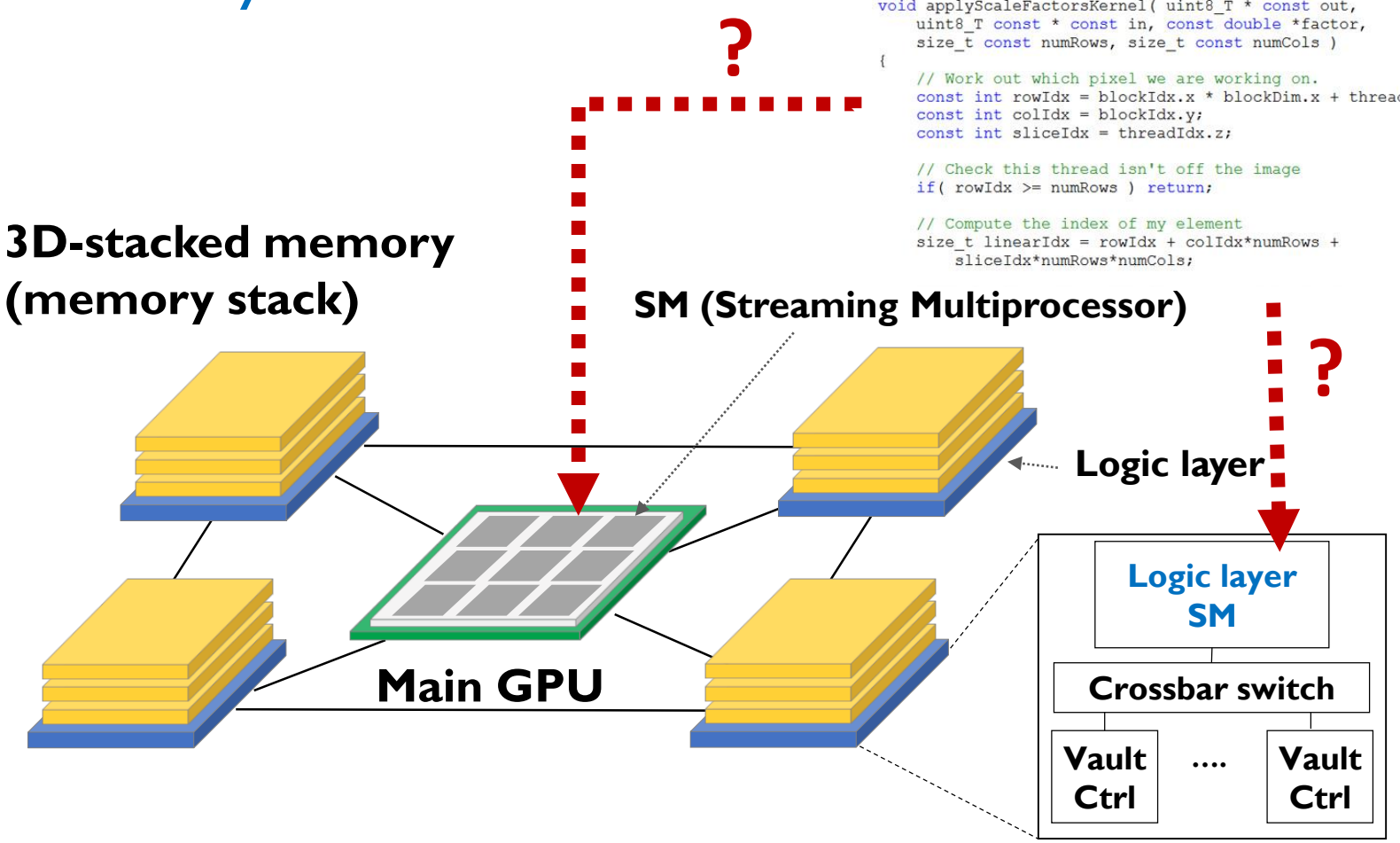
Key Challenge 1: Code Mapping

- **Challenge 1:** Which operations should be executed in memory vs. in CPU?

```
__global__
void applyScaleFactorsKernel( uint8_T * const out,
    uint8_T const * const in, const double *factor,
    size_t const numRows, size_t const numCols )
{
    // Work out which pixel we are working on.
    const int rowIdx = blockIdx.x * blockDim.x + threadIdx.x;
    const int colIdx = blockIdx.y;
    const int sliceIdx = threadIdx.z;

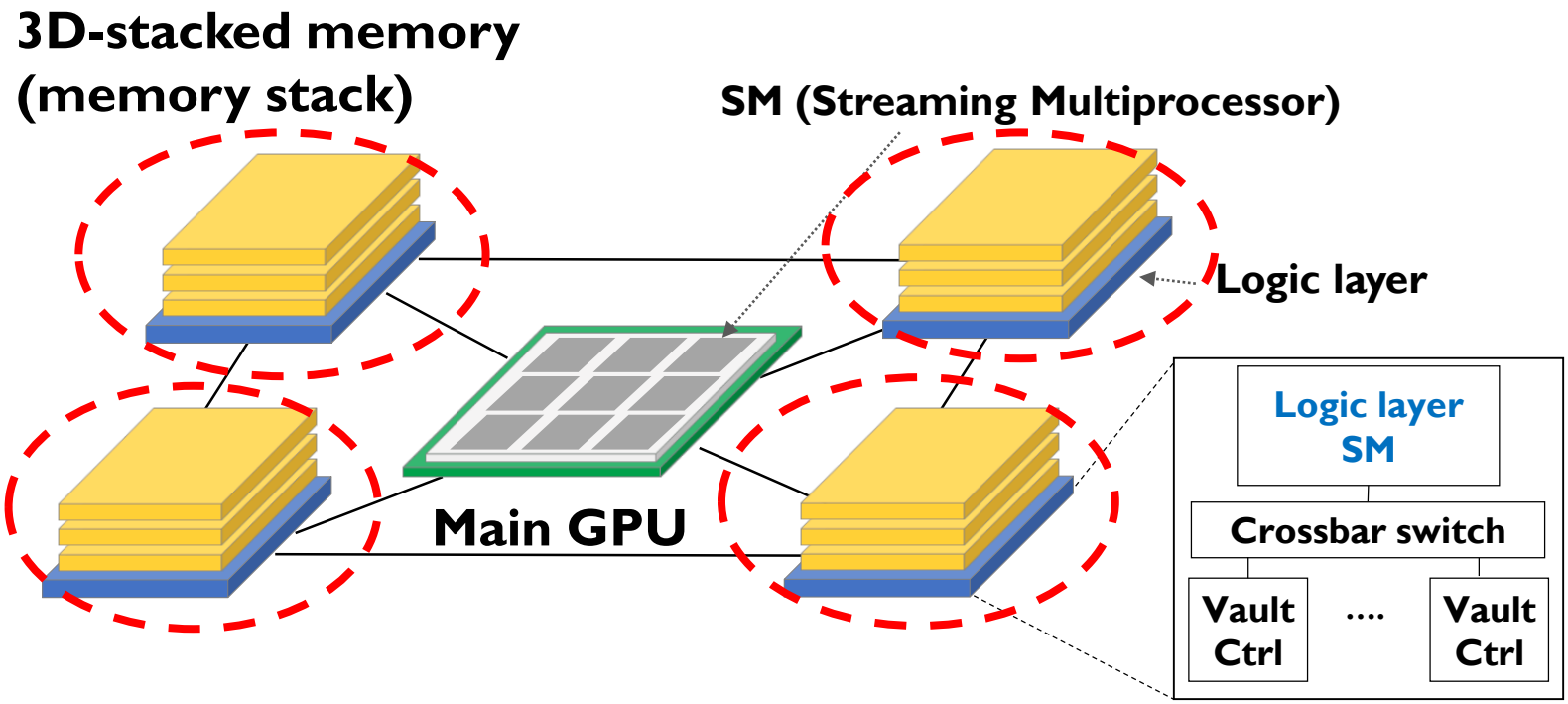
    // Check this thread isn't off the image
    if( rowIdx >= numRows ) return;

    // Compute the index of my element
    size_t linearIdx = rowIdx + colIdx*numRows +
        sliceIdx*numRows*numCols;
```



Key Challenge 2: Data Mapping

- **Challenge 2:** How should data be mapped to different 3D memory stacks?



How to Do the Code and Data Mapping?

- Kevin Hsieh, Eiman Ebrahimi, Gwangsun Kim, Niladrish Chatterjee, Mike O'Connor, Nandita Vijaykumar, Onur Mutlu, and Stephen W. Keckler, **"Transparent Offloading and Mapping (TOM): Enabling Programmer-Transparent Near-Data Processing in GPU Systems"**
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Nandita Vijaykumar[‡] Onur Mutlu[§‡] Stephen W. Keckler[†]
[‡]Carnegie Mellon University [†]NVIDIA [*]KAIST [§]ETH Zürich

How to Schedule Code?

- Ashutosh Pattnaik, Xulong Tang, Adwait Jog, Onur Kayiran, Asit K. Mishra, Mahmut T. Kandemir, Onur Mutlu, and Chita R. Das, **"Scheduling Techniques for GPU Architectures with Processing-In-Memory Capabilities"**
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Scheduling Techniques for GPU Architectures with Processing-In-Memory Capabilities

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[1]Pennsylvania State University [2]College of William and Mary
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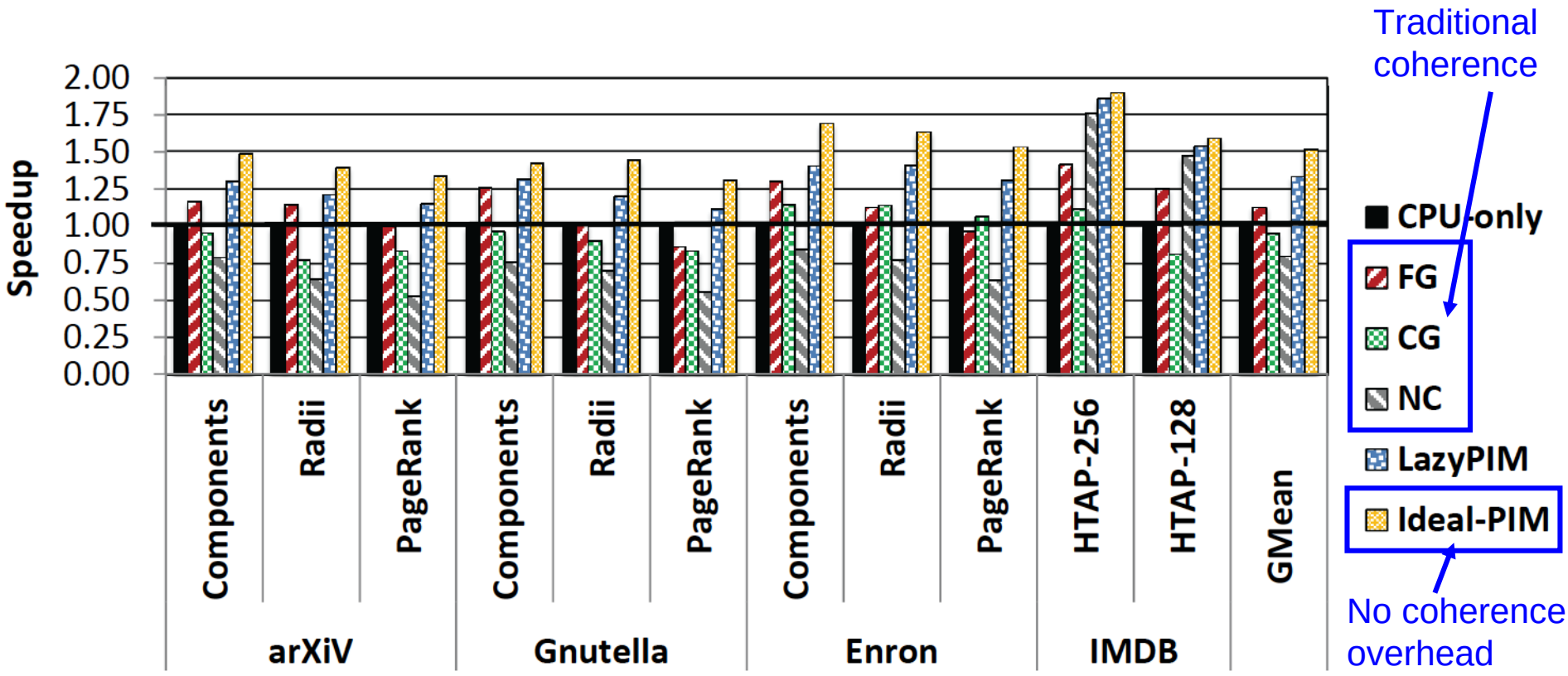
Challenge: Coherence for Hybrid CPU-PIM Apps



How to Maintain Coherence?

- Amirali Boroumand, Saugata Ghose, Minesh Patel, Hasan Hassan, Brandon Lucia, Kevin Hsieh, Krishna T. Malladi, Hongzhong Zheng, and Onur Mutlu,
  "LazyPIM: An Efficient Cache Coherence Mechanism for Processing-in-Memory"
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[†]*Carnegie Mellon University* [⋆]*Samsung Semiconductor, Inc.* [§]*TOBB ETÜ* [‡]*ETH Zürich*

How to Support Virtual Memory?

- Kevin Hsieh, Samira Khan, Nandita Vijaykumar, Kevin K. Chang, Amirali Boroumand, Saugata Ghose, and Onur Mutlu,
  "Accelerating Pointer Chasing in 3D-Stacked Memory: Challenges, Mechanisms, Evaluation"
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[†]*Carnegie Mellon University* [‡]*University of Virginia* [§]*ETH Zürich*

How to Design Data Structures for PIM?

- Zhiyu Liu, Irina Calciu, Maurice Herlihy, and Onur Mutlu, **"Concurrent Data Structures for Near-Memory Computing"** *Proceedings of the 29th ACM Symposium on Parallelism in Algorithms and Architectures (**SPAA**)*, Washington, DC, USA, July 2017. [Slides (pptx) (pdf)]

Concurrent Data Structures for Near-Memory Computing

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Simulation Infrastructures for PIM

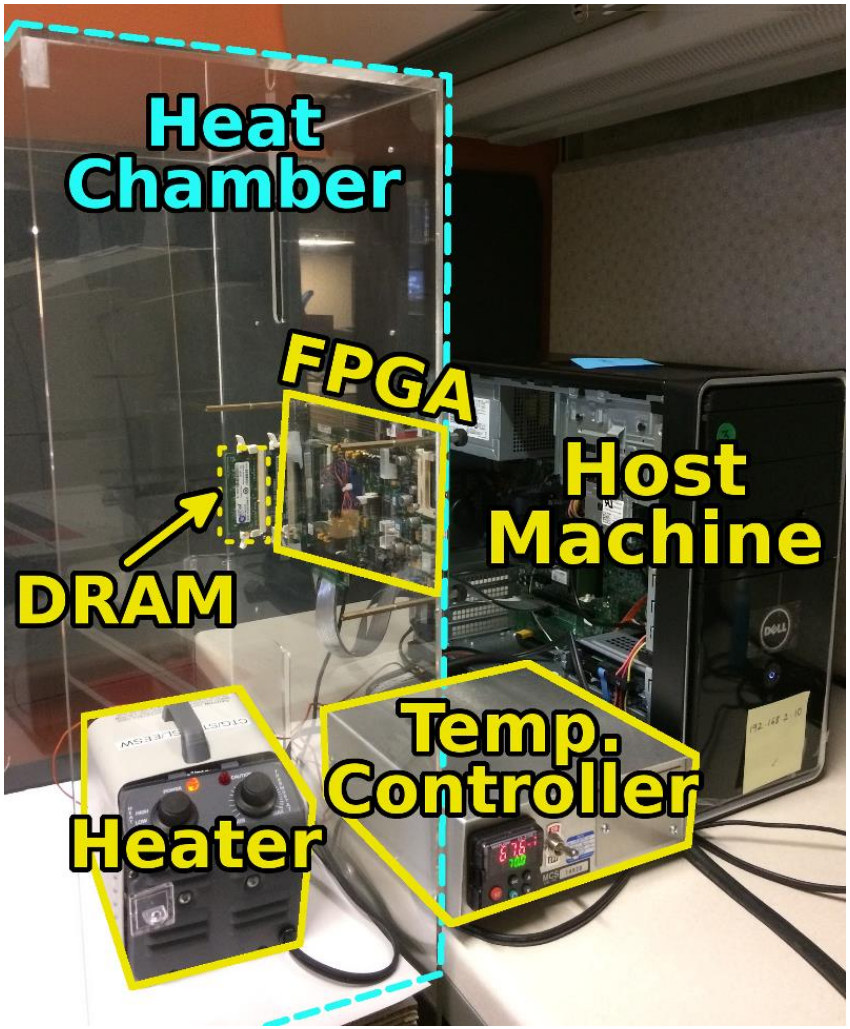
- Ramulator extended for PIM
  - Flexible and extensible DRAM simulator
  - Can model many different memory standards and proposals
  - Kim+, "**Ramulator: A Flexible and Extensible DRAM Simulator**", IEEE CAL 2015.
  - https://github.com/CMU-SAFARI/ramulator

Ramulator: A Fast and Extensible DRAM Simulator

Yoongu Kim[1] Weikun Yang[1,2] Onur Mutlu[1]
[1]Carnegie Mellon University [2]Peking University

An FPGA-based Test-bed for PIM?

- Hasan Hassan et al., **SoftMC: A Flexible and Practical Open-Source Infrastructure for Enabling Experimental DRAM Studies** HPCA 2017.

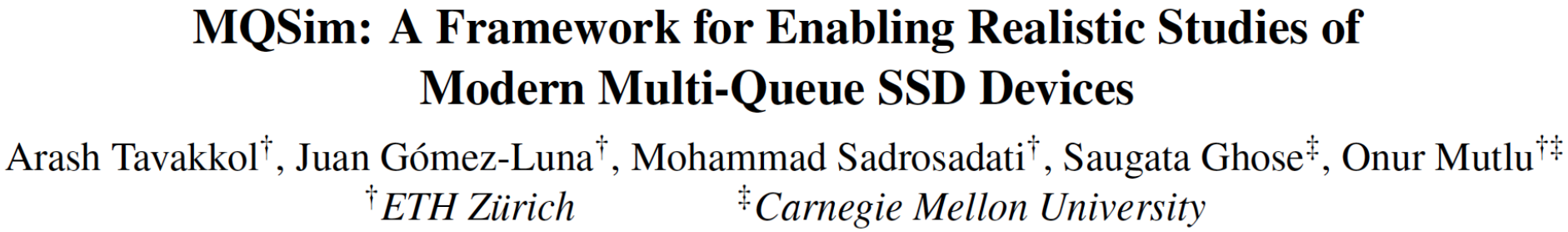


- **Flexible**
- **Easy to Use (C++ API)**
- **Open-source**

  github.com/CMU-SAFARI/SoftMC

Simulation Infrastructures for PIM (in SSDs)

- Arash Tavakkol, Juan Gomez-Luna, Mohammad Sadrosadati, Saugata Ghose, and Onur Mutlu,
  "MQSim: A Framework for Enabling Realistic Studies of Modern Multi-Queue SSD Devices"
  *Proceedings of the 16th USENIX Conference on File and Storage Technologies (**FAST**)*, Oakland, CA, USA, February 2018.
  [Slides (pptx) (pdf)]
  [Source Code]



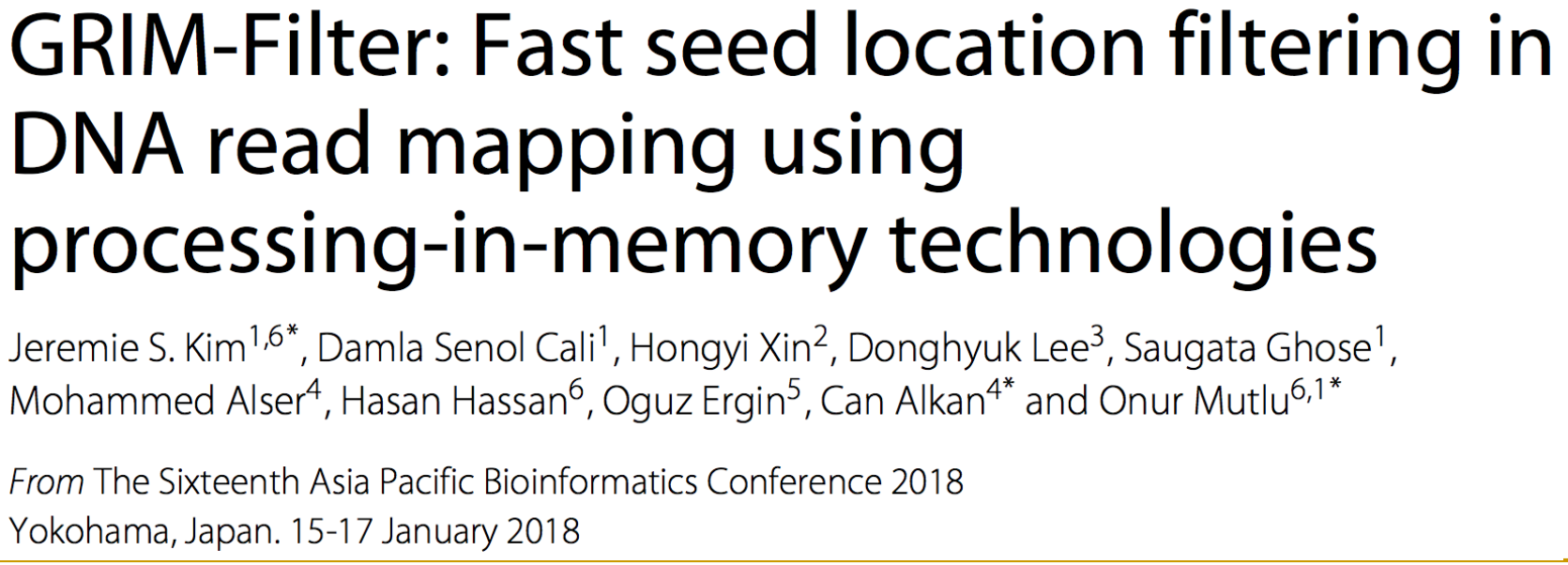
MQSim: A Framework for Enabling Realistic Studies of Modern Multi-Queue SSD Devices

Arash Tavakkol[†], Juan Gómez-Luna[†], Mohammad Sadrosadati[†], Saugata Ghose[‡], Onur Mutlu[†‡]

[†]*ETH Zürich* [‡]*Carnegie Mellon University*

New Applications and Use Cases for PIM

- Jeremie S. Kim, Damla Senol Cali, Hongyi Xin, Donghyuk Lee, Saugata Ghose, Mohammed Alser, Hasan Hassan, Oguz Ergin, Can Alkan, and Onur Mutlu, **"GRIM-Filter: Fast Seed Location Filtering in DNA Read Mapping Using Processing-in-Memory Technologies"**
  BMC Genomics, 2018.
  *Proceedings of the 16th Asia Pacific Bioinformatics Conference (**APBC**)*, Yokohama, Japan, January 2018.
  arxiv.org Version (pdf)



GRIM-Filter: Fast seed location filtering in DNA read mapping using processing-in-memory technologies

Jeremie S. Kim[1,6*], Damla Senol Cali[1], Hongyi Xin[2], Donghyuk Lee[3], Saugata Ghose[1], Mohammed Alser[4], Hasan Hassan[6], Oguz Ergin[5], Can Alkan[4*] and Onur Mutlu[6,1*]

From The Sixteenth Asia Pacific Bioinformatics Conference 2018
Yokohama, Japan. 15-17 January 2018

SAFARI

Genome Read In-Memory (GRIM) Filter:

Fast Seed Location Filtering in DNA Read Mapping using Processing-in-Memory Technologies

Jeremie Kim,
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Saugata Ghose, Mohammed Alser, Hasan Hassan,
Oguz Ergin, Can Alkan, and Onur Mutlu

Carnegie Mellon
İhsan Doğramacı Bilkent University
TOBB UNIVERSITY OF ECONOMICS AND TECHNOLOGY
ETH zürich

Executive Summary

- **Genome Read Mapping** is a very important problem and is the first step in many types of genomic analysis
  - Could lead to improved health care, medicine, quality of life
- Read mapping is an **approximate string matching** problem
  - Find the best fit of 100 character strings into a 3 billion character dictionary
  - **Alignment** is currently the best method for determining the similarity between two strings, but is **very expensive**
- We propose an in-memory processing algorithm **GRIM-Filter** for accelerating read mapping, by reducing the number of required alignments
- We implement GRIM-Filter using **in-memory processing** within **3D-stacked memory** and show up to **3.7x speedup**.

Google Workloads for Consumer Devices: Mitigating Data Movement Bottlenecks

Amirali Boroumand

Saugata Ghose, Youngsok Kim, Rachata Ausavarungnirun,
Eric Shiu, Rahul Thakur, Daehyun Kim, Aki Kuusela,
Allan Knies, Parthasarathy Ranganathan, Onur Mutlu

SAFARI Carnegie Mellon Google

SAMSUNG SEOUL NATIONAL UNIVERSITY ETH zürich

Open Problems: PIM Adoption

Enabling the Adoption of Processing-in-Memory: Challenges, Mechanisms, Future Research Directions

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Carnegie Mellon University

ONUR MUTLU
ETH Zürich and Carnegie Mellon University

https://arxiv.org/pdf/1802.00320.pdf

Enabling the Paradigm Shift

Computer Architecture Today

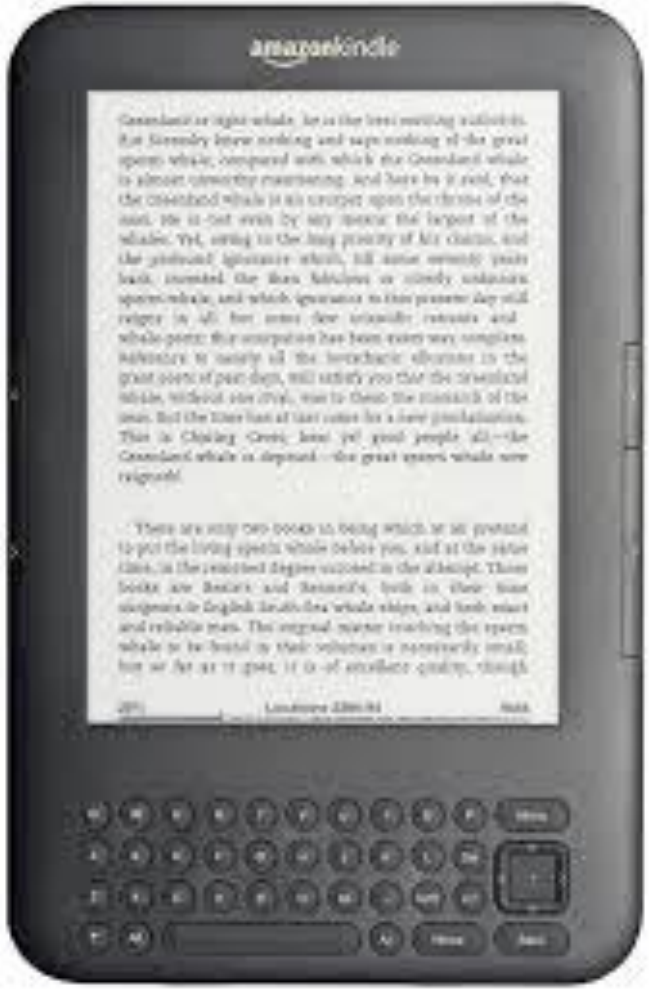
- You can revolutionize the way computers are built, if you understand both the hardware and the software (and change each accordingly)

- You can invent new paradigms for computation, communication, and storage

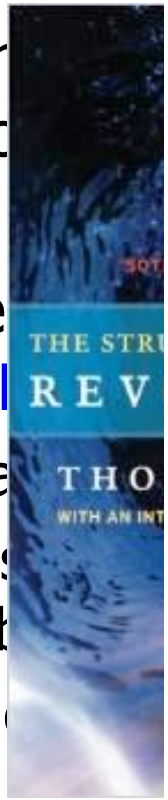
- Recommended book: Thomas Kuhn, "The Structure of Scientific Revolutions" (1962)
  - Pre-paradigm science: no clear consensus in the field
  - Normal science: dominant theory used to explain/improve things (business as usual); exceptions considered anomalies
  - Revolutionary science: underlying assumptions re-examined

Computer Architecture Today

- You can revolutionize the way computers are built, if you understand both [illegible] oftware (and change each ac[illegible]



- You can ir[illegible] communic[illegible]



- Recomme[illegible] ure of Scientific [illegible]
  - Pre-para[illegible] ield
  - Normal [illegible] improve things (b[illegible] anomalies
  - Revoluti[illegible] examined

Challenge and Opportunity for Future

Fundamentally Energy-Efficient (Data-Centric) Computing Architectures

Challenge and Opportunity for Future

Fundamentally High-Performance (Data-Centric) Computing Architectures

Computing Architectures with Minimal Data Movement

One Important Takeaway

Main Memory Needs Intelligent Controllers

Agenda

- Major Trends Affecting Main Memory
- Key Challenges and Solution Directions
  - Robustness: Reliability and Security
  - Energy and Performance: In-Memory Computation
  - Low Latency/Energy and Latency/Energy/Reliability Tradeoffs
  - Scalability and More: Enabling Emerging Technologies
- Solution Principles
- Concluding Remarks

Four Key Issues in Future Platforms

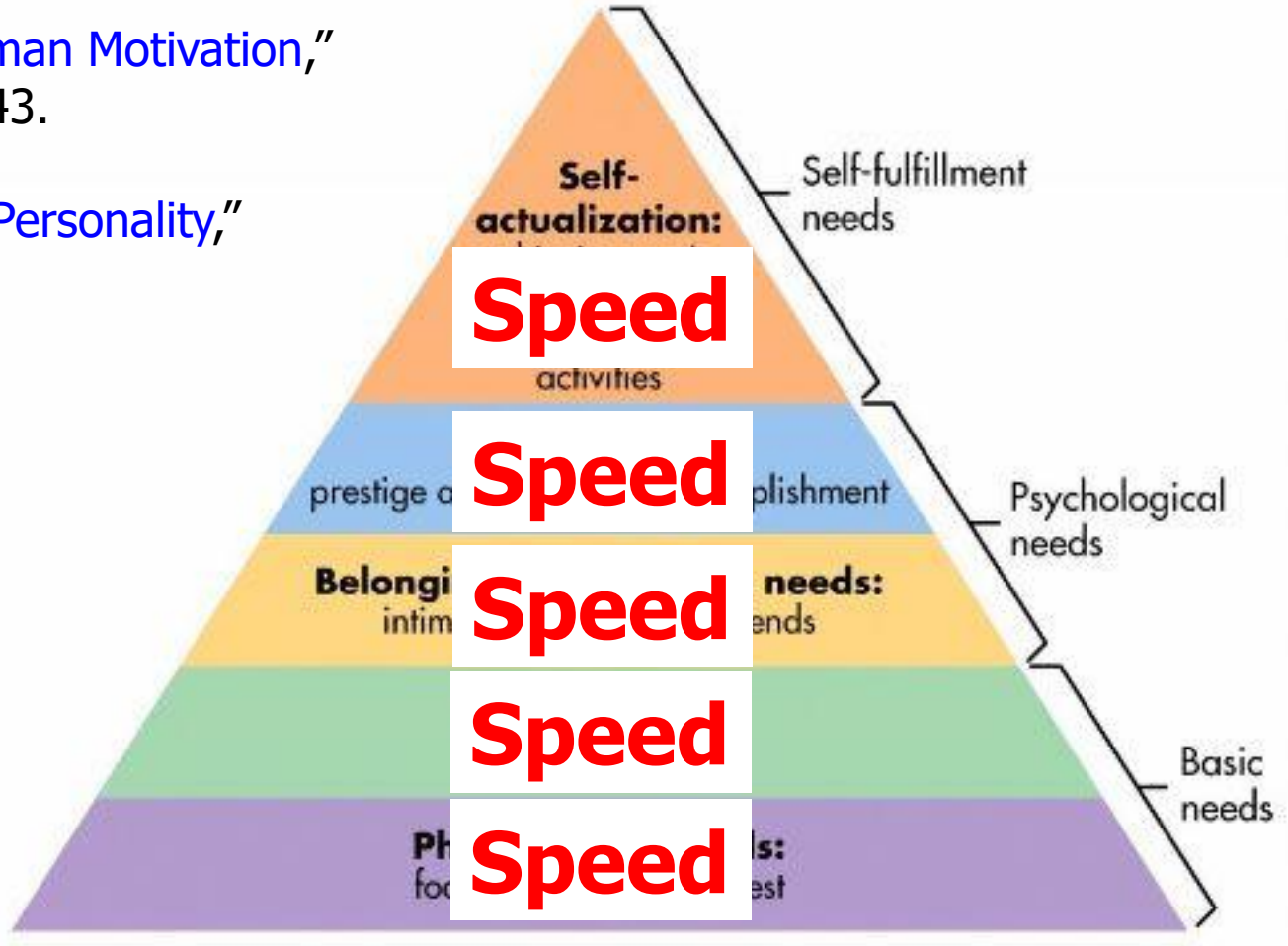
- Fundamentally Secure/Reliable/Safe Architectures
- Fundamentally Energy-Efficient Architectures
  - Memory-centric (Data-centric) Architectures
- Fundamentally Low-Latency Architectures
- Architectures for Genomics, Medicine, Health

Source: http://spectrum.ieee.org/image/MjYzMzAyMg.jpeg

Maslow's Hierarchy of Needs, A Third Time

Maslow, "A Theory of Human Motivation," Psychological Review, 1943.

Maslow, "Motivation and Personality," Book, 1954-1970.

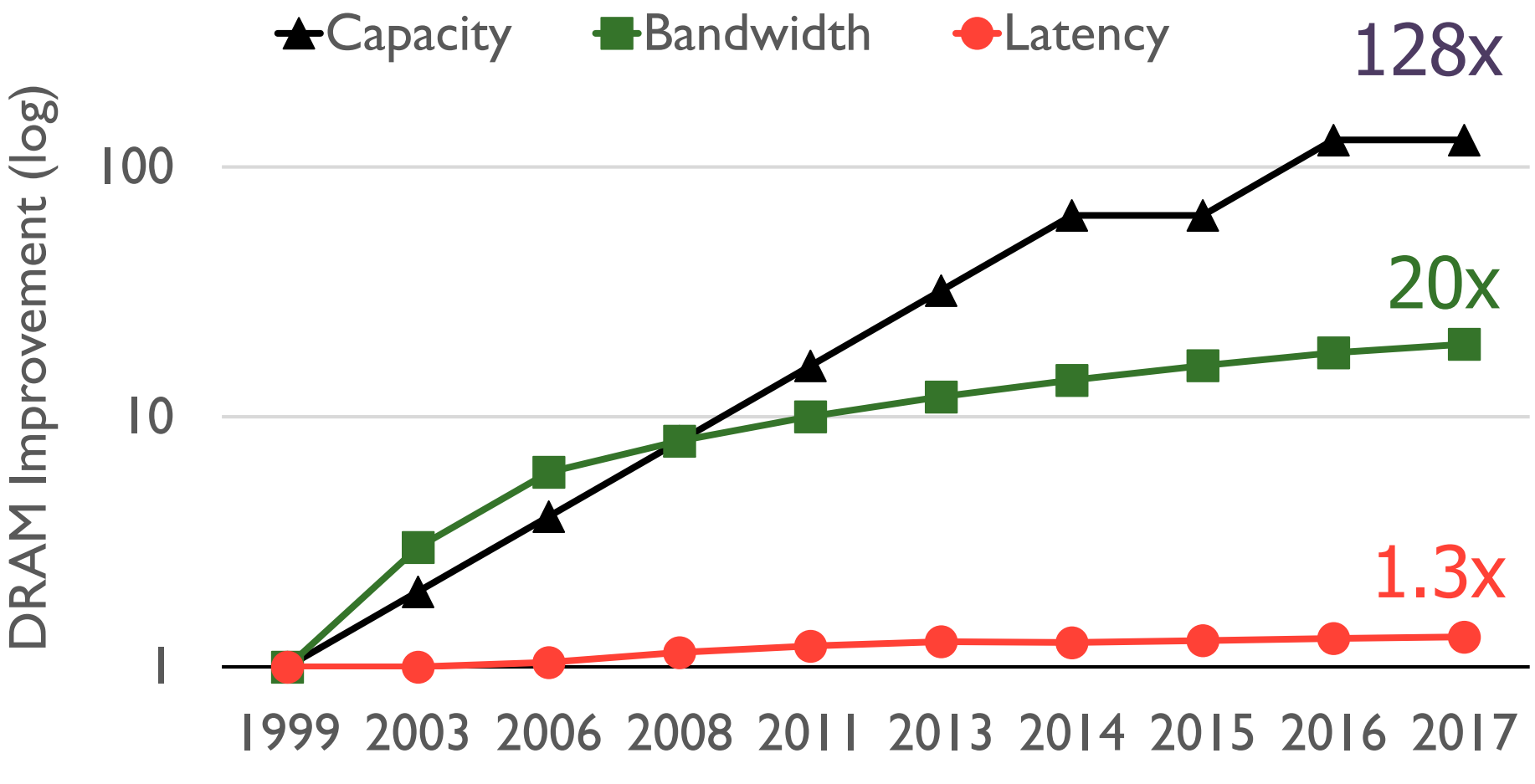


Source: https://www.simplypsychology.org/maslow.html

Challenge and Opportunity for Future

Fundamentally Low-Latency Computing Architectures

Main Memory Latency Lags Behind



Memory latency remains almost constant

A Closer Look …

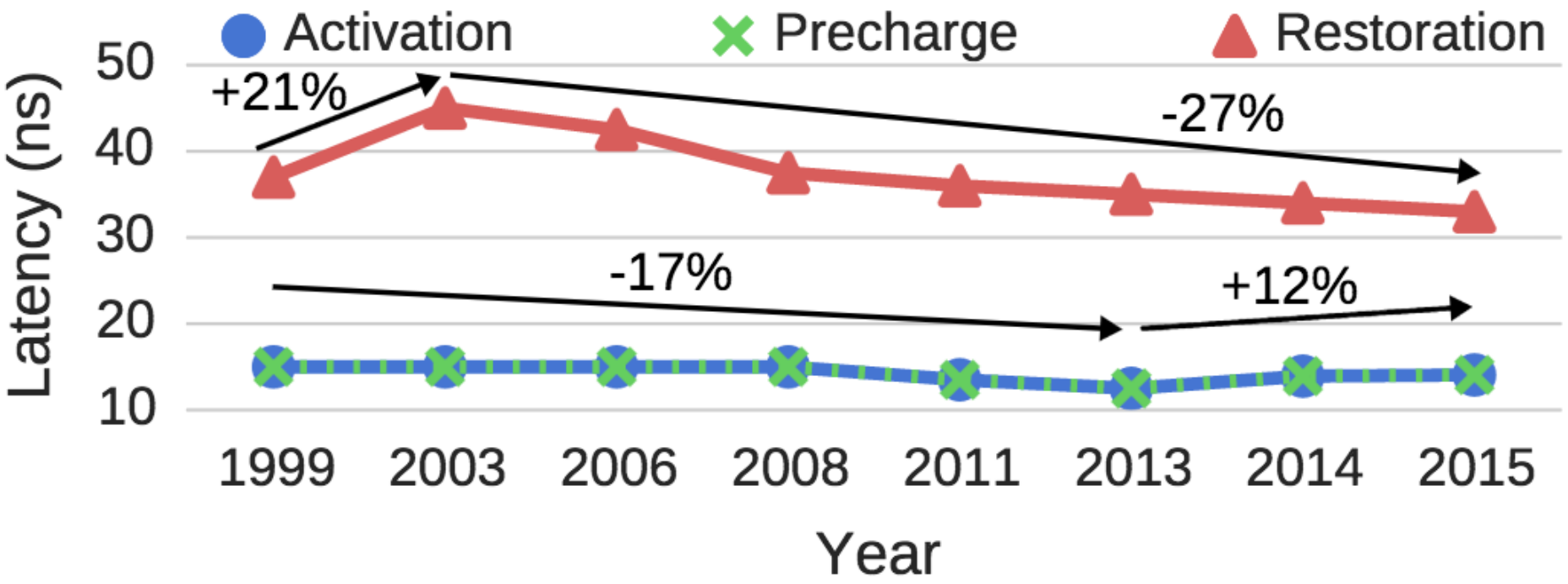
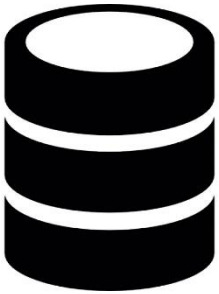


Figure 1: DRAM latency trends over time [20, 21, 23, 51].

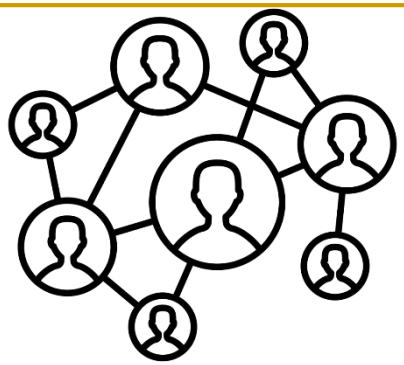
Chang+, "**Understanding Latency Variation in Modern DRAM Chips: Experimental Characterization, Analysis, and Optimization**," SIGMETRICS 2016.

DRAM Latency Is Critical for Performance



In-memory Databases

[Mao+, EuroSys'12;
Clapp+ (**Intel**), IISWC'15]

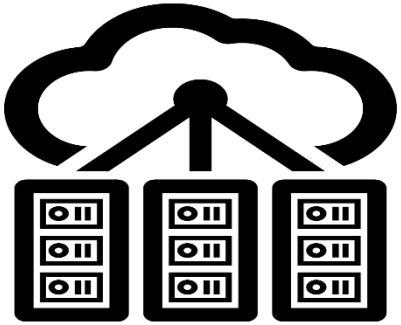


Graph/Tree Processing

[Xu+, IISWC'12; Umuroglu+, FPL'15]

In-Memory Data Analytics

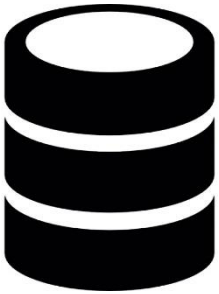
[Clapp+ (**Intel**), IISWC'15;
Awan+, BDCloud'15]



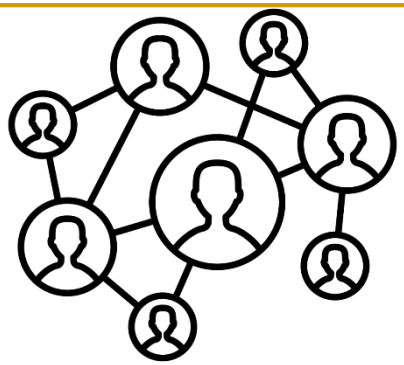
Datacenter Workloads

[Kanev+ (**Google**), ISCA'15]

DRAM Latency Is Critical for Performance



In-memory Databases

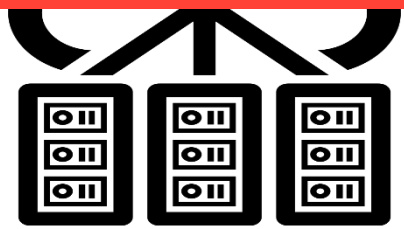


Graph/Tree Processing

Long memory latency → performance bottleneck

In-Memory Data Analytics

[Clapp+ (**Intel**), IISWC'15; Awan+, BDCloud'15]



Datacenter Workloads

[Kanev+ (**Google**), ISCA'15]

The Memory Latency Problem

- High memory latency is a significant limiter of system performance and energy-efficiency
- It is becoming increasingly so with higher memory contention in multi-core and heterogeneous architectures
  - Exacerbating the bandwidth need
  - Exacerbating the QoS problem
- It increases processor design complexity due to the mechanisms incorporated to tolerate memory latency

Retrospective: Conventional Latency Tolerance Techniques

- Caching [initially by Wilkes, 1965]
  - Widely used, simple, effective, but inefficient, passive
  - Not all applications/phases exhibit temporal or spatial locality
- Prefetching [initially in IBM 360/91, 1967]

None of These Fundamentally Reduce Memory Latency

  - ongoing research effort
- Out-of-order execution [initially by Tomasulo, 1967]
  - Tolerates cache misses that cannot be prefetched
  - Requires extensive hardware resources for tolerating long latencies

Truly Reducing Memory Latency

Two Major Sources of Latency Inefficiency

- Modern DRAM is **not** designed for low latency
  - Main focus is cost-per-bit (capacity)
- Modern DRAM latency is determined by **worst case** conditions and **worst case** devices
  - Much of memory latency is unnecessary

Our Goal: Reduce Memory Latency at the Source of the Problem

Why the Long Memory Latency?

- Reason 1: Design of DRAM Micro-architecture
  - Goal: Maximize capacity/area, not minimize latency

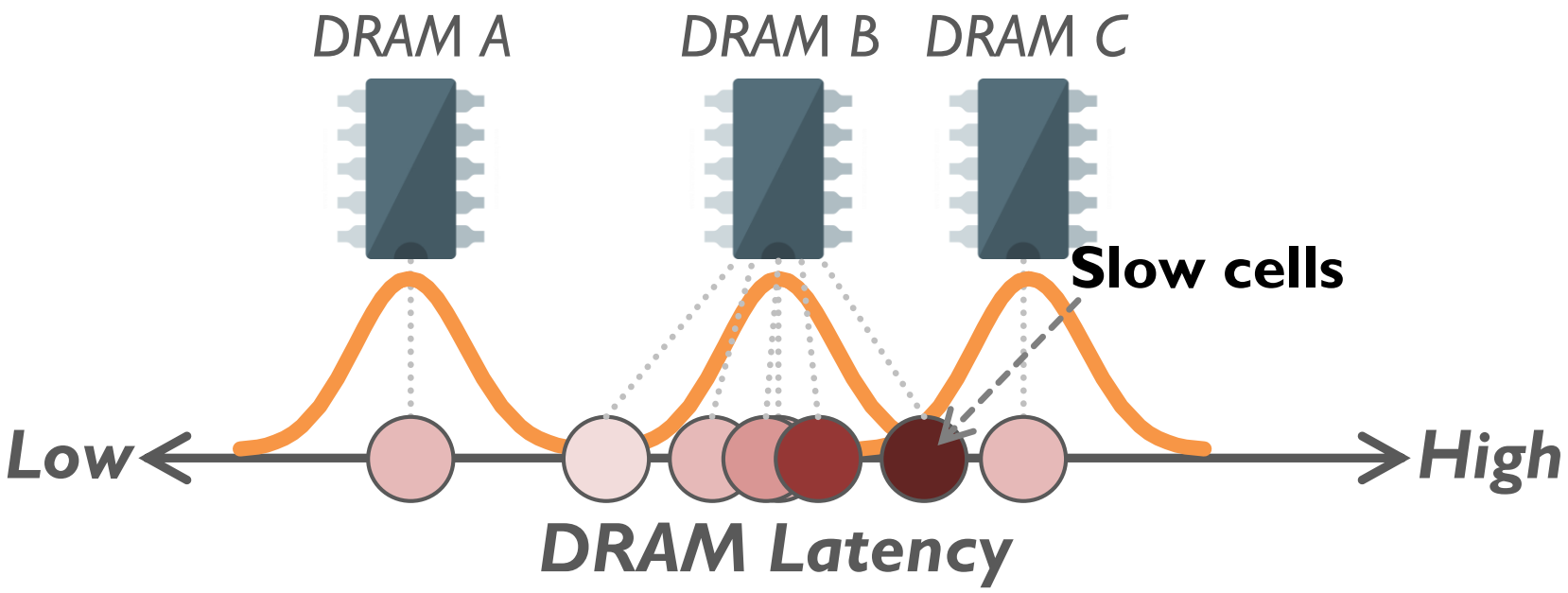
- Reason 2: "One size fits all" approach to latency specification
  - Same latency parameters for all temperatures
  - Same latency parameters for all DRAM chips (e.g., rows)
  - Same latency parameters for all parts of a DRAM chip
  - Same latency parameters for all supply voltage levels
  - Same latency parameters for all application data
  - …

Tackling the Fixed Latency Mindset

- Reliable operation latency is actually very heterogeneous
  - Across temperatures, chips, parts of a chip, voltage levels, …
- Idea: Dynamically find out and use the lowest latency one can reliably access a memory location with
  - Adaptive-Latency DRAM [HPCA 2015]
  - Flexible-Latency DRAM [SIGMETRICS 2016]
  - Design-Induced Variation-Aware DRAM [SIGMETRICS 2017]
  - Voltron [SIGMETRICS 2017]
  - DRAM Latency PUF [HPCA 2018]
  - …
- We would like to find sources of latency heterogeneity and exploit them to minimize latency

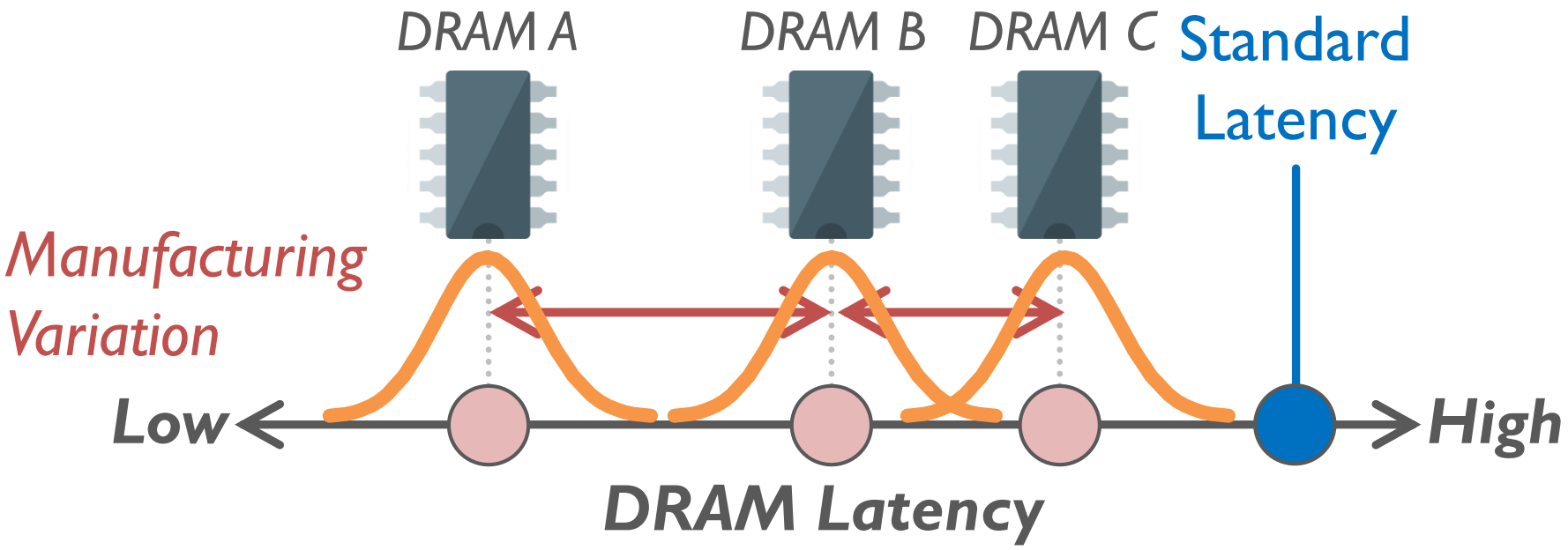
Latency Variation in Memory Chips

Heterogeneous manufacturing & operating conditions → latency variation in timing parameters

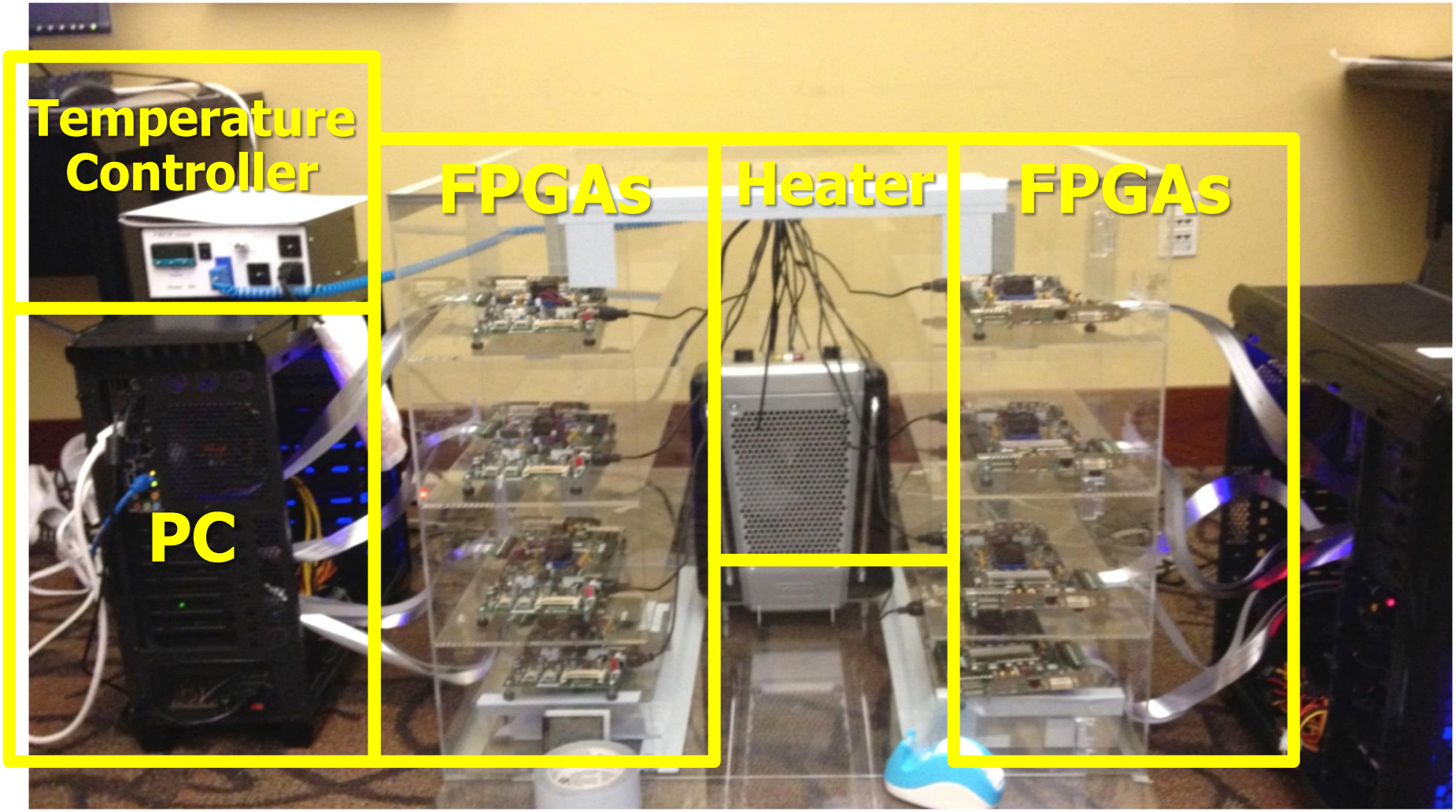


Why is Latency High?

- DRAM latency: Delay as specified in DRAM standards
  - Doesn't reflect true DRAM device latency
- Imperfect manufacturing process → latency variation
- **High standard latency** chosen to increase yield



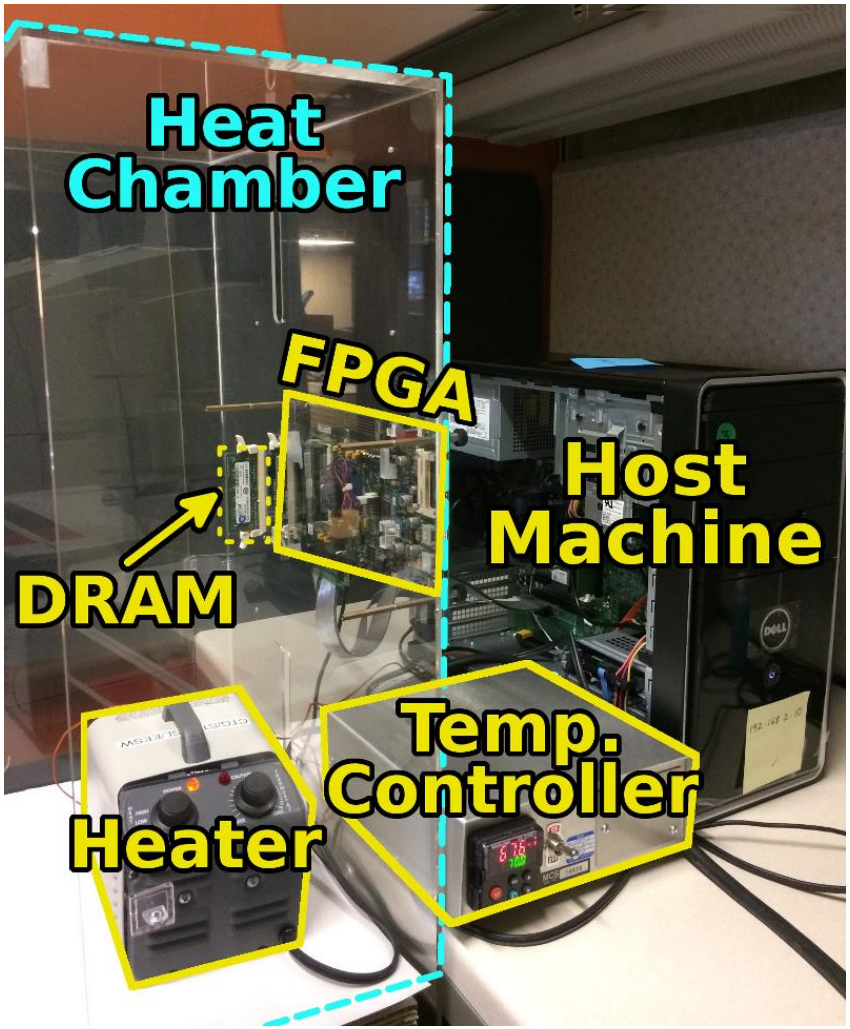
DRAM Characterization Infrastructure



Kim+, "Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors," ISCA 2014.

DRAM Characterization Infrastructure

- Hasan Hassan et al., **SoftMC: A Flexible and Practical Open-Source Infrastructure for Enabling Experimental DRAM Studies**, HPCA 2017.



- **Flexible**
- **Easy to Use (C++ API)**
- **Open-source**

  github.com/CMU-SAFARI/SoftMC

SoftMC: Open Source DRAM Infrastructure

- https://github.com/CMU-SAFARI/SoftMC

SoftMC: A Flexible and Practical Open-Source Infrastructure for Enabling Experimental DRAM Studies

Hasan Hassan[1,2,3] Nandita Vijaykumar[3] Samira Khan[4,3] Saugata Ghose[3] Kevin Chang[3]
Gennady Pekhimenko[5,3] Donghyuk Lee[6,3] Oguz Ergin[2] Onur Mutlu[1,3]

[1]*ETH Zürich* [2]*TOBB University of Economics & Technology* [3]*Carnegie Mellon University*
[4]*University of Virginia* [5]*Microsoft Research* [6]*NVIDIA Research*

Adaptive-Latency DRAM

- *Key idea*
  - **Optimize DRAM timing parameters online**
- *Two components*
  - DRAM manufacturer provides multiple sets of reliable DRAM timing parameters at different temperatures for each DIMM
  - System monitors DRAM temperature & uses appropriate DRAM timing parameters

Lee+, "Adaptive-Latency DRAM: Optimizing DRAM Timing for the Common-Case," HPCA 2015.

Latency Reduction Summary of 115 DIMMs

- *Latency reduction for read & write (55°C)*
  - *Read Latency: **32.7%***
  - *Write Latency: **55.1%***
- *Latency reduction for each timing parameter (55°C)*
  - *Sensing: **17.3%***
  - *Restore: **37.3%** (read), **54.8%** (write)*
  - *Precharge: **35.2%***

Lee+, "Adaptive-Latency DRAM: Optimizing DRAM Timing for the Common-Case," HPCA 2015.

AL-DRAM: Real System Evaluation

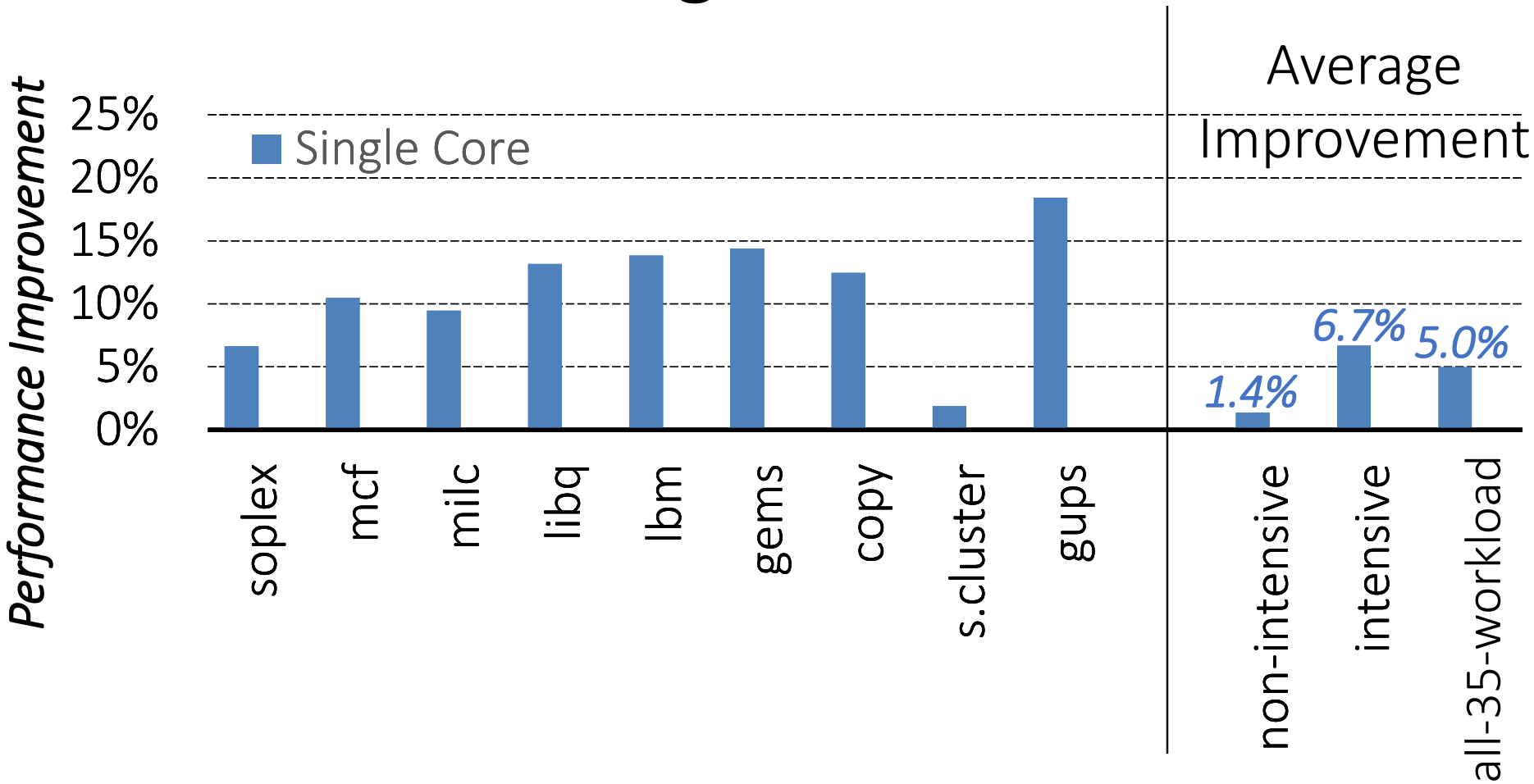
- *System*
  - *CPU: AMD 4386 (8 Cores, 3.1GHz, 8MB LLC)*

D18F2x200_dct[0]_mp[1:0] DDR3 DRAM Timing 0

Reset: 0F05_0505h. See 2.9.3 [DCT Configuration Registers].

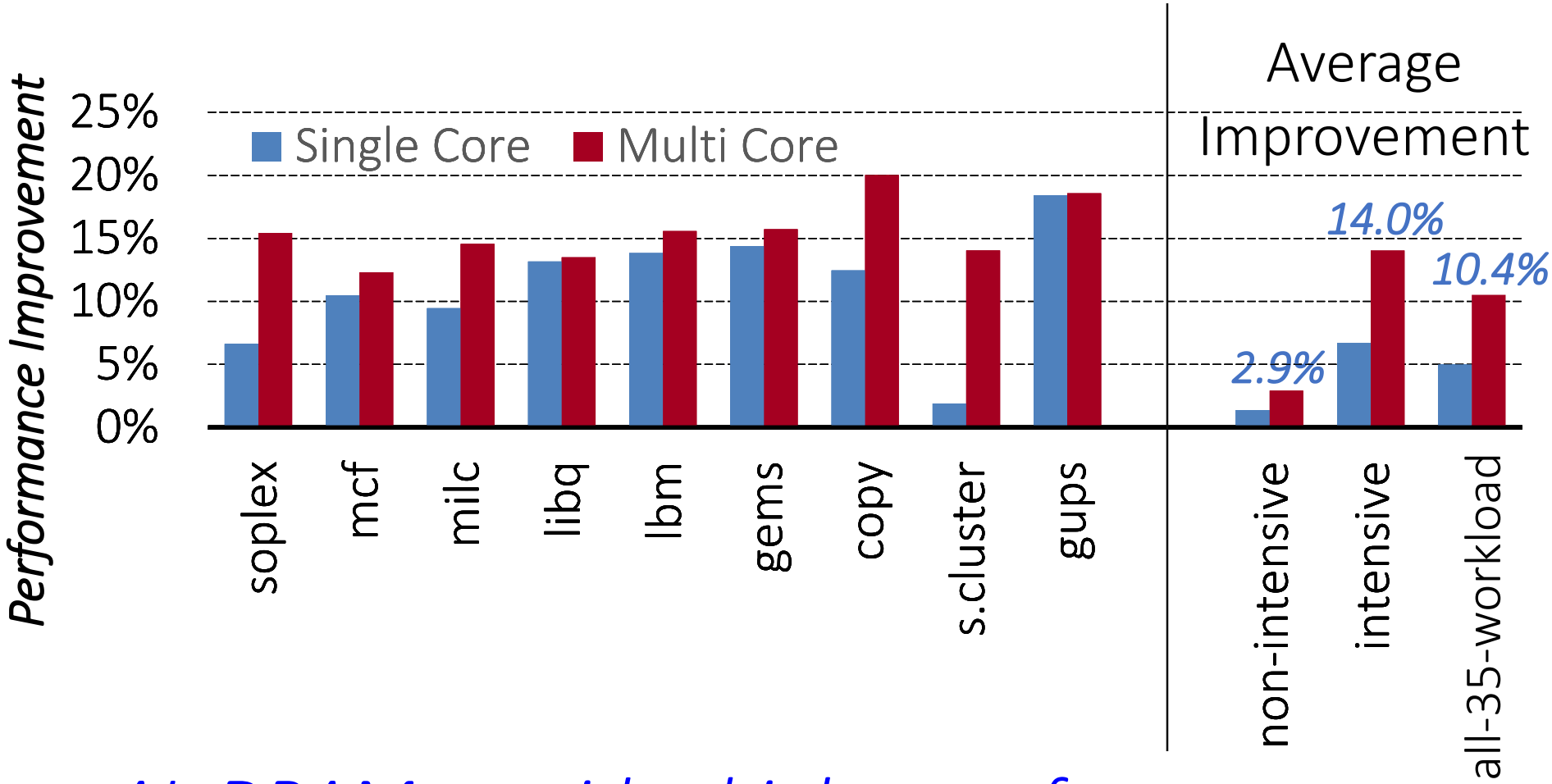
Bits	Description
31:30	Reserved.
29:24	**Tras: row active strobe**. Read-write. BIOS: See 2.9.7.5 [SPD ROM-Based Configuration]. Specifies the minimum time in memory clock cycles from an activate command to a precharge command, both to the same chip select bank. Bits — Description 07h-00h — Reserved 2Ah-08h — <Tras> clocks 3Fh-2Bh — Reserved
23:21	Reserved.
20:16	**Trp: row precharge time**. Read-write. BIOS: See 2.9.7.5 [SPD ROM-Based Configuration]. Specifies the minimum time in memory clock cycles from a precharge command to an activate command or auto refresh command, both to the same bank.

AL-DRAM: Single-Core Evaluation



AL-DRAM ***improves single-core performance*** *on a real system*

AL-DRAM: Multi-Core Evaluation



AL-DRAM provides higher performance on

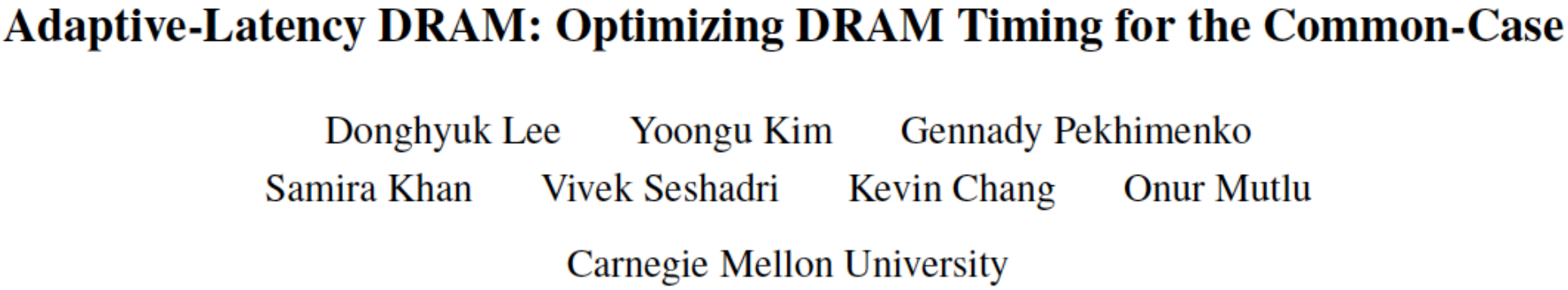
multi-programmed & multi-threaded workloads

Reducing Latency Also Reduces Energy

- AL-DRAM reduces DRAM power consumption by 5.8%
- Major reason: reduction in row activation time

More on Adaptive-Latency DRAM

- Donghyuk Lee, Yoongu Kim, Gennady Pekhimenko, Samira Khan, Vivek Seshadri, Kevin Chang, and Onur Mutlu,
  "Adaptive-Latency DRAM: Optimizing DRAM Timing for the Common-Case"
  *Proceedings of the 21st International Symposium on High-Performance Computer Architecture (**HPCA**)*, Bay Area, CA, February 2015.
  [Slides (pptx) (pdf)] [Full data sets]



Adaptive-Latency DRAM: Optimizing DRAM Timing for the Common-Case

Donghyuk Lee Yoongu Kim Gennady Pekhimenko
Samira Khan Vivek Seshadri Kevin Chang Onur Mutlu

Carnegie Mellon University

Different Types of Latency Variation

- AL-DRAM exploits latency variation
  - Across time (different temperatures)
  - Across chips

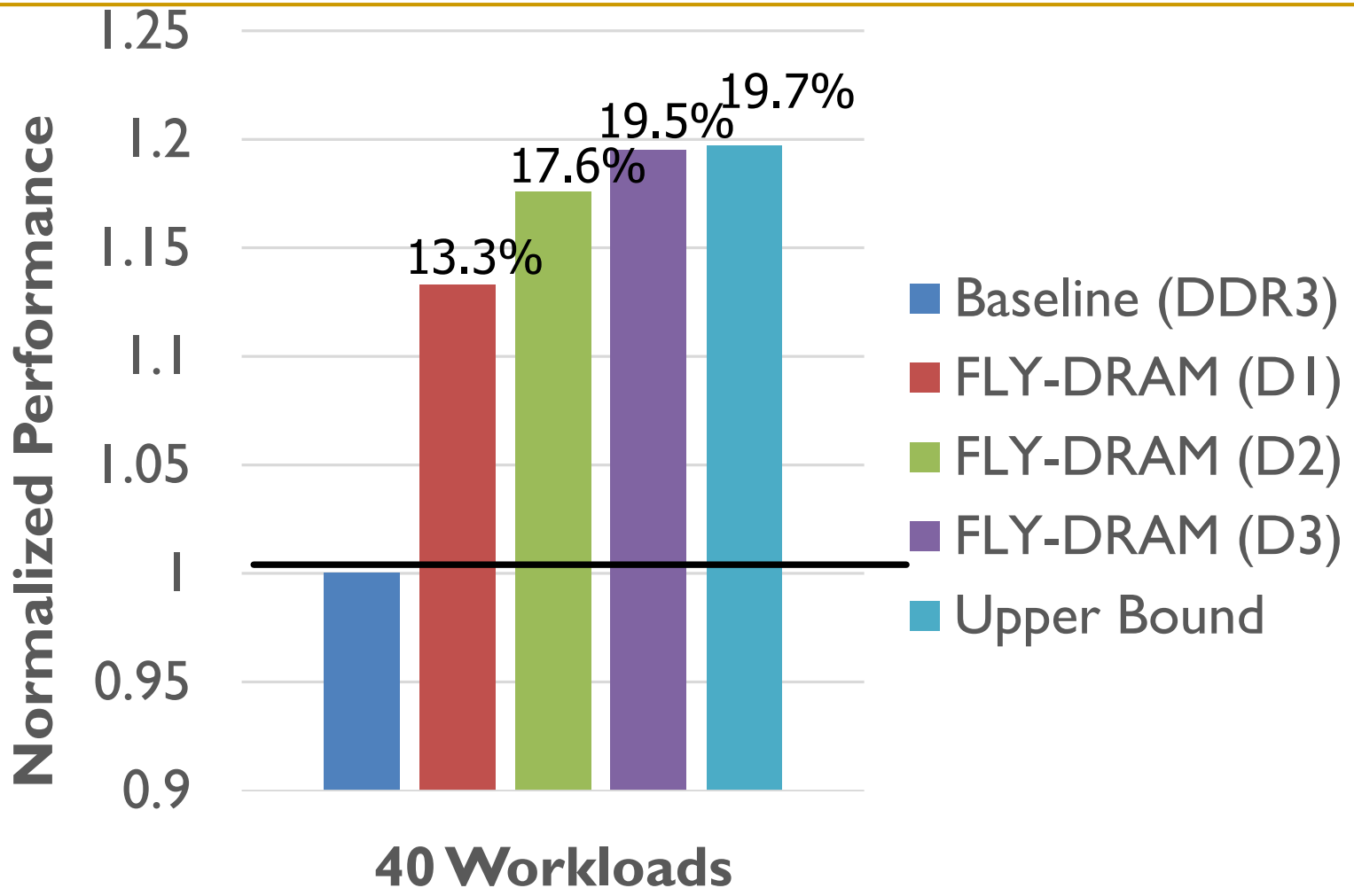
- Is there also latency variation within a chip?
  - Across different parts of a chip

Heterogeneous Latency within A Chip

- **Observation:** DRAM timing errors (slow DRAM cells) are concentrated on certain regions
- **Flexible-LatencY (FLY) DRAM**
  - A software-transparent design that reduces latency
- **Key idea**:
  1) Divide memory into regions of different latencies
  2) *Memory controller:* Use lower latency for regions without slow cells; higher latency for other regions

Chang+, "**Understanding Latency Variation in Modern DRAM Chips: Experimental Characterization, Analysis, and Optimization"**," SIGMETRICS 2016.

Heterogeneous Latency within A Chip



Chang+, "**Understanding Latency Variation in Modern DRAM Chips: Experimental Characterization, Analysis, and Optimization**," SIGMETRICS 2016.

Analysis of Latency Variation in DRAM Chips

- Kevin Chang, Abhijith Kashyap, Hasan Hassan, Samira Khan, Kevin Hsieh, Donghyuk Lee, Saugata Ghose, Gennady Pekhimenko, Tianshi Li, and Onur Mutlu,
  "Understanding Latency Variation in Modern DRAM Chips: Experimental Characterization, Analysis, and Optimization"
  Proceedings of the ACM International Conference on Measurement and Modeling of Computer Systems (***SIGMETRICS***), Antibes Juan-Les-Pins, France, June 2016.
  [Slides (pptx) (pdf)]
  [Source Code]

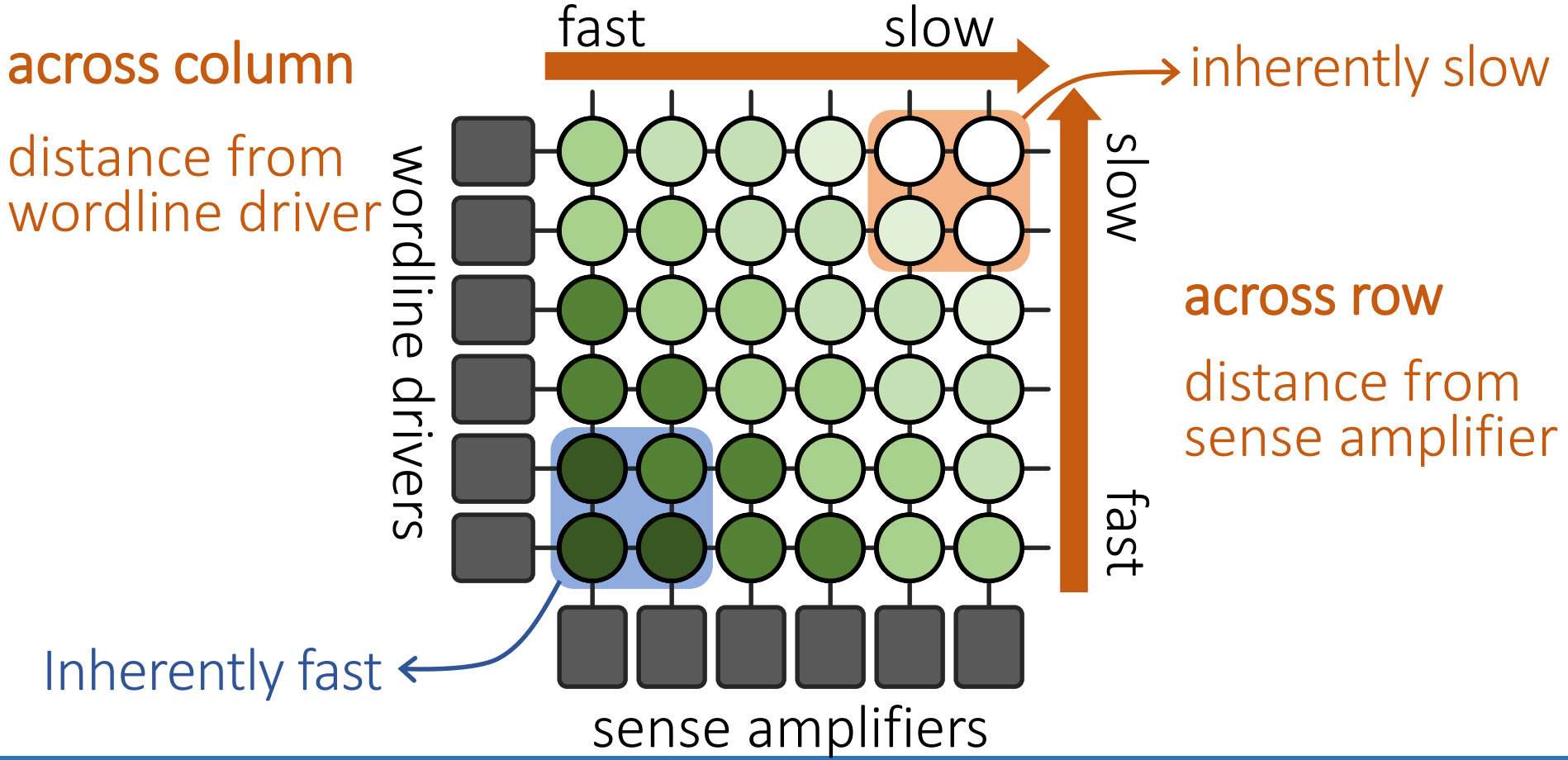
Understanding Latency Variation in Modern DRAM Chips: Experimental Characterization, Analysis, and Optimization

Kevin K. Chang[1] Abhijith Kashyap[1] Hasan Hassan[1,2]
Saugata Ghose[1] Kevin Hsieh[1] Donghyuk Lee[1] Tianshi Li[1,3]
Gennady Pekhimenko[1] Samira Khan[4] Onur Mutlu[5,1]

[1]Carnegie Mellon University [2]TOBB ETÜ [3]Peking University [4]University of Virginia [5]ETH Zürich

Why Is There Spatial Latency Variation Within a Chip?

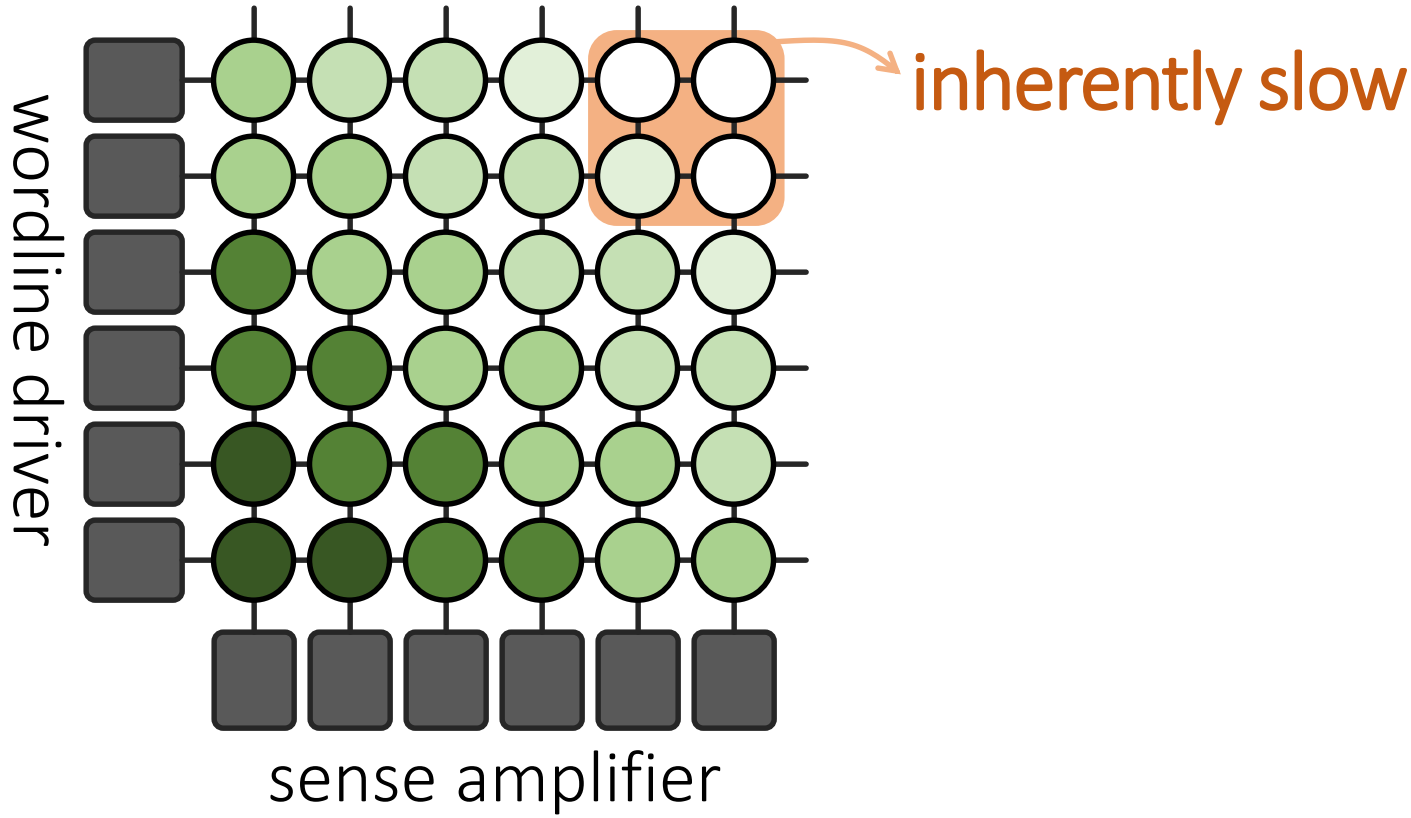
What Is Design-Induced Variation?



Systematic variation in cell access times caused by the ***physical organization*** of DRAM

DIVA Online **Profiling**

Design-**I**nduced-**V**ariation-**A**ware



Profile *only slow regions* to determine min. latency

→ *Dynamic* & *low cost* latency optimization

DIVA Online **Profiling**

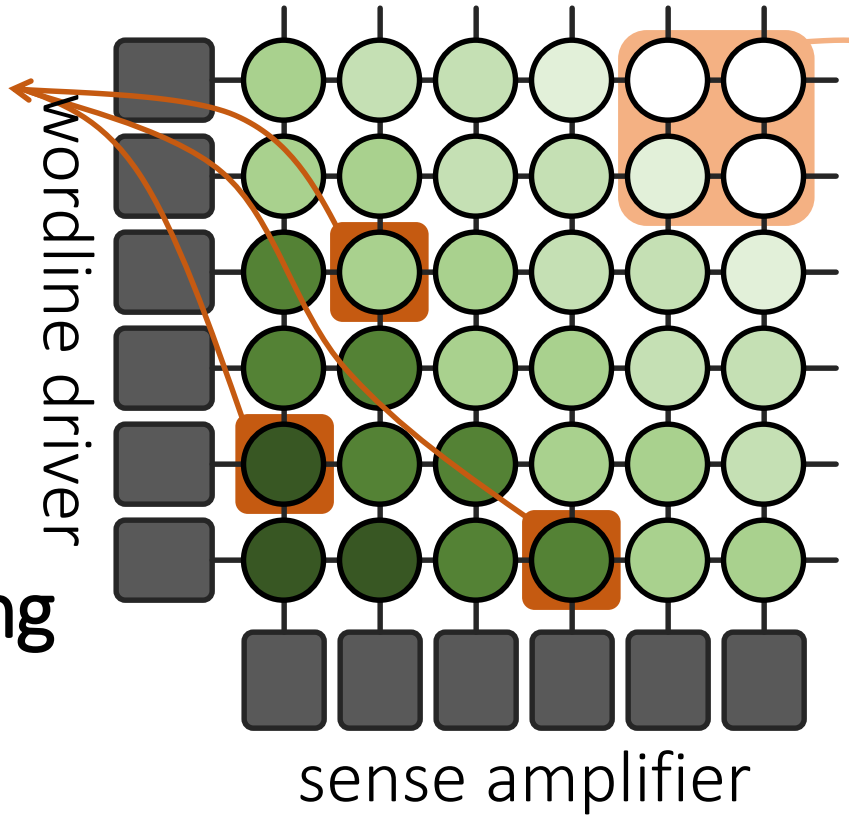
Design-**I**nduced-**V**ariation-**A**ware

slow cells

process variation

random error

error-correcting code



inherently slow

design-induced variation

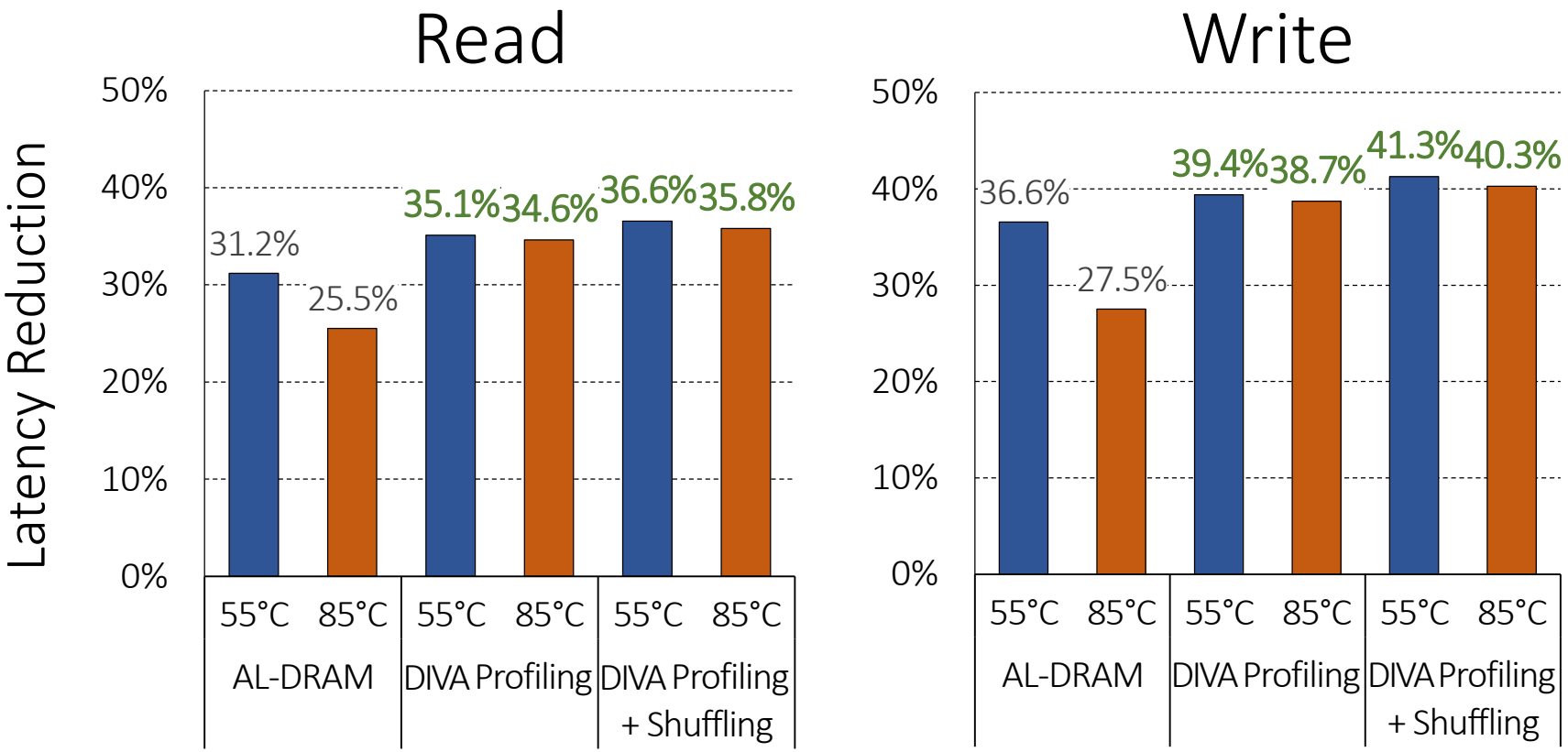
localized error

online profiling

Combine error-correcting codes & online profiling

→ Reliably reduce DRAM latency

DIVA-DRAM Reduces Latency



DIVA-DRAM ***reduces latency more aggressively*** and uses ECC to correct random slow cells

Design-Induced Latency Variation in DRAM

- Donghyuk Lee, Samira Khan, Lavanya Subramanian, Saugata Ghose, Rachata Ausavarungnirun, Gennady Pekhimenko, Vivek Seshadri, and Onur Mutlu,
  "Design-Induced Latency Variation in Modern DRAM Chips: Characterization, Analysis, and Latency Reduction Mechanisms"
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Design-Induced Latency Variation in Modern DRAM Chips: Characterization, Analysis, and Latency Reduction Mechanisms

Donghyuk Lee, NVIDIA and Carnegie Mellon University
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Lavanya Subramanian, Saugata Ghose, Rachata Ausavarungnirun, Carnegie Mellon University
Gennady Pekhimenko, Vivek Seshadri, Microsoft Research
Onur Mutlu, ETH Zürich and Carnegie Mellon University

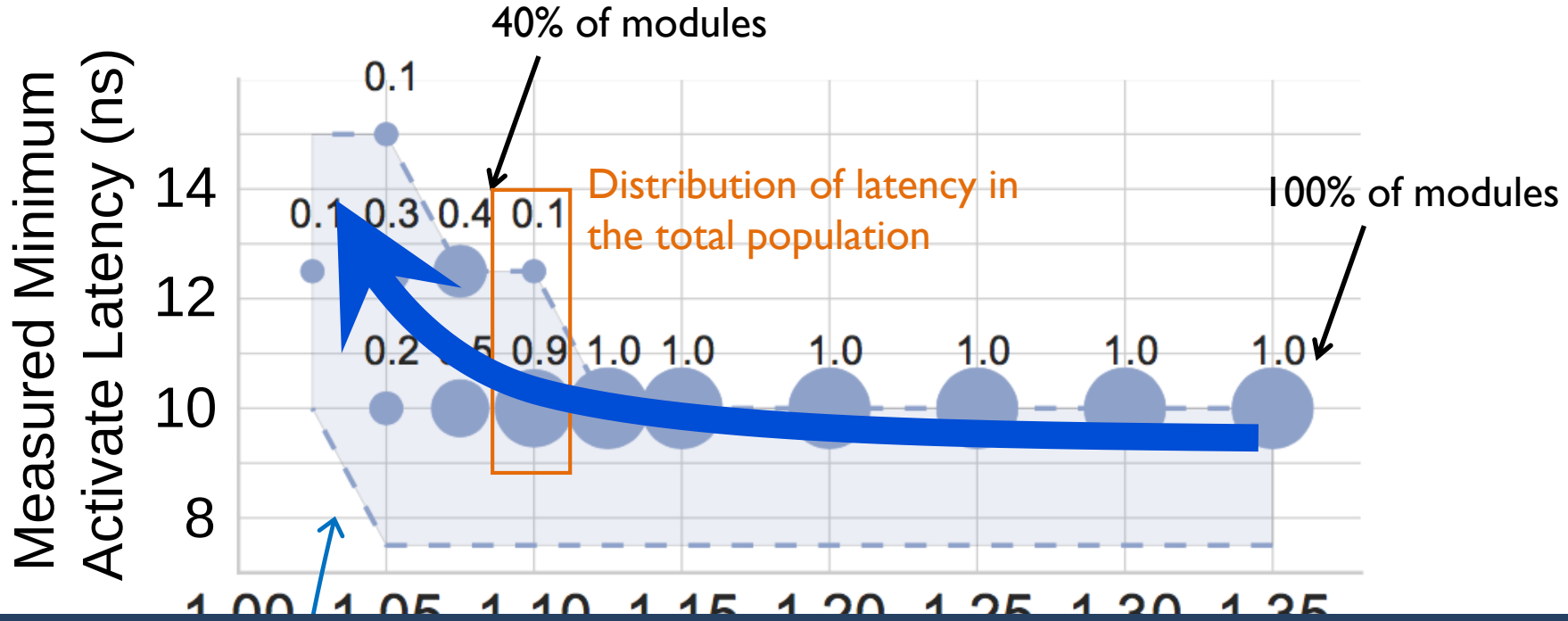
Voltron: Exploiting the Voltage-Latency-Reliability Relationship

Executive Summary

- DRAM (memory) power is significant in today's systems
  - Existing low-voltage DRAM reduces voltage **conservatively**
- Goal: Understand and exploit the reliability and latency behavior of real DRAM chips under ***aggressive reduced-voltage operation***
- Key experimental observations:
  - Huge voltage margin -- Errors occur beyond some voltage
  - Errors exhibit spatial locality
  - Higher operation latency mitigates voltage-induced errors
- **Voltron**: A new DRAM energy reduction mechanism
  - Reduce DRAM voltage **without introducing errors**
  - Use a **regression model** to select voltage that does not degrade performance beyond a chosen target → 7.3% system energy reduction

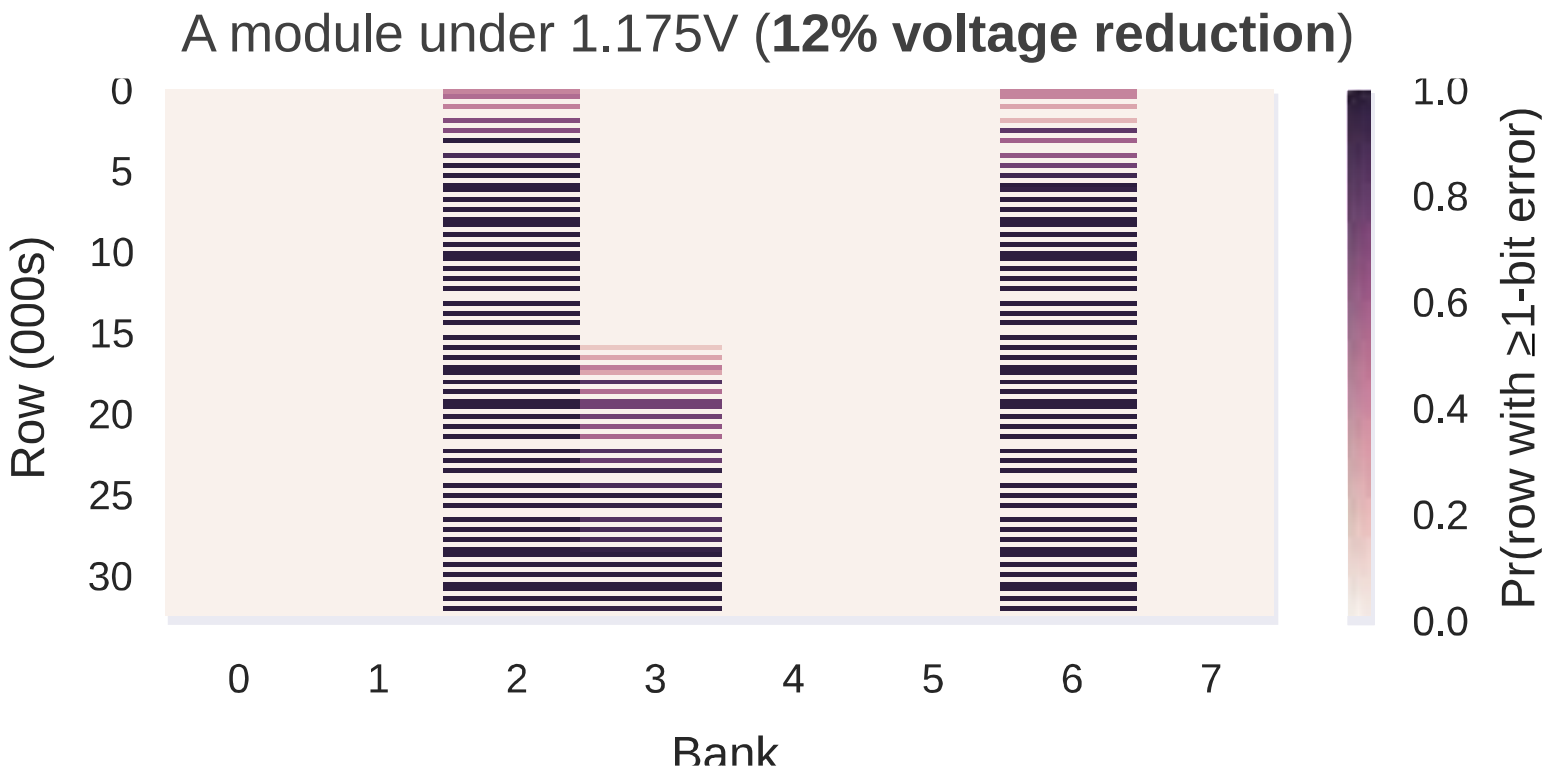
DIMMs Operating at Higher Latency

Measured minimum latency that *does* ***not*** *cause errors* in DRAM modules



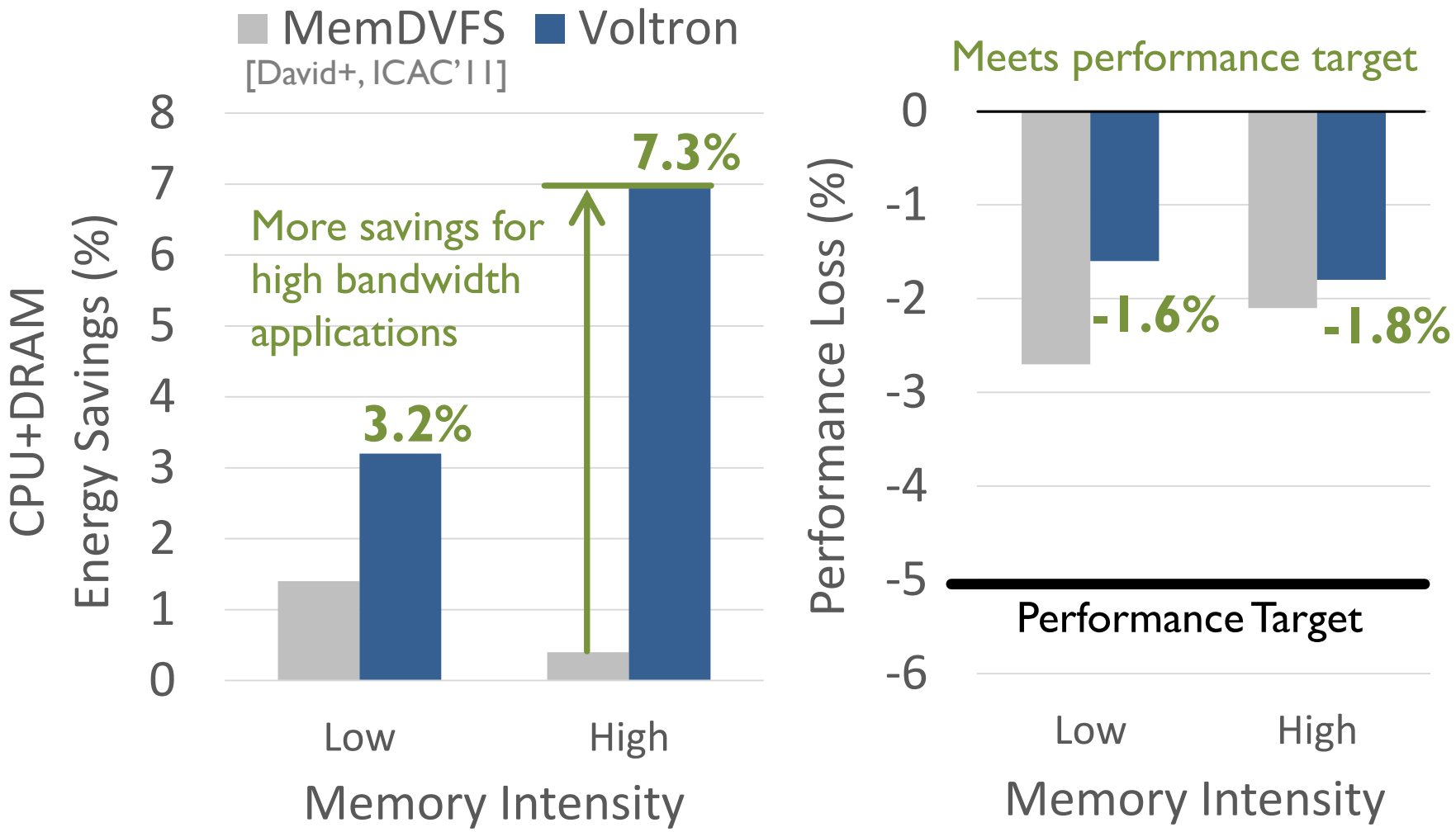
DRAM requires longer latency to access data **without errors** at lower voltage

Spatial Locality of Errors



Errors concentrate in certain regions

Energy Savings with Bounded Performance



Analysis of Latency-Voltage in DRAM Chips

- Kevin Chang, A. Giray Yaglikci, Saugata Ghose, Aditya Agrawal, Niladrish Chatterjee, Abhijith Kashyap, Donghyuk Lee, Mike O'Connor, Hasan Hassan, and Onur Mutlu,
  "Understanding Reduced-Voltage Operation in Modern DRAM Devices: Experimental Characterization, Analysis, and Mechanisms"
  *Proceedings of the ACM International Conference on Measurement and Modeling of Computer Systems (**SIGMETRICS**)*, Urbana-Champaign, IL, USA, June 2017.

Understanding Reduced-Voltage Operation in Modern DRAM Chips: Characterization, Analysis, and Mechanisms

Kevin K. Chang[†] Abdullah Giray Yağlıkçı[†] Saugata Ghose[†] Aditya Agrawal[¶] Niladrish Chatterjee[¶]
Abhijith Kashyap[†] Donghyuk Lee[¶] Mike O'Connor[¶,‡] Hasan Hassan[§] Onur Mutlu[§,†]

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And, What If …

- … we can sacrifice reliability of some data to access it with even lower latency?

The DRAM Latency PUF:

Quickly Evaluating Physical Unclonable Functions by Exploiting the Latency-Reliability Tradeoff in Modern Commodity DRAM Devices

Jeremie S. Kim **Minesh Patel**

Hasan Hassan **Onur Mutlu**

SAFARI

ETH Zürich

Carnegie Mellon

Motivation

- A **PUF** is function that generates a signature **unique** to a given device

- Used in a **Challenge-Response Protocol**
  - Each device generates a unique **PUF response** depending the inputs
  - A trusted server **authenticates** a device if it generates the expected PUF response

DRAM Latency Characterization of 223 LPDDR4 DRAM Devices

- Latency failures come from accessing DRAM with **reduced** timing parameters.

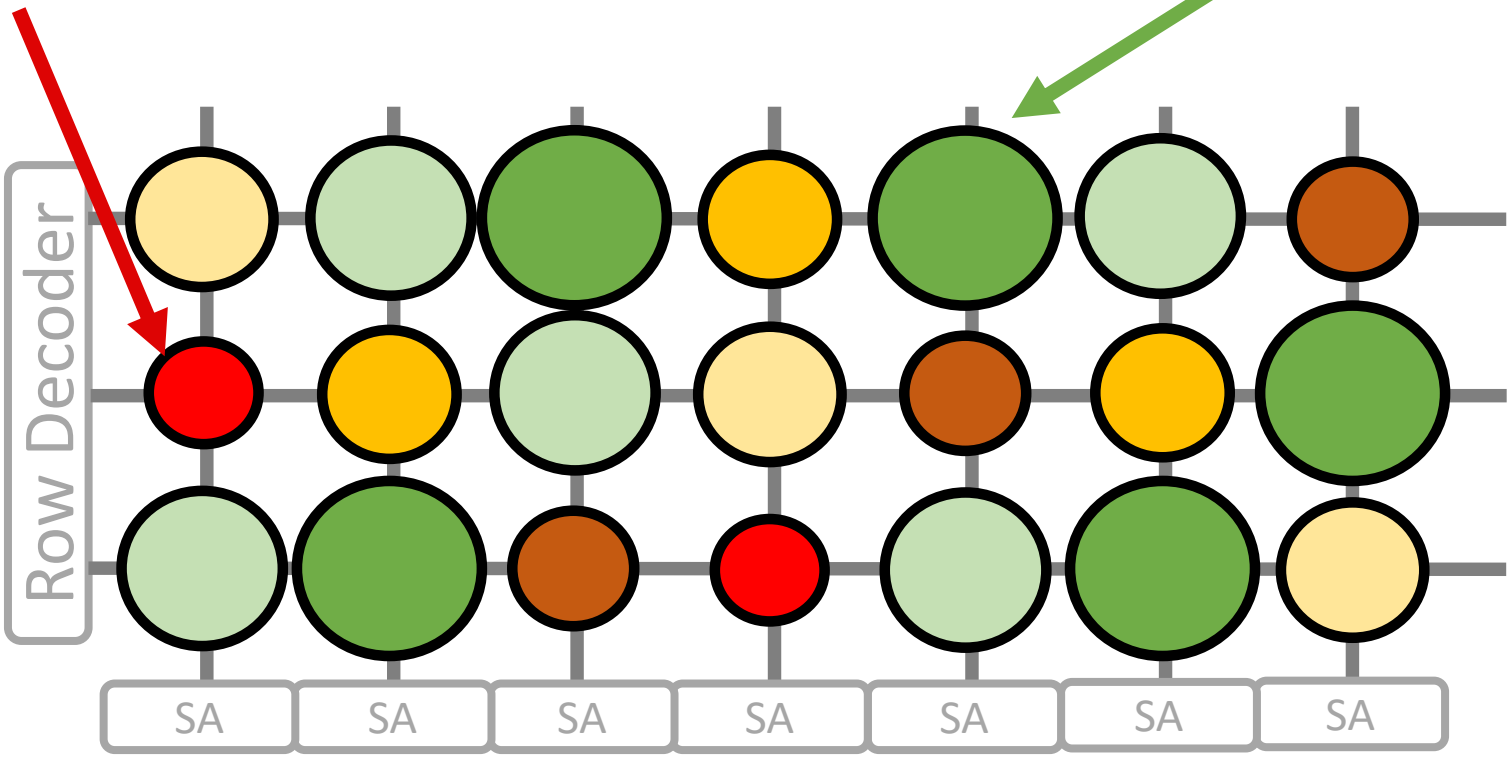
- **Key Observations:**
  1. A cell's **latency failure** probability is determined by **random process variation**

  2. Latency failure patterns are **repeatable and unique to a device**

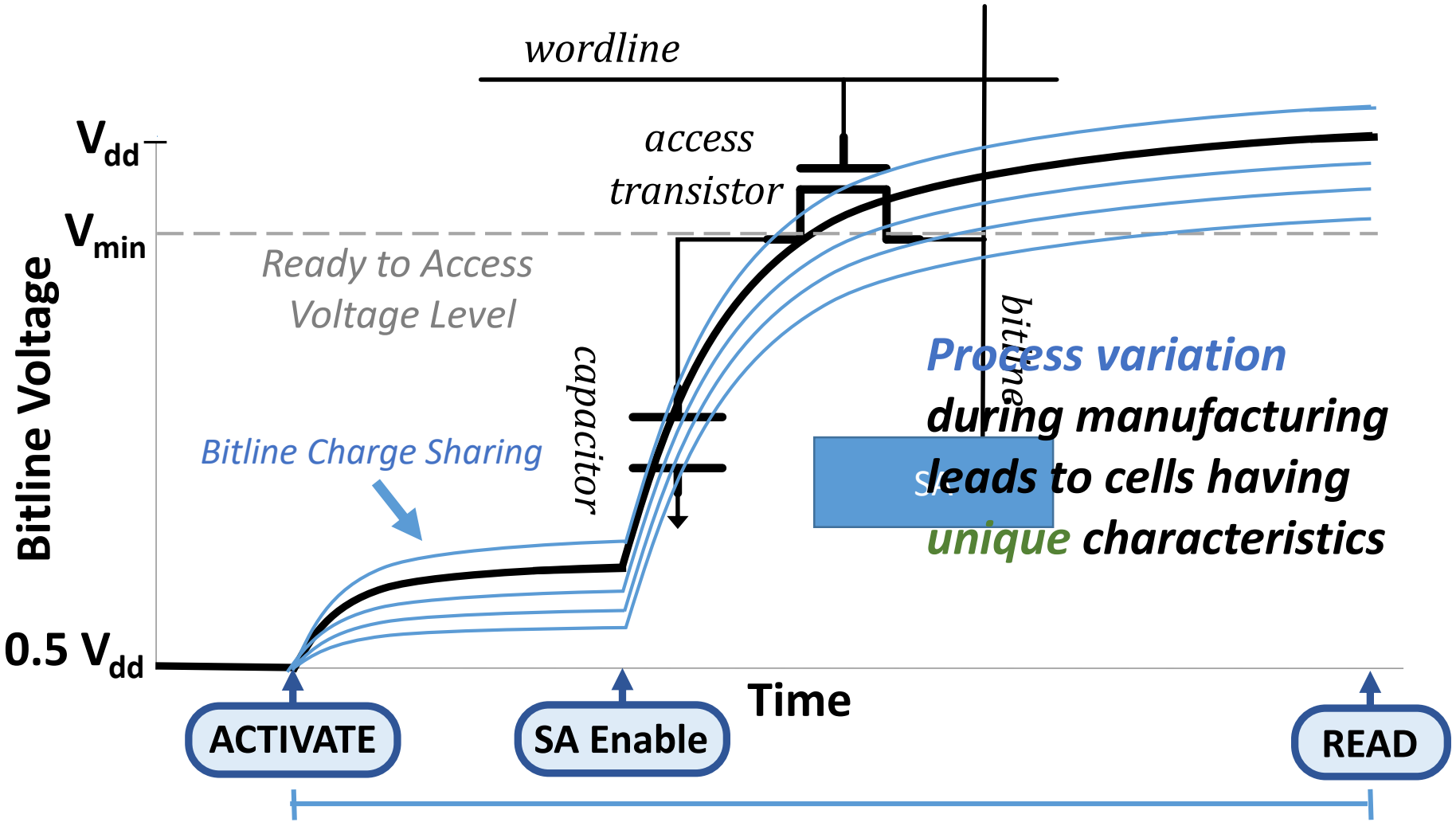
DRAM Latency PUF Key Idea

High % chance to fail with reduced t_{RCD}

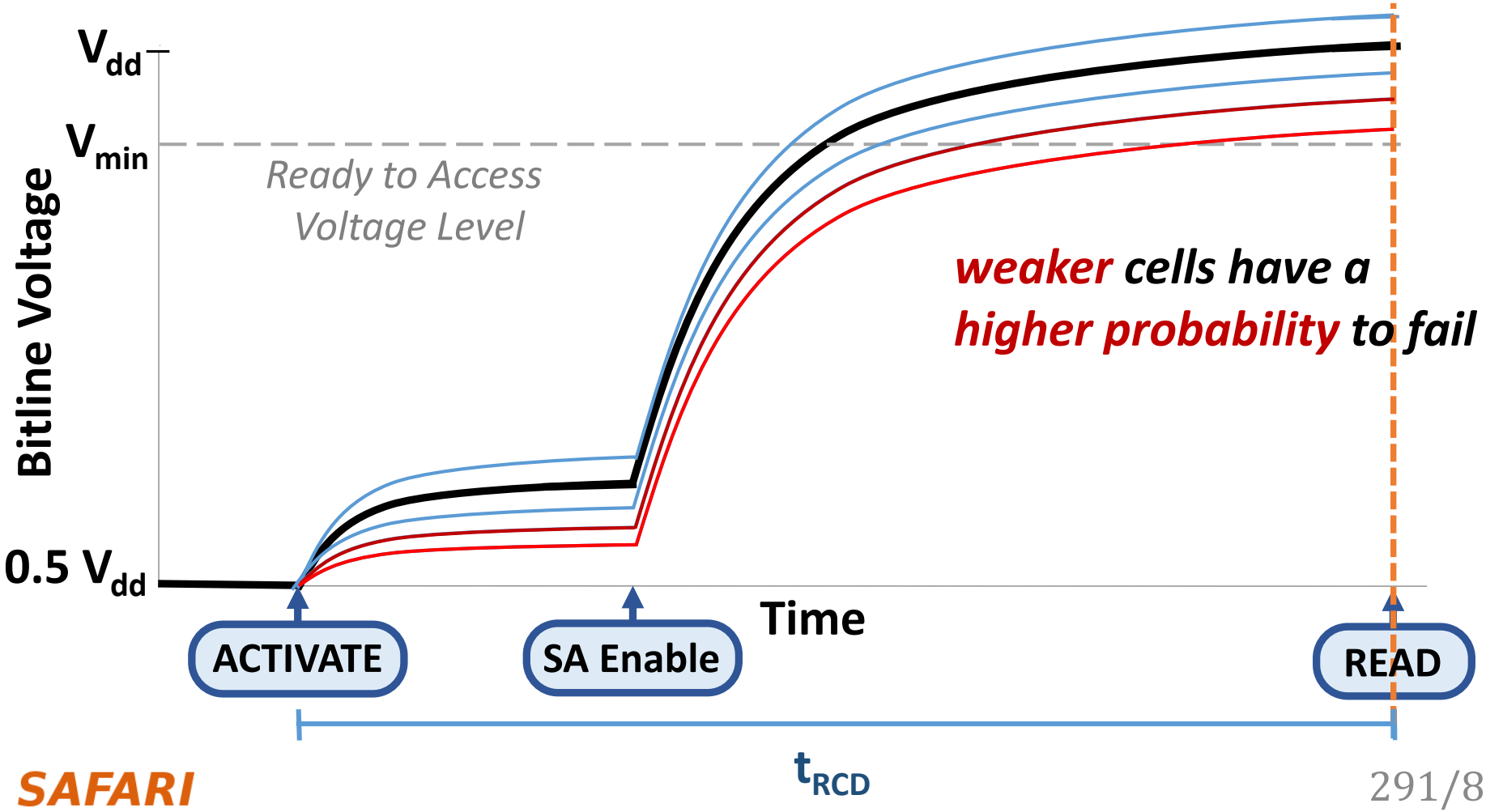
Low % chance to fail with reduced t_{RCD}



DRAM Accesses and Failures



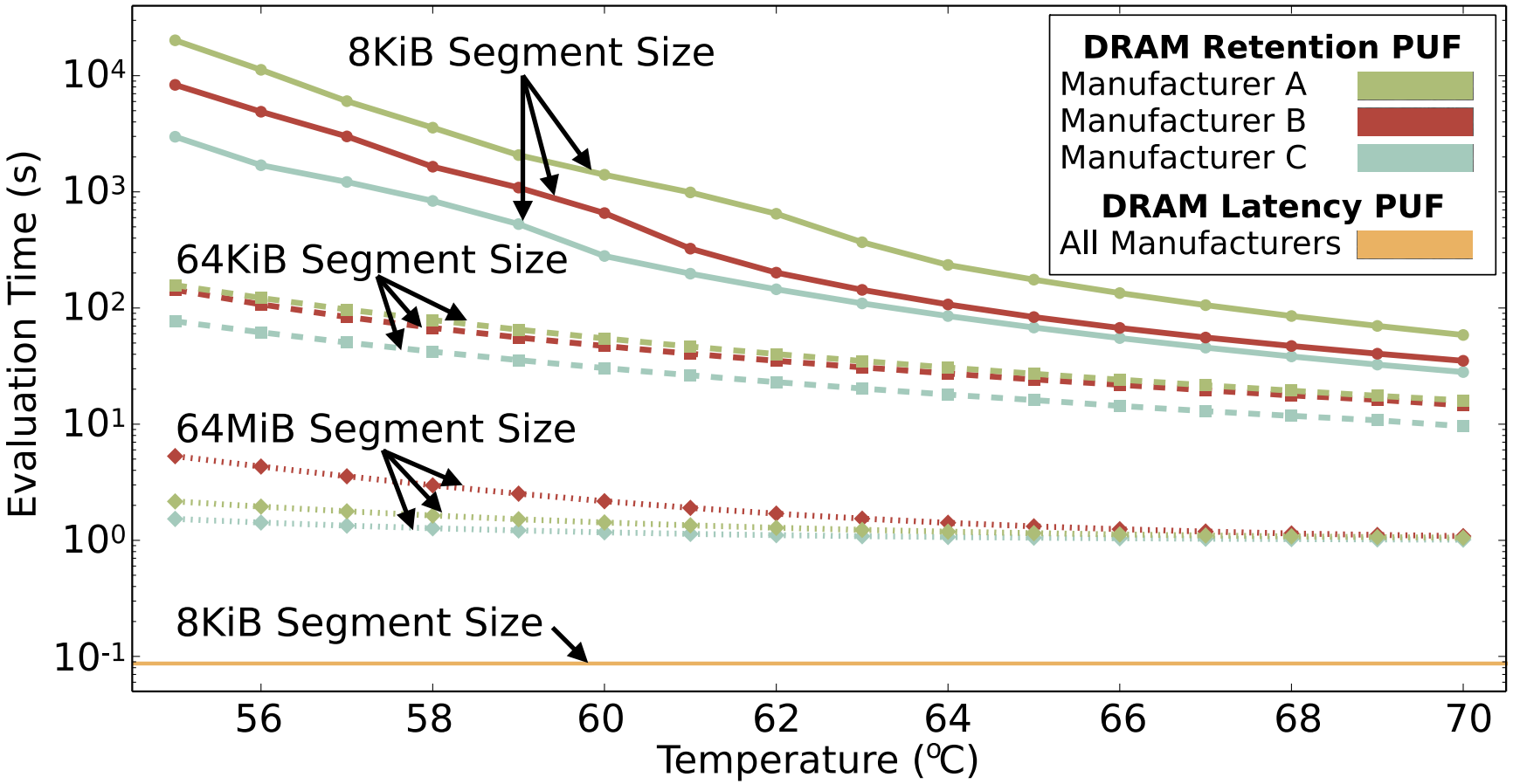
DRAM Accesses and Failures



The DRAM Latency PUF Evaluation

- We generate PUF responses using **latency errors** in a region of DRAM
- The latency error patterns **satisfy PUF requirements**
- The DRAM Latency PUF **generates PUF responses in 88.2ms**

Results



- DL-PUF is **orders of magnitude faster** than prior DRAM PUFs & temperature independent

The DRAM Latency PUF:

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QR Code for the paper

https://people.inf.ethz.ch/omutlu/pub/dram-latency-puf_hpca18.pdf

HPCA 2018

Systems@ETH Zürich

SAFARI

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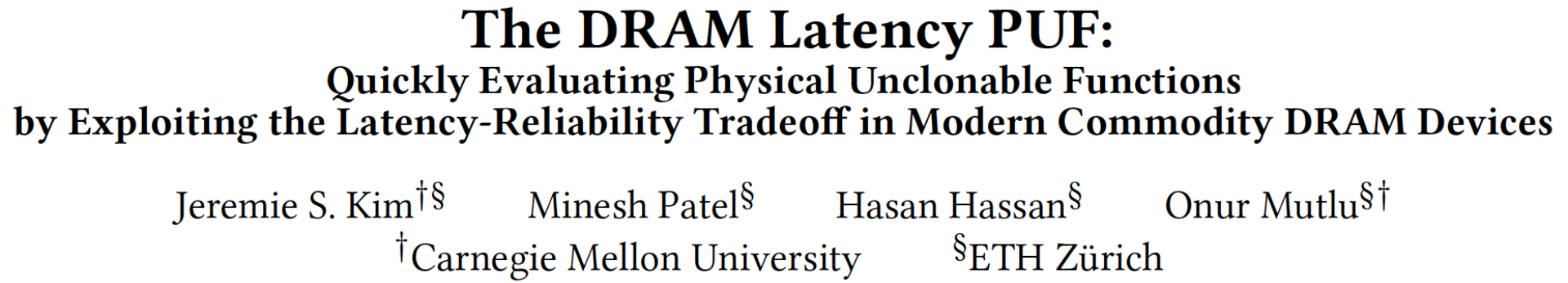
Carnegie Mellon

DRAM Latency PUFs

- Jeremie S. Kim, Minesh Patel, Hasan Hassan, and Onur Mutlu,
  "The DRAM Latency PUF: Quickly Evaluating Physical Unclonable Functions by Exploiting the Latency-Reliability Tradeoff in Modern DRAM Devices"
  *Proceedings of the 24th International Symposium on High-Performance Computer Architecture (**HPCA**)*, Vienna, Austria, February 2018.
  [Lightning Talk Video]
  [Slides (pptx) (pdf)] [Lightning Session Slides (pptx) (pdf)]



The DRAM Latency PUF:
Quickly Evaluating Physical Unclonable Functions by Exploiting the Latency-Reliability Tradeoff in Modern Commodity DRAM Devices

Jeremie S. Kim[†§] Minesh Patel[§] Hasan Hassan[§] Onur Mutlu[§†]
[†]Carnegie Mellon University [§]ETH Zürich

Other Ideas on Reducing DRAM Latency

Reducing Refresh Latency

- Anup Das, Hasan Hassan, and Onur Mutlu,
  "VRL-DRAM: Improving DRAM Performance via Variable Refresh Latency"
  *Proceedings of the 55th Design Automation Conference (**DAC**)*, San Francisco, CA, USA, June 2018.

VRL-DRAM: Improving DRAM Performance via Variable Refresh Latency

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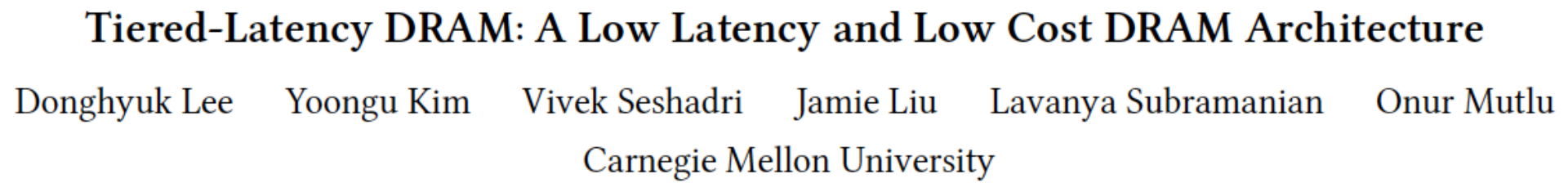
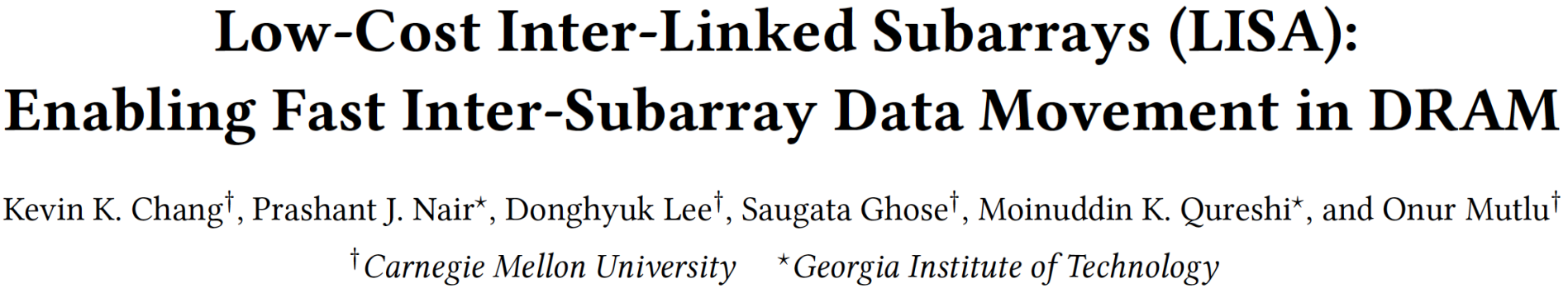
Tiered-Latency DRAM

- Donghyuk Lee, Yoongu Kim, Vivek Seshadri, Jamie Liu, Lavanya Subramanian, and Onur Mutlu,
  "Tiered-Latency DRAM: A Low Latency and Low Cost DRAM Architecture"
  *Proceedings of the 19th International Symposium on High-Performance Computer Architecture (**HPCA**)*, Shenzhen, China, February 2013. Slides (pptx)



LISA: Low-cost Inter-linked Subarrays

- Kevin K. Chang, Prashant J. Nair, Saugata Ghose, Donghyuk Lee, Moinuddin K. Qureshi, and Onur Mutlu,
  "Low-Cost Inter-Linked Subarrays (LISA): Enabling Fast Inter-Subarray Data Movement in DRAM"
  *Proceedings of the 22nd International Symposium on High-Performance Computer Architecture (**HPCA**)*, Barcelona, Spain, March 2016.
  [Slides (pptx) (pdf)]
  [Source Code]



Low-Cost Inter-Linked Subarrays (LISA): Enabling Fast Inter-Subarray Data Movement in DRAM

Kevin K. Chang†, Prashant J. Nair⋆, Donghyuk Lee†, Saugata Ghose†, Moinuddin K. Qureshi⋆, and Onur Mutlu†

†*Carnegie Mellon University* ⋆*Georgia Institute of Technology*

ChargeCache

- Hasan Hassan, Gennady Pekhimenko, Nandita Vijaykumar, Vivek Seshadri, Donghyuk Lee, Oguz Ergin, and Onur Mutlu, **"ChargeCache: Reducing DRAM Latency by Exploiting Row Access Locality"**
  *Proceedings of the 22nd International Symposium on High-Performance Computer Architecture (**HPCA**)*, Barcelona, Spain, March 2016.
  [Slides (pptx) (pdf)]
  [Source Code]

ChargeCache: Reducing DRAM Latency by Exploiting Row Access Locality

Hasan Hassan[†*], Gennady Pekhimenko[†], Nandita Vijaykumar[†]
Vivek Seshadri[†], Donghyuk Lee[†], Oguz Ergin[*], Onur Mutlu[†]

[†] *Carnegie Mellon University* [*] *TOBB University of Economics & Technology*

Challenge and Opportunity for Future

Fundamentally Low-Latency Computing Architectures

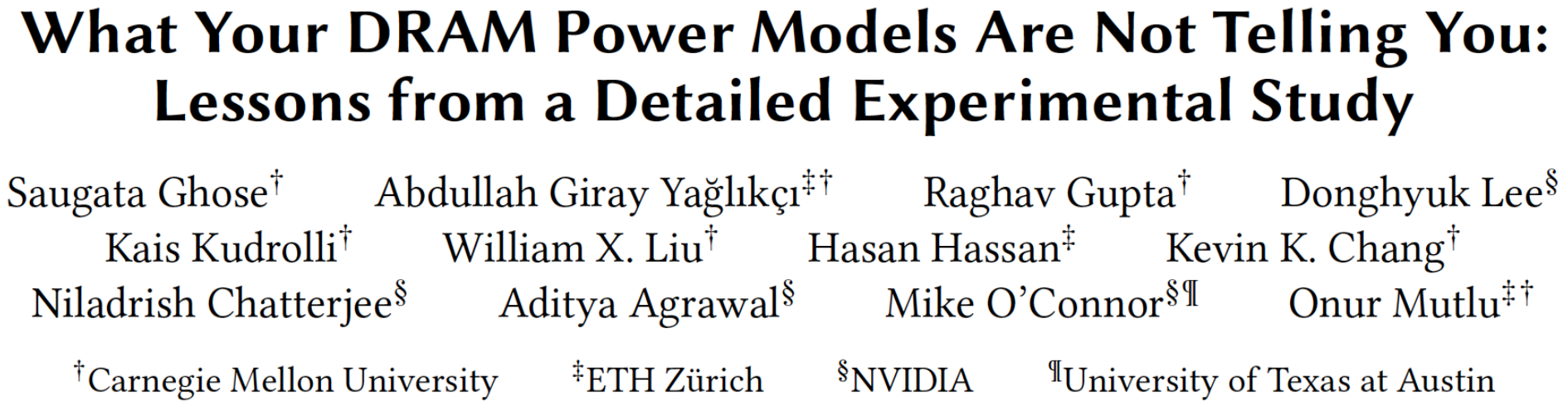
One Important Takeaway

Main Memory Needs Intelligent Controllers

On DRAM Power Consumption

VAMPIRE DRAM Power Model

- Saugata Ghose, A. Giray Yaglikci, Raghav Gupta, Donghyuk Lee, Kais Kudrolli, William X. Liu, Hasan Hassan, Kevin K. Chang, Niladrish Chatterjee, Aditya Agrawal, Mike O'Connor, and Onur Mutlu,
  "What Your DRAM Power Models Are Not Telling You: Lessons from a Detailed Experimental Study"
  *Proceedings of the ACM International Conference on Measurement and Modeling of Computer Systems (**SIGMETRICS**)*, Irvine, CA, USA, June 2018.
  [Abstract]



What Your DRAM Power Models Are Not Telling You: Lessons from a Detailed Experimental Study

Saugata Ghose[†] Abdullah Giray Yağlıkçı[‡†] Raghav Gupta[†] Donghyuk Lee[§]
Kais Kudrolli[†] William X. Liu[†] Hasan Hassan[‡] Kevin K. Chang[†]
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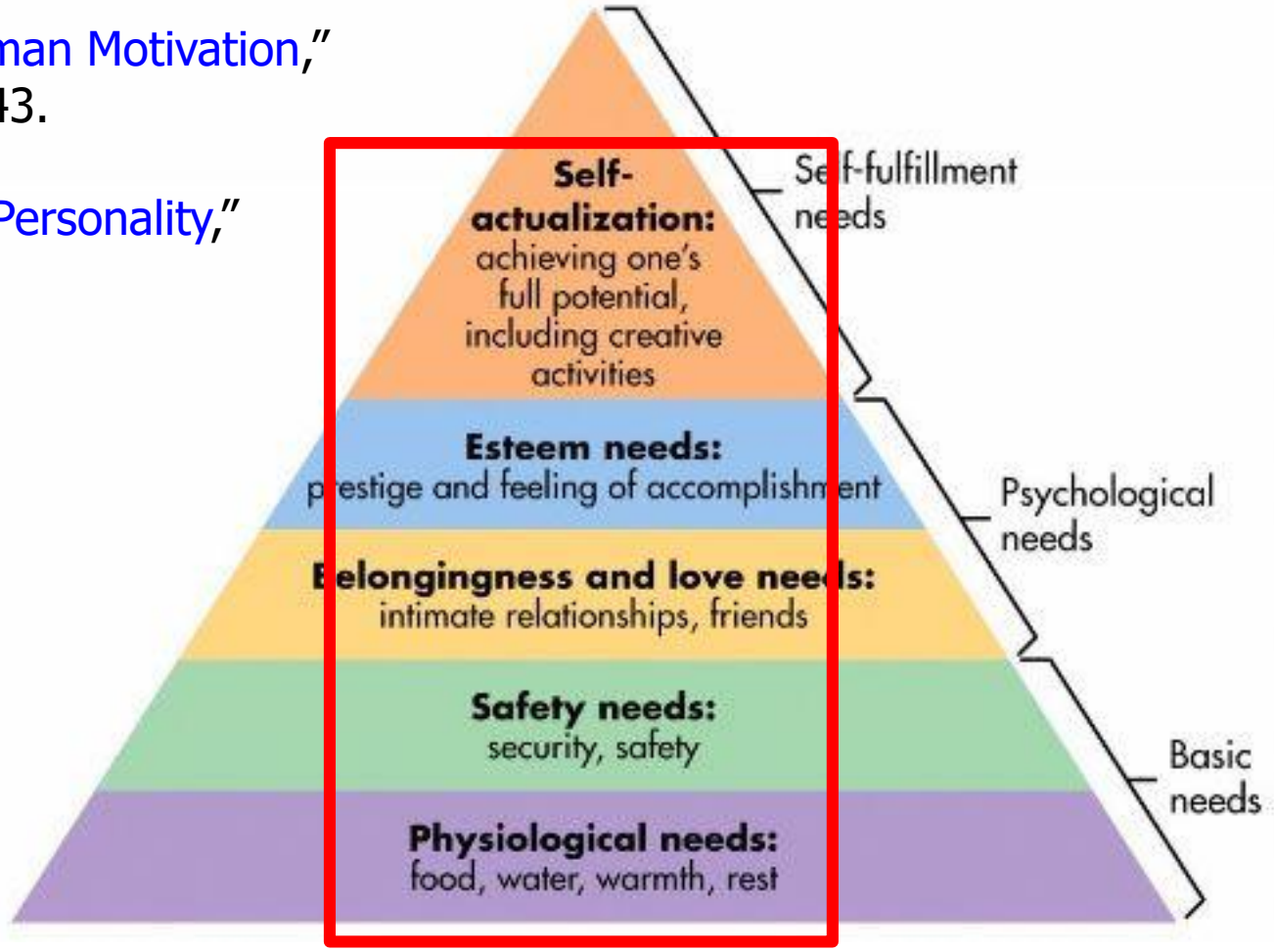
Agenda: Emerging Tech. for Another Time

- Major Trends Affecting Main Memory
- Key Challenges and Solution Directions
  - Robustness: Reliability and Security
  - Energy and Performance: In-Memory Computation
  - Low Latency/Energy and Latency/Energy/Reliability Tradeoffs
  - Scalability and More: Enabling Emerging Technologies
- Solution Principles
- Concluding Remarks

Maslow's Hierarchy of Needs, A Final Time

Maslow, "A Theory of Human Motivation," Psychological Review, 1943.

Maslow, "Motivation and Personality," Book, 1954-1970.



Source: https://www.simplypsychology.org/maslow.html

Challenge and Opportunity for Future

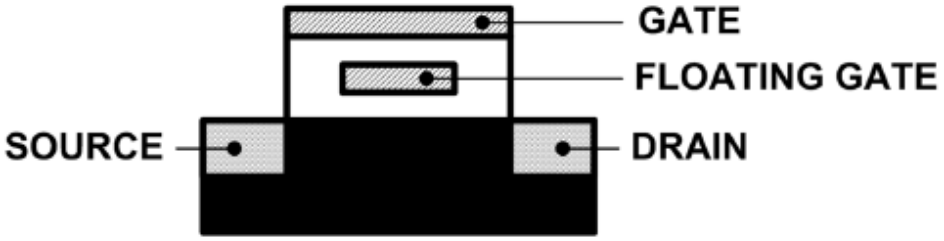
Fundamentally

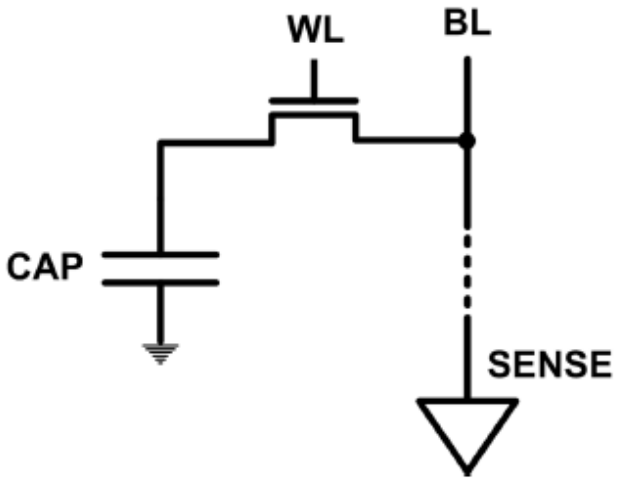
(More) Scalable

Computing Architectures

Scaling Limits of Charge Memory

- Difficult charge placement and control
  - Flash: floating gate charge
  - DRAM: capacitor charge, transistor leakage
- Reliable sensing becomes difficult as charge storage unit size reduces

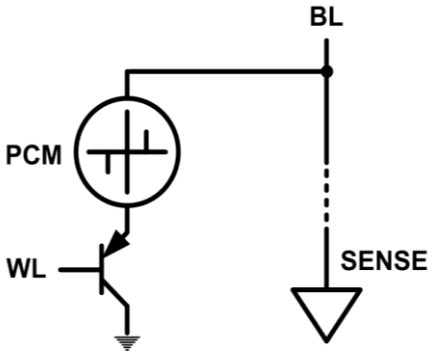




Solution: New Memory Technologies

- Some emerging **resistive** memory technologies seem more scalable than DRAM (and they are non-volatile)

- Example: Phase Change Memory
  - Data stored by changing phase of material
  - Data read by detecting material's resistance
  - Expected to scale to 9nm (2022 [ITRS 2009])
  - Prototyped at 20nm (Raoux+, IBM JRD 2008)
  - Expected to be denser than DRAM: can store multiple bits/cell



- But, emerging technologies have (many) shortcomings
  - Can they be enabled to replace/augment/surpass DRAM?

Charge vs. Resistive Memories

- Charge Memory (e.g., DRAM, Flash)
  - Write data by capturing charge Q
  - Read data by detecting voltage V

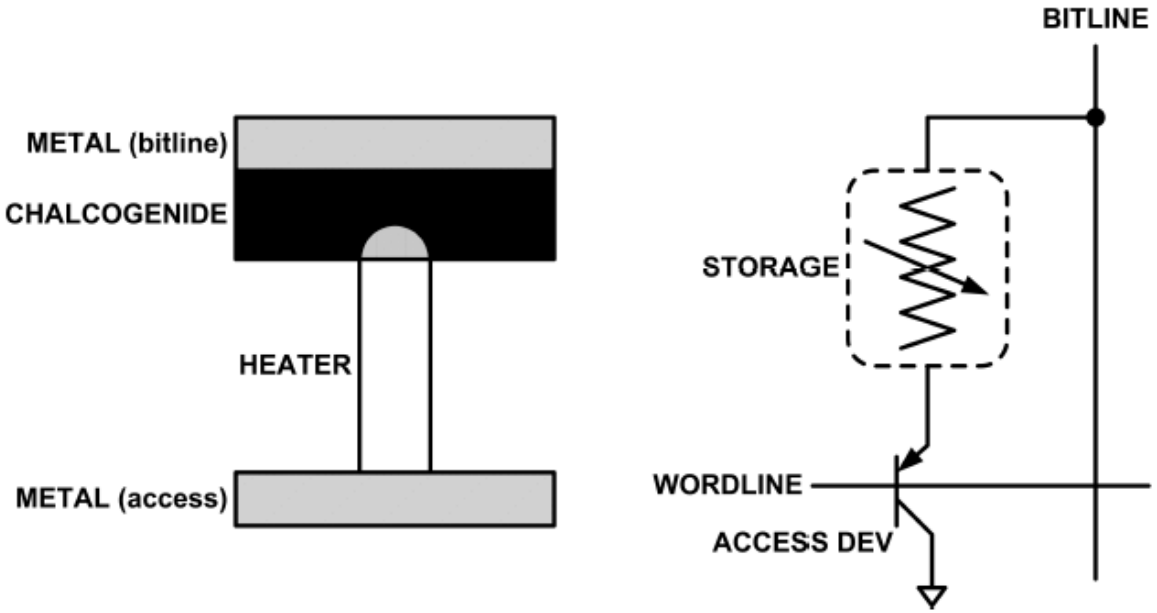
- Resistive Memory (e.g., PCM, STT-MRAM, memristors)
  - Write data by pulsing current dQ/dt
  - Read data by detecting resistance R

Promising Resistive Memory Technologies

- PCM
  - Inject current to change material phase
  - Resistance determined by phase
- STT-MRAM
  - Inject current to change magnet polarity
  - Resistance determined by polarity
- Memristors/RRAM/ReRAM
  - Inject current to change atomic structure
  - Resistance determined by atom distance
- . . .

What is Phase Change Memory?

- Phase change material (chalcogenide glass) exists in two states:
  - Amorphous: Low optical reflexivity and high electrical resistivity
  - Crystalline: High optical reflexivity and low electrical resistivity



PCM is resistive memory: High resistance (0), Low resistance (1)
PCM cell can be switched between states reliably and quickly

Phase Change Memory Properties

- Surveyed prototypes from 2003-2008 (ITRS, IEDM, VLSI, ISSCC)
- Derived PCM parameters for F=90nm

- Lee, Ipek, Mutlu, Burger, "Architecting Phase Change Memory as a Scalable DRAM Alternative," ISCA 2009.
- Lee et al., "Phase Change Technology and the Future of Main Memory," IEEE Micro Top Picks 2010.

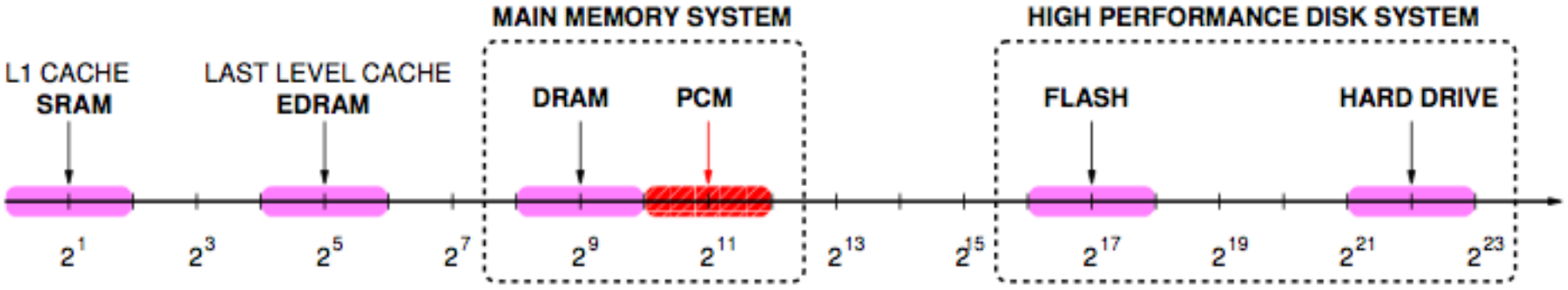
Table 1. Technology survey.

Parameter*	Published prototype									
	Horri[6]	Ahn[12]	Bedeschi[13]	Oh[14]	Pellizer[15]	Chen[5]	Kang[16]	Bedeschi[9]	Lee[10]	Lee[2]
Year	2003	2004	2004	2005	2006	2006	2006	2008	2008	**
Process, F (nm)	**	120	180	120	90	**	100	90	90	90
Array size (Mbytes)	**	64	8	64	**	**	256	256	512	**
Material	GST, N-d	GST, N-d	GST	GST	GST	GS, N-d	GST	GST	GST	GST, N-d
Cell size (μm^2)	**	0.290	0.290	**	0.097	60 nm^2	0.166	0.097	0.047	0.065 to 0.097
Cell size, F^2	**	20.1	9.0	**	12.0	**	16.6	12.0	5.8	9.0 to 12.0
Access device	**	**	BJT	FET	BJT	**	FET	BJT	Diode	BJT
Read time (ns)	**	70	48	68	**	**	62	**	55	48
Read current (μA)	**	**	40	**	**	**	**	**	**	40
Read voltage (V)	**	3.0	1.0	1.8	1.6	**	1.8	**	1.8	1.0
Read power (μW)	**	**	40	**	**	**	**	**	**	40
Read energy (pJ)	**	**	2.0	**	**	**	**	**	**	2.0
Set time (ns)	100	150	150	180	**	80	300	**	400	150
Set current (μA)	200	**	300	200	**	55	**	**	**	150
Set voltage (V)	**	**	2.0	**	**	1.25	**	**	**	1.2
Set power (μW)	**	**	300	**	**	34.4	**	**	**	90
Set energy (pJ)	**	**	45	**	**	2.8	**	**	**	13.5
Reset time (ns)	50	10	40	10	**	60	50	**	50	40
Reset current (μA)	600	600	600	600	400	90	600	300	600	300
Reset voltage (V)	**	**	2.7	**	1.8	1.6	**	1.6	**	1.6
Reset power (μW)	**	**	1620	**	**	80.4	**	**	**	480
Reset energy (pJ)	**	**	64.8	**	**	4.8	**	**	**	19.2
Write endurance (MLC)	10^7	10^9	10^6	**	10^8	10^4	**	10^5	10^5	10^8

* BJT: bipolar junction transistor; FET: field-effect transistor; GST: $Ge_2Sb_2Te_5$; MLC: multilevel cells; N-d: nitrogen doped.
** This information is not available in the publication cited.

Phase Change Memory Properties: Latency

- Latency comparable to, but slower than DRAM



Typical Access Latency (in terms of processor cycles for a 4 GHz processor)

- Read Latency
  - 50ns: 4x DRAM, 10^{-3}x NAND Flash
- Write Latency
  - 150ns: 12x DRAM
- Write Bandwidth
  - 5-10 MB/s: 0.1x DRAM, 1x NAND Flash

Qureshi+, "Scalable high performance main memory system using phase-change memory technology," ISCA 2009.

Phase Change Memory Properties

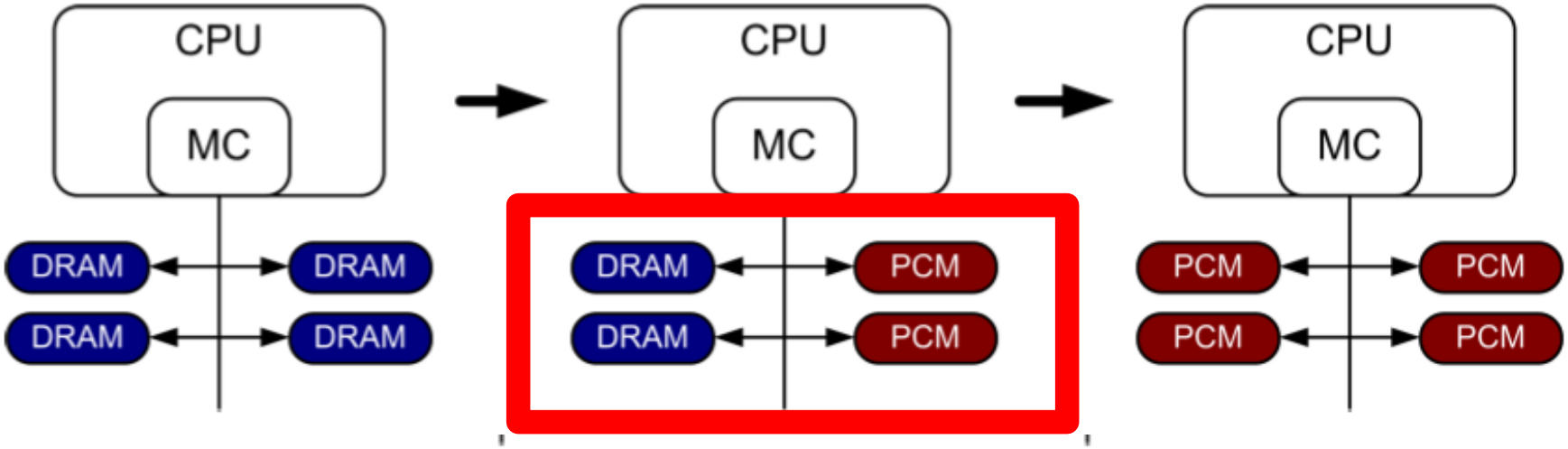
- Dynamic Energy
  - 40 uA Rd, 150 uA Wr
  - 2-43x DRAM, 1x NAND Flash
- Endurance
  - Writes induce phase change at 650C
  - Contacts degrade from thermal expansion/contraction
  - 10^8 writes per cell
  - 10^{-8}x DRAM, 10^3x NAND Flash
- Cell Size
  - 9-12F^2 using BJT, single-level cells
  - 1.5x DRAM, 2-3x NAND (will scale with feature size, MLC)

Phase Change Memory: Pros and Cons

- Pros over DRAM
  - Better technology scaling (capacity and cost)
  - Non volatile → Persistent
  - Low idle power (no refresh)
- Cons
  - Higher latencies: ~4-15x DRAM (especially write)
  - Higher active energy: ~2-50x DRAM (especially write)
  - Lower endurance (a cell dies after ~10^8 writes)
  - Reliability issues (resistance drift)
- Challenges in enabling PCM as DRAM replacement/helper:
  - Mitigate PCM shortcomings
  - Find the right way to place PCM in the system

PCM-based Main Memory (I)

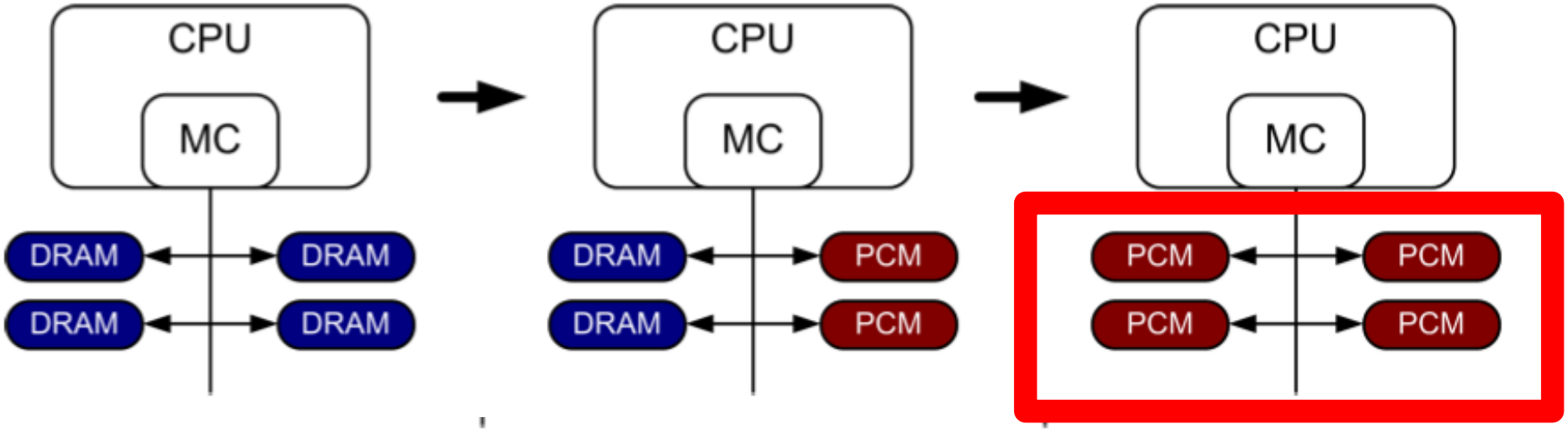
- How should PCM-based (main) memory be organized?



- Hybrid PCM+DRAM [Qureshi+ ISCA'09, Dhiman+ DAC'09]:
  - How to partition/migrate data between PCM and DRAM

PCM-based Main Memory (II)

- How should PCM-based (main) memory be organized?



- Pure PCM main memory [Lee et al., ISCA'09, Top Picks'10]:
  - How to redesign entire hierarchy (and cores) to overcome PCM shortcomings

An Initial Study: Replace DRAM with PCM

- Lee, Ipek, Mutlu, Burger, "Architecting Phase Change Memory as a Scalable DRAM Alternative," ISCA 2009.
  - Surveyed prototypes from 2003-2008 (e.g. IEDM, VLSI, ISSCC)
  - Derived "average" PCM parameters for F=90nm

Density

- 9 - 12F^2 using BJT
- 1.5× DRAM

Latency

- 50ns Rd, 150ns Wr
- 4×, 12× DRAM

Endurance

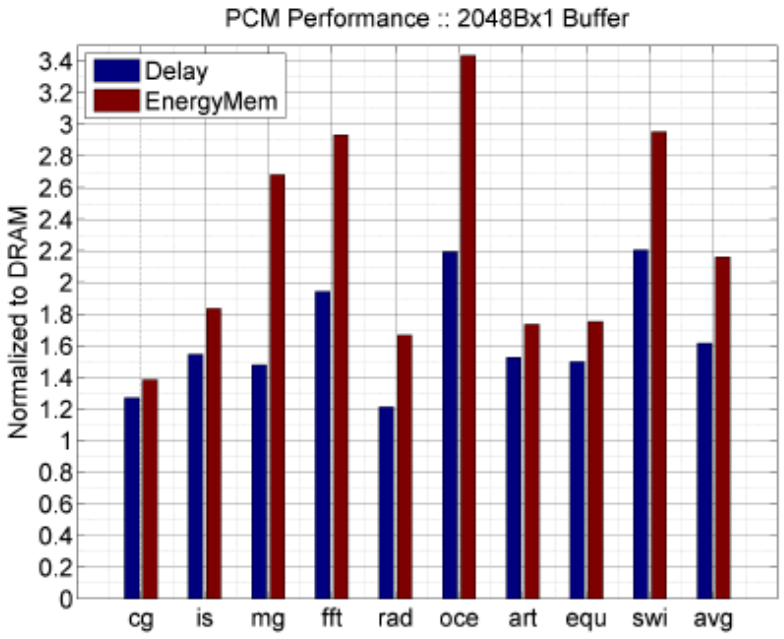
- 1E+08 writes
- 1E-08× DRAM

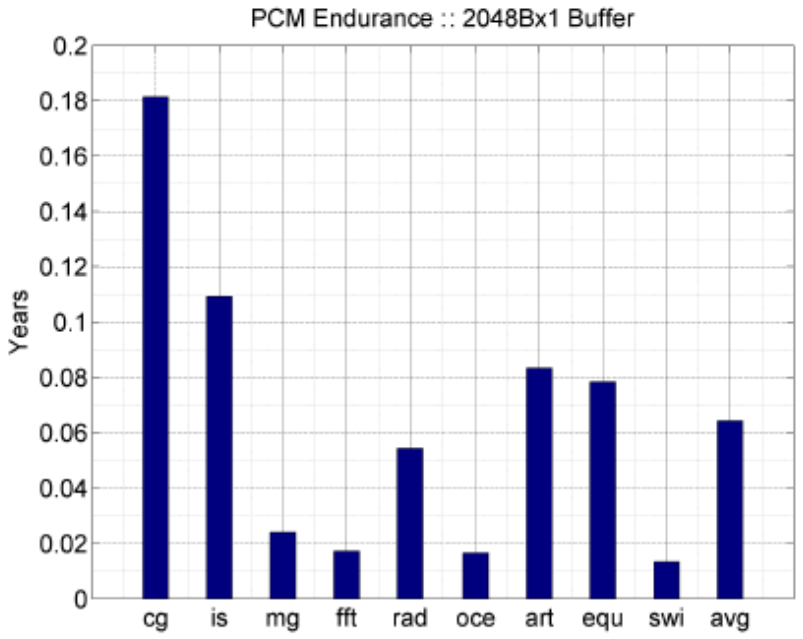
Energy

- 40μA Rd, 150μA Wr
- 2×, 43× DRAM

Results: Naïve Replacement of DRAM with PCM

- Replace DRAM with PCM in a 4-core, 4MB L2 system
- PCM organized the same as DRAM: row buffers, banks, peripherals
- 1.6x delay, 2.2x energy, 500-hour average lifetime



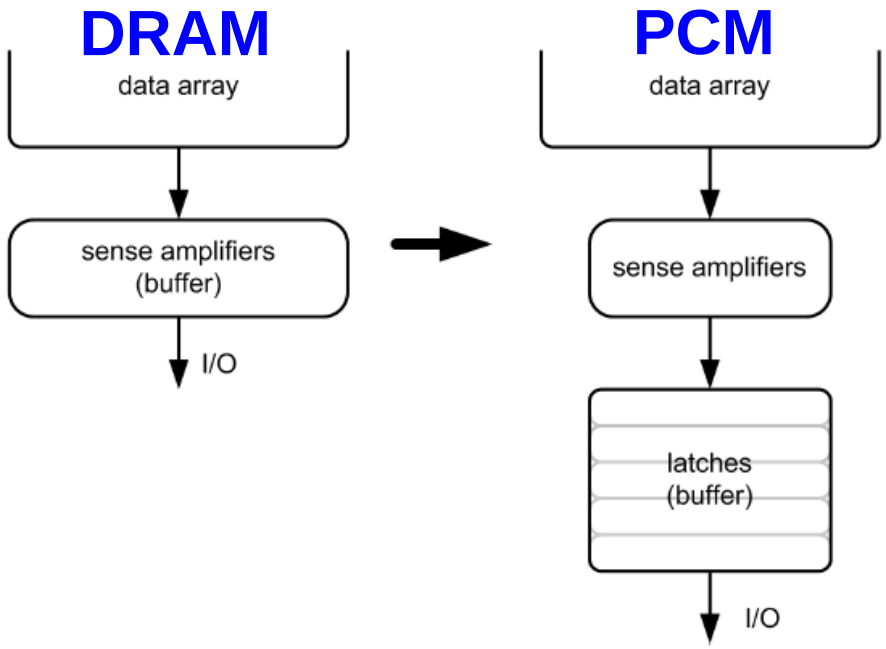


- Lee, Ipek, Mutlu, Burger, "Architecting Phase Change Memory as a Scalable DRAM Alternative," ISCA 2009.

Architecting PCM to Mitigate Shortcomings

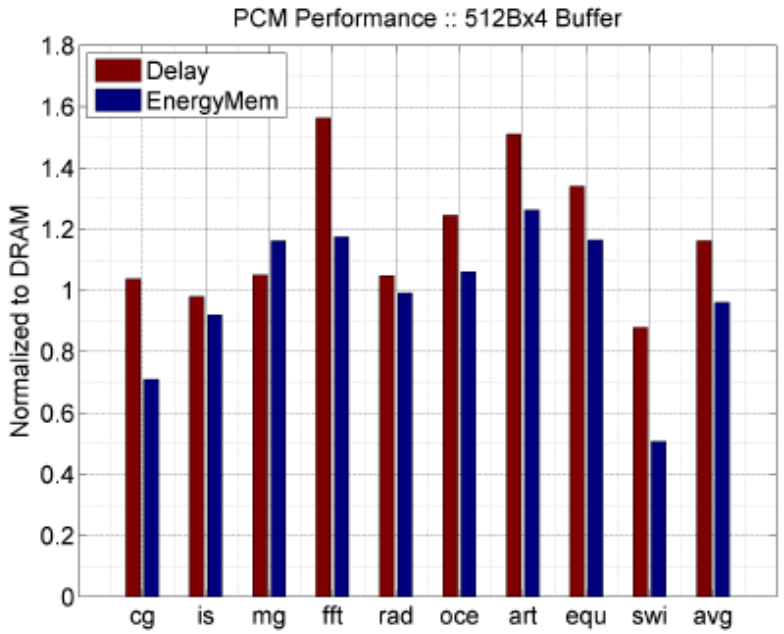
- Idea 1: Use multiple narrow row buffers in each PCM chip
  → Reduces array reads/writes → better endurance, latency, energy

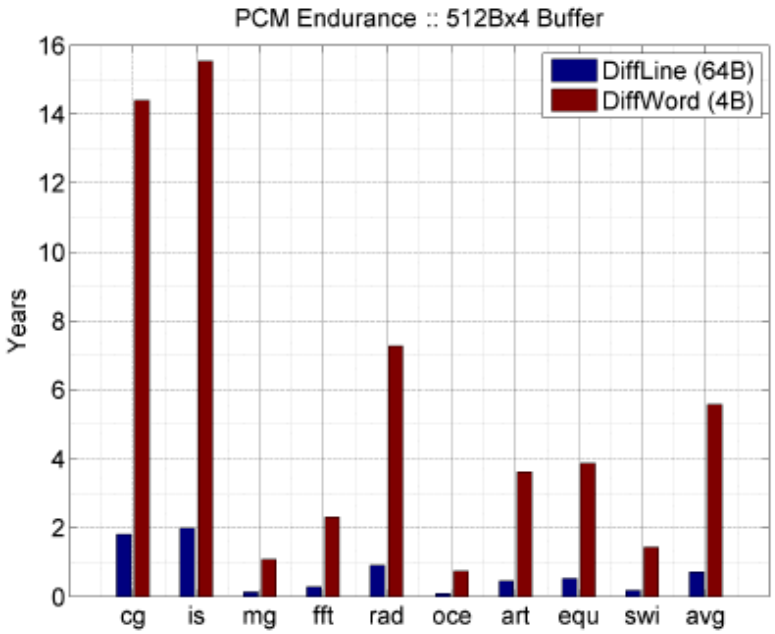
- Idea 2: Write into array at cache block or word granularity
  → Reduces unnecessary wear



Results: Architected PCM as Main Memory

- 1.2x delay, 1.0x energy, 5.6-year average lifetime
- Scaling improves energy, endurance, density

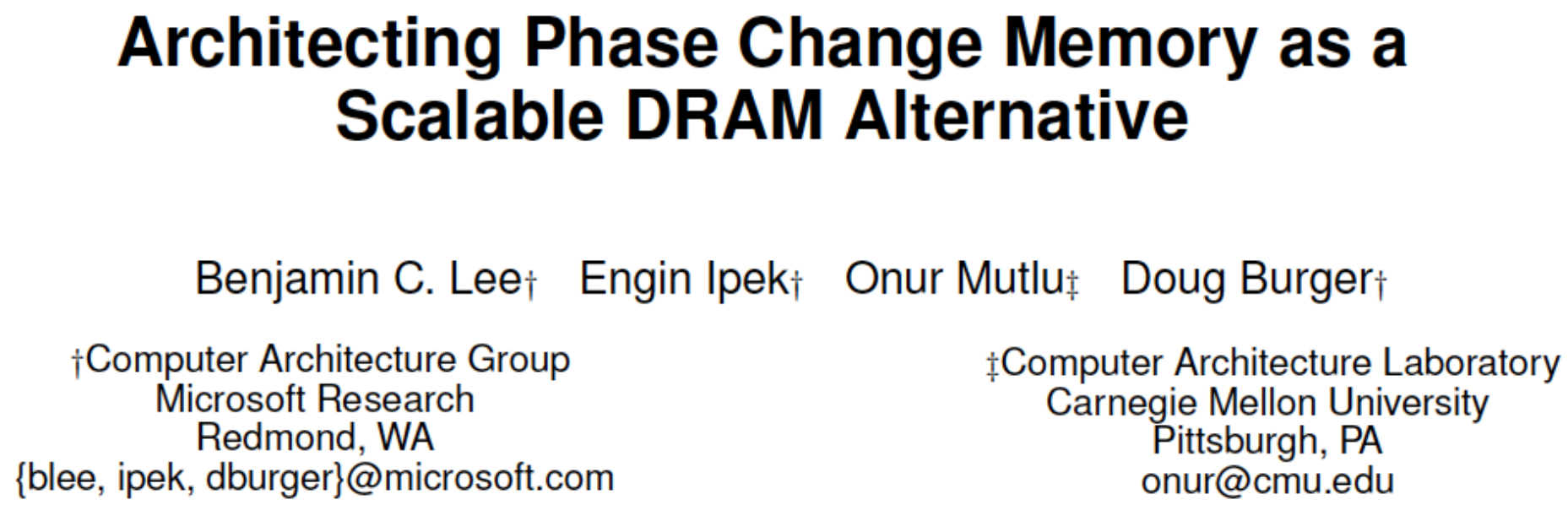




- Caveat 1: Worst-case lifetime is much shorter (no guarantees)
- Caveat 2: Intensive applications see large performance and energy hits
- Caveat 3: Optimistic PCM parameters?

More on PCM as Main Memory (I)

- Benjamin C. Lee, Engin Ipek, Onur Mutlu, and Doug Burger, **"Architecting Phase Change Memory as a Scalable DRAM Alternative"**
  *Proceedings of the 36th International Symposium on Computer Architecture (**ISCA**)*, pages 2-13, Austin, TX, June 2009. Slides (pdf)



Architecting Phase Change Memory as a Scalable DRAM Alternative

Benjamin C. Lee† Engin Ipek† Onur Mutlu‡ Doug Burger†

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{blee, ipek, dburger}@microsoft.com

‡Computer Architecture Laboratory
Carnegie Mellon University
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More on PCM as Main Memory (II)

- Benjamin C. Lee, Ping Zhou, Jun Yang, Youtao Zhang, Bo Zhao, Engin Ipek, Onur Mutlu, and Doug Burger, **"Phase Change Technology and the Future of Main Memory"** *IEEE Micro, Special Issue: Micro's Top Picks from 2009 Computer Architecture Conferences (**MICRO TOP PICKS**)*, Vol. 30, No. 1, pages 60-70, January/February 2010.

PHASE-CHANGE TECHNOLOGY AND THE FUTURE OF MAIN MEMORY

More on PCM as Main Memory (III)

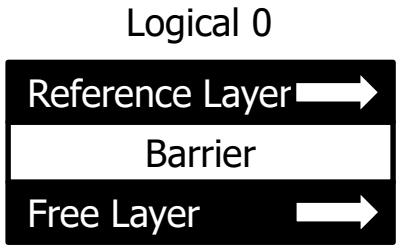
- HanBin Yoon, Justin Meza, Naveen Muralimanohar, Norman P. Jouppi, and Onur Mutlu,
  "Efficient Data Mapping and Buffering Techniques for Multi-Level Cell Phase-Change Memories"
  *ACM Transactions on Architecture and Code Optimization (**TACO**)*, Vol. 11, No. 4, December 2014. [Slides (ppt) (pdf)]
  Presented at the 10th HiPEAC Conference in 2015. [Slides (ppt) (pdf)]

Efficient Data Mapping and Buffering Techniques for Multilevel Cell Phase-Change Memories

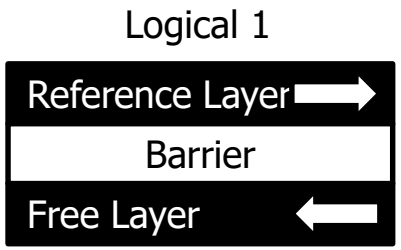
HANBIN YOON* and JUSTIN MEZA, Carnegie Mellon University
NAVEEN MURALIMANOHAR, Hewlett-Packard Labs
NORMAN P. JOUPPI**, Google Inc.
ONUR MUTLU, Carnegie Mellon University

STT-MRAM as Main Memory

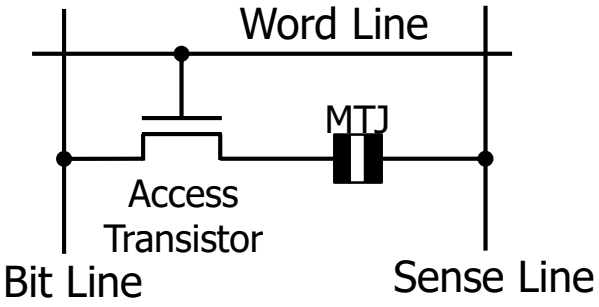
- Magnetic Tunnel Junction (MTJ) device
  - Reference layer: Fixed magnetic orientation
  - Free layer: Parallel or anti-parallel



- Magnetic orientation of the free layer determines logical state of device
  - High vs. low resistance



- Write: Push large current through MTJ to change orientation of free layer
- Read: Sense current flow



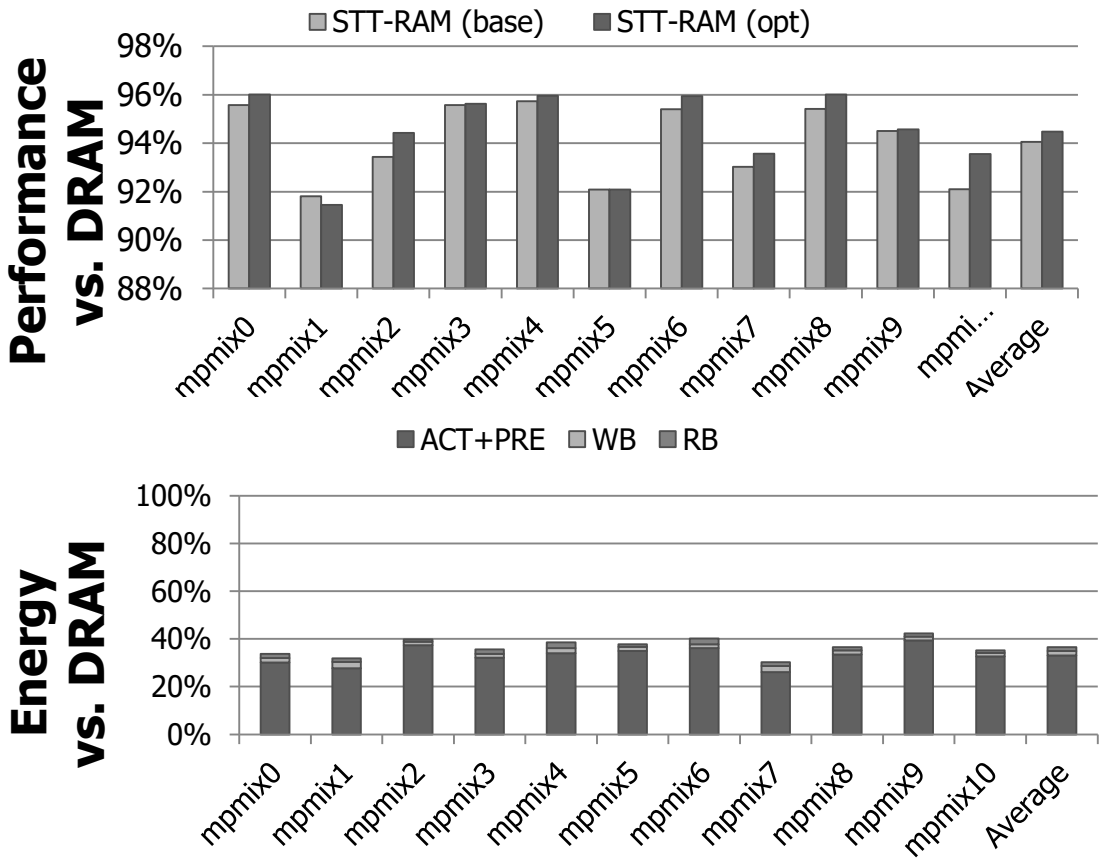
- Kultursay et al., "Evaluating STT-RAM as an Energy-Efficient Main Memory Alternative," ISPASS 2013.

STT-MRAM: Pros and Cons

- Pros over DRAM
  - Better technology scaling (capacity and cost)
  - Non volatile → Persistent
  - Low idle power (no refresh)
- Cons
  - Higher write latency
  - Higher write energy
  - Poor density (currently)
  - Reliability?
- Another level of freedom
  - Can trade off non-volatility for lower write latency/energy (by reducing the size of the MTJ)

Architected STT-MRAM as Main Memory

- 4-core, 4GB main memory, multiprogrammed workloads
- ~6% performance loss, ~60% energy savings vs. DRAM



Kultursay+, "Evaluating STT-RAM as an Energy-Efficient Main Memory Alternative," ISPASS 2013.

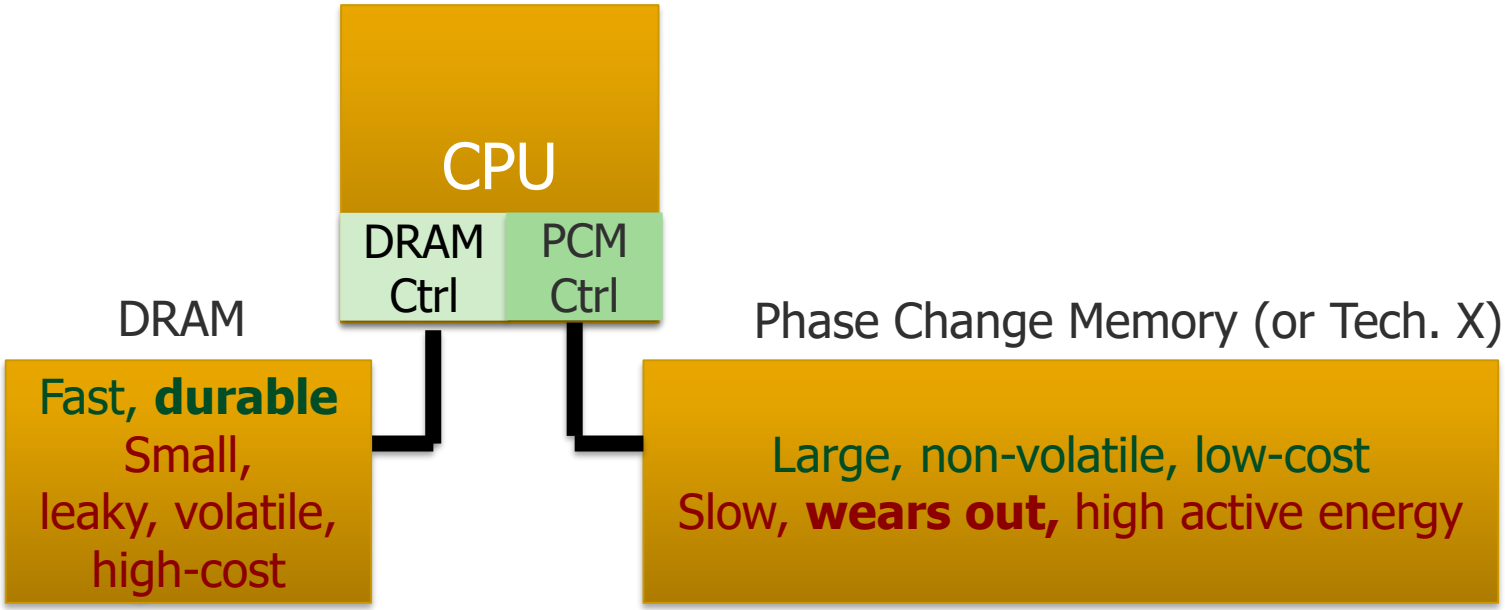
More on STT-MRAM as Main Memory

- Emre Kultursay, Mahmut Kandemir, Anand Sivasubramaniam, and Onur Mutlu,
  "Evaluating STT-RAM as an Energy-Efficient Main Memory Alternative"
  Proceedings of the 2013 IEEE International Symposium on Performance Analysis of Systems and Software (***ISPASS***), Austin, TX, April 2013. Slides (pptx) (pdf)

Evaluating STT-RAM as an Energy-Efficient Main Memory Alternative

Emre Kültürsay*, Mahmut Kandemir*, Anand Sivasubramaniam*, and Onur Mutlu†
*The Pennsylvania State University and †Carnegie Mellon University

A More Viable Approach: Hybrid Memory Systems



Hardware/software manage data allocation and movement
to achieve the best of multiple technologies

Meza+, "Enabling Efficient and Scalable Hybrid Memories," IEEE Comp. Arch. Letters, 2012.

Yoon+, "Row Buffer Locality Aware Caching Policies for Hybrid Memories," ICCD 2012 Best Paper Award.

Challenge and Opportunity

Providing the Best of Multiple Metrics

with

Multiple Memory Technologies

Challenge and Opportunity

Heterogeneous,
Configurable,
Programmable
Memory Systems

Hybrid Memory Systems: Issues

- Cache vs. Main Memory
- Granularity of Data Move/Manage-ment: Fine or Coarse
- Hardware vs. Software vs. HW/SW Cooperative
- When to migrate data?
- How to design a scalable and efficient large cache?
- …

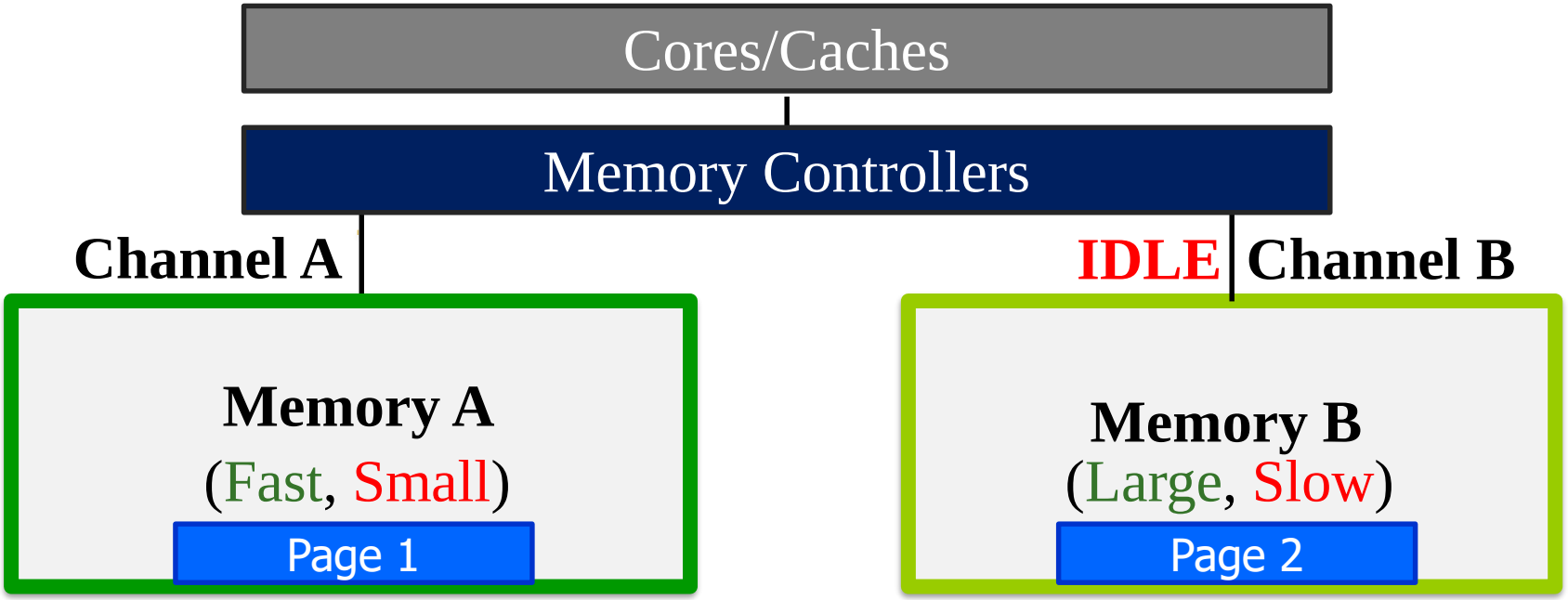
One Option: DRAM as a Cache for PCM

- PCM is main memory; DRAM caches memory rows/blocks
  - Benefits: Reduced latency on DRAM cache hit; write filtering
- Memory controller hardware manages the DRAM cache
  - Benefit: Eliminates system software overhead

- Three issues:
  - What data should be placed in DRAM versus kept in PCM?
  - What is the granularity of data movement?
  - How to design a low-cost hardware-managed DRAM cache?

- Two idea directions:
  - Locality-aware data placement **[Yoon+ , ICCD 2012]**
  - Cheap tag stores and dynamic granularity **[Meza+, IEEE CAL 2012]**

Data Placement in Hybrid Memory



Which memory do we place each page in, to **maximize system performance**?

- Memory A is fast, but small
- Load should be balanced on both channels?
- Page migrations have performance and energy overhead

Data Placement Between DRAM and PCM

- Idea: Characterize data access patterns and guide data placement in hybrid memory
- Streaming accesses: As fast in PCM as in DRAM
- Random accesses: Much faster in DRAM
- Idea: Place random access data with some reuse in DRAM; streaming data in PCM
- Yoon+, "Row Buffer Locality-Aware Data Placement in Hybrid Memories," ICCD 2012 Best Paper Award.

More on Hybrid Memory Data Placement

- HanBin Yoon, Justin Meza, Rachata Ausavarungnirun, Rachael Harding, and Onur Mutlu,
  "Row Buffer Locality Aware Caching Policies for Hybrid Memories"
  *Proceedings of the 30th IEEE International Conference on Computer Design (**ICCD**)*, Montreal, Quebec, Canada, September 2012. Slides (pptx) (pdf)

Row Buffer Locality Aware Caching Policies for Hybrid Memories

HanBin Yoon, Justin Meza, Rachata Ausavarungnirun, Rachael A. Harding and Onur Mutlu
Carnegie Mellon University
{hanbinyoon,meza,rachata,onur}@cmu.edu, rhardin@mit.edu

Utility-Based Hybrid Memory Management

- Yang Li, Saugata Ghose, Jongmoo Choi, Jin Sun, Hui Wang, and Onur Mutlu,
  "Utility-Based Hybrid Memory Management"
  Proceedings of the 19th IEEE Cluster Conference (***CLUSTER***),
  Honolulu, Hawaii, USA, September 2017.
  [Slides (pptx) (pdf)]

Utility-Based Hybrid Memory Management

Yang Li† Saugata Ghose† Jongmoo Choi‡ Jin Sun† Hui Wang⋆ Onur Mutlu†‡
†*Carnegie Mellon University* ‡*Dankook University* ⋆*Beihang University* †*ETH Zürich*

On Large DRAM Cache Design

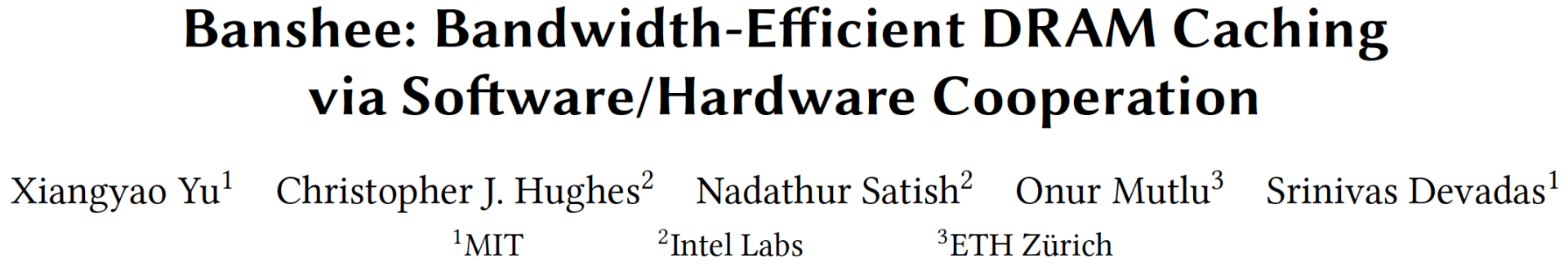
- Justin Meza, Jichuan Chang, HanBin Yoon, Onur Mutlu, and Parthasarathy Ranganathan,
  "Enabling Efficient and Scalable Hybrid Memories Using Fine-Granularity DRAM Cache Management"
  IEEE Computer Architecture Letters (***CAL***), February 2012.

Enabling Efficient and Scalable Hybrid Memories Using Fine-Granularity DRAM Cache Management

Justin Meza* Jichuan Chang† HanBin Yoon* Onur Mutlu* Parthasarathy Ranganathan†
*Carnegie Mellon University †Hewlett-Packard Labs
{meza,hanbinyoon,onur}@cmu.edu {jichuan.chang,partha.ranganathan}@hp.com

HW/SW Cooperative DRAM Cache Design

- Xiangyao Yu, Christopher J. Hughes, Nadathur Satish, Onur Mutlu, and Srinivas Devadas,
  "Banshee: Bandwidth-Efficient DRAM Caching via Software/Hardware Cooperation"
  *Proceedings of the 50th International Symposium on Microarchitecture (**MICRO**)*, Boston, MA, USA, October 2017.



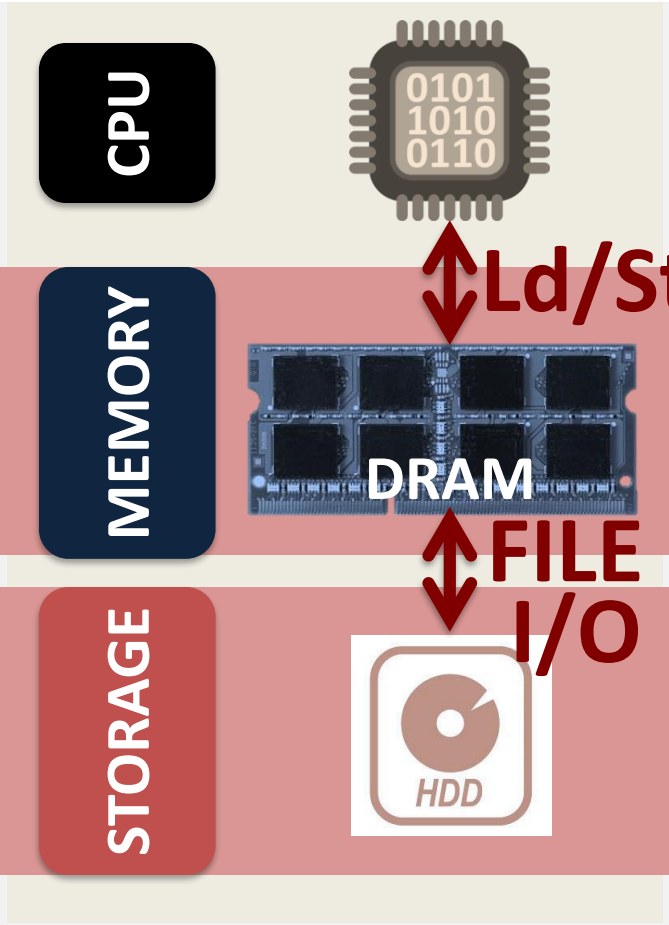
Banshee: Bandwidth-Efficient DRAM Caching via Software/Hardware Cooperation

Xiangyao Yu[1] Christopher J. Hughes[2] Nadathur Satish[2] Onur Mutlu[3] Srinivas Devadas[1]
[1]MIT [2]Intel Labs [3]ETH Zürich

Other Opportunities with Emerging Technologies

- Merging of memory and storage
  - e.g., a single interface to manage all data
- New applications
  - e.g., ultra-fast checkpoint and restore
- More robust system design
  - e.g., reducing data loss
- Processing tightly-coupled with memory
  - e.g., enabling efficient search and filtering

TWO-LEVEL STORAGE MODEL



VOLATILE

FAST

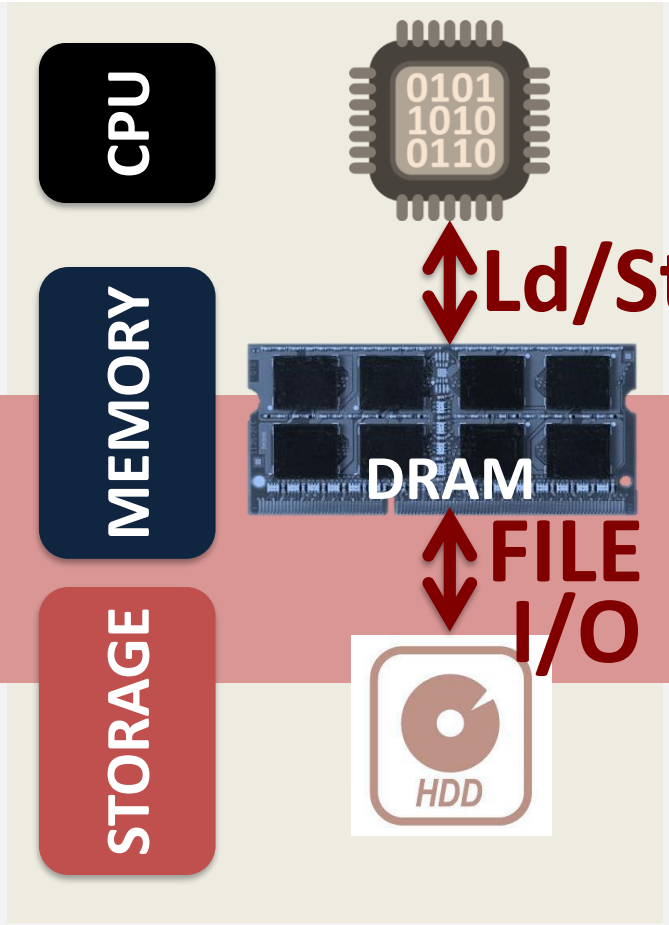
BYTE ADDR

NONVOLATILE

SLOW

BLOCK ADDR

TWO-LEVEL STORAGE MODEL



VOLATILE

FAST

BYTE ADDR

NONVOLATILE

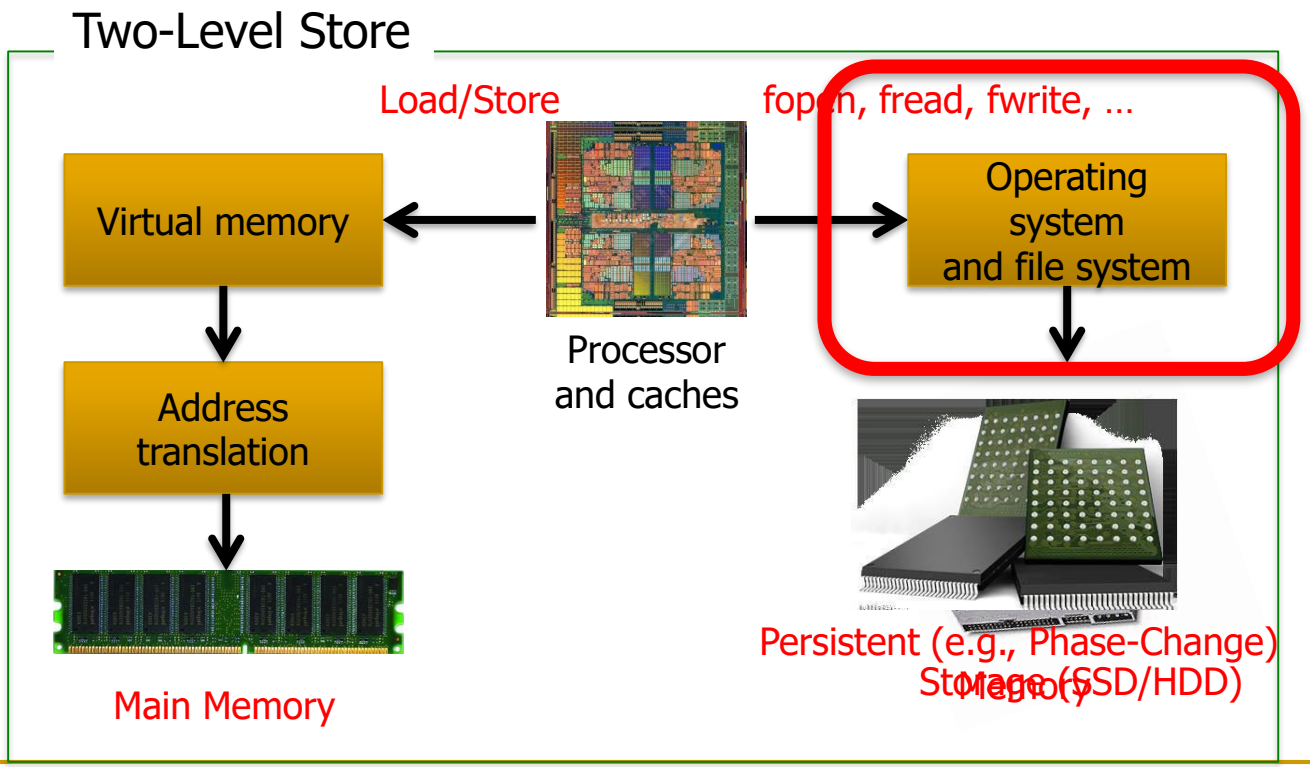
SLOW

BLOCK ADDR

Non-volatile memories combine characteristics of memory and storage

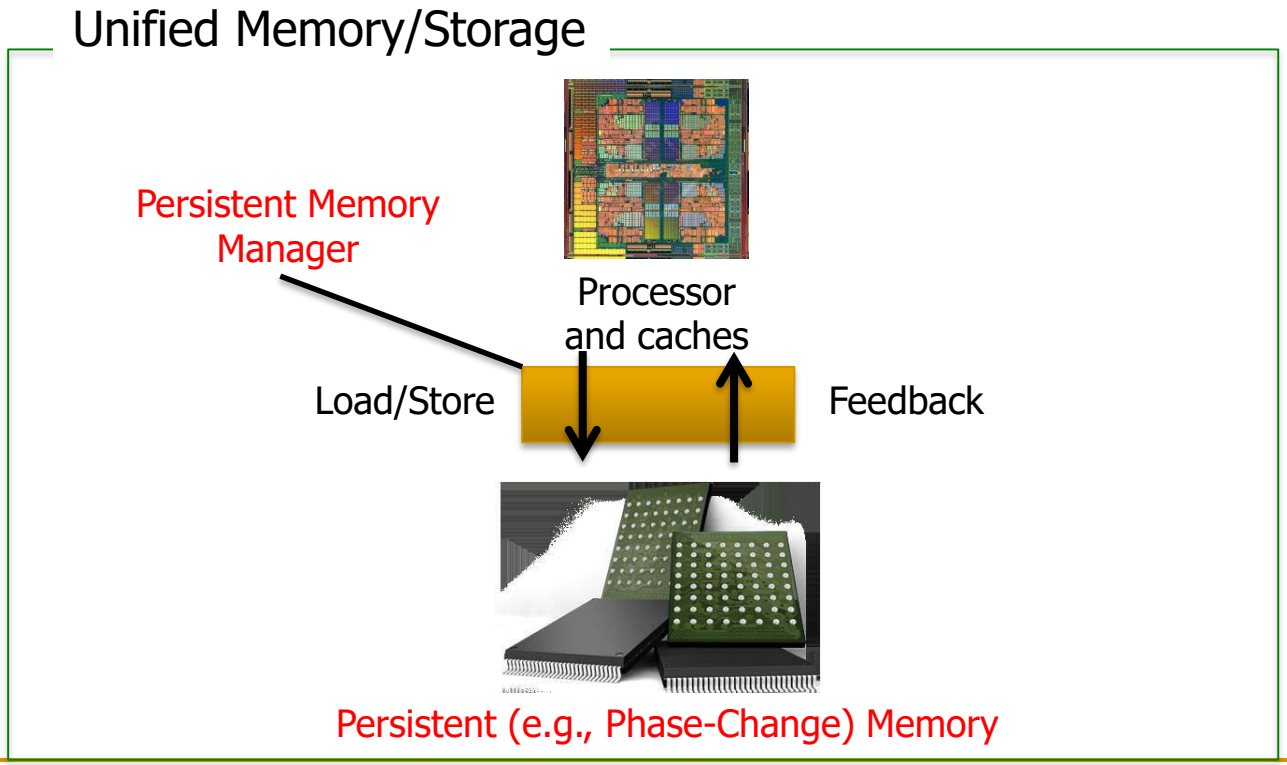
Two-Level Memory/Storage Model

- The traditional two-level storage model is a bottleneck with NVM
  - **Volatile** data in memory → a **load/store** interface
  - **Persistent** data in storage → a **file system** interface
  - Problem: Operating system (OS) and file system (FS) code to locate, translate, buffer data become performance and energy bottlenecks with fast NVM stores



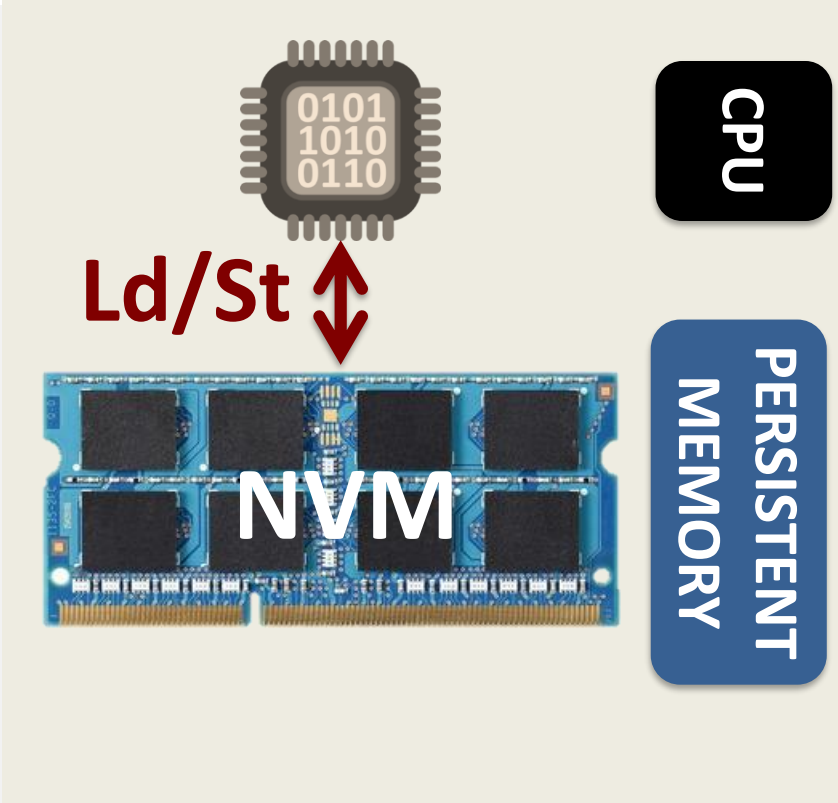
Unified Memory and Storage with NVM

- Goal: Unify memory and storage management in a single unit to eliminate wasted work to locate, transfer, and translate data
  - Improves both energy and performance
  - Simplifies programming model as well



Meza+, "A Case for Efficient Hardware-Software Cooperative Management of Storage and Memory," WEED 2013.

PERSISTENT MEMORY

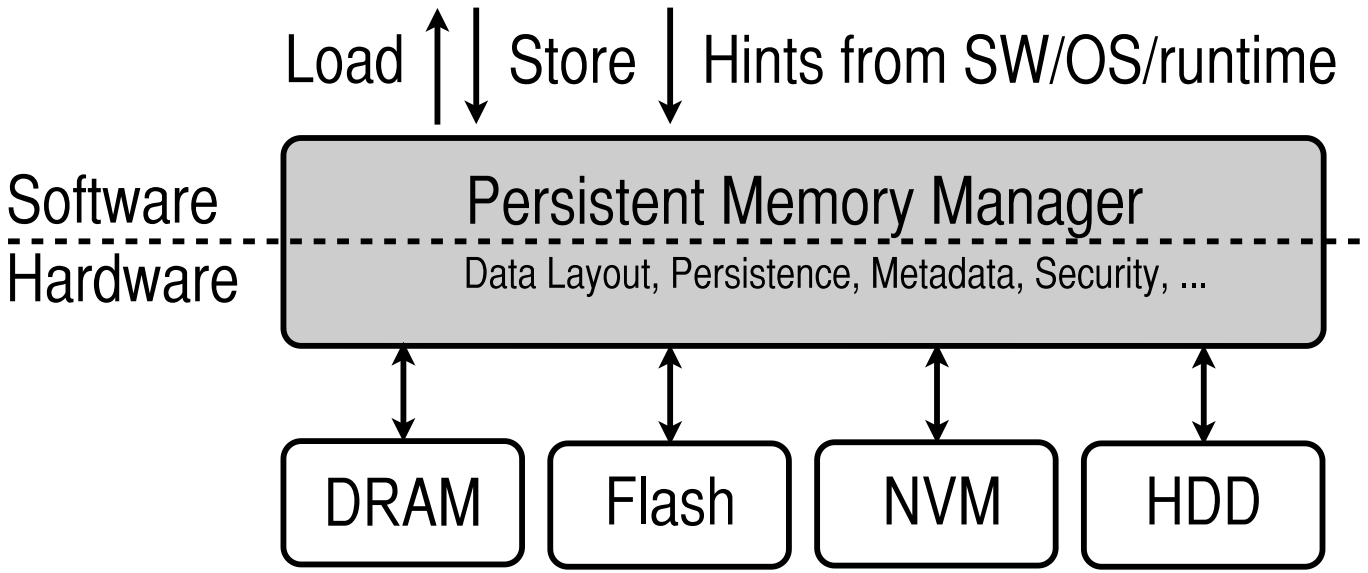


Provides an opportunity to manipulate persistent data directly

The Persistent Memory Manager (PMM)

```
1  int main(void) {
2    // data in file.dat is persistent
3    FILE myData = "file.dat";
4    myData = new int[64];
5  }
6  void updateValue(int n, int value) {
7    FILE myData = "file.dat";
8    myData[n] = value; // value is persistent
9  }
```

Persistent objects

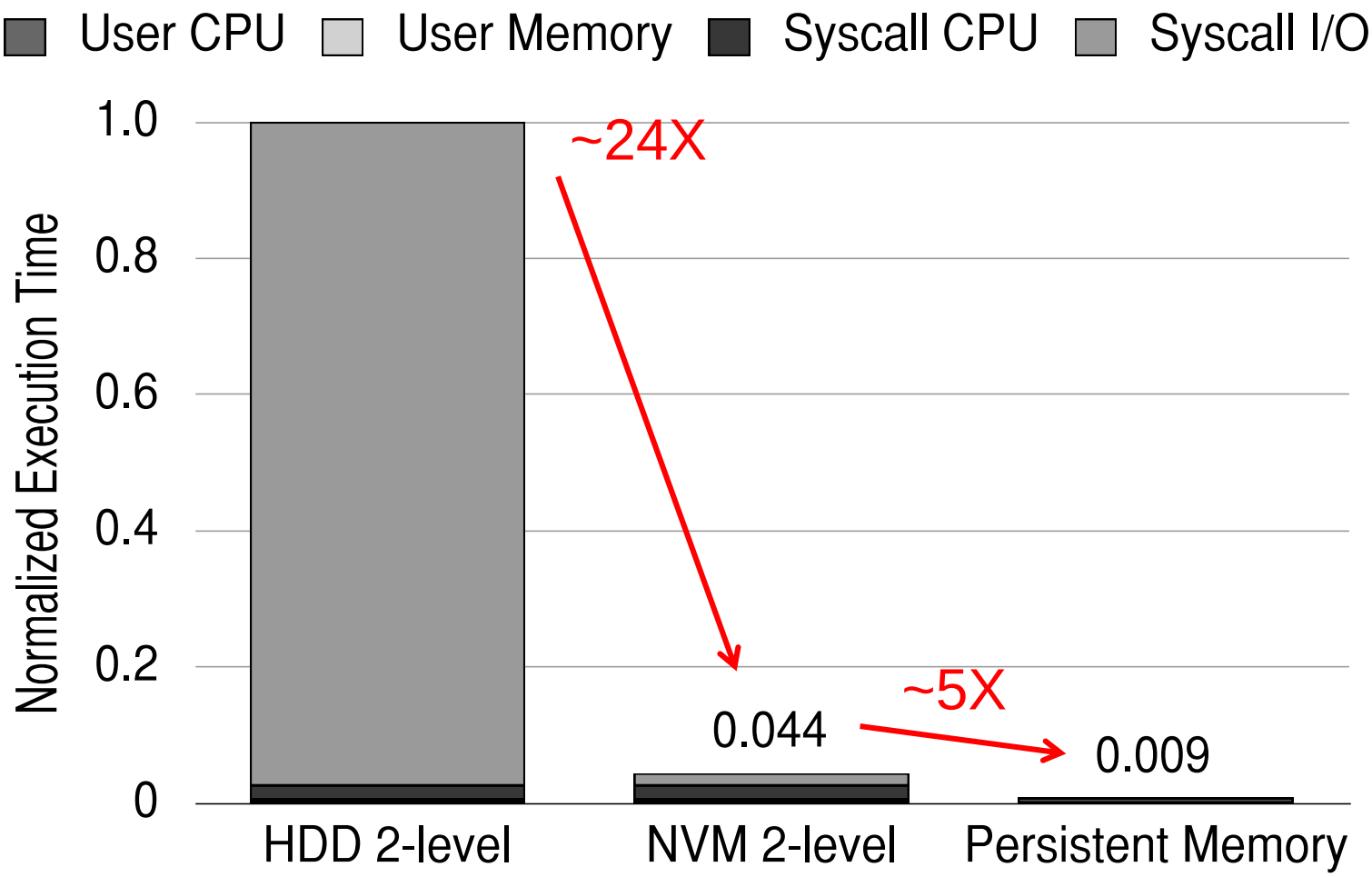


PMM uses access and hint information to allocate, locate, migrate and access data in the heterogeneous array of devices

The Persistent Memory Manager (PMM)

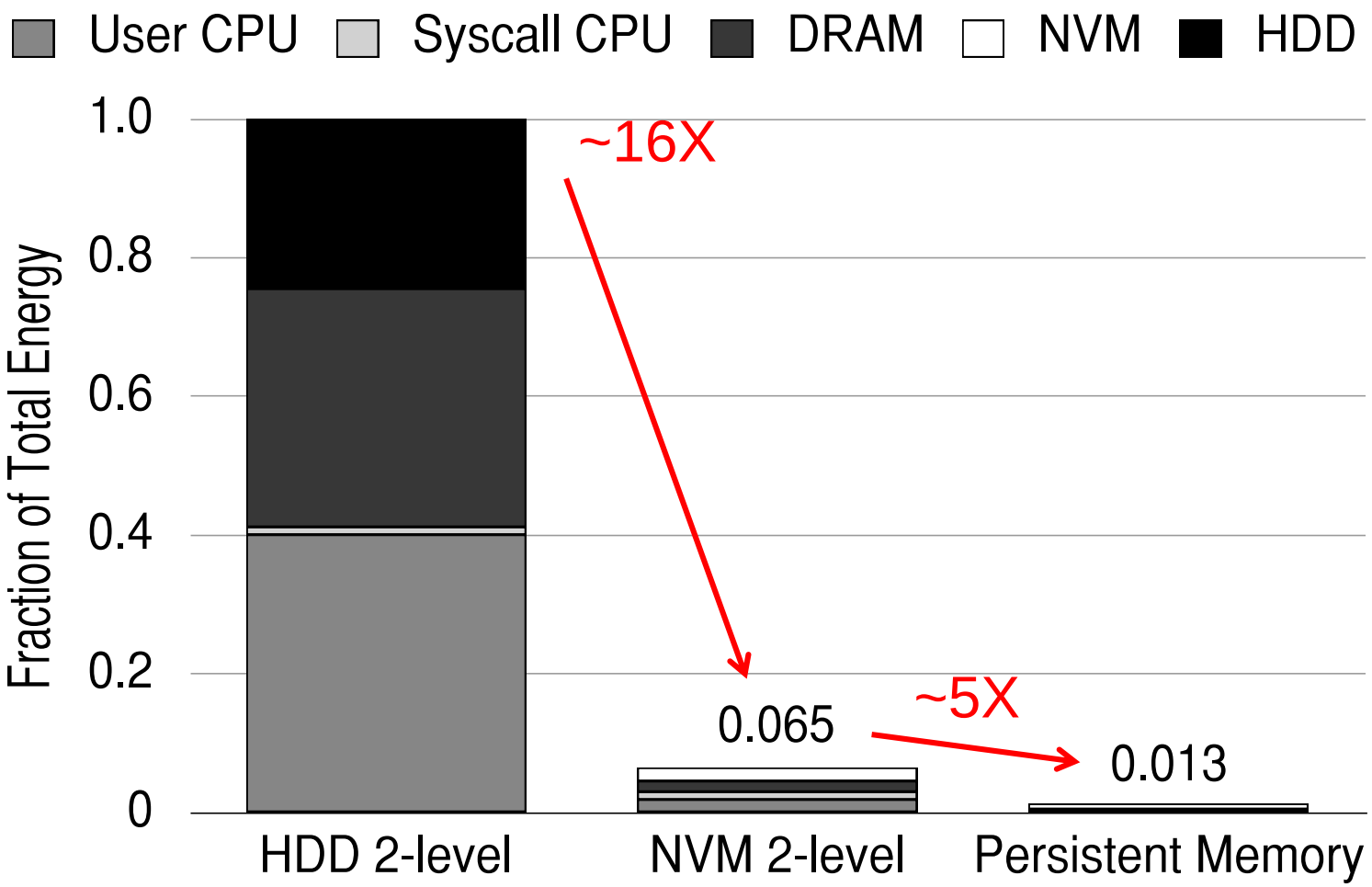
- Exposes a load/store interface to access persistent data
  - Applications can directly access persistent memory → no conversion, translation, location overhead for persistent data
- Manages data placement, location, persistence, security
  - To get the best of multiple forms of storage
- Manages metadata storage and retrieval
  - This can lead to overheads that need to be managed
- Exposes hooks and interfaces for system software
  - To enable better data placement and management decisions
- Meza+, "A Case for Efficient Hardware-Software Cooperative Management of Storage and Memory," WEED 2013.

Performance Benefits of a Single-Level Store



Meza+, "A Case for Efficient Hardware-Software Cooperative Management of Storage and Memory," WEED 2013.

Energy Benefits of a Single-Level Store



Meza+, "A Case for Efficient Hardware-Software Cooperative Management of Storage and Memory," WEED 2013.

On Persistent Memory Benefits & Challenges

- Justin Meza, Yixin Luo, Samira Khan, Jishen Zhao, Yuan Xie, and Onur Mutlu,
  "A Case for Efficient Hardware-Software Cooperative Management of Storage and Memory"
  *Proceedings of the 5th Workshop on Energy-Efficient Design (**WEED**)*, Tel-Aviv, Israel, June 2013. Slides (pptx) Slides (pdf)

A Case for Efficient Hardware/Software Cooperative Management of Storage and Memory

Justin Meza* Yixin Luo* Samira Khan*‡ Jishen Zhao† Yuan Xie†§ Onur Mutlu*
*Carnegie Mellon University †Pennsylvania State University ‡Intel Labs §AMD Research

Challenge and Opportunity

Combined
Memory & Storage

Challenge and Opportunity

A Unified Interface to
All Data

Another Key Challenge in Persistent Memory

Programming Ease

to Exploit Persistence

Enabling Crash Consistency

- Jinglei Ren, Jishen Zhao, Samira Khan, Jongmoo Choi, Yongwei Wu, and Onur Mutlu,
  "ThyNVM: Enabling Software-Transparent Crash Consistency in Persistent Memory Systems"
  *Proceedings of the 48th International Symposium on Microarchitecture (**MICRO**)*, Waikiki, Hawaii, USA, December 2015.
  [Slides (pptx) (pdf)] [Lightning Session Slides (pptx) (pdf)] [Poster (pptx) (pdf)]
  [Source Code]

ThyNVM: Enabling Software-Transparent Crash Consistency in Persistent Memory Systems

Jinglei Ren*† Jishen Zhao‡ Samira Khan†′ Jongmoo Choi+† Yongwei Wu* Onur Mutlu†

†Carnegie Mellon University *Tsinghua University
‡University of California, Santa Cruz ′University of Virginia +Dankook University

Enabling Storage Consistency

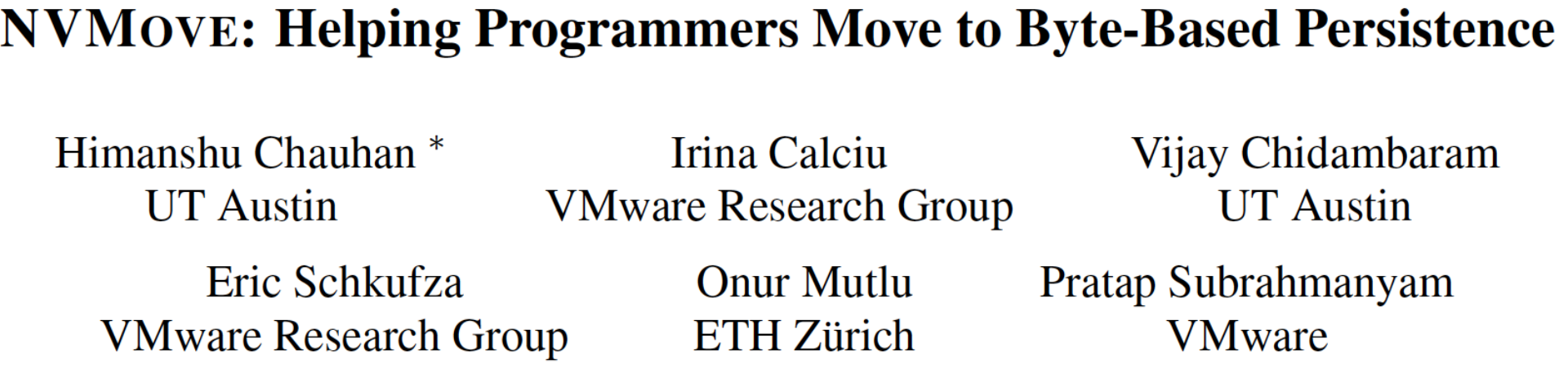
- Youyou Lu, Jiwu Shu, Long Sun, and Onur Mutlu,
  "Loose-Ordering Consistency for Persistent Memory"
  *Proceedings of the 32nd IEEE International Conference on Computer Design (**ICCD**)*, Seoul, South Korea, October 2014. [Slides (pptx) (pdf)]

Loose-Ordering Consistency for Persistent Memory

Youyou Lu †, Jiwu Shu † §, Long Sun † and Onur Mutlu ‡
†Department of Computer Science and Technology, Tsinghua University, Beijing, China
§State Key Laboratory of Computer Architecture, Institute of Computing Technology,
Chinese Academy of Sciences, Beijing, China
‡Computer Architecture Laboratory, Carnegie Mellon University, Pittsburgh, PA, USA
luyy09@mails.tsinghua.edu.cn, shujw@tsinghua.edu.cn, sun-l12@mails.tsinghua.edu.cn, onur@cmu.edu

Tools/Libraries to Help Programmers

- Himanshu Chauhan, Irina Calciu, Vijay Chidambaram, Eric Schkufza, Onur Mutlu, and Pratap Subrahmanyam, **"NVMove: Helping Programmers Move to Byte-Based Persistence"**
  *Proceedings of the 4th Workshop on Interactions of NVM/Flash with Operating Systems and Workloads (**INFLOW**)*, Savannah, GA, USA, November 2016.
  [Slides (pptx) (pdf)]



NVMove: Helping Programmers Move to Byte-Based Persistence

Himanshu Chauhan * — UT Austin
Irina Calciu — VMware Research Group
Vijay Chidambaram — UT Austin
Eric Schkufza — VMware Research Group
Onur Mutlu — ETH Zürich
Pratap Subrahmanyam — VMware

Persistent Memory Control Infrastructure

- Jishen Zhao, Onur Mutlu, and Yuan Xie,
  "FIRM: Fair and High-Performance Memory Control for Persistent Memory Systems"
  *Proceedings of the 47th International Symposium on Microarchitecture (**MICRO**)*, Cambridge, UK, December 2014. [Slides (pptx) (pdf)]
  [Lightning Session Slides (pptx) (pdf)] [Poster (pptx) (pdf)]

FIRM: Fair and High-Performance Memory Control for Persistent Memory Systems

Jishen Zhao*♮†, Onur Mutlu†, Yuan Xie‡*
*Pennsylvania State University, †Carnegie Mellon University, ‡University of California, Santa Barbara, ♮Hewlett-Packard Labs
*juz138@cse.psu.edu, †onur@cmu.edu, ‡yuanxie@ece.ucsb.edu

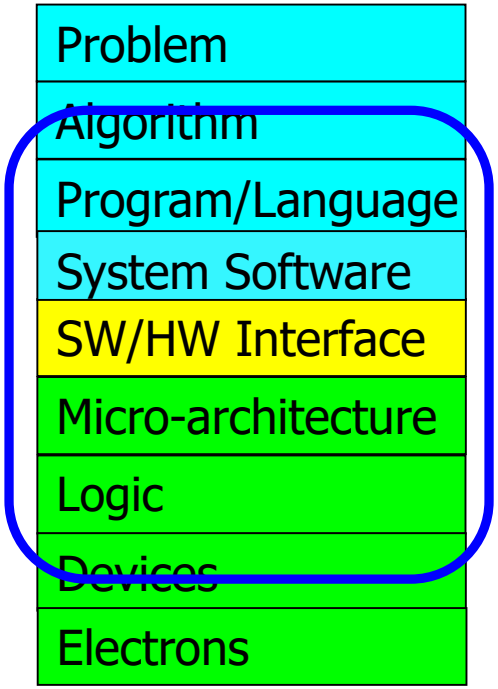
The Future of Emerging Technologies is Bright

- Regardless of challenges
  - in underlying technology and overlying problems/requirements

Can enable:

- Orders of magnitude improvements

- New applications and computing systems



Yet, we have to

- Think across the stack

- Design enabling systems

Challenge and Opportunity for Future

Fundamentally

(More) Scalable

Computing Architectures

Agenda

- Major Trends Affecting Main Memory
- Key Challenges and Solution Directions
  - Robustness: Reliability and Security
  - Energy and Performance: In-Memory Computation
  - Low Latency/Energy and Latency/Energy/Reliability Tradeoffs
  - Scalability and More: Enabling Emerging Technologies
- Solution Principles
- Concluding Remarks

Some Solution Principles (So Far)

- Data-centric system design & intelligence spread around
  - Do not center everything around traditional computation units
- Better cooperation across layers of the system
  - Careful co-design of components and layers: system/arch/device
  - Better, richer, more expressive and flexible interfaces
- Better-than-worst-case design
  - Do not optimize for the worst case
  - Worst case should not determine the common case
- Heterogeneity in design (specialization, asymmetry)
  - Enables a more efficient design (No one size fits all)

Some Solution Principles (More Compact)

- Data-centric design
- All components intelligent
- Better cross-layer communication, better interfaces
- Better-than-worst-case design
- Heterogeneity
- Flexibility, adaptability

Agenda

- Major Trends Affecting Main Memory
- Key Challenges and Solution Directions
  - Robustness: Reliability and Security
  - Energy and Performance: In-Memory Computation
  - Low Latency/Energy and Latency/Energy/Reliability Tradeoffs
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- Solution Principles
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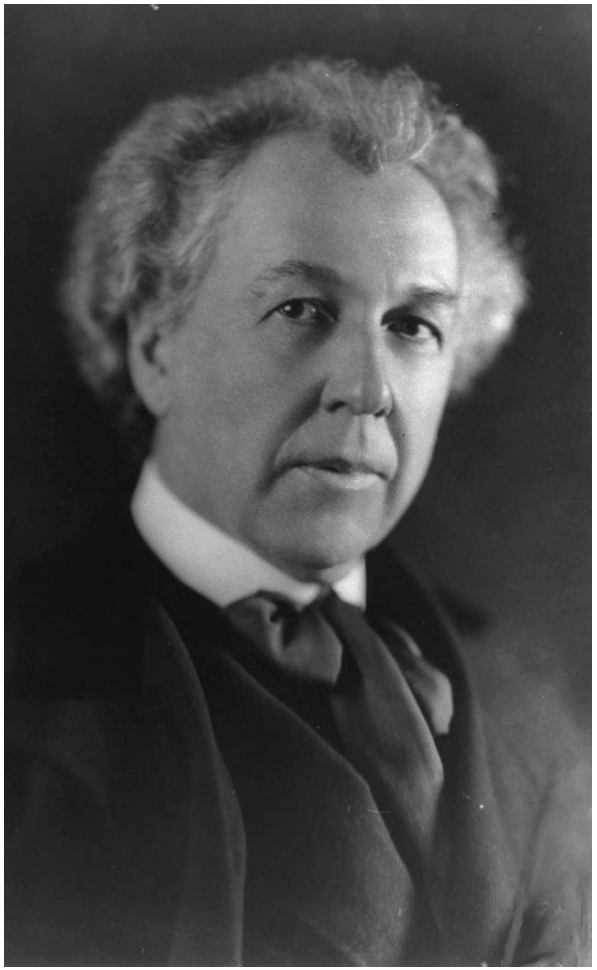
Concluding Remarks

A Quote from A Famous Architect

- "architecture [...] based upon principle, and not upon precedent"

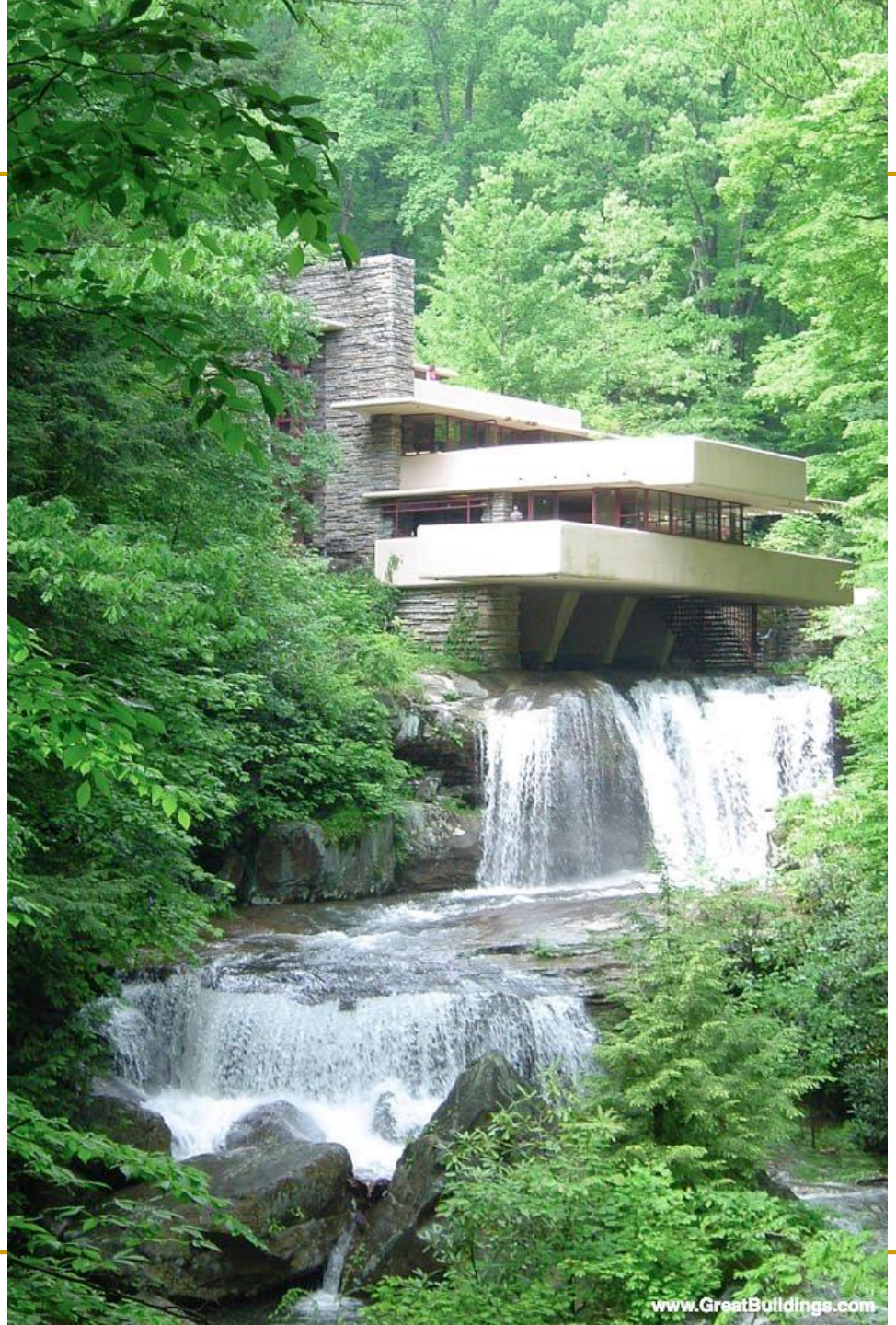


Precedent-Based Design?

- "architecture [...] based upon principle, and not upon precedent"

Principled Design

- "architecture [...] based upon principle, and not upon precedent"


www.GreatBuildings.com

The Overarching Principle

Organic architecture

From Wikipedia, the free encyclopedia

Organic architecture is a philosophy of architecture which promotes harmony between human habitation and the natural world through design approaches so sympathetic and well integrated with its site, that buildings, furnishings, and surroundings become part of a unified, interrelated composition.

A well-known example of organic architecture is Fallingwater, the residence Frank Lloyd Wright designed for the Kaufmann family in rural Pennsylvania. Wright had many choices to locate a home on this large site, but chose to place the home directly over the waterfall and creek creating a close, yet noisy dialog with the rushing water and the steep site. The horizontal striations of stone masonry with daring cantilevers of colored beige concrete blend with native rock outcroppings and the wooded environment.

Another Example: Precedent-Based Design

Source: http://cookiemagik.deviantart.com/art/Train-station-207266944

Principled Design

Source: By Toni_V, CC BY-SA 2.0, https://commons.wikimedia.org/w/index.php?curid=4087256

Another Principled Design

Source: By Martín Gómez Tagle - Lisbon, Portugal, CC BY-SA 3.0, https://commons.wikimedia.org/w/index.php?curid=13764903

Source: http://www.arcspace.com/exhibitions/unsorted/santiago-calatrava/

Principle Applied to Another Structure

Source: By 準建築人手札網站 Forgemind ArchiMedia - Flickr: IMG_2489.JPG, CC BY 2.0, https://commons.wikimedia.org/w/index.php?curid=51492930, https://en.wikipedia.org/wiki/Santiago_Calatrava

Source: https://www.dezeen.com/2016/08/29/santiago-calatrava-oculus-world-trade-center-transportation-hub-new-york-photographs-hufton-crow/

The Overarching Principle

Zoomorphic architecture

From Wikipedia, the free encyclopedia

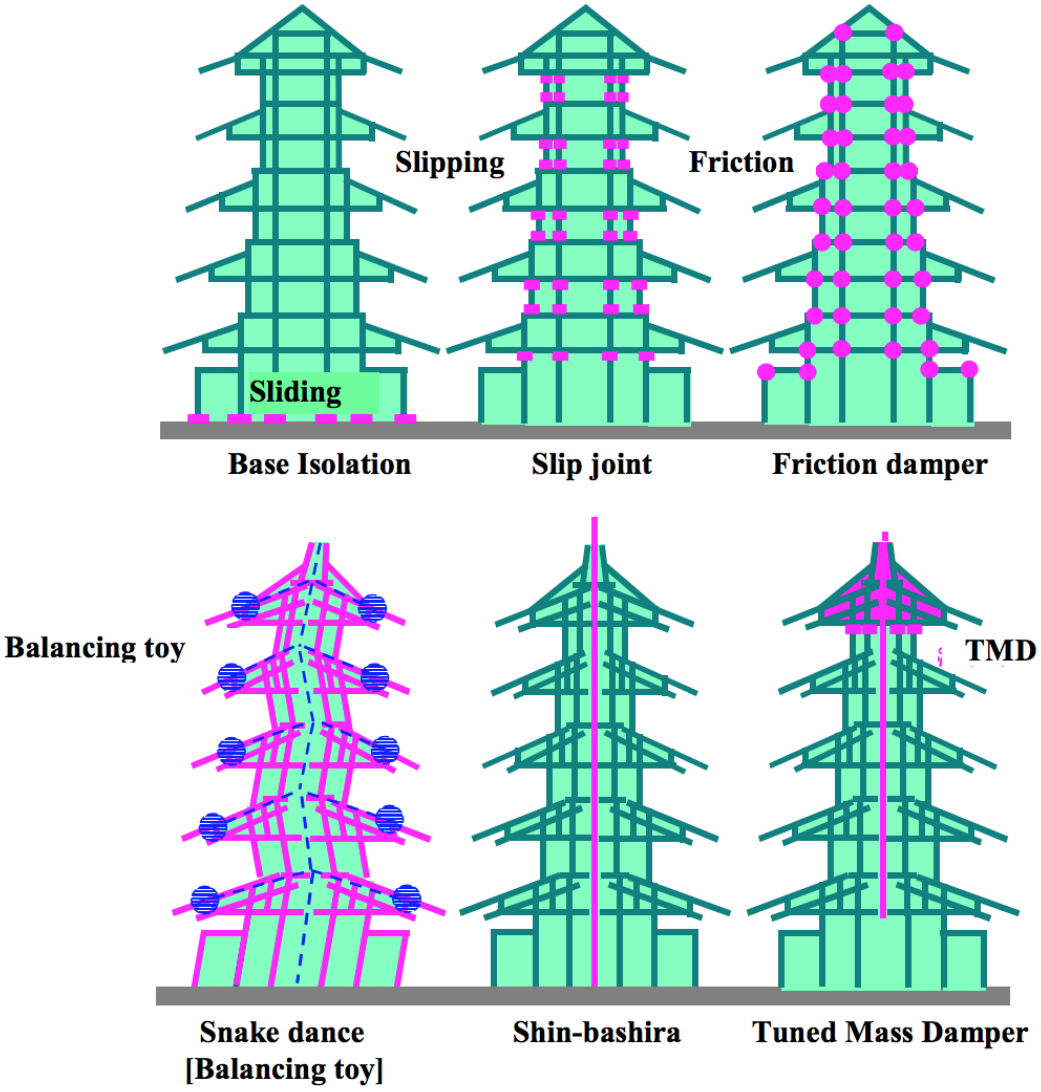
Zoomorphic architecture is the practice of using animal forms as the inspirational basis and blueprint for architectural design. "While animal forms have always played a role adding some of the deepest layers of meaning in architecture, it is now becoming evident that a new strand of biomorphism is emerging where the meaning derives not from any specific representation but from a more general allusion to biological processes."[1]

Some well-known examples of Zoomorphic architecture can be found in the TWA Flight Center building in New York City, by Eero Saarinen, or the Milwaukee Art Museum by Santiago Calatrava, both inspired by the form of a bird's wings.[3]

Another Principled Design

Source: https://web-japan.org/nipponia/nipponia33/en/topic/

Another Principled Design (II)



Source: http://www.iitk.ac.in/nicee/wcee/article/1229.pdf
http://www.hms.civil.uminho.pt/sahc/2010/79.pdf

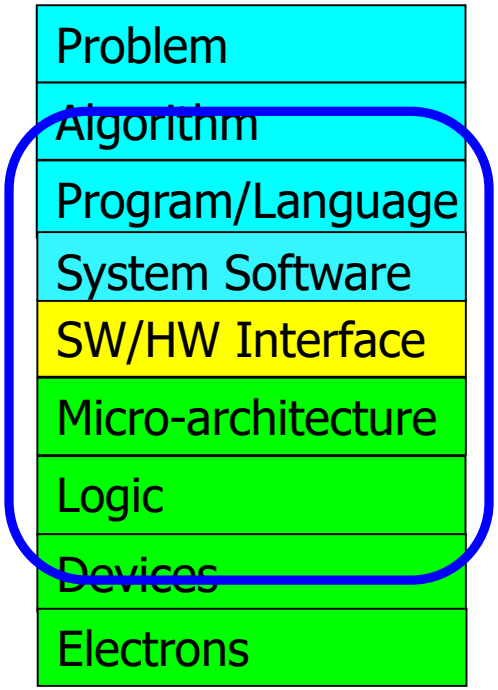
Overarching Principles for Computing?

Source: http://spectrum.ieee.org/image/MjYzMzAyMg.jpeg

Concluding Remarks

- It is time to design principled system architectures to solve the memory problem
- Discover design principles for fundamentally secure and reliable computer architectures
- Design complete systems to be balanced and energy-efficient, i.e., low latency and data-centric (or memory-centric)
- Enable new and emerging memory architectures
- This can
  - Lead to **orders-of-magnitude** improvements
  - **Enable new applications & computing platforms**
  - **Enable better understanding of nature**
  - **…**

We Need to Think Across the Stack



If In Doubt, See Other Doubtful Technologies

- A very "doubtful" emerging technology
  - for at least two decades

Proceedings of the IEEE, Sept. 2017

Error Characterization, Mitigation, and Recovery in Flash-Memory-Based Solid-State Drives

This paper reviews the most recent advances in solid-state drive (SSD) error characterization, mitigation, and data recovery techniques to improve both SSD's reliability and lifetime.

By Yu Cai, Saugata Ghose, Erich F. Haratsch, Yixin Luo, and Onur Mutlu

https://arxiv.org/pdf/1706.08642

Rethinking Memory System Design
(for Data-Intensive Computing)

Onur Mutlu
omutlu@gmail.com
https://people.inf.ethz.ch/omutlu

August 29, 2018

NVMSA-RTCSA Joint Keynote Talk

SAFARI

ETH zürich

Carnegie Mellon

Acknowledgments

- My current and past students and postdocs
  - Rachata Ausavarungnirun, Abhishek Bhowmick, Amirali Boroumand, Rui Cai, Yu Cai, Kevin Chang, Saugata Ghose, Kevin Hsieh, Tyler Huberty, Ben Jaiyen, Samira Khan, Jeremie Kim, Yoongu Kim, Yang Li, Jamie Liu, Lavanya Subramanian, Donghyuk Lee, Yixin Luo, Justin Meza, Gennady Pekhimenko, Vivek Seshadri, Lavanya Subramanian, Nandita Vijaykumar, HanBin Yoon, Jishen Zhao, ...
- My collaborators
  - Can Alkan, Chita Das, Phil Gibbons, Sriram Govindan, Norm Jouppi, Mahmut Kandemir, Mike Kozuch, Konrad Lai, Ken Mai, Todd Mowry, Yale Patt, Moinuddin Qureshi, Partha Ranganathan, Bikash Sharma, Kushagra Vaid, Chris Wilkerson, ...

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- CyLab
- Alibaba, AMD, Google, Facebook, HP Labs, Huawei, IBM, Intel, Microsoft, Nvidia, Oracle, Qualcomm, Rambus, Samsung, Seagate, VMware

Slides Not Covered But Could Be Useful

Readings, Videos, Reference Materials

Accelerated Memory Course (~6.5 hours)

- ACACES 2018
  - Memory Systems and Memory-Centric Computing Systems
  - Taught by Onur Mutlu July 9-13, 2018
  - ~6.5 hours of lectures

- Website for the Course including Videos, Slides, Papers
  - https://people.inf.ethz.ch/omutlu/acaces2018.html
  - https://www.youtube.com/playlist?list=PL5Q2soXY2Zi-HXxomthrpDpMJm05P6J9x

- All Papers are at:
  - https://people.inf.ethz.ch/omutlu/projects.htm
  - Final lecture notes and readings (for all topics)

Reference Overview Paper I

Enabling the Adoption of Processing-in-Memory: Challenges, Mechanisms, Future Research Directions

SAUGATA GHOSE, KEVIN HSIEH, AMIRALI BOROUMAND,
RACHATA AUSAVARUNGNIRUN
Carnegie Mellon University

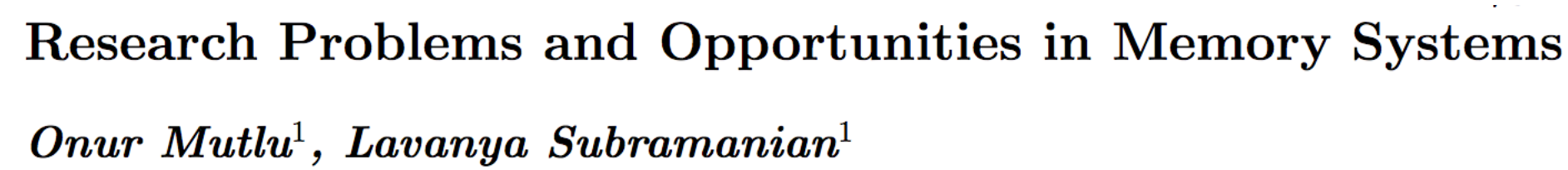
ONUR MUTLU
ETH Zürich and Carnegie Mellon University

Saugata Ghose, Kevin Hsieh, Amirali Boroumand, Rachata Ausavarungnirun, Onur Mutlu, **"Enabling the Adoption of Processing-in-Memory: Challenges, Mechanisms, Future Research Directions"**
Invited Book Chapter, to appear in 2018.
[Preliminary arxiv.org version]

https://arxiv.org/pdf/1802.00320.pdf

Reference Overview Paper II

- Onur Mutlu and Lavanya Subramanian,
  "Research Problems and Opportunities in Memory Systems"
  *Invited Article in Supercomputing Frontiers and Innovations (**SUPERFRI**)*, 2014/2015.

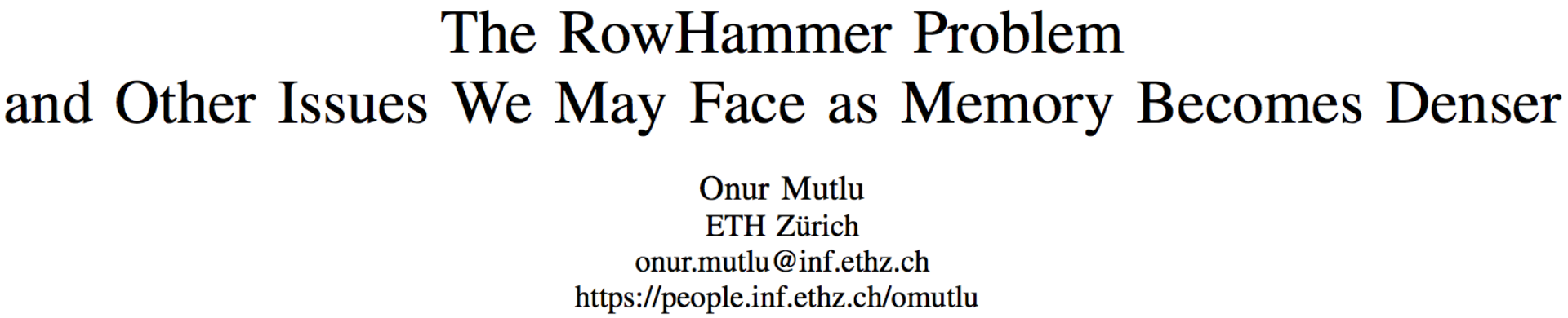

Research Problems and Opportunities in Memory Systems

Onur Mutlu[1], *Lavanya Subramanian*[1]

https://people.inf.ethz.ch/omutlu/pub/memory-systems-research_superfri14.pdf

Reference Overview Paper III

- Onur Mutlu,
  "The RowHammer Problem and Other Issues We May Face as Memory Becomes Denser"
  *Invited Paper in Proceedings of the Design, Automation, and Test in Europe Conference (**DATE**)*, Lausanne, Switzerland, March 2017.
  [Slides (pptx) (pdf)]


The RowHammer Problem
and Other Issues We May Face as Memory Becomes Denser

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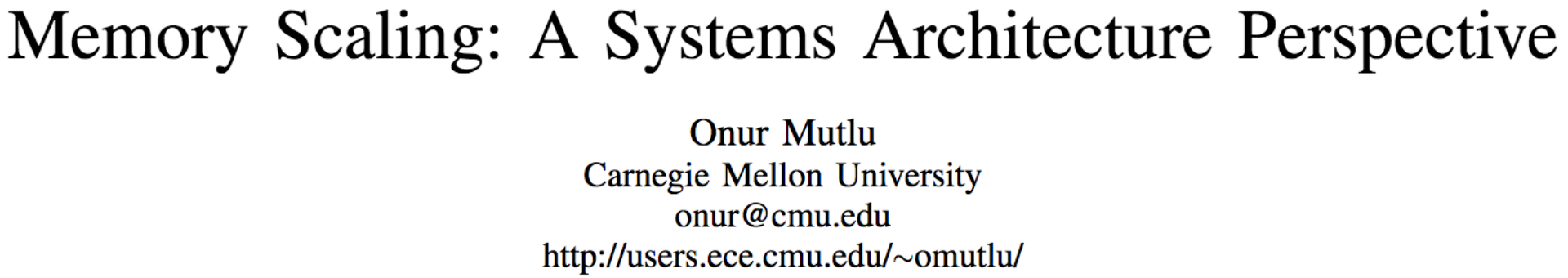
https://people.inf.ethz.ch/omutlu

https://people.inf.ethz.ch/omutlu/pub/rowhammer-and-other-memory-issues_date17.pdf

Reference Overview Paper IV

- Onur Mutlu,
  "Memory Scaling: A Systems Architecture Perspective"
  *Technical talk at MemCon 2013 (**MEMCON**)*, Santa Clara, CA, August 2013. [Slides (pptx) (pdf)]
  [Video] [Coverage on StorageSearch]



Memory Scaling: A Systems Architecture Perspective

Onur Mutlu
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onur@cmu.edu
http://users.ece.cmu.edu/~omutlu/

https://people.inf.ethz.ch/omutlu/pub/memory-scaling_memcon13.pdf

Reference Overview Paper V

Proceedings of the IEEE, Sept. 2017

Error Characterization, Mitigation, and Recovery in Flash-Memory-Based Solid-State Drives

This paper reviews the most recent advances in solid-state drive (SSD) error characterization, mitigation, and data recovery techniques to improve both SSD's reliability and lifetime.

By Yu Cai, Saugata Ghose, Erich F. Haratsch, Yixin Luo, and Onur Mutlu

https://arxiv.org/pdf/1706.08642

Related Videos and Course Materials (I)

- Undergraduate Computer Architecture Course Lecture Videos (2015, 2014, 2013)
- Undergraduate Computer Architecture Course Materials (2015, 2014, 2013)

- Graduate Computer Architecture Course Lecture Videos (2017, 2015, 2013)
- Graduate Computer Architecture Course Materials (2017, 2015, 2013)

- Parallel Computer Architecture Course Materials (Lecture Videos)

Related Videos and Course Materials (II)

- **Freshman Digital Circuits and Computer Architecture Course Lecture Videos (2018, 2017)**
- **Freshman Digital Circuits and Computer Architecture Course Materials (2018)**

- **Memory Systems Short Course Materials**
  (Lecture Video on Main Memory and DRAM Basics)

Some Open Source Tools (I)

- Rowhammer – Program to Induce RowHammer Errors
  - https://github.com/CMU-SAFARI/rowhammer
- Ramulator – Fast and Extensible DRAM Simulator
  - https://github.com/CMU-SAFARI/ramulator
- MemSim – Simple Memory Simulator
  - https://github.com/CMU-SAFARI/memsim
- NOCulator – Flexible Network-on-Chip Simulator
  - https://github.com/CMU-SAFARI/NOCulator
- SoftMC – FPGA-Based DRAM Testing Infrastructure
  - https://github.com/CMU-SAFARI/SoftMC
- Other open-source software from my group
  - **https://github.com/CMU-SAFARI/**
  - **http://www.ece.cmu.edu/~safari/tools.html**

Some Open Source Tools (II)

- MQSim – A Fast Modern SSD Simulator
  - https://github.com/CMU-SAFARI/MQSim
- Mosaic – GPU Simulator Supporting Concurrent Applications
  - https://github.com/CMU-SAFARI/Mosaic
- IMPICA – Processing in 3D-Stacked Memory Simulator
  - https://github.com/CMU-SAFARI/IMPICA
- SMLA – Detailed 3D-Stacked Memory Simulator
  - https://github.com/CMU-SAFARI/SMLA
- HWASim – Simulator for Heterogeneous CPU-HWA Systems
  - https://github.com/CMU-SAFARI/HWASim

- Other open-source software from my group
  - **https://github.com/CMU-SAFARI/**
  - **http://www.ece.cmu.edu/~safari/tools.html**

More Open Source Tools (III)

- A lot more open-source software from my group
  - https://github.com/CMU-SAFARI/
  - http://www.ece.cmu.edu/~safari/tools.html

Referenced Papers

- All are available at

  https://people.inf.ethz.ch/omutlu/projects.htm

  http://scholar.google.com/citations?user=7XyGUGkAAAAJ&hl=en

  https://people.inf.ethz.ch/omutlu/acaces2018.html

Ramulator: A Fast and Extensible DRAM Simulator

[IEEE Comp Arch Letters'15]

Ramulator Motivation

- DRAM and Memory Controller landscape is changing
- Many new and upcoming standards
- Many new controller designs
- A fast and easy-to-extend simulator is very much needed

Segment	*DRAM Standards & Architectures*
Commodity	DDR3 (2007) [14]; DDR4 (2012) [18]
Low-Power	LPDDR3 (2012) [17]; LPDDR4 (2014) [20]
Graphics	GDDR5 (2009) [15]
Performance	eDRAM [28], [32]; RLDRAM3 (2011) [29]
3D-Stacked	WIO (2011) [16]; WIO2 (2014) [21]; MCDRAM (2015) [13]; HBM (2013) [19]; HMC1.0 (2013) [10]; HMC1.1 (2014) [11]
Academic	SBA/SSA (2010) [38]; Staged Reads (2012) [8]; RAIDR (2012) [27]; SALP (2012) [24]; TL-DRAM (2013) [26]; RowClone (2013) [37]; Half-DRAM (2014) [39]; Row-Buffer Decoupling (2014) [33]; SARP (2014) [6]; AL-DRAM (2015) [25]

Table 1. Landscape of DRAM-based memory

Ramulator

- Provides out-of-the box support for many DRAM standards:
  - DDR3/4, LPDDR3/4, GDDR5, WIO1/2, HBM, plus new proposals (SALP, AL-DRAM, TLDRAM, RowClone, and SARP)
- ~2.5X faster than fastest open-source simulator
- Modular and extensible to different standards

Simulator (clang -O3)	*Cycles (10^6)*		*Runtime (sec.)*		*Req/sec (10^3)*		*Memory (MB)*
	Random	*Stream*	*Random*	*Stream*	*Random*	*Stream*	
Ramulator	652	411	752	249	133	402	2.1
DRAMSim2	645	413	2,030	876	49	114	1.2
USIMM	661	409	1,880	750	53	133	4.5
DrSim	647	406	18,109	12,984	6	8	1.6
NVMain	666	413	6,881	5,023	15	20	4,230.0

Table 3. Comparison of five simulators using two traces

Case Study: Comparison of DRAM Standards

Standard	*Rate (MT/s)*	*Timing (CL-RCD-RP)*	*Data-Bus (Width×Chan.)*	*Rank-per-Chan*	*BW (GB/s)*
DDR3	1,600	11-11-11	64-bit × 1	1	11.9
DDR4	2,400	16-16-16	64-bit × 1	1	17.9
SALP†	1,600	11-11-11	64-bit × 1	1	11.9
LPDDR3	1,600	12-15-15	64-bit × 1	1	11.9
LPDDR4	2,400	22-22-22	32-bit × 2*	1	17.9
GDDR5 [12]	6,000	18-18-18	64-bit × 1	1	44.7
HBM	1,000	7-7-7	128-bit × 8*	1	119.2
WIO	266	7-7-7	128-bit × 4*	1	15.9
WIO2	1,066	9-10-10	128-bit × 8*	1	127.2

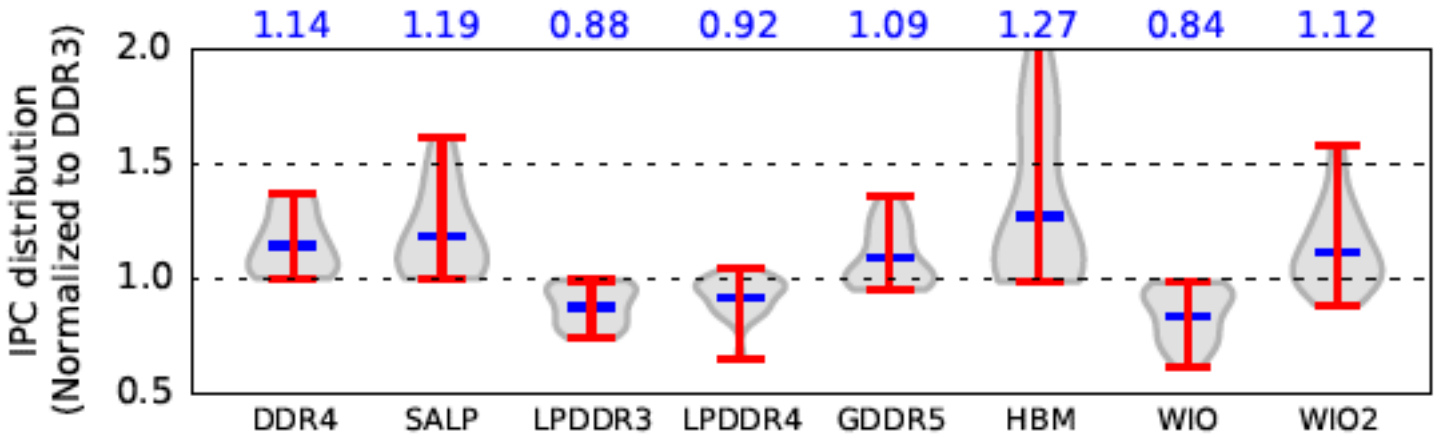


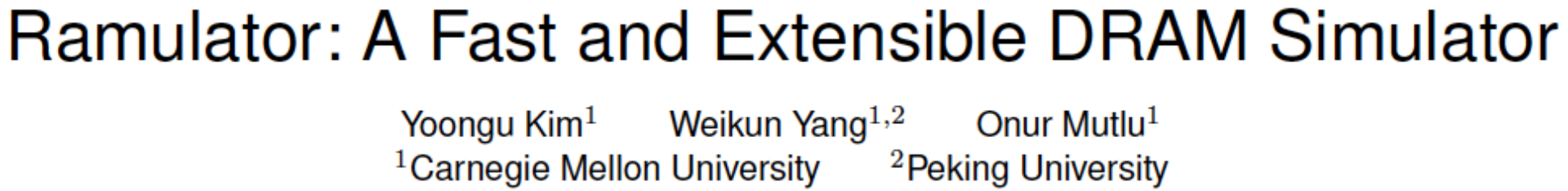
Figure 2. Performance comparison of DRAM standards

Across 22 workloads, simple CPU model

Ramulator Paper and Source Code

- Yoongu Kim, Weikun Yang, and Onur Mutlu,
  "Ramulator: A Fast and Extensible DRAM Simulator"
  IEEE Computer Architecture Letters (***CAL***), March 2015.
  [Source Code]

- Source code is released under the liberal MIT License
  - https://github.com/CMU-SAFARI/ramulator



End of Backup Slides

Brief Self Introduction

- Onur Mutlu
  - Full Professor @ ETH Zurich CS, since September 2015 (officially May 2016)
  - Strecker Professor @ Carnegie Mellon University ECE/CS, 2009-2016, 2016-…
  - PhD from UT-Austin, worked at Google, VMware, Microsoft Research, Intel, AMD
  - https://people.inf.ethz.ch/omutlu/
  - omutlu@gmail.com (Best way to reach me)
  - https://people.inf.ethz.ch/omutlu/projects.htm
- Research and Teaching in:
  - Computer architecture, computer systems, hardware security, bioinformatics
  - Memory and storage systems
  - Hardware security, safety, predictability
  - Fault tolerance
  - Hardware/software cooperation
  - Architectures for bioinformatics, health, medicine
  - …